

Vol. 50 • No. 1

January 2007



Microwave Journal

Radar/Antennas

**Use of Military Antenna
Technology in Modern
Communications**

**Design of a
Non-symmetric Ground
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**Integrated Short
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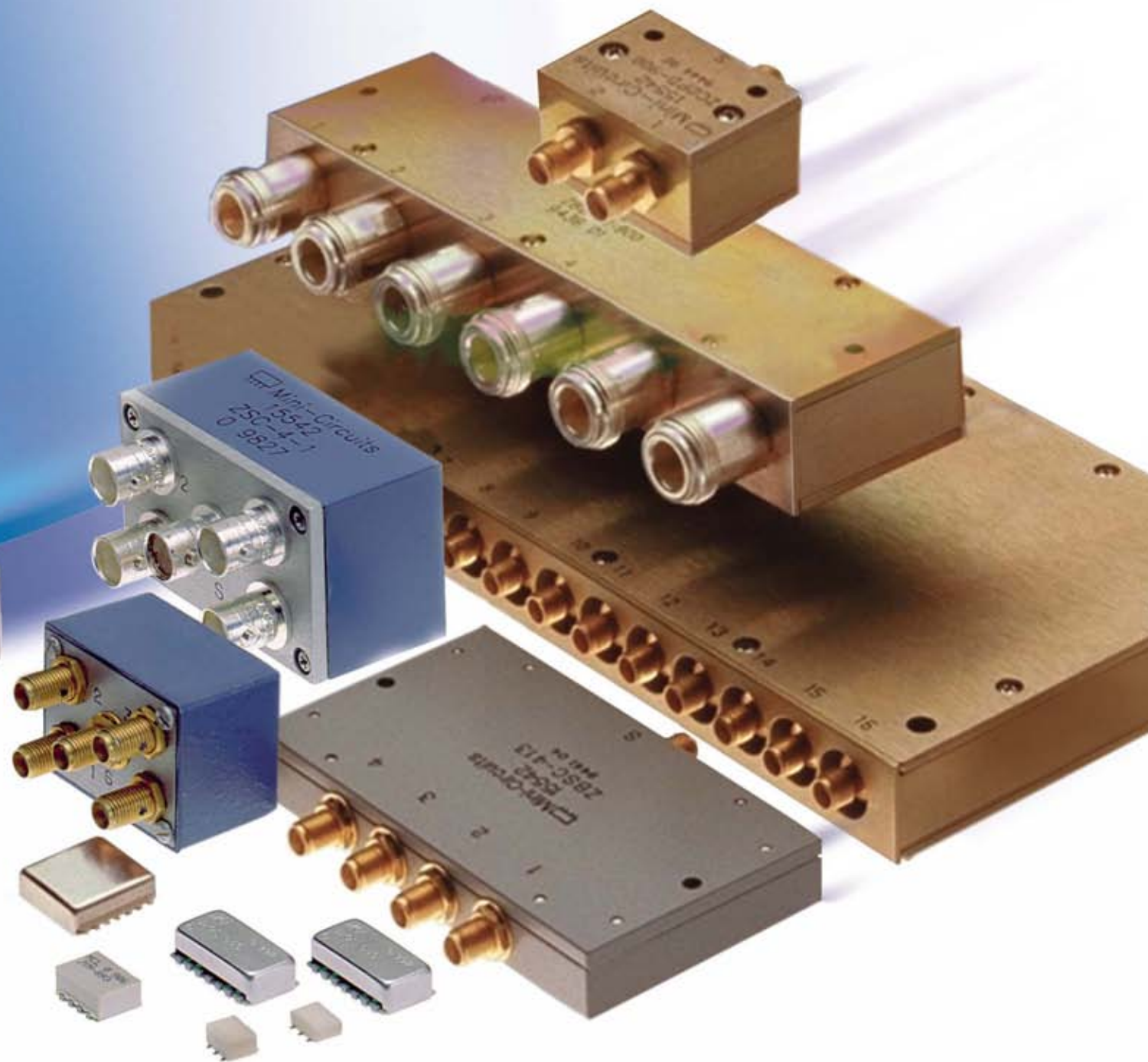
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Our November cover included the image of a MEMS chip, which was manufactured by WiSpry. We apologize for not giving them proper attribution for the image.

THIS MONTH ON THE WEB

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A complete wrap-up of all news, information and product announcements at this year's IEEE Radio and Wireless Symposium, including a detailed look at the new products on display at RWS 2007.



JTRS/SINCGARS Ultra-broadband
(30 to 2000 MHz) Airborne Blade
Antenna for Sub-sonic Aircraft and
Helicopters

By Joseph R. Jahoda
Chief Technology Officer
Astron Wireless Inc.

A white paper introducing "HESA™ Technology," a unique and proprietary set of advanced techniques providing high efficiency, sensitivity and accuracy in Astron's miniaturized and standard DF antenna systems.

RF Component Industry Review: July-September 2006

Strategy Analytics reports that almost 60 percent of leading suppliers of RF components reported significant profits in Q3. The majority of RF component suppliers reported strong profits in the third quarter of 2006, due in large part to the continued strength in demand for cellphone components.



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EAST MEETS WEST



As I write this, I've just returned from the Asia Pacific Microwave Conference (APMC) in Yokohama, Japan. Having never been to Japan, this was a new experience for me. While I enjoyed the cultural differences that Japan offers, I was also struck by the similarities between East and West.

The big news in Japan all week wasn't about the national economy, education or politics. It was all about Dice-K. As in Daisuke Matsuzaka, the 26 year-old pitching phenom of the Seibu Lions. This was the final week of negotiations with the Boston Red Sox, and all talk revolved around the potential deal. When I mentioned to anyone that I was from Boston, they would immediately exclaim, "Matsuzaka!" My Japanese representative, Mr. Ishii, could recite the Sox lineup as well as any diehard fan. When the deal was culminated at the end of the week, we all celebrated the victory. It seems that when it comes to baseball, it is indeed a small world.

The theme of this year's MTT-S IMS event is "Microwaves Across the Pacific," and like the sport of baseball, our industry has truly become global. Microwave Week is certainly an international event, with attendees and exhibitors representing nearly 30 countries last year. This year, more than 30 percent of the submitted papers came from Asia, and all indications are that we will have the largest Asian attendance in the history of the conference. There has been a good

deal of promotion targeted to the Asia Pacific engineering community, including at the recent APMC, which had representatives from both *Microwave Journal* and MTT-S.

There has been much debate about the show being in Honolulu. However, there's no debating the fact that the MTT-S IMS is the premier industry event of the year. The technical conference is second to none, and offers the opportunity to become current on all of the latest technologies being advanced worldwide. The exhibition is the largest of its kind, bringing together the latest products available, many of which will be debuted at the show. And the event remains the optimum networking environment, where old friendships are renewed and new relationships are established.

I traveled far to attend the APMC, and it was well worth the trip. I saw some old friends and I made some new ones. We talked about business, baseball and many other things. I expect that we'll continue those conversations in June in Honolulu. I hope that you'll join us.

Best wishes for the New Year.

Carl Sheffres
Publisher

PS: Watch for the newly redesigned *Microwave FLASH* email newsletter, which now features weekly updates on the IMS conference and exhibition, as well as travel and entertainment information. You can subscribe to the newsletter at www.mwjjournal.com.

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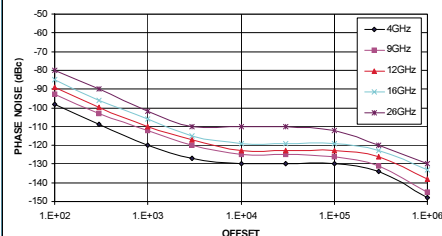
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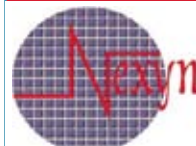
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How it works: Harlan has selected one question from his "Ask Harlan" column to be featured in the magazine. Please visit www.mwjjournal.com/askharlan to provide an answer to this month's featured question (see below). Harlan will be monitoring the responses and will ultimately choose the best answer to the question. Although all of the responses to the featured question will be posted on our web site, we plan to publish the winning answer in the March issue. All responses must be submitted by **February 7, 2007**, to be eligible for the participation of the January question.

The winning response will win a free book from Artech House, along with an "I Asked Harlan!" t-shirt. In addition, everyone who submits a legitimate response will be sent an "I Asked Harlan!" t-shirt.

November Question and Winning Response

The November question was submitted by Subhash Janakiraman from Icon Systems Inc.:

Dear Harlan,

I am trying to test an RF communication link inside an enclosed chamber which is free from RF leakage. I want to emulate a test in the same set up in such a way that the receiver and transmitter are 30 metres apart. I thought calculating the signal strength at this distance and attenuating the transmit power accordingly will justify my testing. Is that true? Am I justified to introduce that attenuation to account for the distance despite the fact that there is no free space loss? Can you point me to a link to calculate the attenuation in the transmit power due to varying distances?

The winning response to the November question is from Melanie Barclay of Scientific Research Corp.:

If I name these variables as follows: Received Power = P_r Transmitter Power = P_t Transmitting Antenna Gain = G_{ta} Spreading Loss = L_s Atmospheric Loss = L_a Receiving Antenna Gain = G_{ra} then the following equation is true: $P_r = P_t + G_{ta} - L_s - L_a + G_{ra}$. Notice that there are two losses in the equation above: Spreading Loss and Atmospheric Loss. Spreading Loss is defined as being related to distance, as: $L_s(\text{dB}) = 32.4 + 20\log(\text{base } 10)(\text{distance in km}) + 20\log(\text{base } 10)(\text{frequency in MHz})$. It appears that you will want to consider this in determining the total losses related to distance. That leaves atmospheric loss (attenuation). The best way to determine the atmospheric loss is to refer to a chart, rather than an equation. I referred to page 14 of a book from Artech House by David Adamy called *EW 101: A First Course in Electronic Warfare*. Figure 2.3 in this book is a graph of atmospheric attenuation (in dB) per kilometer of transmission path. This graph has frequency (GHz) on the X-axis, and Atmospheric Loss (dB per km) on the Y-axis. You will have to look at the graph and find where the line is at the frequency you are transmitting.

Harlan's response:

I don't think the measurement will be valid since the antennas will be too close. You can add the estimated loss due to range, but the loss due to the distorted antenna patterns will have an unknown effect. There is a good discussion of link propagation along with the various factors that affect it in *Introduction to RF Propagation*, J. Seybold, Wiley, 2005, ISBN#0-471-65596-1.

This Month's Question of the Month (answer on-line at www.mwjjournal.com/askharlan)

John McFarland from SNC has submitted this month's question:

Dear Harlan,

Can you explain why the polarization sense of a circularly polarized plane wave changes when it bounces off a reflecting surface? For instance, Right Hand Circular Polarization (RHCP) turns into Left Hand Circular Polarization (LHCP) when undergoing a single bounce off a reflector. The sense of the polarization is defined by the sense (CW/CCW) of rotation of the composite wave (vector sum of the H and V waves) as viewed in the direction of its propagation. When the incident wave undergoes two bounces—say off a dihedral corner reflector—it changes back to the originally incident sense, e.g., RHCP undergoing two bounces will propagate back to the transmitter as RHCP. I know this is what happens from experience, but I have never been able to explain why.

If your response is selected as the winner, you'll receive a free book of your choice from Artech House. Visit the Artech House on-line bookstore at www.artechhouse.com for details on hundreds of professional-level books in microwave engineering and related areas (maximum prize retail value \$150).

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THE USE OF BROADBAND MILITARY ANTENNA TECHNOLOGY IN MODERN COMMUNICATIONS SYSTEMS

For many years, military applications have required broad bandwidth communication links, incorporating antennas that have a similar broadband capability. Often the antennas must operate over a frequency range of several octaves. Consequently, antenna structures that have multi-octave capability have been designed and manufactured and these techniques are now proving very useful in designing antenna products for modern commercial communications systems. This article considers the evolution of commercial communications systems, particularly the increasing demand for new frequency bands before focussing on two types of antenna—spiral and bi-conical—that merit particular consideration.

MODERN COMMUNICATIONS REQUIREMENTS

Many communication systems are required to provide coverage in the 900 MHz frequency range. As networks have evolved, additional bands have been utilised at 1700 to 2200 MHz for DCS, PCS and UMTS capabilities. In addition to these frequencies, coverage is often required for TETRA (approximately 400 MHz), wireless LAN and wireless local loop (approximately 2500, 3500 and 5500 MHz). To satisfy all of these requirements, it is necessary for the antennas to provide effective coverage from 400 MHz to 6 GHz.

In some applications, this may be accomplished by a series of individual antennas each

assigned to a specific portion of the band. To avoid many antenna types being required and for a more discreet appearance, however, it is often preferable to provide coverage over the entire frequency range from a single antenna. Furthermore, there are additional benefits of using just one antenna. Apart from general aesthetics, it can aid in obtaining the planning authorization for the antennas siting, where avoiding a proliferation of antennas cluttering the otherwise clean lines of a new building can satisfy architectural requirements.

Antenna requirements will include a multi-band capability that may be fixed or mobile access point or base station, as most modern equipment is designed to be multi-functional. This multi-functionality is part of the appeal of many modern systems. The professional user will need the equipment to work without having to adjust its operating mode. The transition between operating bands is, therefore, required to be seamless for both the access point and the subscriber. If a subscriber in a given system is to be mobile, then the antenna radiation pattern will be omni-directional so that coverage is assured, regardless of the orientation of the subscriber with respect to the adjacent access points. In a fixed system, the subscriber antenna may be required to be directional, oriented towards the nearest base

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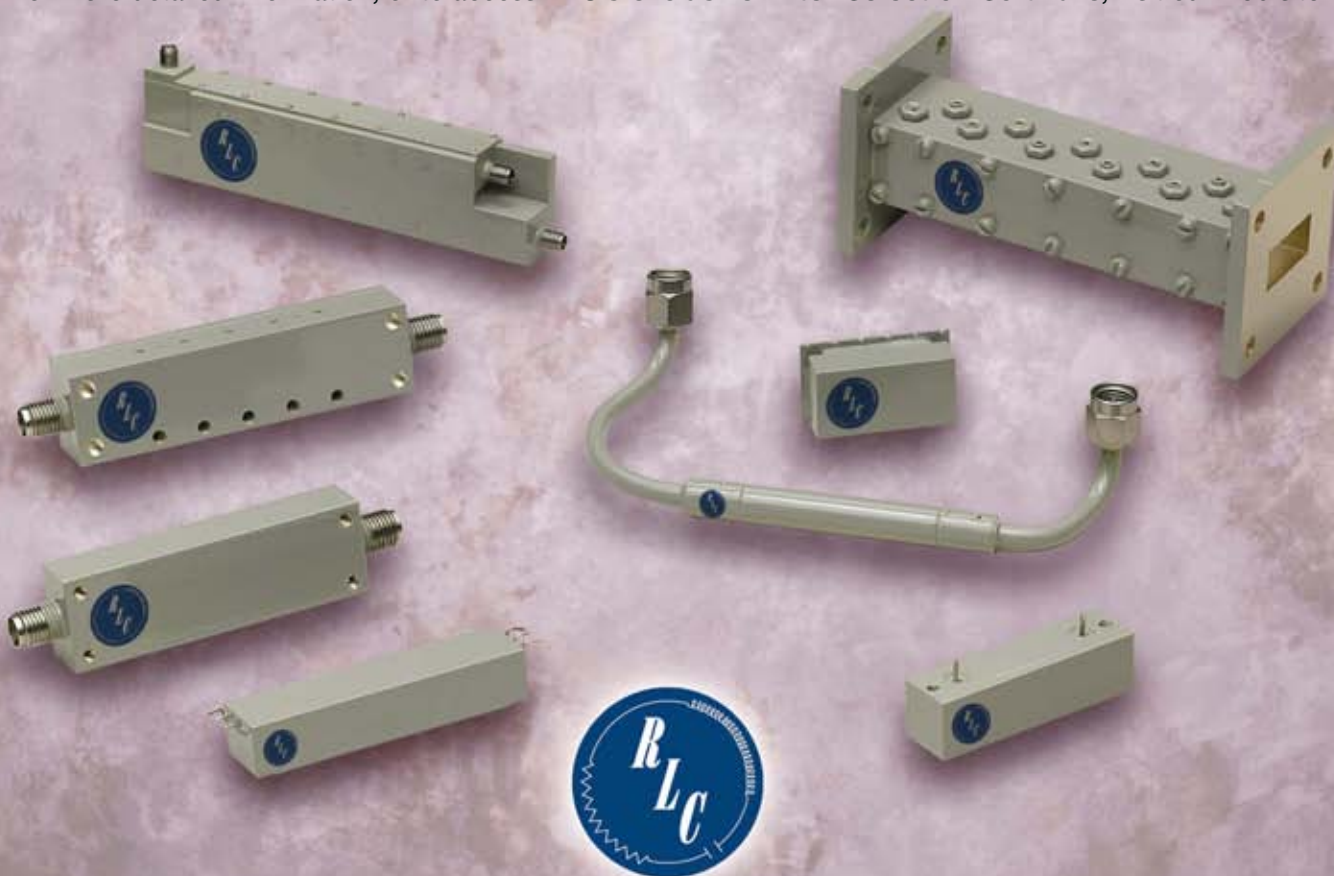
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station for optimum performance. Base stations can be deployed in a number of configurations. Sometimes an omni-directional base station is required and is placed in the centre of a coverage area. In other scenarios, a cluster of sector antennas may be deployed at a single location with each covering a sector of the area around the base station. Systems typically employ sector angles ranging from 30° to 180°. The polarisation used in

systems also varies. It may either be a linear vertical, horizontal or 45° slant, or even circular, each having advantages which vary according to the system protocols and architecture. Further system benefits may be obtained through the use of additional antennas. The provision of spatial diversity, polarisation diversity, adaptive antennas, or multiple-input, multiple-output (MIMO) antenna configurations all serve to increase the statistical

likelihood that a link can be maintained with acceptable signal-to-noise ratio for successful operation. The scope of this article is to consider the performance of a single antenna system, rather than looking at the further benefits that might be obtained by combining several antennas.

SPIRAL ANTENNAS

The spiral antenna has long been used in military applications for direction finding systems and for general threat detection. **Figure 1** shows a typical 2 to 18 GHz, cavity-backed spiral antenna and **Figure 2** shows an electromagnetic simulation performed on such an antenna, indicating the field strengths present on various parts of the structure. In these applications, the antennas generally have requirements for a uniform pattern shape, with respect to amplitude and phase from one antenna to another. Also, the main beam should exhibit a smooth curve without any points of inflection, which is said to be monotonic. A typical radiation pattern for such an antenna is shown in **Figure 3**. It is generally more important in these applications to control the beam shape and match the performance of the antenna from unit to unit than to maximise the gain of the antenna. For many commercial com-

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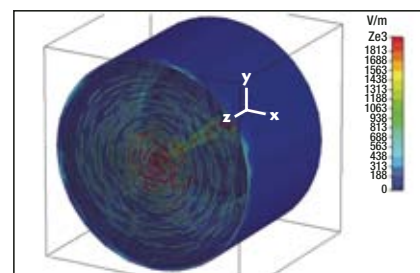
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▲ Fig. 1 A 2 to 18 GHz cavity-backed spiral antenna.



▲ Fig. 2 Electromagnetic simulation of a cavity-backed spiral antenna.

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munication systems, it is more important to fill efficiently an area with a signal than to produce a very precise beam shape. The spiral radiating structure used in this example is very much suited to this mode of operation, but no longer needs to be used in conjunction with a cavity loaded with an absorber. Two types of antenna can then be created using this type of structure: a bi-directional structure where the spiral is allowed to radiate

freely into space in both directions normal to its plane, or a higher gain, uni-directional structure, where a reflector plate is positioned close to the spiral such that the radiation in one direction is reflected and the forward gain is therefore enhanced. **Figure 4** shows a bi-directional spiral antenna. Note the additional proprietary features used to extend the frequency coverage. An electromagnetic simulation of a similar type of antenna is

shown in **Figure 5**. The radiation characteristics for a bi-directional spiral antenna such as this are shown in **Figure 6**. It can be seen that when the polarisation is left-hand circular in a forward direction, it is right-hand circular in the opposite direction. Thus, in a transition region in between, it will be linear. Such a pattern

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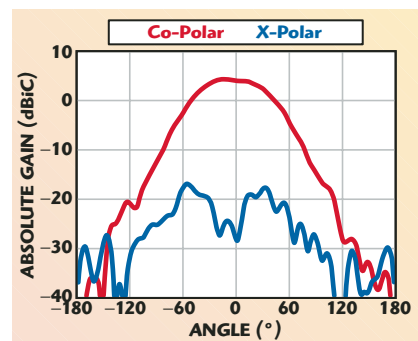
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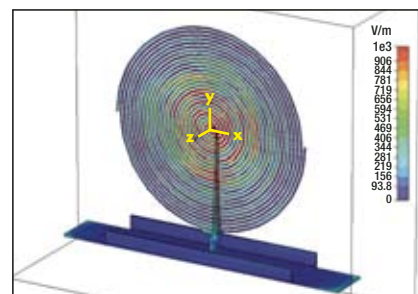
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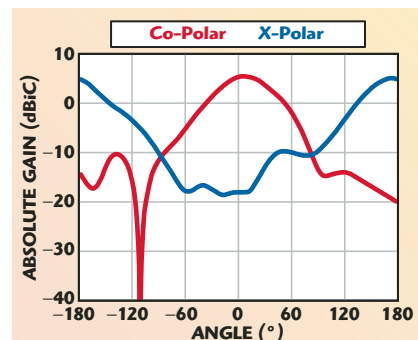
▲ Fig. 3 Typical radiation pattern for a cavity-backed spiral antenna.



▲ Fig. 4 A bi-directional spiral antenna.



▲ Fig. 5 Electromagnetic simulation of a bi-directional spiral antenna.

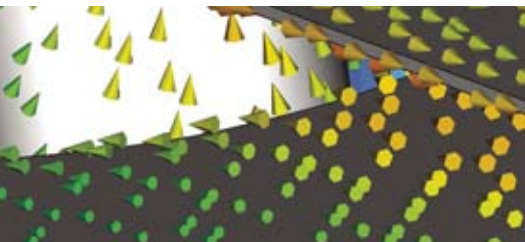


▲ Fig. 6 Typical radiation pattern for a bi-directional spiral antenna.



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is an advantage in many deployments. For example, if an antenna is to be placed in a corridor or hall, then a bi-directional antenna of this type is ideally suited. Sometimes, a more directional antenna is desired while retaining its broadband properties. This would typically be for a deployment in the corner of the area to be covered, such as a large hall or atrium. In this case, the reflector plate serves to increase the gain in the forward di-

rection. **Figure 7** shows a typical radiation pattern for such a uni-directional low profile spiral antenna. Depending upon the size of spiral selected, it is possible to provide coverage across the band between 400 MHz and 6 GHz. These antennas are used in systems where all the communication bands are required to be transmitted or received by a single antenna, either when originally installed or at some time in the future.



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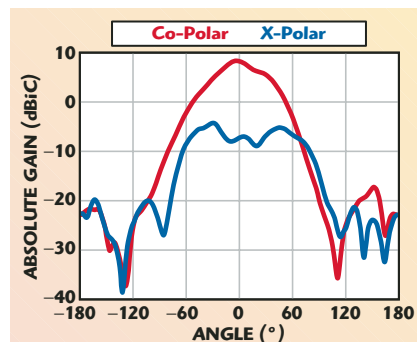


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BI-CONICAL ANTENNAS

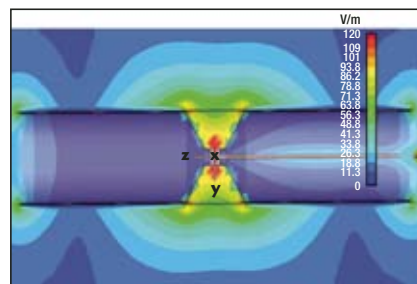
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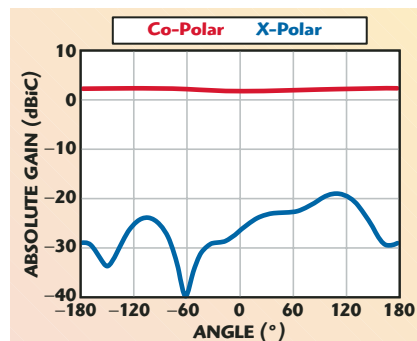
▲ Fig. 7 Typical radiation pattern for a uni-directional spiral antenna.



▲ Fig. 8 A bi-conical antenna.



▲ Fig. 9 Electromagnetic simulation of a bi-conical antenna.



▲ Fig. 10 Typical radiation pattern for a bi-conical antenna.

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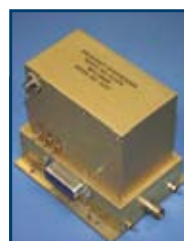
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large frequency range. These antennas produce a linearly polarised signal and exhibit extremely low azimuth ripple, meaning that the omni-directional characteristics are excellent. Depending upon the degree of input return loss degradation that can be tolerated, the effective bandwidth of such a structure is in the region of two octaves. This will depend upon the extent to which the structure has been miniaturised by the choice of transition re-

gion from a cone to a cylinder, or if an entirely conical section has been used. **Figures 8 and 9** show a bi-conical antenna and its electromagnetic simulated results, respectively. **Figure 10** shows its measured performance and the very low ripple in the azimuth pattern can clearly be seen. Although the high power handling capability is not always important in commercial communications systems, the small size of these structures makes them very at-

tractive in this application. For example, a product capable of covering the whole frequency band from 800 MHz to 2.2 GHz can be packaged in a structure of 32 mm diameter by 225 mm long. It is possible to achieve wider bandwidths, but a compromise has to be made in terms of the diameter of the product. A larger diameter could extend the frequency of operation. These antenna structures retain their radiation pattern characteristic over this very wide frequency range. This makes them suitable for microcell and picocell applications where the antennas can be employed to provide a signal boost (in a railway station, for example). Antennas with this kind of radiation pattern would be the most effective for a central deployment.

CONCLUSION

There is an increasing demand for new frequency bands to be added to modern communications networks. As these new frequency bands become available for commercial use, system antennas have to be upgraded to cover these additional frequencies. If an existing antenna was not originally designed with sufficient bandwidth, it will not maintain its performance over these wider frequency ranges. However, design variations, applied to traditional spiral and bi-conical broadband antenna structures, have resulted in commercial products that are well suited to these requirements, using technology originally developed for military applications. ■



Chris Walker received his BSc degree in theoretical physics from Cambridge University in 1982. He has worked with EEV, Litton and CPI, developing vacuum tubes for radar and communication systems. He joined European Antennas,

part of Cobham Antennas Division of Cobham plc, in 1998, where he has been involved in the design and manufacture of directional flat panel antennas, base station sector antennas and omni-directional antennas within the range from 250 MHz to 40 GHz for military and commercial applications within satellite, data, WiMAX, WLAN, telemetry, security, surveillance and broadcast systems. He is presently technical director of European Antennas Ltd. with responsibility for assessment, modeling and development of antennas for future technologies.

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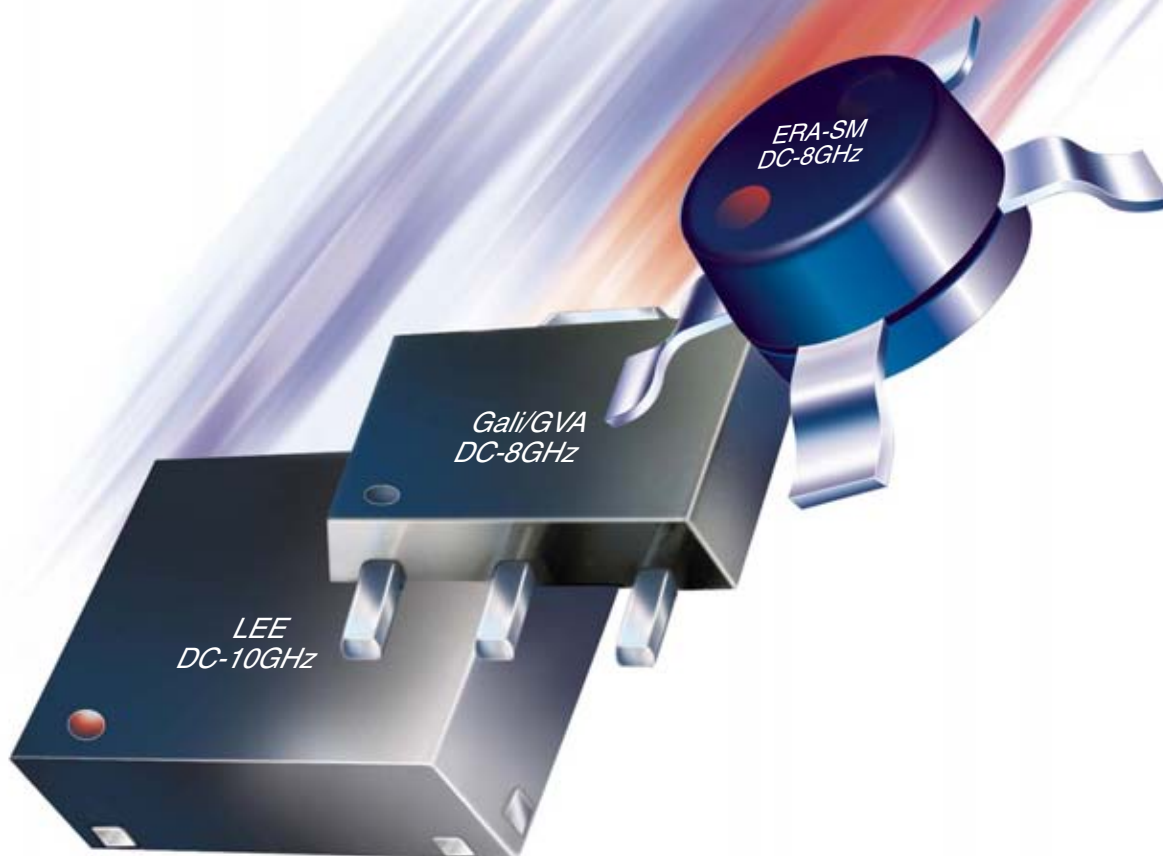
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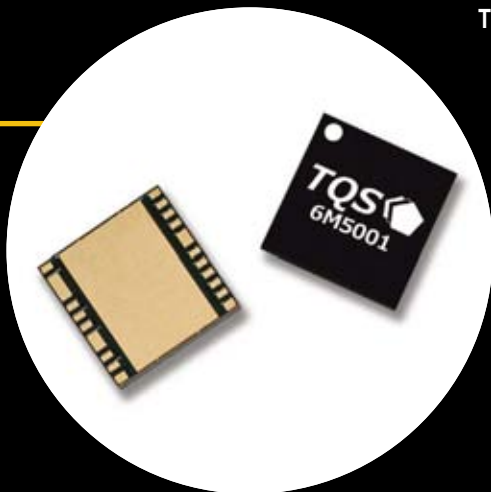
DID YOU KNOW?



FACT #1: RENOWNED AS NIGHTTIME HUNTERS, OWLS ALSO SEE WELL IN DAYLIGHT AND HAVE ACUTE HEARING — SO FINELY TUNED THAT SOME CAN HUNT ENTIRELY BY SOUND.

FACT #2: RENOWNED AS A GaAs INNOVATOR, TRIQUINT ALSO OFFERS THE WORLD'S MOST HIGHLY INTEGRATED QUAD-BAND EDGE AND UMTS (WCDMA) PA MODULES USED BY MAJOR OEMs ACROSS THE GLOBE.

Owls fascinate us. Long the objects of superstition, owls in reality are stealthy and skillful hunters with a voracious appetite for reducing the rodent population, making them great friends of humanity. Although their hunting skill is popularly attributed to great eyesight, they also hear extremely well, making them one of nature's most versatile predators.



TriQuint is known as an innovative GaAs / SAW manufacturer, but our versatility extends much farther and like the owl, our vision is taking us to new fields. We've used our GaAs and SAW heritage to create the world's smallest, most highly integrated RF front-end modules – enabling us to become a leading supplier to the largest wireless handset makers.

The 2007 GSM World Congress in Barcelona will again see TriQuint release a broad range of new products for EDGE and UMTS (WCDMA). Just as owls cover a wide range, so TriQuint continues to work with all major transceiver makers to deliver products with enviable performance: higher integration – greater PAE – smaller size.



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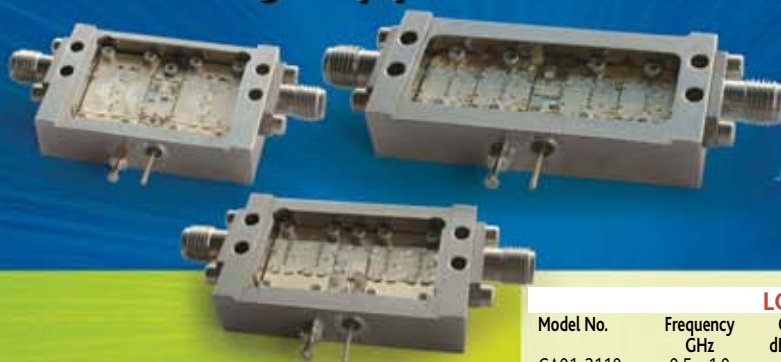
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LOW NOISE OCTAVE BAND AMPLIFIERS

Model No.	Frequency GHz	Gain dB MIN	Noise Figure dB	Output Power (dBm) MIN @ P1 dB Comp PT	3rd Order ICP dBm TYP	VSWR MAX
CA01-2110	0.5 - 1.0	28	1.0 MAX, 0.7 TYP	+10	+20	2.0:1
CA12-2110	1.0 - 2.0	30	1.0 MAX, 0.7 TYP	+10	+20	2.0:1
CA24-2110	2.0 - 4.0	32	1.2 MAX, 1.0 TYP	+10	+20	2.0:1
CA48-2110	4.0 - 8.0	32	1.4 MAX, 1.2 TYP	+10	+20	2.0:1
CA812-3110	8.0 - 12.0	27	1.8 MAX, 1.6 TYP	+10	+20	2.0:1
CA1218-4110	12.0 - 18.0	25	2.0 MAX, 1.8 TYP	+10	+20	2.0:1

ULTRA-BROADBAND & MULTI-OCTAVE BAND AMPLIFIERS

Model No.	Frequency GHz	Gain dB MIN	Noise Figure dB	Output Power (dBm) MIN @ P1 dB Comp PT	3rd Order ICP dBm TYP	VSWR MAX
CA0102-3110	0.1 - 2.0	28	2.0 Max, 1.5 Typ	+10	+20	2.0:1
CA0106-3110	0.1 - 6.0	28	2.0 Max, 1.5 Typ	+10	+20	2.0:1
CA0108-3110	0.1 - 8.0	26	2.2 Max, 1.8 Typ	+10	+20	2.0:1
CA0108-4112	0.1 - 8.0	32	3.0 MAX, 1.8 TYP	+22	+32	2.0:1
CA26-3110	2.0 - 6.0	26	2.0 MAX, 1.5 TYP	+10	+20	2.0:1
CA26-3113	2.0 - 6.0	28	4.0 MAX, 3.0 TYP	+27	+37	2.0:1
CA26-4114	2.0 - 6.0	22	5.0 MAX, 3.5 TYP	+30	+40	2.0:1
CA618-4112	6.0 - 18.0	25	5.0 MAX, 3.5 TYP	+23	+33	2.0:1
CA618-5113	6.0 - 18.0	24	5.0 MAX, 3.5 TYP	+27	+37	2.0:1
CA618-6114	6.0 - 18.0	35	5.0 MAX, 3.5 TYP	+30	+40	2.0:1
CA618-6115	6.0 - 18.0	35	6.0 MAX, 3.5 TYP	+32	+41	2.0:1
CA218-4110	2.0 - 18.0	30	5.0 MAX, 3.5 TYP	+20	+30	2.0:1
CA218-4112	2.0 - 18.0	29	5.0 MAX, 3.5 TYP	+24	+34	2.0:1
CA218-4113	2.0 - 18.0	29	5.0 MAX, 3.5 TYP	+27	+37	2.0:1

NARROW BAND AMPLIFIERS

Model No.	Frequency GHz	Gain dB MIN	Noise Figure dB	Output Power (dBm) MIN @ P1 dB Comp PT	3rd Order ICP dBm TYP	VSWR MAX
LOW NOISE:						
CA01-2110	0.4 - 0.5	28	0.75 MAX, 0.45 TYP	+10	+20	2.0:1
CA01-2112	0.8 - 1.0	28	0.75 MAX, 0.45 TYP	+10	+20	2.0:1
CA12-3116	1.2 - 1.6	25	0.75 MAX, 0.5 TYP	+10	+20	2.0:1
CA23-3110	2.2 - 2.4	30	0.75 MAX, 0.5 TYP	+10	+20	2.0:1
CA23-3110	2.7 - 2.9	29	0.7 MAX, 0.5 TYP	+10	+20	2.0:1
CA34-2110	3.7 - 4.2	28	1.0 MAX, 0.5 TYP	+10	+20	2.0:1
CA56-3110	5.4 - 5.9	40	1.0 MAX, 0.5 TYP	+10	+20	2.0:1
CA78-4110	7.25 - 7.75	32	1.2 MAX, 1.0 TYP	+10	+20	2.0:1
CA910-3110	9.0 - 10.6	25	1.4 MAX, 1.2 TYP	+10	+20	2.0:1
CA1315-3110	13.75 - 15.4	25	1.6 MAX, 1.5 TYP	+10	+20	2.0:1
CA1819-4110	17.7 - 18.3	20	2.0 MAX, 1.8 TYP	+10	+20	2.0:1

MEDIUM POWER:

CA12-3114	1.35 - 1.85	30	4.0 MAX, 3.0 TYP	+33	+41	2.0:1
CA23-4110	2.7 - 2.9	32	4.0 MAX, 3.0 TYP	+33	+41	2.0:1
CA34-6116	3.1 - 3.5	40	4.5 MAX, 3.5 TYP	+35	+43	2.0:1
CA56-5114	5.9 - 6.4	30	5.0 MAX, 4.0 TYP	+30	+40	2.0:1
CA812-6116	8.0 - 12.0	30	5.0 MAX, 4.0 TYP	+33	+41	2.0:1
CA1213-7110	12.2 - 13.25	28	6.0 MAX, 5.5 TYP	+33	+42	2.0:1
CA1218-5116	12.0 - 18.0	35	6.0 MAX, 5.0 TYP	+30	+40	2.0:1
CA1415-7110	14.0 - 15.0	30	5.0 MAX, 4.0 TYP	+30	+40	2.0:1
CA1722-4110	17.0 - 22.0	25	3.5 MAX, 2.8 TYP	+21	+31	2.0:1
CA1718-4110	17.7 - 18.1	25	5.0 MAX, 4.5 TYP	+27	+37	2.0:1

COMPETITIVE PRICING OFFERED

Model No.	Frequency GHz	Gain dB MIN	Noise Figure dB	Output Power (dBm) MIN @ P1 dB Comp PT	Unit Price Qty 1-9 \$US
CA12-A02	1.0-2.0	26	1.6	+10	\$395
CA24-A02	2.0-4.0	26	1.8	+10	\$395
CA48-A02	4.0-8.0	24	2.0	+10	\$395
CA812-A02	8.0-12.0	22	2.5	+10	\$395
CA1218-A02	12.0-18.0	16	3.5	+10	\$395

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Northrop Grumman Expands Radar Role in Missile Testing

In the fall, Northrop Grumman-developed C-band radar for the US Navy participated in the successful test of the Ground-based Midcourse Defense (GMD) system, marking the first time a Navy Strategic Systems Program radar has been used by the US Missile

Defense Agency (MDA) to optimize data collection and enhance mission success. The GMD test occurred on September 1, 2006, and involved launching a ground-based interceptor from Vandenberg Air Force Base, CA.

This test adds to Northrop Grumman's ongoing success using this extremely mobile radar, year-round, to collect data on Navy ballistic missile tests in both Pacific and Atlantic test ranges. As a trusted supplier of transportable large-dish radars, Northrop Grumman has demonstrated the ability to rapidly relocate large radar systems worldwide to remote land locations and aboard sea-based platforms on demand.

The GMD test is one such example of the company's ability to bring a radar on-line to a sea-based platform in a short time frame. Within three weeks of a request for additional assets, Northrop Grumman—under the direction of the US Navy Strategic Systems Program Office—relocated the Navy Mobile Instrumentation System (NMIS) C-band radar from Cape Canaveral, FL, to California, and installed the radar system aboard the Navy ship USNS Pathfinder. The ship was then positioned approximately 600 miles off the coast of California to track the interceptor flight.

"This disassembly, ground transport, reassembly and installation of the Northrop Grumman-developed radar aboard the USNS Pathfinder within a three week window demonstrates Northrop Grumman's ability to respond to rapid real-world situations requiring high performance discriminating radars," said Frank Moore, vice president of the Northrop Grumman Missile Defense Division. "The valuable data collected from this additional radar asset will further enhance MDA's ability to thoroughly analyze system performance and build confidence in future flight tests."

The radar successfully tracked the GMD interceptor from the point it broke the horizon, throughout separation and intercept. Data is being combined with information from other sensors to provide a thorough analysis to MDA of all aspects of the test to make adjustments to ensure future mission success.

The NMIS C-band radar is an instrumentation radar used normally for data collection and Navy missile testing, under contract to Navy SSP. The company has also developed mechanically steered radars to support major US weapons test and evaluation programs for the US Navy, where Northrop Grumman is a major provider of block upgrades.

Raytheon Achieves Satellite Communications Milestone

Raytheon Co.'s Navy Multiband Terminal (NMT) is the first advanced, next-generation satellite communications (SATCOM) system to successfully log on to and communicate with the US Government's Milstar SATCOM system, using low and medium data rate

waveforms. The system will provide naval commanders and sailors with greater data capacity, as well as improved protection against enemy intercept and jamming. Raytheon has also demonstrated that its NMT is fully compatible with existing submarine and shore antennas, an important life-cycle cost-savings objective of the NMT program.

This achievement follows Raytheon's earlier success in developing the first Software Communications Architecture (SCA)-compliant SATCOM system to validate the advanced extended data rate communications waveform. This waveform provides highly protected and high speed communications with the Department of Defense's (DoD) new Advanced Extremely High Frequency satellite constellation planned for operation in 2010. Raytheon's non-proprietary, SCA implementation of these waveforms meets the DoD's vision to make them available for future developments, significantly reducing costs. "Raytheon's designers logged more than 13,000 hours on-board ships and submarines collecting data to understand what matters most to the Navy," said Jerry Powlen, vice president of Network Centric Systems Integrated Communications Systems. "These achievements demonstrate Raytheon's ability to continue to provide the Navy with the most reliable, affordable and user friendly advanced SATCOM capability."

With more than 500 Navy SATCOM systems currently fielded, Raytheon's NMT solution builds on the company's extensive experience and innovative solutions in naval communications. NMT, which replaced several existing SATCOM systems developed and maintained by Raytheon during the last 20 years, is expected to be installed in more than 300 ships, submarines and shore stations.

The Navy's communications program office, which reports to the Navy's program executive office for command, control, communications, computers and intelligence, is responsible for developing and delivering NMT capabilities to the fleet.

"Our NMT SATCOM design features over 95 percent commonality of parts," said Powlen. "For our customer, that means it can share a significant percentage of parts between ships, subs and shore stations, without additional investment and logistic costs. In fact, our total life-cycle design even reduces the number of personnel needed to operate and maintain the system, while minimizing the training needed to support it. We consider these critical features for the future."



Lockheed Martin's Compact Kinetic Energy Missile Successful in Flight Test

armed target, the test also gathered missile performance and lethality data. This flight was the last of three guided flight tests for the year. The key advantages of the CKEM system are its deployability and tremendous overmatch in lethality, which defeats all projected future armored combat vehicles. The CKEM weapon system also provides increased countermeasure effectiveness and survivability while allowing the soldier to engage the toughest and most sophisticated armored targets.

"This test demonstrated the efficacy of CKEM against a difficult target—an up-armored tank—at long range," said Loretta Painter, CKEM Advanced Technology Demonstration (ADT) program manager at the US Army Research and Development Command (RDECOM), Aviation and Missile Research, Development and Engineer-

Lockheed Martin successfully conducted a guided test flight of its Compact Kinetic Energy Missile (CKEM) against a main battle tank recently at Eglin Air Force Base, FL. All objectives for this test were achieved. In addition to demonstrating CKEM's capability against an ar-

ing Center (ARMDEC), Redstone Arsenal, AL. "This test collected target effects data to characterize the lethality of CKEM and validates what CKEM could provide to the warfighter."

"Another successful CKEM test bodes well for our soldiers because it means we are well positioned in being able to develop this tremendously lethal, hit-to-kill technology," said Rick Edwards, vice president-Tactical Missiles for Lockheed Martin Missiles and Fire Control. "We have a long history of successful designing, developing and producing hit-to-kill missile systems. CKEM will expand the battle space, provide increased mutual support and defeat all known threat countermeasures." The remaining flight test planned is designed to demonstrate CKEM's ability to fill current lethality gaps against enhanced reactive armor. CKEM will be particularly effective in bridging the Army's capability gaps identified for the Infantry Brigade Combat Team and the Stryker Brigade Combat Team by ensuring lethality overmatch at both close and extended ranges. CKEM is the next generation kinetic-energy anti-tank missile. It is less than 60 inches long and weighs less than 100 pounds, yet has an extended range for direct fire, line-of-sight engagements and provides the Infantry Brigade Combat Teams, Stryker Brigades and Future Combat System platforms overwhelming lethality overmatch against all potential target sets. ■

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Triumvirate Awarded Multi-role in R&D

On behalf of the armed forces of Italy and Sweden, FMV, Swedish Defence Materiel Administration, has awarded Saab Microwave Systems AB, Selex Sistemi Integrati S.p.A and Elettronica S.p.A the second phase of a three-phase research and development programme supporting the development of the next generation of microwave multi-function, multi-role systems—Multi-role Active Electronically Scanned Antenna (M-AESA).

The programme will be fully financed by the two countries and the three participating companies will exploit the potential of AESA technologies in future defence electronic systems and aim to achieve the product vision of a true multi-role electronics package capable of active and passive sensing, jamming and special communications. It will not only support this vision but also contribute, in the shorter term, to the development of multifunction radar and EW systems.

The introduction of M-AESA technology, comprising digital beam forming, will greatly increase the performance of future microwave systems. Its benefits include the ability to detect, track and identify small targets in complex environments and to detect, track, identify and jam emitter and communication threats, thus providing the possibility of designing flexible multipurpose electronics in advanced platforms. The multipurpose electronics include functions from radar and electronic warfare, as well as communications.

MEAD Consortium Explores MEMS Technology

QinetiQ, acting as the prime and in partnership with 21 other organisations from industry, academia and the UK defence supply chain, has formed the MEMS Applications for Defence (MEAD) consortium. Its remit is to take a new approach to developing MEMS technology for defence purposes in a UK Ministry of Defence (MoD)-backed project worth £3.2 M over three years. Initially, the consortium will road map the technology, explore exploitation routes and investigate novel MEMS approaches for use in two defence application areas.

Firstly, the MoD has a requirement for deployable, unattended sensor networks, and QinetiQ will lead this area. Here the need is for small, lightweight, minimal cost military grade sensors that remove the need for expert placement, alignment and recovery. Typically these sensors fall into four groups: robust, low noise, high sensitivity acoustic microphones; orientation sensors; seismic sensors; and magnetic sensors.

Secondly, there is a need to indicate the presence of explosives, so the MEAD consortium will investigate techniques for sampling air and detecting compounds that warn of the proximity of an explosive device. Smiths Detection will lead this research package. As part of its remit the consortium will also research the potential failure modes of MEMS devices.

Ed Swindle, MoD Research Acquisition Organisation, stated: "This is a great opportunity for the MoD to foster innovation and co-operation across a broad supply base to access leading-edge technology and accelerate its application in a new generation of MEMS devices that address real defence needs. This new partnership model is a key element in the continued process of defence research competition."

Remodelling of Paris Command and Control Centre

The French armaments directorate (DGA) is completely restructuring the information and communication systems of the Paris Strategy Centre, in a project known by the French abbreviation OE SIC PSP. The associated contract worth around €70 M has been awarded to EADS Defence & Security Systems and Thales, along with their partners INEO and Cegelec, and covers the implementation of a programme for remodelling the information and communication systems of the French High Command of the Paris Strategy Centre (PSP).

The two-phase project is due to be realized over six years, with a potential five-year contract extension for maintenance. The new system will offer a combined and open command centre for the military and the secret services and be capable of implementing an Information Management policy that promotes the transmission of information and operational efficiency.

The PSP system will enable France to supply a joint staff Operational Headquarters, thus meeting the aims of the European Union. From 2007 on, the new system will provide a highly reconfigurable network architecture and enable the command centre to have an initial capacity level at its disposal that will promote cooperation using a modernized information system that synergizes with the existing one.

Innos Supports UK Nanotechnology NoE

Innos is providing integration engineering support and prototyping services for the UK Framework 6 Network of Excellence SiNANO Project. The consortium is funded by the European Union, with the Engineering and Physical Sciences Research Council (EP-



SRC) providing additional access to the Innos fabrication facility to the different UK academic partners—the UK Universities of Warwick, Southampton, Cambridge and Newcastle. The underlying principle of the project is to explore different technology routes and achieve very high speed, silicon-based nanoscale devices, which can be adopted in the future engineering of ICs.

Each partner in the SiNANO project provides the different areas of expertise required in developing these advanced devices using basic materials science, from the design and fabrication through to characterisation and device modelling. The research will aim to enhance device performance and integration.

In order to support the four main UK partners Innos has set up an internal task force led by Riccardo Varrazza, commercial integration engineer at the company's Southampton headquarters. "Achieving the production of IC components at nanometric dimensions could herald a revolution in IC technology, involving the integration of nanoscale CMOS and emerging post-CMOS logic and memory devices," said Varrazza. "Together with SiNANO we are committed to enhance device performance and integration, to meet the ever increasing demands of communications and computing."

Alcatel-Lucent: Leader in Comms Solutions

Alcatel and Lucent Technologies have completed their merger transaction and begun operations as the world's leading communication solutions provider. The new company, Alcatel-Lucent, with one of the largest global R&D capabilities in communications and the

broadest wireless, wireline and services portfolio, is incorporated in France, with executive offices located in Paris. The company trades on Euronext Paris and the New York Stock Exchange under a new common ticker.

With a worldwide presence in 130 countries, 79,000 employees (after completion of the Thales transaction) and balanced revenues across all regions, Alcatel-Lucent has strong customer relationships with the 100 largest telecommunications operators in the world. The company will have four geographic regions: Asia-Pacific, Europe and North, Europe and South, and North America.

There will be five Business Groups: the Wireline Business Group, the Wireless Business Group and the Convergence Business Group (addressing the needs of the carrier market), the Enterprise Business Group and the Service Business Group. ■

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2-32	50 ± 1	0.06	1.10:1	2500w	C50-101-481/1N
0.5-50	50 ± 1	0.10	1.10:1	2000w	C50-100-481/1N
0.5-100	30 ± 1	0.30	1.15:1	200w	C30-102-481/2*
0.5-100	40 ± 1	0.20	1.15:1	200w	C40-103-481/2*
20-200	50 ± 1	0.20	1.15:1	500w	C50-108-481/4N
20-400	30 ± 1	0.30	1.15:1	50w	C30-107-481/3*
100-500	40 ± 1	0.20	1.15:1	500w	C40-105-481/4N
500-1000	50 ± 1	0.20	1.15:1	500w	C50-106-481/4N

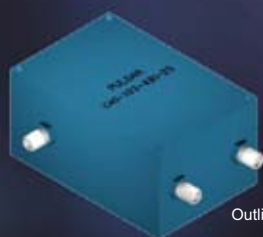
Directivity greater than 20 dB

* Available in SMA and N Connectors

High Power Combiners 25 to 400 Watt Input

Freq. Range (MHz)	Isolation (dB)	Insertion Loss dB max.	Total Input Power max.	VSWR max.	P/N
2-Way					
800-1000	25	0.3	100w	1.20:1	PPS2-12-450/1N
800-2200	18	0.5	100w	1.40:1	PPS2-10-450/1N
1700-2200	20	0.4	100w	1.30:1	PPS2-11-450/1N
10-250	25	0.5	200w	1.20:1	PP2-13-450/50N
250-500	20	0.3	100w	1.30:1	PPS2-16-450/20N
500-1000	20	0.3	100w	1.30:1	PPS2-15-450/20N
4-Way					
20-400	20	0.6	400w	1.30:1	PP4-50-452/2N
100-700	25	1.2	25w	1.40:1	P4-P06-440
30-1100	20	1.5	25w	1.50:1	P4-P09-440
5-1500	20	1.5	25w	1.50:1	P4-P10-440

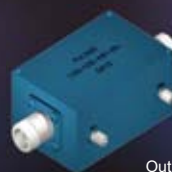
* Available in SMA and N Connectors



Outline 481/2S



Outline 452/2N



Outline 481/4N



Outline 450/1N

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TYPICAL SPECIFICATIONS

Model No.	RF	Frequency (MHz) LO	IF	LO Pwr. (dBm)	IP3 (dBm)	1dB Comp. (dBm)	Conv.Loss (dB)	Isolation (dB) L-R L-I	Price \$ ea. Qty.(1-9)
LAVI-9VH+	820-870	990-1040	120-220	+19	+36	+23	7.2	46 46	15.95
LAVI-10VH+	300-1000	525-1175	60-875	+21	+33	+20	6.3	50 45	22.95
LAVI-17VH+	470-1730	600-1800	70-1000	+21	+32	+20	6.8	52 50	22.95
LAVI-22VH+	425-2200	525-2400	100-700	+21	+31	+20	7.7	50 45	24.95
LAVI-2VH+	2-1100	2-1100	2-1000	+23	+34	+23	7.5	48 47	24.95
LAVI-25VH+	400-2500	650-2800	70-1500	+23	+32	+20	7.5	50 45	24.95

U.S. Patent Number 6,807,407



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Model	Freq. (MHz)	Z	Price \$ea. (Qty. 25)
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SBTC-2-20+	200-2000	50Ω	3.49
SBTC-2-25+	1000-2500	50Ω	3.49
SBTC-2-10-75+	10-1000	75Ω	3.49
SBTC-2-15-75+	500-1500	75Ω	3.49
SBTC-2-10-5075+	50-1000	50/75Ω	3.49
SBTC-2-10-7550+	5-1000	50/75Ω	3.49

U.S. Patent No. 6,963,255

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IEEE Begins Wireless Communications Standard for Power Systems

security and on-site testing practices for wireless technologies in power system operations. The standard, IEEE P1777™ “Using Wireless Data Communications in Power System Operations,” will focus on newer technologies, such as WiFi, Bluetooth, Zigbee, WiMAX and cellular phones. In addition to the practical aspects of wireless use, it also will address the dissemination of information on the uses, benefits and concerns of wireless technologies in the industry. IEEE P1777 will evaluate the potential of wireless technologies in power systems to determine where they are viable alternatives to wire systems and what further development they need in order to meet robustness, security and reliability and other requirements. The standard will explore the potential uses of wireless technologies at many levels of power system operations, including substations, underground vaults, transmission and distribution circuits, generation and distributed generation plants, and customer electrical and metering equipment. IEEE P1777 is sponsored by the IEEE Power Engineering Society.

The IEEE Standards Association, a globally recognized standard-setting body, develops consensus standards through an open process that brings diverse parts of an industry together. These standards set specifications and procedures based on current scientific consensus. The IEEE-SA has a portfolio of more than 870 completed standards and more than 400 standards in development. For information on IEEE-SA, visit <http://standards.ieee.org/>.

RFID-based Strategies for Aerospace and Defense Supply Chains

One area that shows particular promise for the use of RFID in an A&D manufacturing environment is “MRO”: maintenance, repair and overhaul. “MRO supply chain is about safety and security, as well as efficiency,” says ABI Research director Michael Liard. “A&D companies have evolved a new supply chain equation: maintenance strategy + supply side strategy = supply chain strategy. RFID

Wireless data communications offers many benefits in power systems, but it also presents security, reliability and other concerns. In order to help the industry address the potential of this technology, the IEEE has begun work on a new standard to create functional, performance,

Aerospace and defense companies are increasingly looking for ways to gain competitive advantage through the enhanced management of supply chains and assets. By 2011, the A&D Radio Frequency Identification (RFID) market is expected to realize revenue in excess of \$2 B.

can fulfill many MRO event requirements by enabling real-time track-and-trace and unique identification.” Given the one-off equipment maintenance and supply chain management focus of most A&D organizations, an integrated MRO supply chain strategy with linkage between in-line equipment performance and supplier capability is critical. An integrated MRO supply chain can improve service performance in a manufacturer’s storeroom by simplifying inventory, purchasing, and other business processes. Integrated supply allows the centralization of all sourcing, procurement, receiving, internal distribution and service to one supplier. The full benefit of integrated supply is achieved when all MRO supply chain functions are outsourced, thereby allowing a plant to better focus on its core competencies. “Integrated MRO strategies based on RFID tagging can deliver marked efficiencies to the processes of locating parts, tools and materials, and to producing the significant amounts of documentation required to meet regulations in the aerospace and defense industry,” notes Liard. “RFID is an enabling technology that can facilitate a shift from corrective to predictive maintenance strategies.” The new ABI Research study, “The RFID Aerospace and Defense Market,” provides an assessment of the opportunities business benefits of RFID in A&D markets. It forms part of the company’s RFID Research Service, which includes research reports, research briefs, market data, on-line databases, ABI insights and analyst inquiry support.

ZigBee Emerges as the Wireless Mesh Network of Choice

In-Stat believes that because of the clarity of the ZigBee standard, the organizational strength of the ZigBee Alliance and the involvement of several of the world’s largest semiconductor companies, ZigBee will emerge as the dominant wireless mesh networking technology.

Wireless mesh networks are a mosaic of proprietary and non-proprietary implementations. The IEEE 802.15.4 Working Group was designed to create unified standards for short range, self-configuring mesh networks. ZigBee is a networking layer that is built on top of the IEEE 802.15.4 standard. The ZigBee Alliance is an organization that has been the keeper of the ZigBee standard and is an open community of 200 companies that is charged with the promotion of the technology and testing of equipment.

“ZigBee is designed to create interoperability among silicon vendors and facilitate common software and profile platforms for end users in specific applications,” says Chris Kissel, In-Stat analyst. “The addition of ZigBee to 802.15.4 gives an OEM or other end-user the assurance of multiple sources of silicon.”

Recent research by In-Stat found the following:

- In 2006, In-Stat estimates between 4.5 million and 10.5 million ZigBee RF components will be sold.



- Commercial building control is, and will continue to be, the largest 802.15.4/ZigBee application.
- In 2005, North America represented 53 percent of all 802.15.4/ZigBee nodes in use.

The research, "Building up ZigBee and 802.15.4 Chipsets and Applications," covers the market for 802.15.4/ZigBee components. It includes analysis of how companies differentiate their products on the component level, a status update on how countries plan to regulate ZigBee, estimated bill of materials of ZigBee chipsets and ZigBee modules. It also includes detailed scenarios about the challenges 802.15.4/ZigBee faces in market verticals—residential automation, commercial applications, medical, industrial and smart cards. Forecast breakouts through 2010 of 802.15.4/ZigBee shipments by region, frequency and application, and in-depth vendor profiles of ZigBee silicon, systems and software providers are provided.

This research is part of In-Stat's Multimedia and Interface Technologies Service, which identifies and forecasts key interface technologies and multimedia semiconductors. It examines competitors, industry agendas, market shares, technology platforms, semiconductor technology and shipments. Technology penetration within a myriad of end equipment market is explored. Supply and demand-side insights are combined to examine these dynamic, evolving technologies.

Over 500 Million Mobile Broadband Users by 2010

According to Strategy Analytics' recent report, "Beyond 3G: Looking for True Mobile Broadband," new alternative technologies will contribute just six percent of the forecast 500 million mobile broadband users globally by 2010. Despite all the hype surrounding al-

ternative technologies, like WiMAX, it is iterations of existing technologies which will dominate the mobile broadband arena in the short term. Technologies such as mobile WiMAX and UMTS TDD will lead the alternative technology camp, but enhancements to existing technologies, including HSPA and EV-DO revision A+ will comprise the bulk of the market and are where the money lies in the short term. "We are not likely to see technologies like mobile WiMAX or indeed, anything else, really take-off until the next decade," comments Sara Harris, senior industry analyst at Strategy Analytics and author of this report. "However, HSPA and EV-DO will be more than acceptable for most users, giving them the speed and flexibility they want to use their fixed Internet applications on the move." ■



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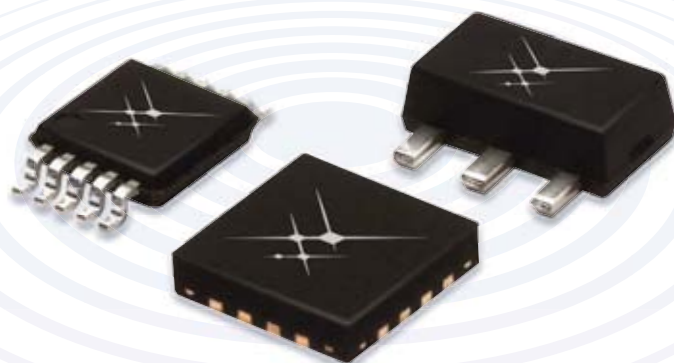
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Frequency Band	3 dB Band (GHz) Typ.	V _{CC} (V) Typ.	I _{CC} (mA)	Gain @ 2 GHz (dB) Typ.	NF @ 2 GHz	Output IP3 @ 2 GHz (dBm) Typ.	Package
LF-3 GHz	3	3.5	40	20.0	4.8	27	SOT-89

GaAs SPDT Switch 100 MHz-6 GHz Medium Power — SKY13286-359LF

Frequency Band	Description	Insertion Loss Range (dB) Typ	Isolation Range (dB) Typ.	IP3 > 0.5 GHz (dBm) Typ.	Package
100 MHz-6 GHz	High Isolation SPDT	0.8-1.5	62-42	49	QFN-16 (4 x 4 mm)

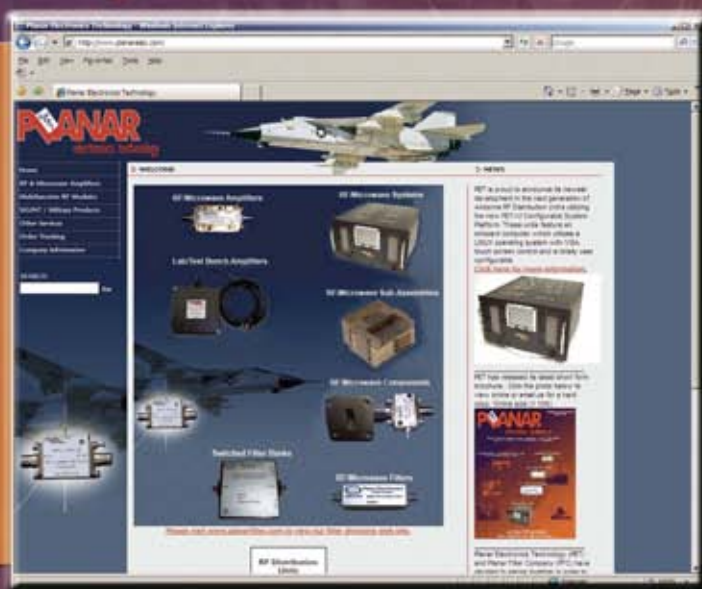
GaAs Digital Attenuator 500 MHz-3 GHz 5 Bits, 1 dB LSB — SKY12323-303LF

Frequency Band	Description	Insertion Loss Range (dB) Typ.	Attenuation Range (dB) Typ.	IP3 > 0.5 GHz (dBm) Typ.	Package
500 MHz-3 GHz	5 Bit, LSB 1 dB, Single Positive Control Voltage	1.40-2.30	31	45	MSOP-10EP



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New listings offering hundreds of new models.

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Terms and Conditions: This sale applies only to amplifiers that are ordered between January 1, 2007 and March 31, 2007. The sale is only for amplifiers listed on the present PET web site. The sales price is for any listed amplifier that has 30 dB of gain or less and has a maximum operating frequency of 20 GHz. The ten piece minimum order requirement must be met. Up to three different models totaling ten pieces may be ordered and will still be considered to meet the minimum order requirement. The specifications shown are typical. If a specific guaranteed specification is required please specify this requirement at the time of ordering and additional charges may apply. PET reserves the right to change the contents of its web site and/or model availability at anytime without notice. Specifications are subject to change without notice.

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INDUSTRY NEWS

■ **Kulicke & Soffa Industries Inc.** closed the previously announced purchase of **Alphasem**, a supplier of die bonder equipment, from Dover Technologies International Inc., a subsidiary of Dover Corp. The purchase price was \$27.1 M in cash, after a working capital adjustment and subject to further post closing adjustments.

■ **Fox Electronics**, a supplier of frequency control products, announced the opening of a new Asia Pacific sales office in Taiwan. The new office has been established to support the rapid growth of the company's sales in the Asia Pacific region, including Taiwan and China. The new Fox Asia Pacific sales office is located at 12F-6, 378 Ming An West Road, Hsin-Chuang, Taipei Hsien 242 Taiwan, ROC.

■ **Tehuti Networks**, a semiconductor company providing 10 Gigabit Ethernet single-chip, low power TCP/IP acceleration controllers, announced it has opened a new office and expanded its personnel in Taiwan. The office is headed by Jerry Lee, who serves as the company's Asia-Pacific regional sales manager. Lee will manage the sales and technical support of Tehuti Networks' controller and board-level products throughout the Asia-Pacific.

■ **Micro-Ant Inc.** is relocating its operations to a larger facility in Easton, MA. The additional space is required to accommodate the company's growing staff and manufacturing department, and will include a 40-foot, fully-instrumented anechoic test chamber for antenna measurements. Micro-Ant is an established leader in the design and manufacture of antennas for the satellite communications industry, including satellite radio, GPS and two-way voice/data.

■ **Applied Wave Research Inc.** (AWR®), El Segundo, CA, and Shanghai Research Institute of Microelectronics (SHRIME), **Peking University**, China, announced that AWR is donating its entire suite of radio frequency (RF) design software in a collaborative effort to advance Peking University's high frequency design curriculum. The donation is the first step in a long-term program that will establish a joint RF design and research laboratory at the university's research institute. The laboratory will spearhead high frequency research projects in Shanghai and develop unified process design kits (PDK) and value-added RF intellectual property (IP) for key foundry processes in China.

■ **Keithley Instruments Inc.**, a leader in solutions for emerging measurement needs, announced it has partnered with **Mesatronic Group**, Voiron, France, to develop advanced probe cards for semiconductor parametric testers used in RF and low current DC applications.

■ **QUALCOMM Inc.** and **Motorola Inc.** announced an expansion in their relationship. In addition to collaborating on CDMA2000®, the two companies will now be work-

AROUND THE CIRCUIT

ing together to bring UMTS handsets to global markets. Motorola Mobile Devices has approved QUALCOMM's Mobile Station Modem™ chipsets for incorporation into future UMTS handset designs.

■ **Melexis Microelectronic Integrated Systems N.V.** and **Atmel® Corp.** announced their collaboration to propose innovative solutions for 13.56 MHz RFID readers and Near Field Communication (NFC) devices. They will target applications such as passport and ID verification, contactless payment, transaction and peer-to-peer information exchange.

■ **SiGe Semiconductor Inc.** and **Nordnav Technologies AB** announced they have collaborated on a GPS/Galileo receiver for consumer electronic products. The companies have combined SiGe's SE4120L radio front-end with Nordnav's E5000 software to offer a receiver system with the high performance, small size and power efficiency that is essential for mobile devices.

■ Customer premises equipment (CPE) manufacturers can now deliver WiMAX-enabled products to market even faster with a production-ready reference design from **Freescale Semiconductor**, **Wavesat** and **Celestica**. Celestica, a world leader in electronics manufacturing services, has joined a pre-existing collaboration between Freescale and Wavesat to enhance a comprehensive platform for the rapid creation of WiMAX-enabled products.

■ **StratEdge**, a leader in the design and production of semiconductor packages for microwave, millimeter-wave and high speed digital devices, announced that one of its SE20 power amplifier packages is playing a key role in transmitting signals with information gathered from Mars Exploration Rovers *Spirit* and *Opportunity* back to earth. The power amplifier package is used to protect the gallium arsenide monolithic microwave integrated circuits (MMIC) and ensure signal integrity.

■ **Gilland Electronics**, Morgan Hill, CA, announced that its business partner, **ELVA-1 Ltd.**, St. Petersburg, Russia, received FCC equipment authorization for PPC-1000-E point-to-point wireless radios. This authorization enables these 1.25 Gbps, full-duplex wireless Ethernet links, operating in the 71 to 76 GHz and 81 to 86 GHz bands, to be made available to the United States market.

■ **Amphenol RF** announced that it is now authorized to market the QN interface as a member of the Quick Lock Formula® Alliance. Amphenol RF signed a QMA and QN license agreement with **Huber+Suhner AG** and **Radiall SA** earlier this year and is now QLF® certified on both the QMA and QN interface.

■ **Compel Electronics SpA**, a designer and manufacturer of interconnection systems and cable assemblies, announced that the company has received ISO 14001 certification.

Ultra

WIDE BANDWIDTH



Voltage Controlled Oscillators

Model	Frequency (MHz)	Tuning Voltage (VDC) *	DC Bias VDC @ I (Max)	Typical PhaseNoise @ 10 kHz (dBc/Hz)
DCMO514-5	50 - 140	0.5 - 24	+5 @ 30 mA	-105
DCMO616-5	65 - 160	0.5 - 24	+5 @ 35 mA	-108
DCMO1027	100 - 270	0 - 24	+5 to 12 @ 35 mA	-112
DCMO1129	110 - 290	0.5 - 24	+5 to +12 @ 35 mA	-105
DCMO1545	150 - 450	0.5 - 24	+5 to 12 @ 35 mA	-108
DCMO1857	180 - 570	0.5 - 24	+5 to 12 @ 30 mA	-108
DCMO2260-5	220 - 600	0.5 - 24	+5 @ 35 mA	-108
DCMO2476	240 - 760	0.5 - 24	+5 to 12 @ 35 mA	-108
DCMO3288-5	320 - 880	0.5 - 24	+5 @ 35 mA	-109
DCFO35105-5	350 - 1050	0 - 25	+5 @ 40 mA	-112
DCMO50120-5	500 - 1200	0.5 - 24	+5 @ 40 mA	-118
DCMO50120-12	500 - 1200	0.5 - 24	+12 @ 35 mA	-103
DCMO60170-5	600 - 1700	0 - 25	+5 @ 35 mA	-99
DCMO80210-5	800 - 2100	0.5 - 24	+5 @ 35 mA	-96
DCMO80210-10	800 - 2100	0.5 - 24	+10 @ 35 mA	-100
DCMO90220-5	900 - 2200	0.5 - 24	+5 @ 35 mA	-98
DCMO90220-12	900 - 2200	0.5 - 25	+12 @ 35 mA	-99
DCMO100200-12	1000 - 2000	0.5 - 24	+12 @ 35 mA	-105
DCMO100230-12	1000 - 2300	0.5 - 24	+12 @ 35 mA	-101
DCMO100230-5	1000 - 2300	0.5 - 24	+5 @ 35 mA	-98
DCMO110250-5	1100 - 2500	0.5 - 28	+5 @ 35 mA	-100
DCMO135270-8	1350 - 2700	0.5 - 20	+8 @ 35 mA	-93
DCMO150318-5	1500 - 3200	0.5 - 20	+5 @ 30 mA	-93
DCMO150320-5	1500 - 3200	0.5 - 18	+5 @ 60 mA	-92
DCMO172332-5	1720 - 3320	0.5 - 24	+5 @ 30 mA	-94
DCMO190410-5	1900 - 4100	0.5 - 16	+5 @ 50 mA	-90
DCMO250512-5	2500 - 5125	0.5 - 24	+5 @ 50 mA	-78

* Guaranteed sub bands with lower tuning voltages. See specification sheet for details.



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The Model 1517 switch matrix's 16 inputs and 16 outputs can be configured in any combination HF (HF 1.5 – 32 MHz) or UHF (20 – 1000MHz). It is designed for small to medium sized antenna interfacing installations.

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Application images courtesy of U.S. Army

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AROUND THE CIRCUIT

■ **White Mountain Labs**, a leader in test and characterization of advanced technologies, announced that its new testing facility has passed the ISO 17025 reaccreditation audit. The company acquired full accreditation for the second consecutive year and received a rare, perfect audit for the new testing facility, The Center for ESD. This achievement designates White Mountain Labs as the only ESD laboratory with ISO 17025 accreditation globally.

■ Hiromichi Toda, president of **Anritsu Corp.**, announced that the company has been awarded the prestigious 2006 Test & Measurement Global Excellence of the Year Award by Frost & Sullivan. The Frost & Sullivan Global Excellence of the Year Award is bestowed upon the company that has demonstrated global excellence in given business functions, such as sales, marketing, customer service, technology innovation, product quality, supply chain management and growth strategy.

■ At the Association for Manufacturing Excellence (AME) International Lean Enterprise Conference, **M2 Global Technology Ltd.** was named winner of the Southwest Region AME Manufacturing Excellence Award. The company was recognized for its commitment to attainment of excellence in manufacturing and productivity.

CONTRACTS

■ **ITT Corp.** announced it will provide comprehensive spectrum engineering support to the Defense Information Systems Agency (DISA), Joint Spectrum Center (JSC) on the Electromagnetic Spectrum Engineering Services Contract. Under the contract, ITT will provide engineering systems support, technical analysis, test support and long-term strategic planning as JSC meets national security and military objectives related to the use of the electromagnetic spectrum. The contract has a three-year base value of \$147 M and if all options on the contract are exercised, a potential total value of \$545 M.

■ Naval Surface Warfare Center Crane Division has awarded a five-year contract valued in excess of \$6.3 M to **Triton Electron Technology Division**, Easton, PA, for the repair, remanufacture or replacement of traveling wave tubes in support of the AN/ALQ-126B ECM system.

■ **Skyworks Solutions Inc.**, an innovator of high performance analog and mixed-signal semiconductors enabling mobile connectivity, announced that **MediaTek Inc.**, a supplier of worldwide consumer IC chipsets, will be incorporating Skyworks' Helios™ radio across several next-generation EDGE wireless communication platforms. This agreement demonstrates Skyworks' ability to effectively partner with a leading system solution provider following the company's exit of the baseband business.

FINANCIAL NEWS

■ **ANADIGICS Inc.** reports sales of \$44.8 M for the third quarter ended September 30, 2006, compared to \$29.3 M for the same period in 2005. Net loss for the quarter was



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- ◆ Two internal signal sources (four-port model) mean fast intermodulation measurements and mixer characterization without an additional signal generator
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- ◆ And, for the first time, a new method enables you to perform pulse profile measurements of very short pulses at high dynamic range and resolution easily and cost-efficiently

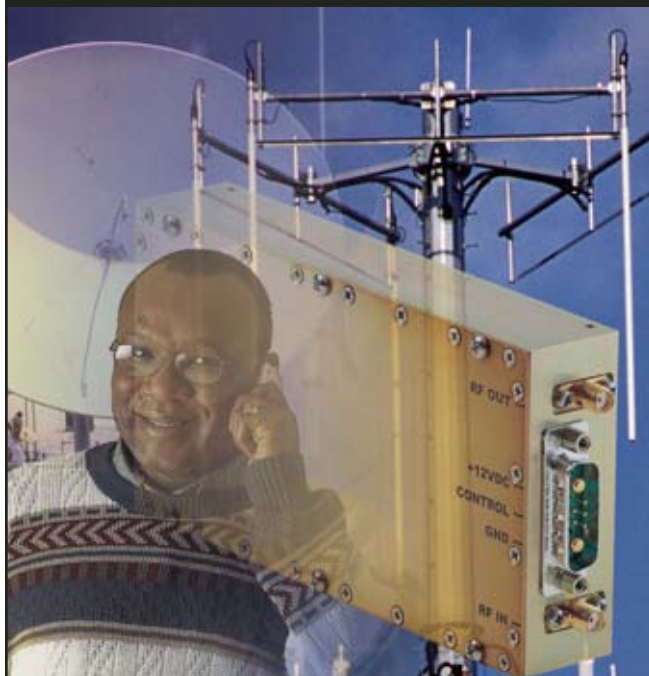


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- UMTS (Universal Mobile Telecomm System) Band – 2 to 2.3 GHz
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AROUND THE CIRCUIT

\$1.3 M (\$0.03/per share), compared to a net loss of \$6.8 M (\$0.20/per share) for the third quarter of last year.

■ **Electro Rent Corp.** reports sales of \$30 M for the first quarter of 2007 ended August 31, 2006, compared to \$26.6 M for the same period in 2006. Net income for the quarter was \$4.8 M (\$0.18/per diluted share), compared to a net income of \$5 M (\$0.19/per diluted share) for the first quarter of last year.

■ **Ansoft Corp.** reports sales of \$20.5 M for the second quarter of fiscal 2007 ended October 31, 2006, compared to \$18 M for the same period in 2006. Net income for the quarter was \$3.7 M (\$0.14/per diluted share), compared to a net income \$4.1 M (\$0.16/per diluted share) for the second quarter of last year.

■ **Endwave Corp.** reports sales of \$18.8 M for the third quarter of 2006 ended September 30, 2006, compared to \$14.3 M for the same period in 2005. Net income for the quarter was \$911,000 (\$0.06/per diluted share), compared to a net loss of \$193,000 (\$0.02/per share) for the third quarter of last year.

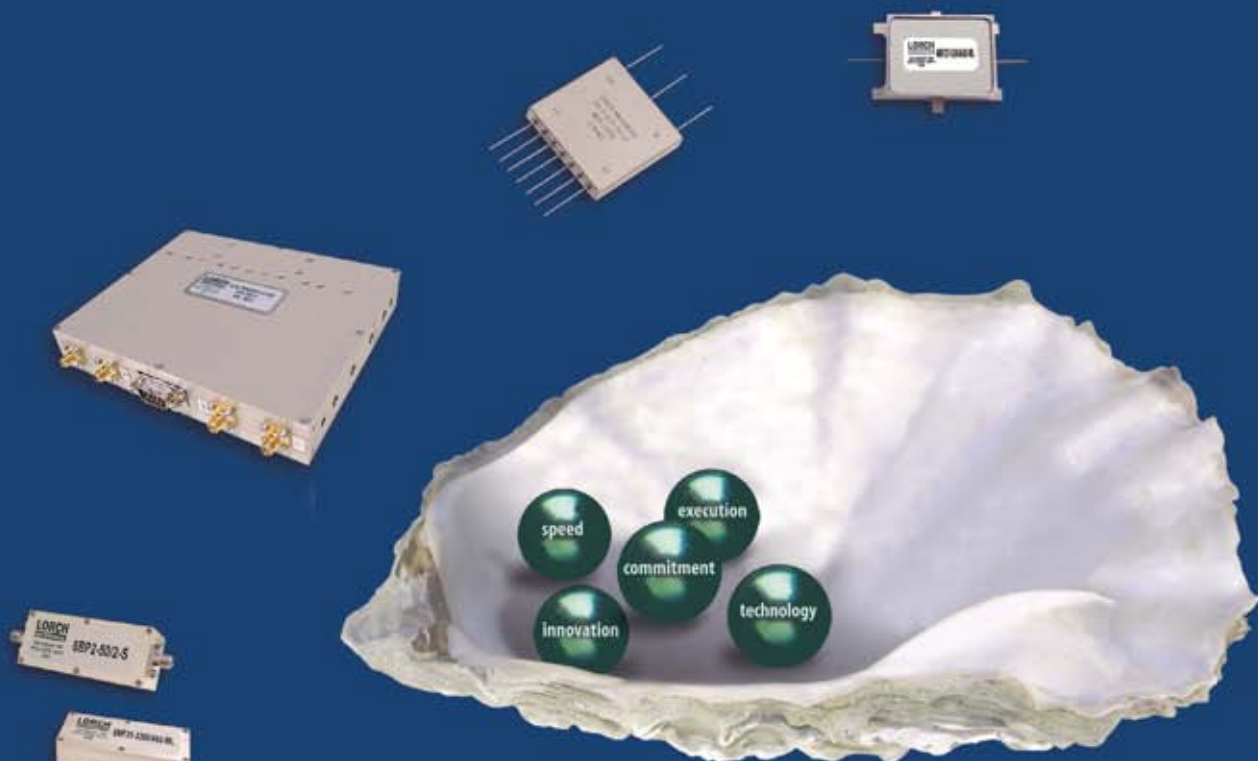
■ **Tower Semiconductor Ltd.**, a pure-play independent specialty foundry, announced that it has expanded its equity private placement, originally announced on November 1, 2006, and raised additionally approximately \$11 M in immediate gross proceeds from Israeli investors.

■ **Technical Communities Inc.**, a service provider for technical organizations that sell to US government agencies and prime federal contractors, has completed a Series D Convertible Preferred financing. While specific terms were not disclosed, the privately held company announced the financing included participation by all previous leading venture investors including Crosspoint Venture Partners, Netmarket Partners, New Enterprise Associates (NEA) and Technology Crossover Ventures (TCV). Technical Communities plans to use the funds to expand its offer to additional markets and for potential acquisitions.

NEW MARKET ENTRIES

■ **PulseWave RF™** is a fabless semiconductor company that has developed a digital high efficiency RF power amplifier module for wireless infrastructure. The company's proprietary Class M Power technology is a digital MCPA module that simultaneously sets new industry benchmarks for cost, size and efficiency. Based in Austin, TX, PulseWave RF is a privately held company with funding from Oak Investment Partners, Austin Ventures, Bay Partners, Genesis Campus and Freescale.

■ **The Phoenix Co.** introduces a new design and manufacturing capability to provide unique solutions for ruggedizing COTS antenna elements. This capability consists of taking a customer selected antenna element, designing an electrical and mechanical transition from the antenna element to the connector and packaging it together to meet demanding environmental and mechanical



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requirements such as IP67 or 68. An engineered mechanical transition is utilized to overcome the effects of different coefficients of linear thermal expansion between the antenna element and the connector. The antennas can be supplied with FCC Rule 15 compliant connectors. For more information, visit www.phoenixofchicago.com.

PERSONNEL

■ RF Micro Devices Inc. (RFMD) announced that **John (Jack) Harding**, the co-founder, chairman, president and CEO of eSilicon Corp., has been elected to the RFMD board of directors. Harding was elected to fill an existing vacancy at the November 1 board meeting and his appointment to the board was effective immediately. Harding co-founded eSilicon Corp., a privately held company, which designs and manufactures complex, custom chips for a broad and growing portfolio of large and small firms. eSilicon is venture-capital backed and has attained an annual revenue run rate approaching \$100 M.

■ UltraSource Inc., a supplier of custom thin film circuits and ceramic interconnect devices, announced the addition of **Jeff Bergart** as chief financial officer (CFO). Prior to his employment at UltraSource, Bergart held financial management roles at several New England-based organizations, including as CFO at Digital Equipment Corp. and KROHNE Inc. In his role as CFO, Bergart will be responsible for managing UltraSource's Finance, IT and Talent Management Groups.

■ Antenova Ltd. announced the appointment of **Mike Edwards** as vice president of worldwide sales and marketing. Antenova further announced the promotion of **CL Lim** to vice president and general manager of Asia. Edwards has over 25 years experience of direct and indirect sales, marketing and senior management in the semiconductor and components industry. Lim has more than 26 years in international sales, business development and technical operations in the wireless and telecommunication industry.



▲ Jim Greene

■ LDKF Laser & Electronics has recently announced the promotion of **Jim Greene** to the position of vice president, sales and marketing. With this new position Greene will be responsible for the control and management of sales and marketing throughout North America. Greene began his career with LDKF North America in 2001, with his latest position being national sales manager.

■ Auriga Measurement Systems LLC announced the addition of **Ted Lewis** as director of global sales. Lewis has over 20 years of experience of growing sales and focusing on building strong customer relations. Previous to Auriga, Lewis was self-employed as a consultant providing specialized services in the development of sales and customer-centered organizations. In addition, Lewis was



CABLES



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Strength, ruggedness, and reliability...*supercharged!* That's what you get when you choose Mini-Circuits ultra-flexible precision test cables. Engineered to be a workhorse for your day-to-day test operations, these triple shielded cable assemblies are qualified to at least 20,000 bends, employ an advanced strain relief system, and are equipped with passivated stainless steel connectors, so you can rely on them to **flex, connect and disconnect over and over and over again!** They're so rugged, each test cable is backed by our 6 month guarantee*. With low insertion loss and very good return loss, you can also rely on getting good performance over the wide DC-18GHz band. Need them right away? Overnight shipment is available. So make Mini-Circuits your test cable connection! *Mini-Circuits...we're redefining what VALUE is all about!*

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Frequency Range: DC-18GHz, Impedance: 50 ohms						
Models	Connector Type	Length (Ft.)	Inser. Loss (dB) Midband	Return Loss (dB) Midband	Price \$ ea.	Qty.(1-9)
Male to Male						
CBL-1.5FT-SMSM+	SMA	1.5	0.7	27	68.95	
CBL-2FT-SMSM+	SMA	2	1.1	27	69.95	
CBL-3FT-SMSM+	SMA	3	1.5	27	72.95	
CBL-4FT-SMSM+	SMA	4	1.6	27	75.95	
CBL-6FT-SMSM+	SMA	6	3.0	27	79.95	
CBL-10FT-SMSM+	SMA	10	4.8	27	87.95	
CBL-12FT-SMSM+	SMA	12	5.9	27	91.95	
CBL-15FT-SMSM+	SMA	15	7.3	27	100.95	
CBL-2FT-SMNM+	SMA to N-Type	2	1.1	27	99.95	
CBL-3FT-SMNM+	SMA to N-Type	3	1.5	27	104.95	
CBL-4FT-SMNM+	SMA to N-Type	4	1.6	27	112.95	
CBL-6FT-SMNM+	SMA to N-Type	6	3.0	27	114.95	
CBL-15FT-SMNM+	SMA to N-Type	15	7.3	27	156.95	
CBL-2FT-NMNM+	N-Type	2	1.1	27	102.95	
CBL-3FT-NMNM+	N-Type	3	1.5	27	105.95	
CBL-4FT-NMNM+	N-Type	6	3.0	27	112.95	
CBL-15FT-NMNM+	N-Type	15	7.3	27	164.95	
CBL-20FT-NMNM+	N-Type	20	9.4	27	178.95	
CBL-25FT-NMNM+	N-Type	25	11.7	27	199.95	
Female to Male						
CBL-3FT-SFSM+	SMA-F to SMA-M	3	1.5	27	93.95	
CBL-2FT-SFNM+	SMA-F to N-M	2	1.1	27	119.95	
CBL-3FT-SFNM+	SMA-F to N-M	3	1.5	27	124.95	
CBL-6FT-SFNM+	SMA-F to N-M	6	3.0	27	146.95	

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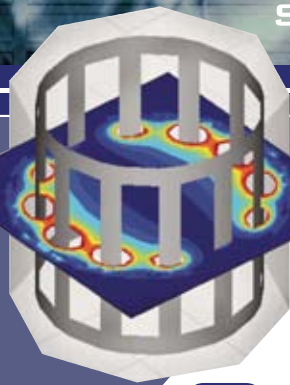
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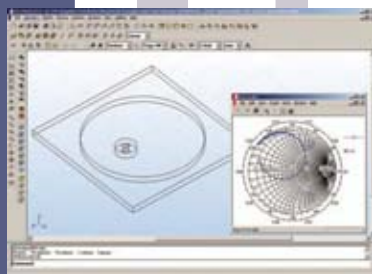


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head of worldwide sales and marketing at Unitek Benchmark in Goffstown, NH, a capital equipment manufacturer serving the microelectronics industry. At Auriga, Lewis will refine and establish Auriga's Global Sales Strategy and Global Sales Channels to grow sales in the three core business lines of Modeling and Design Services, Characterization Instruments, and Test and Measurement Systems.

■ **Peter Barnwell** has been appointed as European business manager for Barry Industries, an Attleboro, MA-based manufacturer of microwave and micro-electronic components and packaging solutions. Barnwell will be based in the UK with responsibility for the sales and marketing activity throughout Europe.



▲ Peter Barnwell

■ RFMW Ltd. hired **Jane Cavin** as the company's new inside sales person for southern California and Arizona. Cavin has more than 20 years of experience in sales, product management, human resources and office management. Cavin comes to RFMW Ltd. from CK Associates, a M/A-COM rep and has experience with distribution from her days at Time, Avnet and Newark.



▲ John Larson III

■ Avago Technologies, a privately held semiconductor company, announced that **John Larson III** was named an IEEE Fellow at the 2006 International Ultrasonics Symposium in Vancouver, British Columbia, Canada. IEEE Fellows are nominated by their peers in numerous engineering fields for extraordinary accomplishment. In his 34-year career with Avago, beginning with Hewlett-Packard Laboratories and Agilent Laboratories, Larson has been part of and has led diverse research and development teams that achieved significant results in acoustics. Today, Avago Technologies' acoustics-based products are embedded in millions of mobile phones, data cards and other wireless devices worldwide. Among his notable contributions to engineering, the IEEE Fellow award recognizes the breakthrough in Film Bulk Acoustic Resonator (FBAR) devices he and his teammates developed as a commercial product for cell phones.

REP APPOINTMENTS

■ **Giga-tronics Inc.**, a manufacturer of instruments, subsystems and microwave components that have broad applications in both commercial and military wireless telecommunications systems, announced a new partnership agreement with **TestMart**, a leading marketplace operator and service provider for the IT, network maintenance, and test and measurement industries. The agreement authorizes TestMart to present a catalog of Giga-tronics' RF and microwave test equipment in bench top and VXI bus configurations.

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- ◆ 20 dB Gain
- ◆ +36 dBm Output IP3
- ◆ Micro-X or SOT89 Packages

InGaP HBT



- ◆ DC - 6.0 GHz
- ◆ +16 dBm P1dB Output Power
- ◆ 16 dB Gain
- ◆ +32 dBm Output IP3
- ◆ SOT89 or QFN Packages

A SELECTION OF OUR SiGe & InGaP HBT GAIN BLOCKS

	Part Number	Technology	Bandwidth (MHz)	Gain (dB)			P1dB (dBm)			Output IP3 (dBm)			NF (dB)
				850MHz	1950 MHz	3500 MHz	850 MHz	1950 MHz	3500 MHz	850 MHz	1950 MHz	3500 MHz	
NEW!	HMC580ST89 (E)	InGaP	1000	18	—	—	20	—	—	35	—	—	2.8
NEW!	HMC589ST89 (E)	InGaP	4000	21	19	16.5	19	19	18	33	32	30	4.0
NEW!	HMC475ST89 (E)	InGaP	4500	22	19	15	22	21	18	36	35	32	3.5
	HMC474MP86 (E)	SiGe	6000	16	14	11	8	8	8	22	22	22	3.0
	HMC476MP86 (E)	SiGe	6000	20	17	13	13	12	13	25	25	26	2.5
	HMC479MP86 (E)	SiGe	5000	15	13	11	19	17	14	34	32	28	4.0
	HMC479ST89 (E)	SiGe	5000	15	13	11	18	16	14	34	32	28	4.1
	HMC481MP86 (E)	SiGe	5000	20	17	13	20	18	15	33	33	29	3.5
	HMC481ST89 (E)	SiGe	5000	20	17	13	20	18	15	33	33	29	3.6
	HMC482ST89 (E)	SiGe	4000	19	17	12	23	20	16	36	35	30	4.0
	HMC311LP3 (E)	InGaP	6000	15	14.5	14	16	15	14	32	30	27	4.5
	HMC311ST89 (E)	InGaP	6000	15	15	15	16	15	14	32	30	27	4.7
	HMC478MP86 (E)	SiGe	4000	22	18	14	18	16	12	32	29	25	2
	HMC478ST89 (E)	SiGe	4000	22	19	14	18	16	11	30	28	25	3
	HMC480ST89 (E)	InGaP	5000	19	16	13	19	18.5	17.5	34	33.5	32	3.0



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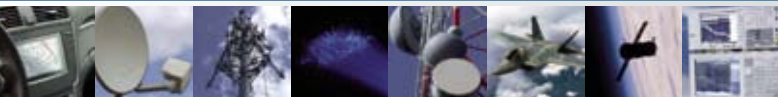
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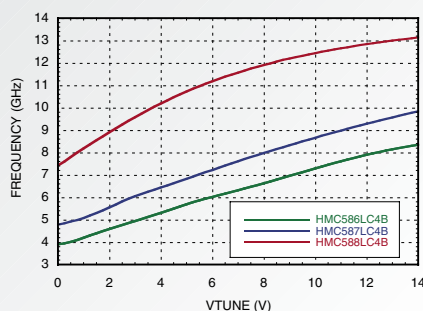
Wideband VCO, 5 to 10 GHz



In Stock!

- ◆ HMC587LC4B
- ◆ Ultra Low SSB Phase Noise:
-95 dBc/Hz @ 100 kHz
- ◆ Single Supply: +5V @ 55 mA
- ◆ RoHS Compliant
4x4 mm SMT Package
- ◆ Other Models Cover 4 to 12.5 GHz

Frequency vs. Tuning Voltage



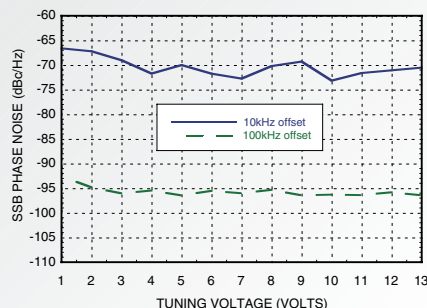
VCO with +16, 23.8 to 24.8 GHz



In Stock!

- ◆ HMC533LP4 (E)
- ◆ Pout: +12 dBm
- ◆ Low Phase Noise:
-95 dBc/Hz @ 100 kHz Typ.
- ◆ RoHS Compliant
5x5 mm SMT "E" Package

SSB Phase Noise vs. Tuning Voltage



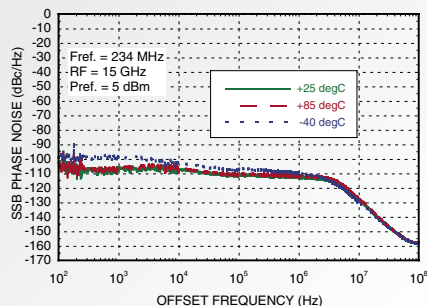
Phase Locked Oscillator, 14.7 - 15.4 GHz



In Stock!

- ◆ HMC535LP4 (E)
- ◆ Pout: +9 dBm
- ◆ Low Phase Noise:
-110 dBc/Hz @ 100 kHz Typ.
- ◆ RoHS Compliant
4x4 mm "E" SMT Package

Phase Noise Performance



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MICROWAVE RADIO, MILITARY AND TEST & MEASUREMENT

A SELECTION OF OUR STANDARD VCOs & PLOs COVERING 2 to 25 GHz!

Frequency (GHz)	Function	Output Power (dBm)	10kHz SSB Phase Noise (dBc/Hz)	100kHz SSB Phase Noise (dBc/Hz)	Bias Supply	Package	Part Number
VCOs with Buffer Amplifiers and Dividers							
2.25 - 2.5	VCO with Buffer	4.5	-89	-115	+3V @ 35mA	LP4	HMC385LP4 (E)
3.15 - 3.4	VCO with Buffer	4.9	-88	-113	+3V @ 39mA	LP4	HMC388LP4 (E)
3.9 - 4.45	VCO with Buffer	5	-81	-106	+3V @ 30mA	LP4	HMC391LP4 (E)
5.8 - 6.8	VCO with Buffer	10	-82	-105	+3V @ 100mA	MS8G	HMC358MS8G (E)
6.1 - 6.72	VCO with Buffer	4.5	-73	-101	+3V @ 31mA	LP4	HMC466LP4 (E)
6.8 - 7.4	VCO with Buffer	11	-80	-106	+3V @ 80mA	LP4	HMC505LP4 (E)
7.8 - 8.7	VCO with Buffer	14	-80	-103	+3V @ 77mA	LP4	HMC506LP4 (E)
13.2 - 13.5	VCO with ÷8	-8	-83	-110	+5V @ 230mA	QS16G	HMC401QS16G (E)
14.0 - 15.0	VCO with ÷8	6	-75	-110	+5V @ 260mA	QS16G	HMC398QS16G (E)
23.8 - 24.8	VCO with ÷16	11	-70	-95	+5V @ 220mA	LP4	HMC533LP4 (E)
NEW! 6.65 - 7.65	VCO with Fo/2	13	-90	-115	+5V @ 230mA	LP5	HMC507LP5 (E)
NEW! 7.3 - 8.2	VCO with Fo/2	15	-90	-116	+5V @ 240mA	LP5	HMC508LP5 (E)
NEW! 7.8 - 8.8	VCO with Fo/2	13	-90	-115	+5V @ 250mA	LP5	HMC509LP5 (E)
NEW! 9.05 - 10.15	VCO with Fo/2	13	-87	-115	+5V @ 265mA	LP5	HMC511LP5 (E)
NEW! 8.45 - 9.55	VCO with Fo/2 & ÷4	13	-90	-113	+5V @ 315mA	LP5	HMC510LP5 (E)
10.43 - 11.46	VCO with Fo/2 & ÷4	7	-85	-110	+3V @ 275mA	LP5	HMC513LP5 (E)
NEW! 10.6 - 11.8	VCO with Fo/2 & ÷4	11	-82	-110	+5V @ 350mA	LP5	HMC534LP4 (E)
11.17 - 12.02	VCO with Fo/2 & ÷4	7	-85	-110	+3V @ 275mA	LP5	HMC514LP5 (E)
11.5 - 12.5	VCO with Fo/2 & ÷4	10	-85	-110	+5V @ 200mA	LP5	HMC515LP5 (E)
NEW! 11.5 - 12.8	VCO with Fo/2 & ÷4	11	-81	-110	+5V @ 350mA	LP5	HMC583LP5 (E)
12.4 - 13.4	VCO with Fo/2 & ÷4	8	-85	-110	+5V @ 260mA	LP5	HMC529LP5 (E)
NEW! 12.5 - 13.9	VCO with Fo/2 & ÷4	10	-80	-110	+5V @ 330mA	LP5	HMC584LP5 (E)
13.6 - 14.9	VCO with Fo/2 & ÷4	7	-82	-110	+5V @ 260mA	LP5	HMC531LP5 (E)
Wideband VCOs							
4 - 8	Wideband VCO	5	-75	-100	+5V @ 55mA	LC4B	HMC586LC4B
5 - 10	Wideband VCO	5	-65	-95	+5V @ 55mA	LC4B	HMC587LC4B
8 - 12.5	Wideband VCO	5	-65	-93	+5V @ 55mA	LC4B	HMC588LC4B
PLOs							
14.7 - 15.4	Phase Locked Oscillator	9	-110	-110	+5V @ 340mA +12V @ 28mA	LP4	HMC535LP4 (E)

HMC VCOs integrate resonator, negative resistance generator and tuning varactor circuits on-chip. No external components are required.

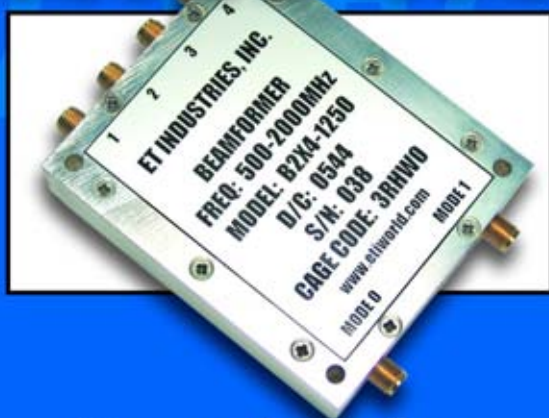
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AROUND THE CIRCUIT

■ **Digi-Key Corp.**, an electronic component distributor, and **SMC Corp. of America** announced the signing of a global distribution agreement. SMC products stocked by Digi-Key include pressure switches, vacuum switches, digital pressure regulators, digital flow switches and accessories. These products are available directly from Digi-Key and are featured in its print and on-line catalogs.

■ **Zilker Labs Inc.** announced that it has signed an agreement with technology distributor **Avnet Electronics Marketing Asia**, an operating group of Avnet Inc. Avnet Electronics Marketing will support Zilker Labs' business throughout the Asia-Pacific region, including major markets such as Korea, Taiwan, China and Hong Kong. Zilker Labs also has an Asian subsidiary, Zilker Labs Asia Ltd., based in Hong Kong, that supports customers throughout Asia.

■ **Centerline Technologies** announced the appointment of **JDM Associates** as the company's exclusive sales representative in Florida and Georgia. In related news, Centerline Technologies also announced the appointment of **Chalman Technologies** as the company's exclusive sales representative in southern California and Arizona.

■ **Reactel Inc.**, a manufacturer of RF and microwave filters, multiplexers, switched filter banks and subassemblies to the commercial, military, industrial and medical industries, announced the appointment of **McBride Scientific Sales** as the company's representative in Texas, Louisiana, Oklahoma and Arkansas. For more information about McBride Scientific Sales, visit www.mcbridescientificsales.com or call Todd McBride at (972) 494-5000.

■ **RLC Electronics Inc.**, a manufacturer of RF and microwave components to both the commercial and military industries, has announced the appointment of **Marktron Inc.** as the company's sales representative in the states of Maryland, Virginia, Delaware and the District of Columbia. Marktron Inc. can be contacted at 1688 East Guide Drive, #304, Rockville, MD 20850 (301) 251-8990, fax: (301) 424-0766 or e-mail John Haynos: johnh@marktron.com.

■ **Aethercomm Inc.** appointed **Youngewirth & Olenick** as the company's exclusive sales representative in southern California, Arizona and New Mexico. Youngewirth & Olenick will represent and support Aethercomm's entire product offering. Youngewirth & Olenick can be reached at 17621 Irvine Blvd., Suite 101, Tustin, CA 92780 (800) 515-1554 or visit: www.yando.com.

WEB SITE

■ **Cornell Dubilier** announces its newly executed capacitor web site, www.cde.com. It features one-click access to 10 technical papers, three capacitor life-temperature calculators, a new thermal modeling applet and one-click access to capacitor types by dielectric, application or type letters. Advanced parametric search pulls up individual ratings and links to data sheets. Application guides and product selector guides make it easy to steer a user through the company's more than 220 capacitor types.

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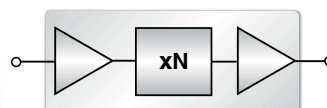
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NEW!	3000 - 4500	Active x2	6 - 9	0	17	-140	LP4	HMC575LP4 (E)
	4500 - 8000	Active x2	9.0 - 16.0	2	15	-140	LP4	HMC368LP4 (E)
	4950 - 6350	Active x2	9.9 - 12.7	0	4	-142	LP3	HMC369LP3 (E)
NEW!	9000 - 14500	Active x2	18 - 29	3	17	-132	Chip	HMC576
NEW!	9000 - 14500	Active x2	18 - 29	3	15	-132	LC3B	HMC576LC3B
NEW!	12000 - 16500	Active x2	24 - 33	3	17	-132	Chip	HMC578
NEW!	12000 - 16500	Active x2	24 - 33	3	15	-132	LC3B	HMC578LC3B
NEW!	13500 - 15500	Active x2	27 - 31	5	20	-128	LC4B	HMC577LC4B
NEW!	16000 - 23000	Active x2	32 - 46	3	13	-127	Chip	HMC579
	2450 - 2800	Active x4	9.8 - 11.2	-15	3	-142	LP4	HMC443LP4 (E)
	3600 - 4100	Active x4	14.4 - 16.4	-15	0	-140	LP4	HMC370LP4 (E)
	1237.5 - 1400	Active x8	9.9 - 11.2	-15	6	-136	LP4	HMC444LP4 (E)
	618.75 - 687.5	Active x16	9.9 - 11	-15	7	-130	LP4	HMC445LP4 (E)



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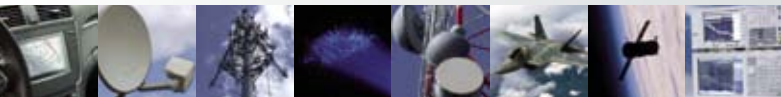
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NEW!	29 - 36	Low Noise	20	22	2.9	11	+3V @ 80mA	C-10 Module	HMC-C027
	2 - 20	Wideband LNA	15	24	2.2	14	+12V @ 65mA	C-1 Module	HMC-C001
	2 - 20	Wideband LNA	14	26	2	18	+12V @ 60mA	C-2 Module	HMC-C002
	2 - 20	Wideband LNA	14	27	2	16	+8V @ 75mA	C-2B Module	HMC-C022
	7 - 17	Wideband LNA	22	25	2.5	14	+8V @ 93mA	C-1 Module	HMC-C016
	17 - 27	Wideband LNA	18	25	3	14	+8V @ 96mA	C-1B Module	HMC-C017
	0.01 - 20	Wideband Driver	16	33	3	23	+12V @ 195mA	C-3 Module	HMC-C004
	0.01 - 20	Wideband Driver	15	30	3	23	+12V @ 225mA	C-3B Module	HMC-C024
NEW!	2 - 35	Wideband Driver	11	26	4	16	+11V @ 92mA	C-10 Module	HMC-C038
NEW!	0.01 - 15	Wideband PA, 1/2 Watt	12	36	4	28	+11V @ 360mA	C-10B Module	HMC-C036
NEW!	0.01 - 15	Wideband PA, 1/2 Watt	12	36	4	28	+11V @ 360mA	C-12 Module	HMC-C037
	2 - 20	Wideband PA	15	34	4	26	+12V @ 310mA	C-2 Module	HMC-C003
	2 - 20	Wideband PA	14	30	4	24	+12V @ 310mA	C-2B Module	HMC-C023
	2 - 20	Wideband PA	28	30	3	25	+12V @ 400mA	C-3B Module	HMC-C026
NEW!	17 - 24	Wideband PA	22	33	3.5	24	+8V @ 250mA	C-10 Module	HMC-C020
NEW!	21 - 31	Wideband PA	15	32	5	24	+8V @ 215mA	C-10 Module	HMC-C021
	0.4 - 1.0	10 Watt PA	40	54	12	40	+12V @ 6.5A	C-7 Module	HMC-C012
	0.8 - 2.0	10 Watt PA	43	56	12	40	+12V @ 6.5A	C-7 Module	HMC-C013
	1.8 - 2.2	15 Watt PA	42	53	6	42	+14V @ 6.5A	C-7 Module	HMC-C008

ATTENUATORS - Digital

	Frequency (GHz)	Function	Loss (dB)	Atten. Range (dB)	Input IP3 (dBm)	Control Input (Vdc)	Package	Part Number
NEW!	DC - 13	6-Bit Digital, Serial Control	3.6	0.5 to 31.5	32	Serial TTL/CMOS	C-6 Module	HMC-C018
	DC - 13	6-Bit Digital	3.2	0.5 to 31.5	38	0 / +5V	C-6 Module	HMC-C025

FREQUENCY DIVIDERS (Prescalers)

	Input Freq. (GHz)	Function	Input Power (dBm)	Output Power (dBm)	100kHz SSB Phase Noise (dBc/Hz)	Bias Supply	Package	Part Number
	0.5 - 18	Divide-by-2	-15 to +10	-4	-150	+5V @ 75mA	C-1 Module	HMC-C005
	0.5 - 18	Divide-by-4	-15 to +10	-4	-150	+5V @ 93mA	C-1 Module	HMC-C006
NEW!	0.5 - 7	Divide-by-5	-15 to +10	-1	-155	+5V @ 80mA	C-1 Module	HMC-C039
	0.5 - 18	Divide-by-8	-15 to +10	-4	-150	+5V @ 98mA	C-1 Module	HMC-C007
NEW!	0.5 - 17	Divide-by-10	-15 to +10	-1	-155	+5V @ 152mA	C-1 Module	HMC-C040

FREQUENCY MULTIPLIERS - Active

	Input Freq. (MHz)	Function	Output Freq. (GHz)	Input Power (dBm)	Output Power (dBm)	100kHz SSB Phase Noise (dBc/Hz)	Package	Part Number
NEW!	3000 - 5000	Active x2	6 - 10	3	17	-140	C-10 Module	HMC-C031
NEW!	9000 - 14500	Active x2	18 - 29	3	16	-132	C-10 Module	HMC-C032
NEW!	12000 - 16500	Active x2	24 - 33	3	17	-132	C-10 Module	HMC-C033
NEW!	16000 - 23000	Active x2	32 - 46	3	13	-130	C-10 Module	HMC-C034

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I/Q MIXERS

RF/LO Freq. (GHz)	Function	IF Frequency (GHz)	Conversion Gain (dB)	Image Rejection (dB)	Input IP3 (dBm)	Package	Part Number
4 - 8.5	I/Q Mixer	DC - 3.5	-7.5	37	23	C-4 Module	HMC-C009

MIXERS

RF Freq. (GHz)	Function	IF Frequency (GHz)	Conversion Gain (dB)	LO/RF Isol. (dB)	Input IP3 (dBm)	Package	Part Number
NEW! 23 - 37	+13 LO, DBL-BAL	DC - 13	-9	35	19	C-11 Module	HMC-C035
16 - 32	+13 LO, DBL-BAL	DC - 8	-8	28	19	C-11 Module	HMC-C014
24 - 38	+13 LO, DBL-BAL	DC - 8	-8.5	35	20	C-11 Module	HMC-C015

PHASE SHIFTERS - Analog

Frequency (GHz)	Function	Insertion Loss (dB)	Phase Range (deg)	2nd harmonic Pin = 10 dBm (dBc)	Control Voltage Range (Vdc)	Package	Part Number
6 - 15	Analog	7	750° @ 6 GHz 450° @ 15 GHz	40	0V to +5V	C-1 Module	HMC-C010

SWITCHES

Frequency (GHz)	Function	Insertion Loss (dB)	Isolation (dB)	Input P1dB (dBm)	Control Input (Vdc)	Package	Part Number
NEW! DC - 20	SPST, Hi Isolation	3	100	23	0 / +5V	C-9 Module	HMC-C019
DC - 20	SPDT, Hi Isolation	2.0	40	23	0 / -5V	C-5 Module	HMC-C011

VOLTAGE CONTROLLED OSCILLATORS

Output Freq. (GHz)	Function	Output Power (dBm)	10kHz SSB Phase Noise (dBc/Hz)	100kHz SSB Phase Noise (dBc/Hz)	Bias Supply	Package	Part Number
NEW! 4 - 8	Wideband VCO	20	-75	-95	+12V @ 185mA	C-1 Module	HMC-C028
NEW! 5 - 10	Wideband VCO	20	-64	-93	+12V @ 195mA	C-1 Module	HMC-C029
NEW! 8 - 12.5	Wideband VCO	21	-59	-83	+12V @ 195mA	C-1 Module	HMC-C030

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C-7	C-9	C-10 / C-10B	C-11	C-12
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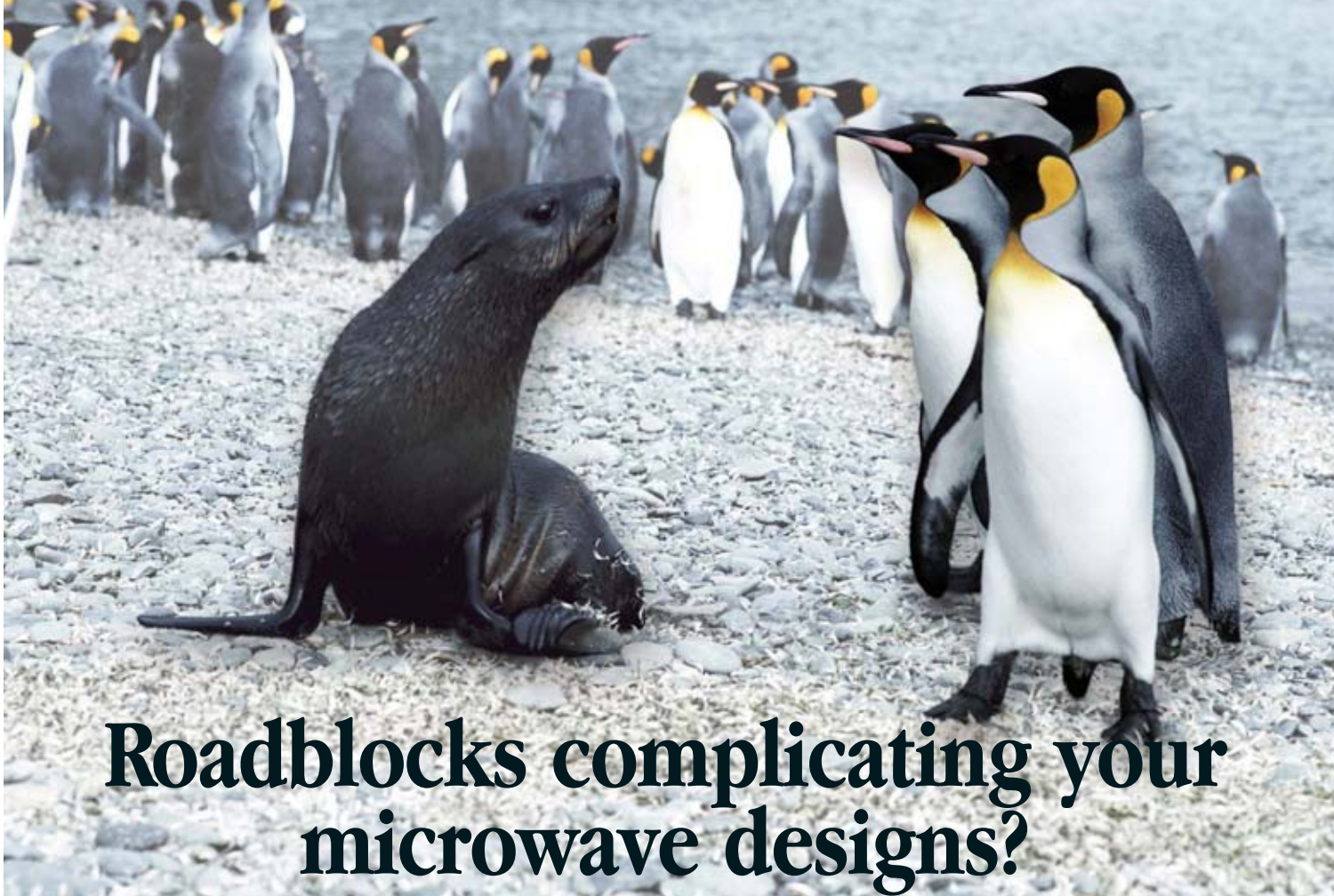
MEMORY EFFECT MINIMIZATION AND WIDE INSTANTANEOUS BANDWIDTH OPERATION OF A BASE STATION POWER AMPLIFIER

Linear amplification and reduction of the memory effect of a wide bandwidth signal have been realized for a next generation base station power amplifier. Using a simple nonlinear LDMOS model, the third-order intermodulation distortion current is analyzed using a third-order power series. The limitations in shorting the envelope and second harmonics are studied. From the analysis, it is proven that the envelope is a more critical component than the second harmonic for the memory effect and linearity. In order to minimize the envelope voltages, a new matching topology is proposed, which consists of a series LC circuit for shorting the device at a low frequency while maintaining a matchable impedance at the operating frequency. The proposed power amplifier was constructed using a 90 W PEP LDMOSFET at a 2.14 GHz center frequency and tested for two-tone and multi-carrier WCDMA signals. The test results show that the memory effect and nonlinearity are drastically reduced for the proposed amplifier. For the two-tone signals, an asymmetry of less than 2 dB up to 60 MHz tone spacing is achieved for the IMD3 and up to 40 MHz for the IMD5. For the WCDMA 20FA signal with a bandwidth of 100 MHz, a linearity improvement of approximately 15 dB is achieved by minimizing the envelope impedances.

The next generation of mobile communication systems will provide a wide variety of new services, from high quality voice to high definition video and high data-rate wireless channels. Moreover, the systems will provide combined services, including the established wire and wireless communications and broadcasting networks. In order to support these services, a wide frequency spectrum will be assigned. The base station power amplifiers for the next generation systems will therefore have to cover a wide instantaneous signal bandwidth, together with a highly linear

amplification. However, the wideband signals may cause severe memory effects and nonlinearities in the power amplifiers.¹

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TABLE I
**DEFINITION OF THE
NONLINEAR COEFFICIENTS
FOR THE AC DRAIN CURRENT**

g_m	$\partial i_D / \partial v_{GS}$
k_{2gm}	$1/2 \cdot (\partial^2 i_D / \partial v_{GS}^2)$
k_{3gm}	$1/6 \cdot (\partial^3 i_D / \partial v_{GS}^3)$
g_0	$\partial i_D / \partial v_{DS}$
k_{2go}	$1/2 \cdot (\partial^2 i_D / \partial v_{DS}^2)$
k_{3go}	$1/6 \cdot (\partial^3 i_D / \partial v_{DS}^3)$
$k_{2gm \& go}$	$(\partial^2 i_D / \partial v_{GS} \partial v_{DS})$
$k_{3gm \& go}$	$1/2 \cdot (\partial^3 i_D / \partial v_{GS}^2 \partial v_{DS})$
$k_{3gm \& 2go}$	$1/2 \cdot (\partial^3 i_D / \partial v_{GS} \partial v_{DS}^2)$

The memory effects are defined as changes in the amplitude and phase of the distortion components, due to the previous signals. The simplest method for characterizing them is to use a two-tone signal.¹⁻⁴ The two-tone signals, with varying tone spacing, are applied to an amplifier to measure the distortion components.

If the distortion characteristics are identical, regardless of the tone spacings, the amplifier can be expected to be memory-less and to operate properly for wideband signals. Therefore, the memory effect becomes a very important design consideration for wideband base station power amplifiers. It is also the limiting factor for the cancellation of distortion when linearizing a power amplifier (PA) by predistortion techniques.^{2,5,6} Many previous authors have tried to analyze the memory effect or reduce it.^{1,4,7,8} The effect is still a big problem for the current base station power amplifiers and is significant even for amplifiers for the universal mobile telecommunications system (UMTS), which has only a 20 MHz signal bandwidth. The objective of this work is to minimize the memory effect of a base station PA and to realize a linear power amplification of a 100 MHz bandwidth signal, which is very important for the next generation PAs. First, the memory effect is analyzed using a simple LDMOS model^{1,9} and then a detailed simulation is carried out using Freescale's MRF5S21090 LDMOS model. The analysis and simulation show that the drain envelope impedance is the most important factor for reducing the memory effect and nonlinearity. A new matching topology is proposed for minimizing the drain and gate envelope impedances. The matching topology consists of a series LC circuit for shorting the device at a low frequency while maintaining a matchable impedance at the operating frequency. The circuits are connected to the gate and drain terminals, rather than to the bias lines, since the circuit can produce a very low impedance, not limited by the quarter-wavelength bias line. For the experimental demonstration, based on the analysis and simulation, a power amplifier was implemented at a 2.14 GHz center frequency and tested using two-tone and multi-carrier down-link wideband code division multiple access (WCDMA) signals. The amplifier, with the reduced envelope impedances, provides drastically reduced memory effects and very linear amplification performance for wideband signals.

ANALYSIS FOR IM3

A general metal-oxide semiconductor (MOS) transistor is a four-terminal device, the terminals being gate, drain,

source and bulk, and the voltages in the transistor are either referred to the source or to the bulk. In the case of a laterally diffused MOS field-effect transistor (LDMOS-FET) used in this work, the voltage between the source and the bulk, v_{bs} , can be neglected because they are tied together. The drain current is described as a function of the gate-to-source voltage, v_{gs} , and the drain-to-source voltage, v_{ds} , and the AC drain current, up to the third-order nonlinear term, can be expressed by the following third-order power series^{1,9}

$$i_d = g_m v_{gs} + K_{2gm} v_{gs}^2 + K_{3gm} v_{gs}^3 + g_0 v_{ds} + K_{2g0} v_{ds}^2 + K_{3g0} v_{ds}^3 + K_{2gm \& g0} v_{gs} v_{ds} + K_{3gm \& 2g0} v_{gs}^2 v_{ds} + K_{3gm \& 2go} v_{gs} v_{ds}^2 \quad (1)$$

where the nonlinear coefficients are defined in **Table 1**.

In order to extract the third-order intermodulation distortion (IM3) level from Equation 1, a FET model is adopted, containing nonlinear C_{gs} , g_m , g_0 and C_{ds} . The gate-to-drain nonlinear capacitance, C_{gd} , has been excluded to simplify the analysis. The nonlinear components can be replaced by linear components and corresponding distortion current sources.^{1,9} The linearized model is shown in **Figure 1**, which contains Norton's equivalent circuit for the input terminal and three nonlinear current sources, i_{NL} , C_{gs} , $i_{NL, gm}$ and $i_{NL, g0 \& C_{ds}}$. Notice that the nonlinear current sources from g_0 and C_{ds} are combined in one source. v_{gs} and v_{ds} are written as functions of frequency as

$$v_{gs}(\omega) = -Z_S(\omega) i_{gs}(\omega) \quad (2)$$

$$v_{ds}(\omega) = -Z_L(\omega) I_{ds}(\omega) \quad (3)$$

where

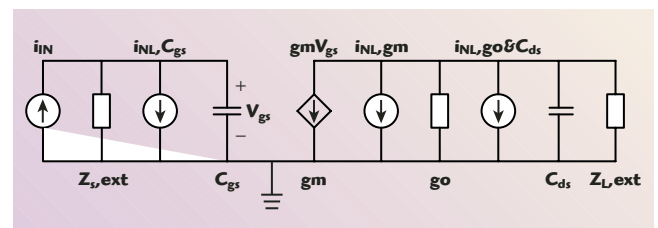
$$Z_S(\omega) = Z_{S,ext}(\omega) \parallel 1 / j\omega C_{gs} \quad (4)$$

$$Z_L(\omega) = Z_{L,ext}(\omega) \parallel 1 / j\omega C_{ds} \parallel 1 / g_0 \quad (5)$$

$$i_{gs}(\omega) = i_{NL, C_{gs}}(\omega) - i_{IN}(\omega) \quad (6)$$

$$i_{ds}(\omega) = g_m v_{gs}(\omega) + i_{NL, gm}(\omega) + i_{NL, g0 \& C_{ds}}(\omega) \quad (7)$$

In Equations 6 and 7, the input current, i_{IN} , has only a fundamental signal component but the nonlinear currents, i_{NL} , have no fundamental component. If an equal power two-tone input signal is applied to the amplifier, from Equation 1, the upper IM3 (IM3U) drain current is found to be



▲ Fig. 1 FET model containing distortion current sources generated by nonlinear C_{gs} , g_m , g_0 and C_{ds} .

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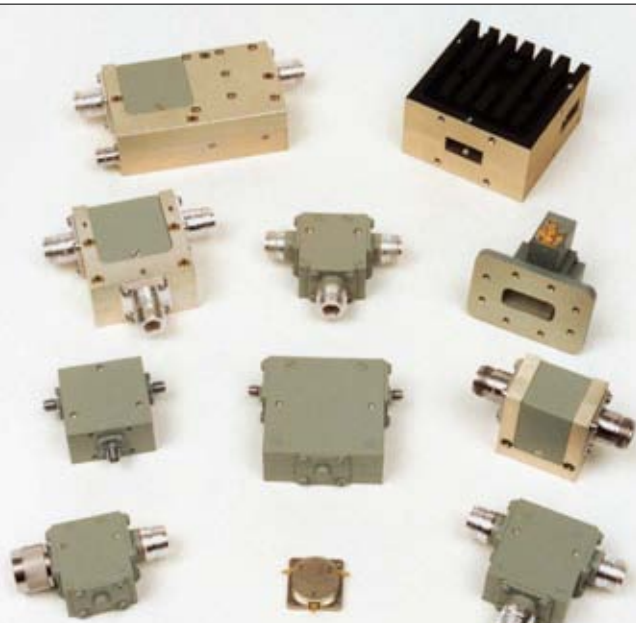
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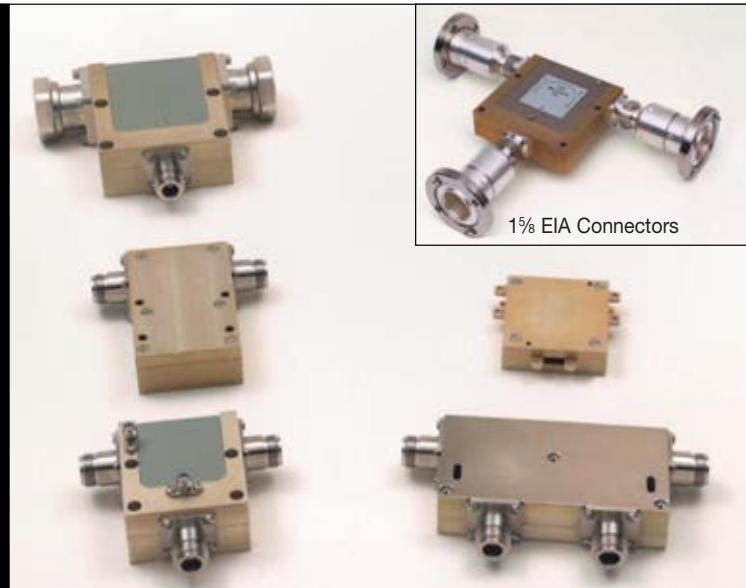
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$$\begin{aligned}
 i_d(2\omega_2 - \omega_1) = & g_m v_{gs}(2\omega_2 - \omega_1) \\
 & + K2_{gm} v_{gs}(\omega_1) v_{gs}(2\omega_2) \\
 & + K2_{gm} v_{gs}(\omega_2) v_{gs}(\omega_2 - \omega_1) \\
 & + \frac{3}{4} K3_{gm} v_{gs}(\omega_1) v_{gs}^2(\omega_2) \\
 & + g_0 v_{ds}(2\omega_2 - \omega_1) \\
 & + K2_{g0} v_{ds}(\omega_1) v_{ds}(2\omega_2) \\
 & + K2_{g0} v_{ds}(\omega_2) v_{ds}(\omega_2 - \omega_1) \\
 & + \frac{3}{4} K3_{g0} v_{ds}(\omega_1) v_{ds}^2(\omega_2) \\
 & + K2_{gm \& g_0} v_{gs}(\omega_1) v_{ds}(2\omega_2) \\
 & + K2_{gm \& g_0} v_{ds}(\omega_1) v_{gs}(2\omega_2) \\
 & + K2_{gm \& g_0} v_{gs}(\omega_1) v_{ds}(\omega_2 - \omega_1) \\
 & + K2_{gm \& g_0} v_{ds}(\omega_1) v_{gs}(\omega_2 - \omega_1) \\
 & + \frac{3}{4} K3_{2gm \& g_0} v_{ds}(\omega_1) v_{gs}^2(\omega_2) \\
 & + \frac{3}{4} K3_{gm \& 2g_0} v_{gs}(\omega_1) v_{ds}^2(\omega_2)
 \end{aligned} \quad (8)$$

The lower IM3 (IM3L) current is identical, but ω_1 and ω_2 are exchanged and the $(\omega_1 - \omega_2)$ term is the complex conjugate of $(\omega_2 - \omega_1)$. Among the fourteen rows of Equation 8, the values of the first, fourth, fifth, eighth, thirteenth and fourteenth rows are not controllable by a matching circuit because the in-band impedance is fixed by the optimum matching point. The values of the remaining eight rows are controllable since they are functions of the gate envelope (third and twelfth rows), gate second harmonic (second and tenth rows), drain envelope (seventh and eleventh rows) or drain second harmonic (sixth and ninth rows) voltages, which are dependant on the harmonic impedances. For convenience, hereafter, the term ‘harmonic’ is applied to the ‘second harmonic’

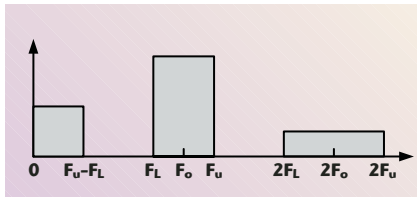


Fig. 2 Spectra distribution of the envelope and second harmonic signals.

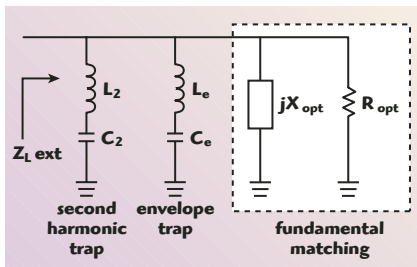


Fig. 3 Ideal output matching circuit with envelope and second harmonic trap circuits.

transmission line. In this case, a wideband short is difficult to achieve, since the dispersion of the line limits the achievable minimum impedance level. Thus, the short should be provided at the gate and drain directly without passing through a quarter-wave line. The termination was achieved by using a simple series LC circuit as will be shown in the following sections.

OUT-OF-BAND IMPEDANCE LIMITATIONS

In this section, the realizable lower limits of the impedances at the second harmonic and envelope frequencies are investigated. This study provides the design guideline for the power amplifier with reduced memory effect.

Ideal Situations

Consider a signal with a center frequency f_o and bandwidth $(f_U - f_L)$. The signal distribution is shown in **Figure 2**, together with the envelope and second harmonic signals. It is assumed that

$$f_o = \frac{(f_U + f_L)}{2} \approx \sqrt{f_U f_L} \quad (9)$$

An ideal matching topology for the output terminal of the FET model is shown in **Figure 3**. The input matching circuit will be identical to the output one. The figure includes the envelope and second harmonic trap circuits as well as an optimum matching circuit for the fundamental signal. This circuit topology is beneficial for the termination of the harmonic voltages compared to the conventional termination at the bias line, since the impedance dispersion caused by the quarter-wave bias line is eliminated. However, the circuit effectively adds up a reactive impedance at the fundamental frequency and should be designed properly. In order to have impedances of the same magnitude at both frequency edges, $2f_L$ and $2f_U$, the second harmonic trap circuit, L_2 and C_2 , must resonate at $2\sqrt{\omega_U \omega_L}$. That is

$$L_2 C_2 = 1 / 4\omega_U \omega_L \approx 1 / (2\omega_0)^2 \quad (10)$$

If the envelope trap and fundamental matching circuits have fairly high impedances at the second harmonic frequency, the output load impedances for the second harmonics, $Z_{L,ext}(2f_U)$ and $Z_{L,ext}(2f_L)$, are complex conjugate and their magnitudes are

$$|Z_{L,ext}(2f_U)| = |Z_{L,ext}(2f_L)| = 4\pi L_2 (f_U - f_L) \quad (11)$$

As expected, the impedances are related to the inductance and signal bandwidth.

Next, a very large capacitor C_e is needed to short the envelope signal. Again, the second harmonic trap and fundamental matching circuits are assumed to have fairly high impedances at the envelope frequency. Then the magnitude of $Z_{L,ext}(f_U - f_L)$ is given by

$$|Z_{L,ext}(f_U - f_L)| = 2\pi L_e (f_U - f_L) \quad (12)$$

From Equations 11 and 12, it can be expected that the envelope impedance, $Z_{L,ext}(f_U - f_L)$, is one half of the second harmonic impedance, $Z_{L,ext}(2f_U)$, for the same magni-

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tude of L_e and L_2 . Finally, the optimal fundamental signal matching is achieved by

$$-jX_{\text{opt}}(\omega) = \{j\omega L_2 + 1/(j\omega C_2)\} \| j\omega L_e \| 1/j\omega C_{\text{ds}} \quad (13)$$

where $\omega_L \leq \omega \leq \omega_U$. If the impedances of the envelope and second harmonic trap circuits at the fundamental frequency are extremely small, it may be impossible to match it in practice. Such a matching problem will restrict the values of L_e , L_2 and C_2 . Thus, the lower limits of the realizable second harmonic and envelope impedances are determined.

Practical Situations

Since a base station PA designer generally uses a packaged transistor, one cannot avoid the inductive effect of the bond-wires between the transistor die and the package lead-frame. The bond-wire inductance may give a certain advantage, such as stabilization of the device and increase of the usable bandwidth, when it is used together with an internal matching circuit. However, it obviously acts as an obstacle in controlling the envelope and harmonic impedances. For this work, the packaged MRF5S21090 LDMOSFET manufactured by Freescale was chosen. The transistor is composed of two 45 W cells and is able to deliver 90 W peak envelope power (PEP). The equivalent circuit with the internal matching of a 45 W cell is shown in **Figure 4**. At the envelope frequency, the capacitors for the internal matching can be ignored and thus the external envelope impedance is changed according to frequency by just the series bond-wire inductors, L_{g1} and L_{g2} for the gate and L_{d2} for the drain. The impedances at the envelope frequency for the input and output, $Z_{S,\text{ext}}(f_U - f_L)$ and $Z_{L,\text{ext}}(f_U - f_L)$, are then given by

$$|Z_{S,\text{ext}}(f_U - f_L)| = 2\pi(L_{g1} + L_{g2} + L_e)(f_U - f_L) \quad (14)$$

and

$$|Z_{L,\text{ext}}(f_U - f_L)| = 2\pi(L_{d2} + L_e)(f_U - f_L) \quad (15)$$

On the other hand, for the second harmonic terminations, the gate and drain external matching impedances outside the package, $Z'_{S,\text{ext}}$ and $Z'_{L,\text{ext}}$, are given by

$$Z'_{S,\text{ext}}(\omega = 2\omega_1 \approx 2\omega_2) =$$

$$-1/(j\omega C_{\text{pad}}/2) \| [j\omega L_{g2} + (j\omega L_{g1} \| 1/j\omega C_{g,\text{mos}})] \quad (16)$$

$$Z'_{L,\text{ext}}(\omega = 2\omega_1 \approx 2\omega_2) = -1/(j\omega C_{\text{pad}}/2) \| j\omega L_{d2} \quad (17)$$

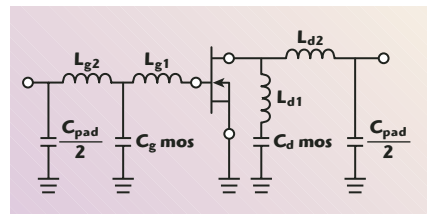
Equations 16 and 17 can be realized easily by a harmonic matching circuit including the series L_2C_2 resonant circuit, because it has a narrow fractional bandwidth contrary to the wide bandwidth of the envelope signal. For the implementation of the envelope termination, a very large capacitor, such as a large tantalum capacitor, with a rather small inductor should be used. The impedance level is limited by the inductors as shown in Equations 14 and 15. Therefore, the envelope is harder to terminate than the second harmonic and the envelope components can be more important than the second harmonics in linearity as well as memory effect. In a practical sense, how-

ever, one cannot guarantee that the envelope trap and fundamental matching circuits have fairly high impedances compared to the second harmonic impedance. As a result, in the envelope trap circuit, a simultaneous matching for the fundamental signal and second harmonic is needed. If the values of the internal matching components are not exactly known, it is very difficult to design the termination circuits. Thus, the circuit has been optimized experimentally for a low memory effect and high linearity, focused on the envelope signal.

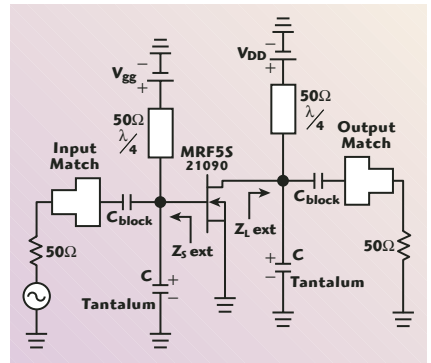
SIMULATIONS

To show the contributions to the memory effect from the gate and drain envelope components, the MRF5S21090 LDMOS model has been simulated using the Advanced Design System version 2004A (ADS2004A) for two-tone signals with a 2.14 GHz center frequency and tone spacings of up to 100 MHz. **Figure 5** shows the circuit diagram for the simulation. In the simulation, a high voltage tantalum capacitor for the envelope trap has been selected and its scattering parameters were extracted with a network analyzer and used to support the practical implementation. The tantalum capacitor has a capacitance of 10 μF , which is large enough to short the envelope signal up to 100 MHz and also has parasitic frequency-dependant resistive and inductive components. The measured impedances of the tantalum capacitor are $0.15 + j0.75 \Omega$ and $0.84 + j15.7 \Omega$ at 100 MHz and 2.14 GHz, respectively. The parasitic inductive impedance, which is approximately 1.2 nH, was used for blocking the fundamental signal instead of L_e . Of course, the inductance should be resonated out by the fundamental matching circuit. It should be noted that the tantalum capacitor, used for the memory effect control, is on the matching circuit, not on the bias line. The gate and drain bias voltages are supplied through the quarter-wave transmission lines which are used to design the conventional narrow-band PA. The characteristic impedances of the lines are 50 Ω and the bias voltages are $V_{\text{GG}} = 4.063$ and $V_{\text{DD}} = 27$ V, respectively. The amplifier operates in class-AB mode with a quiescent drain current of 850 mA.

In order to investigate the effect of the tantalum capacitors, the simulations have been performed for four cases: (1) without the tantalum capacitors; (2) with the tantalum capacitor on the gate only; (3) with



▲ Fig. 4 Equivalent circuit of half of the packaged MRF5S21090 LDMOS.



▲ Fig. 5 Circuit diagram for the MRF5S21090 LDMOS.



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	Linear LNA	24	1.2	16
	Power Amp.	29	2.0	13
		32	2.2	12
MESFET	Linear Amp.	22	2.5	12
		24	2.7	12
HBT	Gain Block	20	3.0	18
		19	5.5	18
		18	5.0	15

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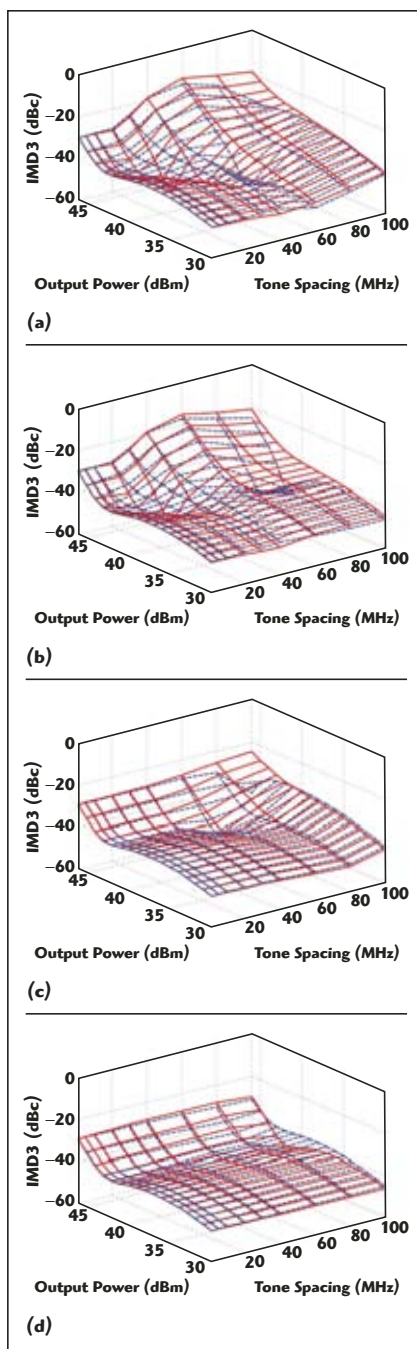
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▲ Fig. 6 Simulation results for the two-tone signals; (a) without capacitors, (b) with a capacitor on the gate only, (c) with a capacitor on the drain only and (d) with capacitors on both gate and drain.

the tantalum capacitor on the drain only; and (4) with the tantalum capacitors on both the gate and drain. In all cases, the input and output matching circuits have been optimized to have the same fundamental impedances, $Z_{S,ext}$ (2.14 GHz) = 2.08 $-j3.54 \Omega$ and $Z_{L,ext}$ (2.14 GHz) = 2.15 $-j2.0 \Omega$, and for a gain flatness within 0.2 dB over the 100 MHz bandwidth and high linearity for a two-tone sig-

nal with 1 MHz tone spacing. The simulation results for the two-tone signals are shown in **Figure 6**. The IMD3 (power ratio of IM3 to the fundamental signal) has been plotted as a function of the average output power and the two-tone spacing. The output power has been swept from 30 to 46 dBm in 1 dB steps for tone spacings of 1, 5, 10, 20, 30, 40, 60, 80 and 100 MHz. The red and blue lines represent the upper and lower limits of IMD3 (IMD3U and IMD3L, respectively). The simulation results show that the proposed PA of case 4 has a drastically reduced memory effect and an improved IMD performance for all tone spacings compared to the conventional one. Thus, it is clear that the envelope component is more important than the second harmonic for the device, since only the envelope has been controlled. The following additional information can be obtained:

- For a narrow-band signal, the quarter-wave transmission line can provide sufficient short for the envelope signal and the memory effect is not important.
- For a medium-band signal, the drain envelope voltage is the dominant component for the memory effect and linearity.
- For a low power and wideband signal, the gate envelope voltage is more important than the drain one. It may be due to the larger multiplication factor than for the drain envelope.
- For a high power and wideband signal, the drain envelope voltage is more important than the gate voltage but both the gate and drain envelope voltages should be controlled to reduce the memory effect and nonlinearity.

As a result, the best way is to minimize both the gate and drain envelope impedances.

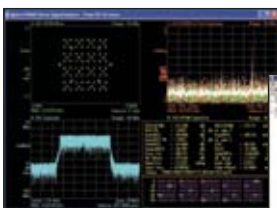
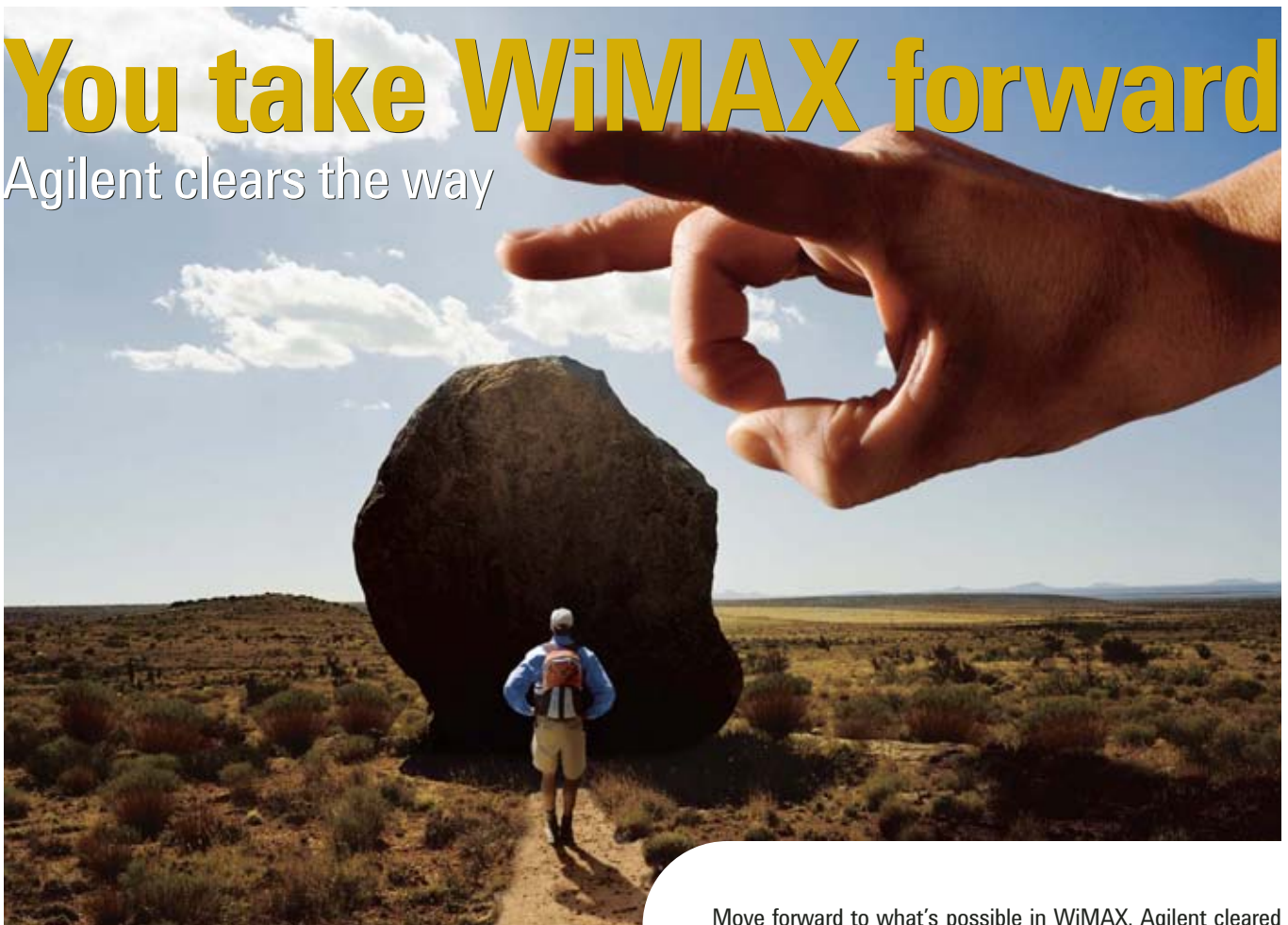
EXPERIMENTAL RESULTS

Wideband Performance Test Using Multi-carrier WCDMA Signals

For experimental demonstration, two PAs have been implemented, with and without the tantalum capacitors (cases 1 and 4), at 2.14 GHz using the MRF5S21090 LDMOS transistors and RF35 printed circuit boards. The PAs have been optimized to have similar performance in gain flatness

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- ▶ Gain 12 ~ 33 dB



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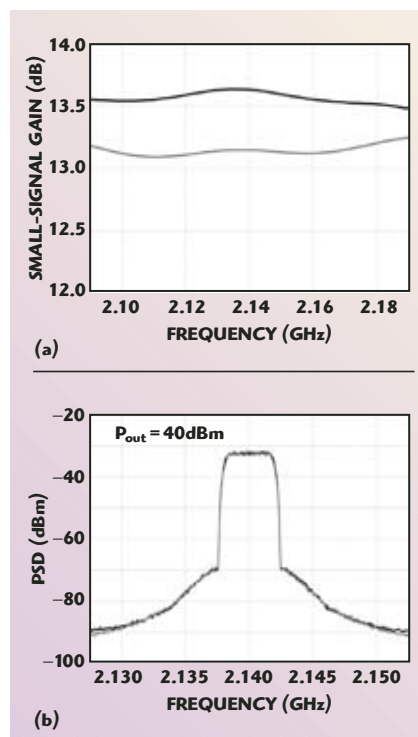
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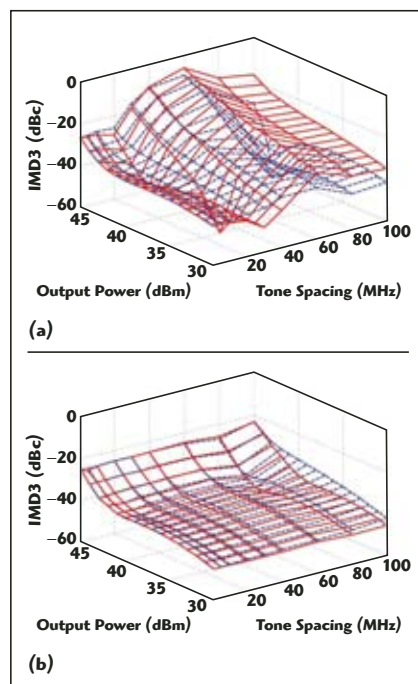
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and linearity to a down-link WCDMA 1FA signal at the same bias point, $V_{DD} = 27$ V and $I_{DSQ} = 850$ mA. **Figure 7** shows the measured small-signal gains and power spectral densities



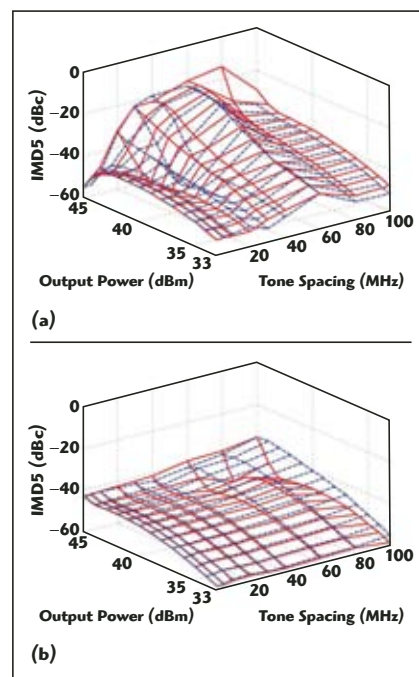
▲ Fig. 7 The measured small-signal gain (a) and WCDMA 1FA spectra (b) at 40 dBm for the conventional (w/o tantalum capacitors) and the proposed (with tantalum capacitors) PAs.



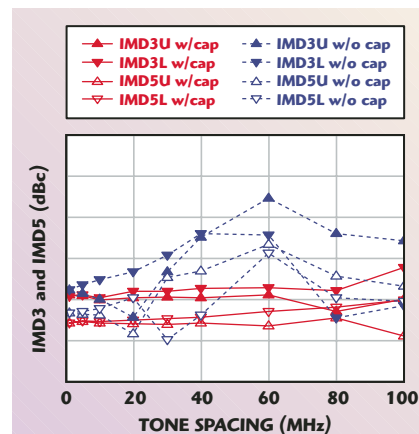
▲ Fig. 8 Measured IMD3 for the two-tone signals (a) without tantalum capacitors and (b) with tantalum capacitors.

(PSD) at an average output power of 40 dBm. The drain efficiencies of the two amplifiers are nearly the same, approximately 18.5 percent at 40 dBm. The PAs deliver flat gains within 0.2 dB over a 100 MHz bandwidth and adjacent channel leakage ratios (ACLR) of approximately -38 dBc.

Like for the simulation, the two PAs have been tested for the two-tone signal. **Figure 8** shows the measured IMD3. The IMD5 has also been measured and the results are shown in **Figure 9**. For convenience, their cross sectional view at 40 dBm is shown in **Figure 10**. The proposed PA, with the tantalum capacitors, displays a state-of-the-art IMD perform-



▲ Fig. 9 Measured IMD5 for the two-tone signals (a) without tantalum capacitors and (b) with tantalum capacitors.



▲ Fig. 10 IMD3 and IMD5 measured at 40 dBm.

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ZHL-5W-2G	800-2000	49	+37	+38	8.0	+44	24	2.0	995.00
ZHL-10W-2G	800-2000	43	+40	+41	7.0	+50	24	5.0	1295.00
ZHL-20W-13	20-1000	50	+41	+43	3.5	+50	24	2.8	1395.00
No Heat Sink/Fan									
ZHL-5W-2GX	800-2000	49	+37	+38	8.0	+44	24	2.0	945.00
ZHL-10W-2GX	800-2000	43	+40	+41	7.0	+50	24	5.0	1220.00
ZHL-20W-13X	20-1000	50	+41	+43	3.5	+50	24	2.8	1320.00
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TABLE II

AVERAGE OUTPUT POWER MEASURED AT -35 dBc ACLR ACCORDING TO THE NUMBER OF WCDMA SIGNAL CARRIERS

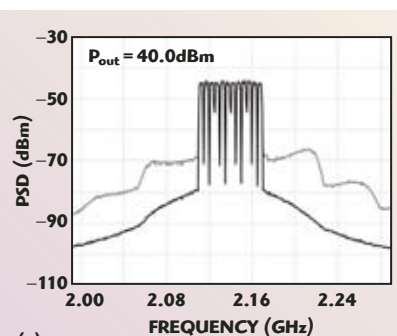
Number of Carriers (FA)	Signal Bandwidth (MHz)	Output Power (dBm)	PAR @ 0.01% CCDF (dB) (Number of Signal Source (EA))
4	20	40.3	9.82 (1)
6	30	40.0	10.23 (1)
8	40	40.3	9.82 (2)
12	60	40.0	10.23 (2)
16	80	39.6	11.30 (2)
20	100	38.9	12.43 (2)

mance in terms of memory effect and linearity. It has an asymmetry of less than 2 dB up to 60 MHz tone spacing for the IMD3 and up to 40 MHz for the IMD5, over all power levels. In order to show the instantaneous wideband performance of the proposed PA, it has been tested for the WCDMA 4, 6, 8, 12, 16 and 20 FA signals, which have 20, 30, 40, 60, 80 and 100 MHz bandwidths, respectively. The 4 and 6 FA signals are generated using Agilent's E4438C signal generator and the remainders using two generators. The test

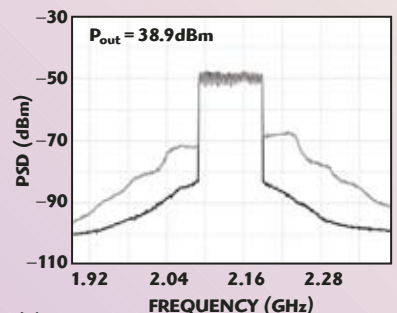
method is to measure the average output power at -35 dBc ACLR for the respective signals and the results are shown in **Table 2**, together with the signal information. The test result shows that the performance of the proposed PA is mainly dependent on the peak-to-average power ratio (PAR), but not on the signal bandwidth. This is due to the extended instantaneous bandwidth of the PA. **Figure 11** shows the measured power spectral densities (PSD) for the WCDMA 12 and 20 FA signals. For the comparison, the spectra of the conventional PA have been also displayed. The proposed PA delivers a linear power amplification performance for a wideband signal compared to the conventional one.

Predistortion Linearization Test for Confirming the Reduced Memory Effect

In order to confirm the reduced memory effect, the output spectra of the two PAs have been compared for a WCDMA 4FA signal with 20 MHz bandwidth and linearized the pro-

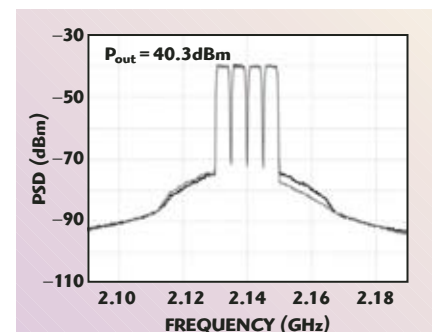


(a)



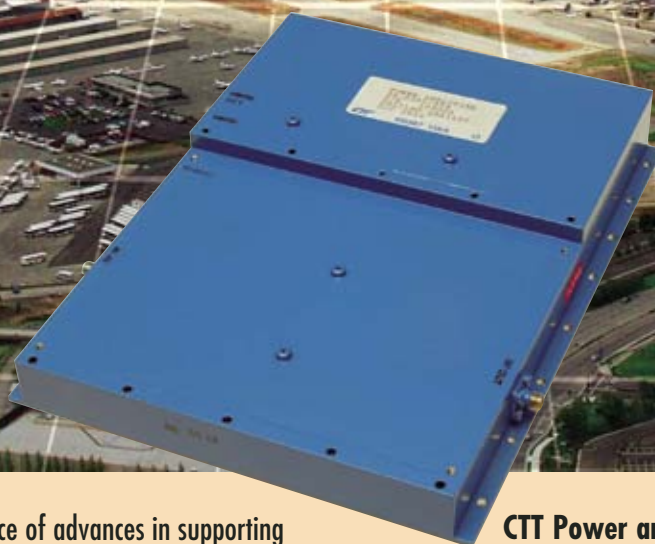
(b)

▲ Fig. 11 Measured WCDMA 12 (a) and 20FA (b) spectra for amplifiers with and without tantalum capacitors.



▲ Fig. 12 Measured WCDMA 4FA spectra for PAs with and without tantalum capacitors.

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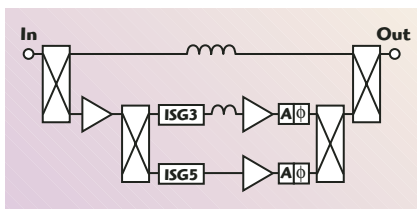
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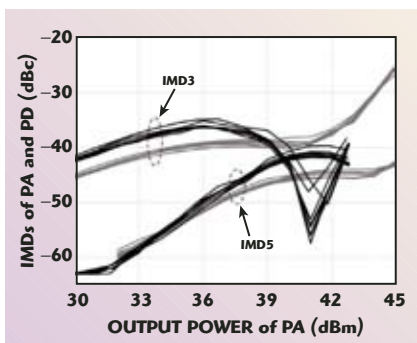
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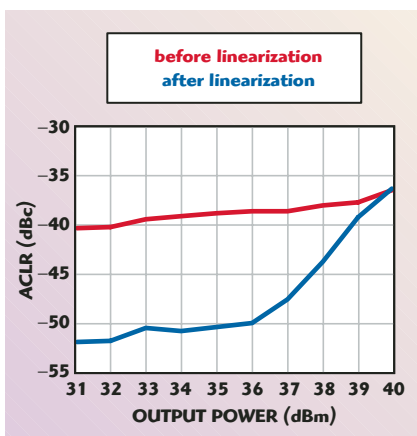
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▲ Fig. 13 Block diagram of the implemented third- and fifth-order analog predistorter.



▲ Fig. 14 Measured two-tone (up to 2 MHz spacing) characteristics of the PA and PD.



▲ Fig. 15 Measured ACLR for the WCDMA 4FA signal before and after linearization.

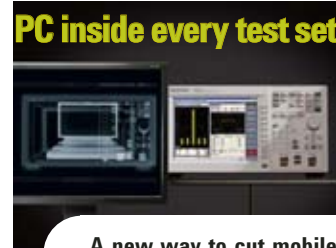
posed PA using an analog predistorter (PD). It is a good approach, since the memory effect restricts mainly the linearization level of PDs. **Figure 12** shows the measured WCDMA 4FA spectra, which deliver an average output power of 40.3 dBm with an ACLR of approximately -35 dBc. As predicted, the proposed PA delivers a well-balanced spectrum but the conventional one does not.

A third- and fifth-order analog PD was constructed to linearize the proposed PA. The block diagram for the implemented PD is given in **Figure 13**.⁶ The two-tone characteristics for the proposed amplifier and PD up to 20 MHz tone spacing are represented in **Figure 14**. As shown, the IMD

characteristics between the PA and PD are similar up to the output power of about 39 dBm, implying that the PA can be linearized below that power if it is memory-less.² **Figure 15** shows the linearization result for the WCDMA 4FA signal. The PA has been linearized by more than 11 dB at average output powers below 36 dBm. If the IMD characteristic of the PD at high power levels is similar to that of the PA, a better linearization performance could be achieved at the high power levels. Nevertheless, the test results are sufficient to show that the memory effect of the proposed PA is drastically reduced. Contrary to the low memory PA, the conventional PA does not produce any significant error cancellation, less than 2 dB linearization.

CONCLUSION

The IM3 components of a power amplifier have been analyzed using third-order power series. The envelope and second harmonic voltages create additional nonlinear components over the internal IM3 generation. The voltages are major sources of memory effect. They can be eliminated by providing a short at the envelope and second harmonic frequencies on the gate and drain terminals of the device. But there are some practical limits for reduced impedances. Through analysis and simulation, it was proved that the envelope voltage is a more important source than the second harmonic for the memory effect and linearity. In order to minimize the memory effect and extend the instantaneous bandwidth, the envelope signals have been shorted using a large capacitor and small inductor. The inductor is practically a short at the envelope frequency, but has a high impedance at the fundamental frequency. The circuit can be realized using a large tantalum capacitor, with its parasitic inductive impedance of about 1.2 nH used to block the fundamental signal, instead of using additional inductors. For two-tone signals with up to 100 MHz tone spacing, the contributions to the memory effect and nonlinearity of the gate and drain envelope voltages have been simulated according to tone spacings and power levels. The simulation results have displayed the drastically reduced memory effect



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and the improved IMD performance for the proposed amplifier.

For the experiment, the proposed amplifier has been implemented using Freescale's MRF5S21090 LDMOS-FET with a 90 W PEP at 2.14 GHz and tested using two-tone and down-link multi-carrier WCDMA signals. For the two-tone signals, the experimental results are similar to the simulation. For the multi-carrier down-link WCDMA signals up to 20 FA, with a 100 MHz signal bandwidth, a nearly bandwidth-independent linearity characteristic has been found for the amplifier. The proposed amplifier has delivered well-balanced and considerably linearized spectra for the multi-carrier WCDMA signals, up to 20 FA, compared to the conventional one. The reduced memory effect could be confirmed by a predistortion linearization test for a WCDMA 4FA signal. These experimental results demonstrate clearly that the proposed power amplifier is the best performing wideband amplifier for next generation base station applications. ■

ACKNOWLEDGMENTS

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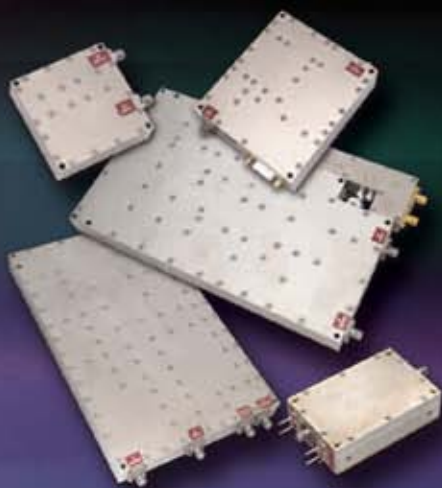
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DUAL-BAND ASSEMBLY OF INTEGRATED SHORT BACKFIRE ANTENNAS

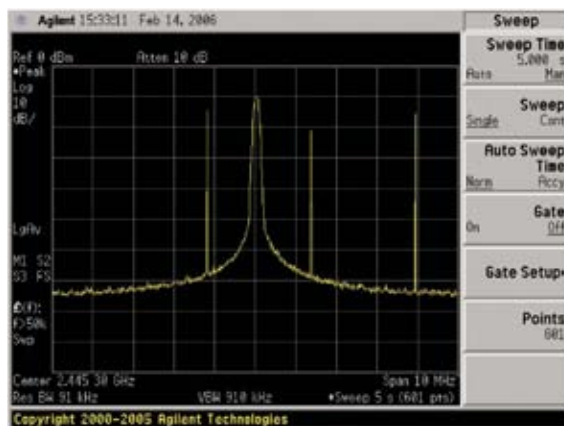
A dual-frequency assembly of two short backfire (SBF) antennas, one large for low frequencies (LF) and one small for high frequencies (HF), is described in this article. The two antennas are located on the same axis and, since they have a common reflector, are regarded as integrated. Such integration is cost-effective, compact, robust and simple to build. Simple design equations for the octagonal reflectors are proposed in this article and a method of moment (MoM)-based electromagnetic solver was utilized for a numerical study of two SBF antenna constructions: a 3 GHz single (not integrated) antenna and a 1.2/4.8 GHz dual-frequency antenna assembly. The accuracy of the design and numerical analysis procedure was confirmed by comparing the results obtained for the 3 GHz octagonal SBF, with reliable experimental data of an antenna prototype with circular reflectors. The single 1.2 and 4.8 GHz octagonal SBF antennas were found to have gain values of 14.4 and 15 dB, respectively, while the corresponding values for the integrated version are 14.2 and 15.4 dB.

The short backfire (SBF) is a highly effective aperture antenna of simple and compact construction. Basically, it consists of three elements: two parallel reflectors, large and small, spaced a half-wavelength apart, which form a leaky resonant cavity, and a cavity feed (half-wave dipole,^{1–3} waveguide or horn,^{4,5} or microstrip antenna^{6,7}). The large and small antenna reflectors are usually circular in shape and have diameters that may vary within the ranges $(1.5\text{--}2.3)\lambda_0$ and $(0.3\text{--}0.65)\lambda_0$, respectively. However, from classical gain, bandwidth, match and size considerations, the large reflector is typically set to $2\lambda_0$ and the small reflector to $0.5\lambda_0$. The dipole feed is positioned at the mid-point between reflectors,

that is at a distance $0.25\lambda_0$ from each of them. Here, λ_0 is the antenna resonant (design) wavelength. As a rule, the large reflector is fit with a quarter- or half-wavelength wide rim, which results in side lobe and back lobe pattern reduction and a gain increase. The SBF antenna dimensions given above are based on the extensive experience of many researchers⁸ and provide the reference for this work.

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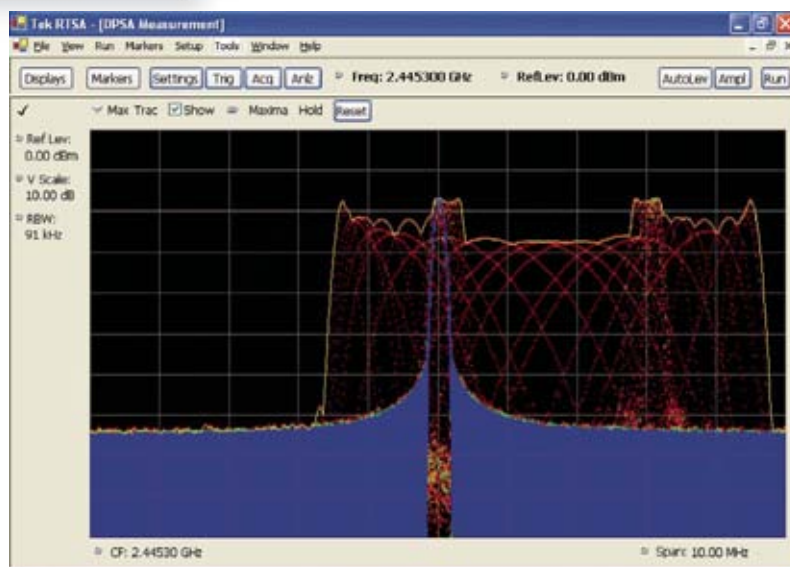
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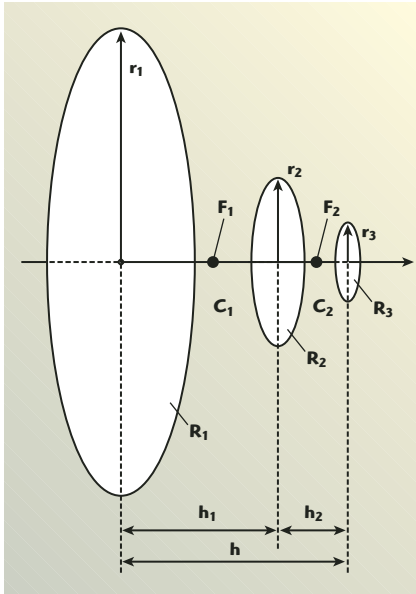
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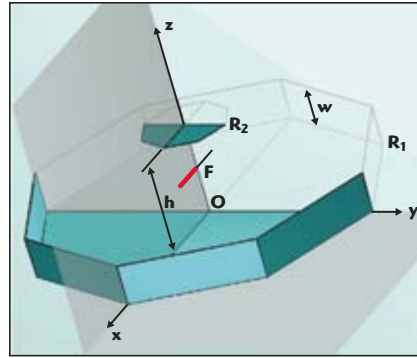
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▲ Fig. 1 Geometry of a dual-band SBF antenna assembly with circular reflectors.

Henceforth, they are referred to as standard dimensions. Although often circular, the backfire reflectors can have various shapes: polygonal (square, hexagonal, octagonal), elliptical, etc. The short backfire antenna has been used extensively as a directive building element in various single-band broadside arrays.^{9,10} A dual-frequency assembly (array) of two short backfire antennas (large or LF and small or HF) is described in this article. The antennas are arranged on the same axis and, since they have a common reflector, are regarded as integrated. In this way, the following advantageous effects are achieved. First, the common reflector plays two roles at once: as a small reflector for the LF antenna and as a large reflector for the HF antenna. Second, the blocked aperture region, resulting from the small reflector of the LF antenna, is exploited for the HF antenna. Such integration makes the SBF assembly simple to build, compact and robust. For standard radii of the disk reflectors, the low and high design frequencies of the two dipole-fed antennas should be in the standard proportion 1:4.^{1,2} Circular (disk) reflectors are frequently replaced by polygonal, and, in particular, by octagonal reflectors, which are close in shape to the circular ones and are very practical for construction.^{11,12} This article's first author originally introduced the dual-band assembly of two integrated octagonal short back-



▲ Fig. 2 Half portion of a single SBF antenna computer-simulated model.

fire antennas.⁸ This SBF antenna system was employed 25 years ago in an UHF earth station for satellite tracking and space telemetry that operated at the frequencies 137 and 470 MHz, that is for a reflector design frequency ratio of 1:3.43, which differs from the standard frequency proportion. At that time, the dual-frequency SBF antenna assembly was designed based on approximated analytical equations and was optimized experimentally by means of the conventional “cut and try” routine. The work reported here started with the design of a single 3 GHz SBF antenna with octagonal reflectors. The resultant numerically obtained radiation parameters were checked against experimental ones for a SBF antenna with circular reflectors,³ and found equivalent in gain. This allowed a validation of the design procedure. Next, the SBF antenna design and numerical procedures were extended to the axial arrangement of two integrated octagonal SBF antennas, large and small, and tuned respectively at 1.2 and 4.8 GHz, according to the optimum frequency proportion of 1:4. In contrast with the previous dual-band SBF antenna development, the availability of specialized electromagnetic tools, such as the method of moments (MoM)-based WIPL-D software,¹³ now allows a more rapid, thorough and precise design process.

BASIC GEOMETRY OF TWO INTEGRATED SHORT BACKFIRE ANTENNAS

Figure 1 shows the basic configuration of a dual-frequency assembly of two integrated SBF antennas, stacked along the Z axis. The disk reflectors are specified as R_1 , R_2 and R_3 . They have radii r_1 , r_2 and r_3 , cor-

respondingly, which are chosen here equal to the standard values

$$\begin{aligned} r_1 &= \lambda_{1,0} \\ r_2 &= 0.25\lambda_{1,0} = \lambda_{2,0} \\ r_3 &= 0.25\lambda_{2,0} \end{aligned} \quad (1)$$

where $\lambda_{1,0}$ and $\lambda_{2,0}$ are the two design wavelengths.

The reflector doublets R_1R_2 and R_1R_3 form the two open SBF resonant cavities (antennas) C_1 and C_2 of axial lengths $h_1 \approx 0.5 \lambda_{1,0}$ and $h_2 \approx 0.5 \lambda_{2,0}$, respectively. Thus, the total antenna length is $h = h_1 + h_2 \approx 0.625 \lambda_{1,0} \approx 2.5 \lambda_{2,0}$. The second disk reflector R_2 is common to the two antenna cavities and acts as a small reflector for the cavity C_1 and a large reflector for the cavity C_2 , that is the two SBF cavities (antennas) are integrated in one double-frequency structure. The cavities are fed by single-wire half-wave dipoles, F_1 and F_2 , respectively, and are matched to their feed cables at the design frequencies $f_{1,0} = c/\lambda_{1,0}$ and $f_{2,0} = \lambda c/\lambda_{2,0}$. Here, $c = 3 \cdot 10^8$ m/s is the free-space wave velocity. From Equation 1, it follows that the frequency ratio $k_f = f_{2,0}/f_{1,0}$ is equal to four as is the ratio between the disk radii, $r_1/r_{1+i} = k_f = 4$, $i = 1, 2$.

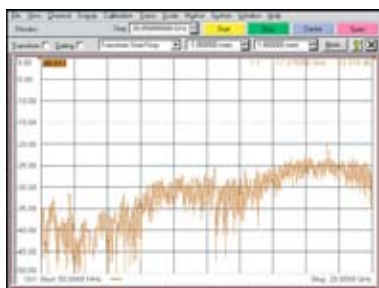
COMPUTER-AIDED DESIGN: VALIDATION OF THE METHODOLOGY FOR SINGLE SHORT BACKFIRE ANTENNA WITH OCTAGONAL REFLECTORS

Figure 2 shows the half portion of the 3D computer simulation model of a single SBF antenna. The antenna comprises two octagonal reflectors, the rimmed large reflector R_1 and the planar small reflector R_2 , made of a metal sheet of thickness $t = 2$ mm. The leaky cavity formed by the reflectors is fed through a half-wave dipole F positioned in the middle of them. The reflector rim has a half-wavelength width. The general n -sided polygonal reflector is regarded as a good approximation to the disk reflector when both have equal surfaces.¹³ This condition is satisfied if the j -th ($j = 1$ or 2) polygonal reflector is inscribed into the corresponding circle of equivalent radius r'_j given by

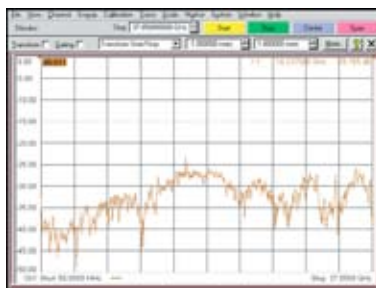
$$r'_j = r_j \sqrt{\frac{2\pi}{n \sin\left(\frac{2\pi}{n}\right)}} \quad (2)$$

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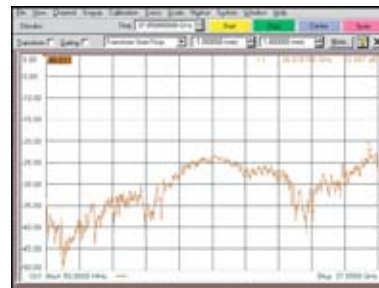
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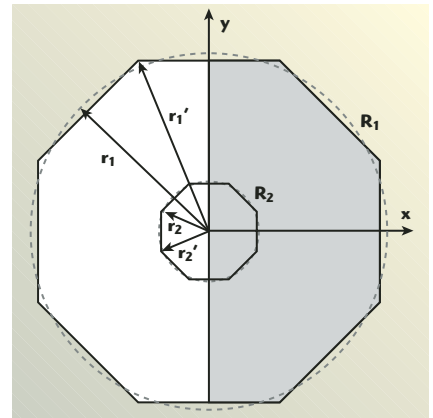
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where r_i is equal to $r_1 = \lambda_0$ or $r_2 = 0.25\lambda_0$, the radius of the respective large and small circular reflectors, where λ_0 is the design wavelength.

In the case of octagonal reflectors $n = 8$ and $r'_i = 1.054r_i$, and thus, for the single octagonal reflector SBF antenna, Equation 1 yields

$$\begin{aligned} r'_1 &= 1.054r_1 \\ r'_2 &= 1.054r_2 = 0.264\lambda_0 \end{aligned} \quad (3)$$

The circular reflectors of radii r_1 and r_2 , and the equal-in-surface octagonal reflectors of radii r'_1 and r'_2 , respectively, are projected together in the transverse plane xOy , as shown in **Figure 3**. A design frequency of 3 GHz was chosen to compare the computational results with the reliable experimental data for a SBF antenna that, as part of separate research, was built and measured at AFCRL.³ The present numerical



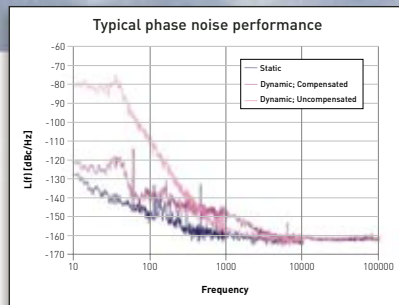
▲ Fig. 3 xOy -plane projection of the computer-simulated model of the half portion of a single octagonal SBF antenna.

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TABLE I
DIMENSIONS AND RADIATION
PARAMETERS OF 3 GHz ANTENNAS
WITH CIRCULAR AND EQUIVALENT
OCTAGONAL REFLECTORS

Basic Dimensions and Parameters

Big reflector diameter (mm)	$2\gamma_1 = 200 (2\lambda_0)^\circ$ $2\gamma'_1 = 210.8 (2.11\lambda_0)^{\circ*}$
Small reflector diameter (mm)	$2\gamma_2 = 50 (0.5\lambda_0)^\circ$ $2\gamma'_2 = 52.7 (0.527\lambda_0)^{\circ*}$
Distance between big reflector and dipole feed (mm)	$25 (0.25\lambda_0)^\circ$
Distance between big and small reflector (antenna length) (mm)	$50 (0.5\lambda_0)^\circ$
Rim depth (mm)	$50 (0.5\lambda_0)^\circ$
Metal sheet thickness (mm)	$2^{\circ*}$
Directive gain (dB)	15.1° $14.7^{\circ*}$
Aperture efficiency (%)	83° $76^{\circ*}$
Half-power beamwidth	$34^{\circ*}$ 34° average $^{\circ*}$
First side lobe level (dB)	$\leq -22^\circ$ $\leq -23^{\circ*}$
Back lobe level (dB)	$< -30^\circ$ $< -27^{\circ*}$
Max. cross-polar level (dB)	-21 (at 45° plane) $^{\circ*}$
$^{\circ}$ Standard Prototype with Disk Reflectors ^{3,8} $^{\circ*}$ Computer-simulated Model with Octagonal Reflectors	

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treatment considers octagonal reflectors designed according to Equations 2 and 3, and the analysis was made by means of the WIPL-D electromagnetic software. The measured and numerical dimensions and radiation parameters of the circular SBF prototype and its equivalent octagonal model are summarized and compared in **Table 1**.

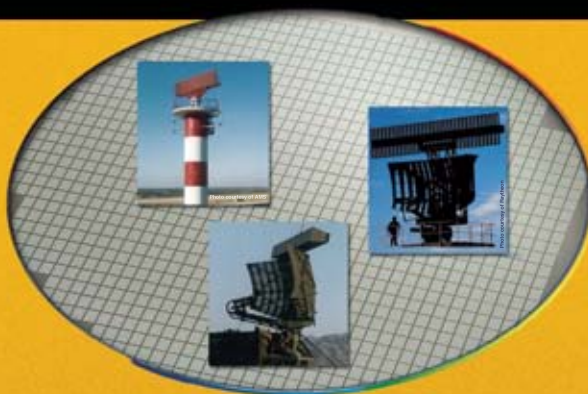
The WIPL-D simulated numerical patterns of the 3 GHz octagonal

model and the experimental patterns of the corresponding AFCRL circular prototype are shown in **Figure 4** for the E-plane and the H-plane cuts. As seen, the octagonal-reflector antenna has numerical radiation parameters very close to those measured for the corresponding circular-reflector prototype. This provides evidence that Equations 1 and 3, introduced by the authors, and the numerical simulation procedure, are well suited for

the design of equivalent octagonal reflector SBF antennas and assemblies. The resonant input resistance of the free-space located single-wire feed dipole, with a 0.005 to 0.01 radius to lambda ratio, ranges from approximately 60 to 70 Ω and is therefore roughly matched to a 50 Ω cable. But, placed between the two reflectors, its input resistance decreases to approximately 17 to 20 Ω , which corresponds to a VSWR of 3.0 to 2.5. A better input match can be achieved by using an appropriate matching device, which may cause additional antenna loss and bandwidth reduction. The present work has shown that, in the case of a short backfire antenna, a very good input match to a 50 Ω cable is possible by using one of the following two techniques: a feed antenna with much greater free-space input resistance, 300 Ω folded dipole, for instance,¹⁴ or a small deviation from the standard half-wavelength SBF antenna length. In both cases, the feed dipole is positioned in the middle between the reflectors.

The input match for three versions of the SBF antenna is illustrated in

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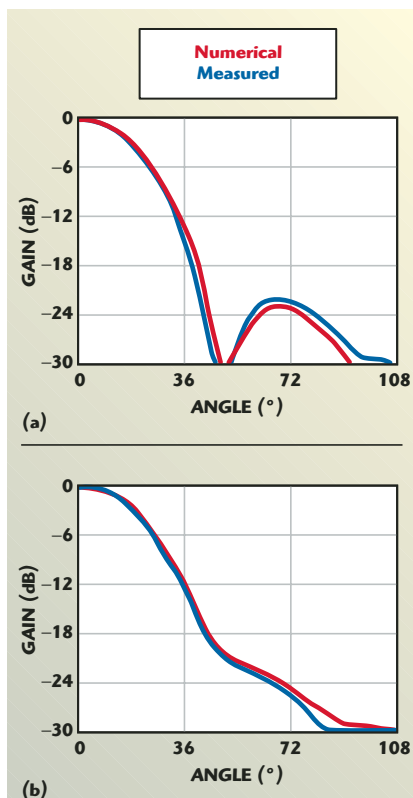


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▲ Fig. 4 Computer-simulated and measured gain radiation pattern of a 3 GHz single BF antenna; (a) E-plane and (b) H-plane.

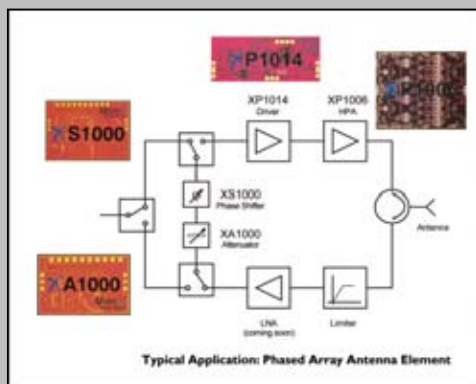


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Figure 5, where the reflection coefficient S_{11} is drawn versus the frequency. Case 1 is for a standard-size SBF antenna fed by a single-wire half-wave dipole with a diameter of 1.5 mm and a length of 20.7 mm, or equal to 0.207λ . For the design frequency $f_0 = 3$ GHz, S_{11} is -7.25 dB. This corresponds to a VSWR (at f_0) of 2.45, or to a mismatch power loss of 0.9 dB. Case 2 is for the same standard-size SBF antenna but fed by a folded two-

wire dipole, 5 mm in width and 17.5 mm in length. The first dipole wire, in the center of which the feed terminals are located, is 2 mm in diameter, while the second dipole wire has a diameter of 1.5 mm. In Case 3, the SBF antenna is similar to that of Case 1 with the only difference that the antenna length is slightly increased for better impedance match: from $0.5\lambda_0$ (50 mm) to $0.56\lambda_0$ (56 mm). The minimum or design frequency values of

S_{11} in Case 2 and Case 3 are smaller than -40 dB, which is far below the -10 dB level. It is known that the free-space single-wire half-wave dipole has a smaller input bandwidth than the corresponding folded (two-wire) dipole. Placed in the cavity of the increased-length SBF antenna, the single-wire dipole has a bandwidth of 6.2 percent, which is much greater than the bandwidth of 2.8 percent for the SBF antenna fed by the folded dipole. The SBF antenna rim width is not very important for the input match quality, but it plays a key role for the antenna gain, radiation pattern shape and polarization. If $w = 0$, the SBF antenna with octagonal reflectors has a gain of 13.2 dBi, which is 1.8 dB below the gain of the SBF antenna with a half-wave rim (see Table 1).

DESIGN OF TWO INTEGRATED SHORT BACKFIRE ANTENNAS WITH OCTAGONAL REFLECTORS

Based on the previous results, a system of two integrated SBF antennas (see **Figure 6**) is considered, comprising



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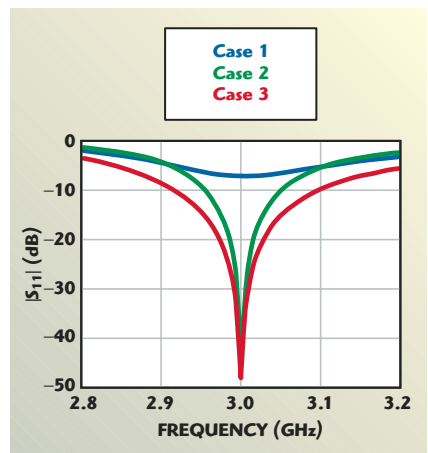


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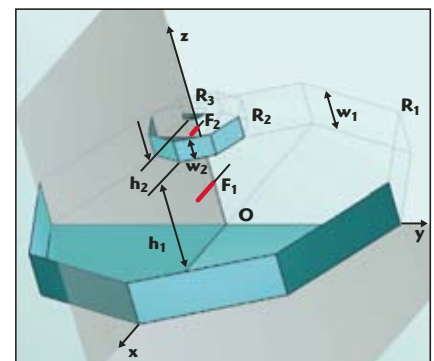
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▲ Fig. 5 Magnitude of S_{11} for three different cases.



▲ Fig. 6 Half portion of an integrated octagonal short SBF antenna computer-simulated model.



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ing three octagonal rather than circular reflectors, R_1 and R_2 (rimmed) and R_3 (not rimmed), and two half-wave dipoles as feeds, F_1 and F_2 . As was found from Equation 2, in the case of octagonal reflectors $r'_j = 1.054r_j$, and thus Equations 1 are modified here to

$$\begin{aligned} r'_1 &= 1.054\lambda_{1,0} \\ r'_2 &= 0.264\lambda_{1,0} = 1.054\lambda_{2,0} \\ r'_3 &= 0.264\lambda_{2,0} \end{aligned} \quad (4)$$

In **Table 2**, the basic dimensions of a dual-band assembly consisting of two SBF integrated octagonal antennas are summarized for the respective design frequencies (wavelengths): $f_{1,0} = 1.2$ GHz ($\lambda_{1,0} = 250$ mm) and $f_{2,0} = 4.8$ GHz ($\lambda_{2,0} = 62.5$ mm). The reflector radii r'_1 , r'_2 and r'_3 have been calculated from Equations 2 and 4, and the half-wave rim widths w_1 and w_2 of reflectors R_1 and R_2 were set to $0.25\lambda_{1,0}$ and $0.5\lambda_{2,0}$, respectively. For the given di-

pole-wire radii, $a_1 = 0.008\lambda_{1,0}$ and $a_2 = 0.008\lambda_{2,0}$, the rest of the dimensions, that is the individual antenna lengths h_1 and h_2 and the feed-dipole resonant lengths l_1 and l_2 , were found by computer optimization for best possible gain and input match to a 50 Ω cable. In both antennas, a good input match was produced by a small increase of the standard half-wavelength antenna length, 5.2 percent for the LF antenna and 16.2 percent for the HF antenna. As seen from Table 2, the optimum antenna lengths h_1 and h_2 expressed in the corresponding design wavelengths are different, which is due to the dissimilarity in their rim widths w_1 and w_2 , joint antenna positioning and electromagnetic influence. The total antenna length includes also the second reflector thickness t_2 , or $h = h_1 + h_2 + t_2$. In order to increase the compactness of the overall design, the rim of the large reflector R_1 was chosen as $\lambda_{1,0}/4$, whereas for the HF antenna, gain improvement results from choosing the rim of the common reflector R_2 as $\lambda_{2,0}/2$. The radiation patterns of the optimized single and integrated octagonal short backfire antennas are subsequently presented. **Figure 7** illustrates the co-polar (a) and cross-polar (b) 45°-plane gain radiation patterns of the 1.2 GHz single and integrated SBF anten-

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TABLE II

DIMENSIONS OF DUAL-BAND ASSEMBLY OF OCTAGONAL SBF ANTENNAS FOR DESIGN FREQUENCIES (WAVELENGTHS) 1.2 GHz (250 mm) AND 4.8 GHz (62.5 mm)

$$r'_1 = 263.5 \text{ mm or } 1.054\lambda_{1,0}$$

$$r'_2 = 65.9 \text{ mm or } 0.264\lambda_{1,0}$$

$$r'_3 = 16.5 \text{ mm or } 0.264\lambda_{2,0}$$

$$w_1 = 62.5 \text{ mm or } 0.250\lambda_{1,0}$$

$$w_2 = 31.2 \text{ mm or } 0.500\lambda_{2,0}$$

$$h_1 = 131.5 \text{ mm or } 0.526\lambda_{1,0}$$

$$h_2 = 36.3 \text{ mm or } 0.581\lambda_{2,0}$$

$$h = 169.3 \text{ mm or } 0.667\lambda_{1,0}$$

$$\alpha_1 = 2.0 \text{ mm or } 0.008\lambda_{1,0}$$

$$\alpha_2 = 0.5 \text{ mm or } 0.008\lambda_{2,0}$$

$$l_1 = 48.9 \text{ mm or } 0.196\lambda_{1,0}$$

$$l_2 = 10.5 \text{ mm or } 0.168\lambda_{2,0}$$

$$t_1 = 2.5 \text{ mm or } 0.010\lambda_{1,0}$$

$$t_2 = 1.5 \text{ mm or } 0.024\lambda_{2,0}$$

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S8W2	8	±0.60
S9W2	9	-0.4, +0.8
S10W2	10	±0.60
S12W2	12	±0.60
S15W2	15	±0.60
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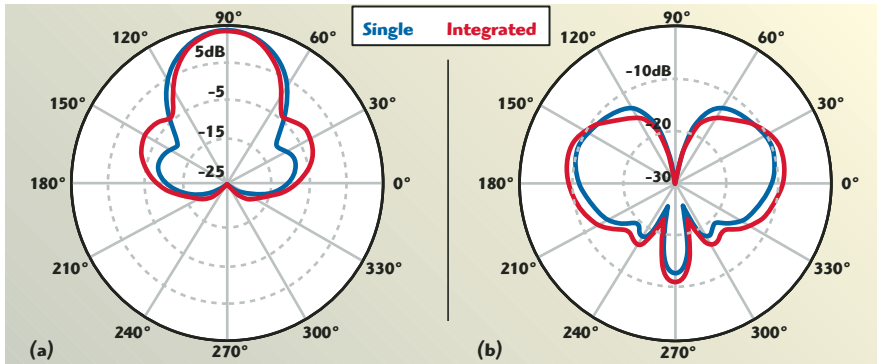


Fig. 7 Co-polar (a) and cross-polar (b) 45°-plane radiation patterns of 1.2 GHz single and integrated SBF antennas.

nas. As seen from these figures, the integrated short backfire antennas have radiation patterns that do not differ much from those of the single backfire antennas. The co-polar 45°-plane patterns of the single and integrated antennas are close except in the side lobe regions, where the electromagnetic shadowing by the small antenna causes approximately a 5 dB increase in the side lobe levels. It is found that the antenna integration produces a gain reduction of only 0.2 dB and a maximum cross-polarization increase of 1.4 dB. Similar co-polar and cross-polar radiation patterns of the single and integrated 4.8 GHz antennas are shown in **Figure 8**. Here the integration does not produce a gain reduction but a gain enhancement of 0.4 dB. This apparent inconsistency in the gain behavior may be attributed to the difference in the rim widths and to the dissimilarity in the electromagnetic shadowing and mutual input coupling. Because the feed dipoles of the two SBF antennas are well isolated by their leaky wave cavities, the mutual coupling between the

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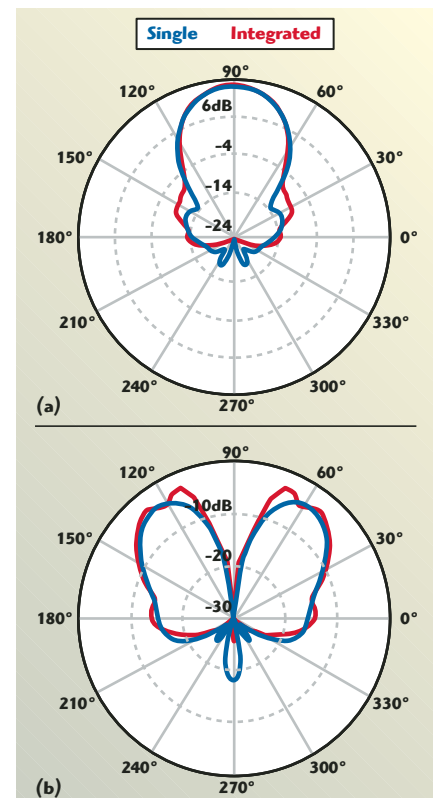


Fig. 8 Co-polar (a) and cross-polar (b) 45°-plane radiation patterns of 4.8 GHz single and integrated SBF antennas.

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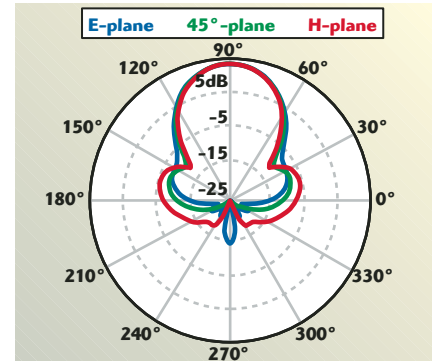
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two feed ports is very small, less than -50 dB at the LF port and less than -35 dB at the HF port.

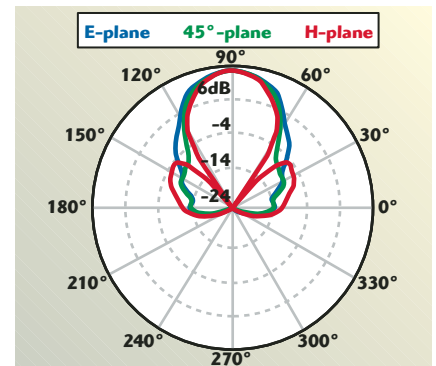
In both LF and HF SBF antennas, the size adjustment resulting from the optimization process does not significantly deteriorate the original or standard-size antenna radiation patterns. **Figures 9 and 10** show the co-polar radiation patterns of the 1.2 GHz and 4.8 GHz integrated SBF antennas in three cut planes: E-plane, 45°-plane and H-plane.

plane. It is seen that the main lobe of the 1.2 GHz antenna has an almost rotational symmetry, which does not hold for the 4.8 GHz antenna main lobe and for the side lobes of both antennas. In the HF antenna, a significant side lobe reduction compared to the LF antenna is produced, ranging from 3 to 15 dB in an angular region of 150° . **Figure 11** compares the corresponding co-polar and cross-polar 45°-plane radiation patterns of the 1.2 and 4.8 GHz integrated

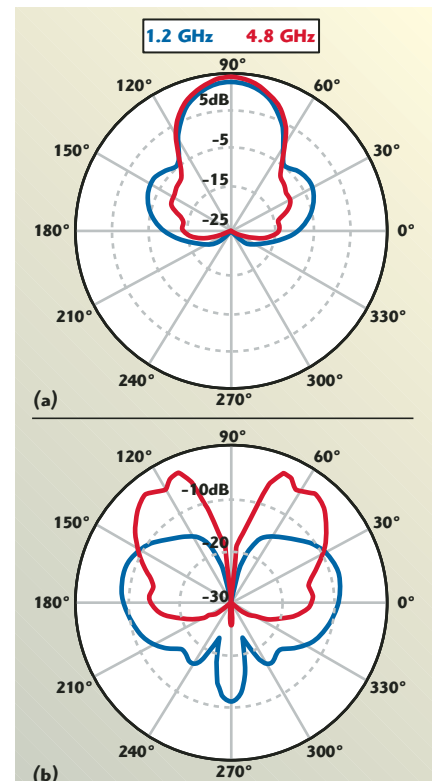
antennas. From the co-polar patterns, it is obvious that the HF antenna has a



▲ Fig. 9 Co-polar gain patterns of an integrated 1.2 GHz SBF antenna.



▲ Fig. 10 Co-polar gain patterns of a 4.8 GHz antenna.



▲ Fig. 11 Co-polar (a) and cross-polar (b) 45°-plane radiation patterns of two integrated antennas.

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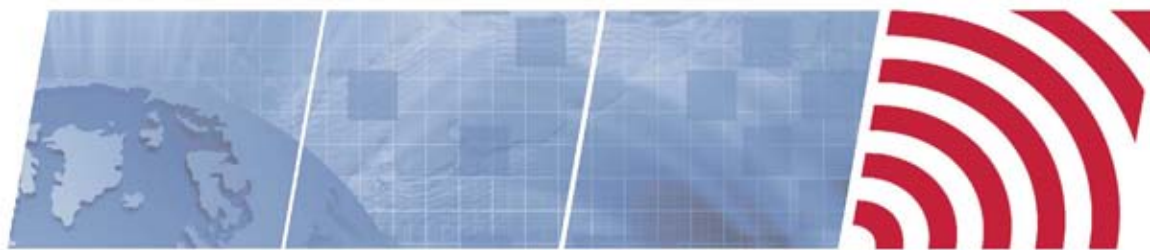
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1.2 dB larger gain and much lower secondary lobes and back-to-front ratio. In contrast, the LF antenna has a broader and lower level cross-polar pattern in the main lobe area.

Finally, the 3D co-polar and cross-polar gain patterns are plotted in **Figure 12** for the 1.2 GHz integrated antenna and in **Figure 13** for the 4.8 GHz integrated antenna. The basic antenna parameters of the single (non-integrated) and integrated SBF antennas are summarized in **Table 3**, which also specifies the match and bandwidth antenna properties. The integrated SBF antennas have a very good resonance input match and frequency bandwidth, which are better than those of the non-integrated SBF antennas matched also by means of antenna length optimization.

CONCLUSION

An assembly of two axially integrated short backfire antennas, tuned

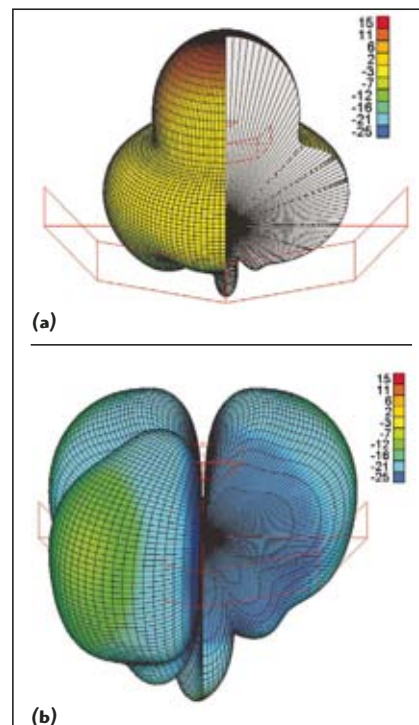
at frequencies in a ratio of 1:4, was described and studied numerically. An approximate design equation for dimensioning the SBF antenna octagonal reflectors is proposed and combined with a MoM-based electromag-

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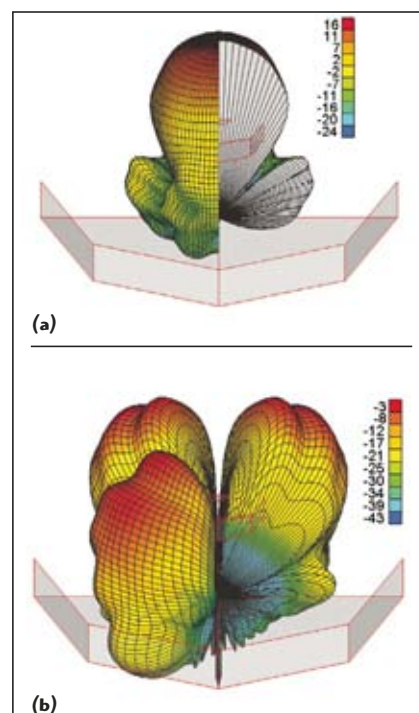
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▲ Fig. 12 Three-dimensional co-polar (a) and cross-polar (b) gain patterns of a 1.2 GHz integrated antenna.



▲ Fig. 13 Three-dimensional co-polar (a) and cross-polar (b) gain patterns of a 4.8 GHz integrated antenna.

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TABLE III

RADIATION AND INPUT MATCH PARAMETERS OF SINGLE AND INTEGRATED SBF ANTENNAS

Integrated SBF Antennas	1.2 GHz Antenna: Integrated/Single	4.8 GHz Antenna: Integrated/Single
Directive gain (dB)	14.2/14.4	15.4/15
Aperture efficiency (%)	67/70	88/81
45° plane max side lobe (dB)	-15.2/-20.8	-23/-25
45° plane beamwidth (°)	31.3/34.5	30/33
45° plane max. cross-polar (dB)	-23.3/-24.6	-20/-20.5
45° plane back-to-front ratio (dB)	-20.8/-21.5	-28.2/-26.5
S ₁₁ at design frequency (dB)	-21/-22	-23/-25
Input bandwidth, (%) at S ₁₁ = -10 dB	6.3/5.5	7/4.5

netic analysis tool for a numerical design, size optimization and antenna parameter analysis. The thorough numerical examination of the antenna assembly has demonstrated that it is not only compact and simple to build, but also possesses attractive properties for many applications, such as a double-band operation, a reasonable gain of approximately 14 to 15 dB, good linear polarization and match characteristics. For both antennas, mismatch losses less than 0.05 dB at the design frequency, and less than 0.45 dB over the frequency band of approximately 6 to 7 percent, have been attained by means of the proposed antenna length-variation technique. The approach may also lend itself to the design of circular polarization antennas by using two orthogonal feed dipoles. ■

ACKNOWLEDGMENT

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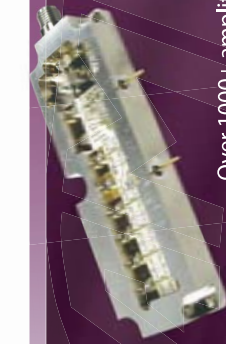
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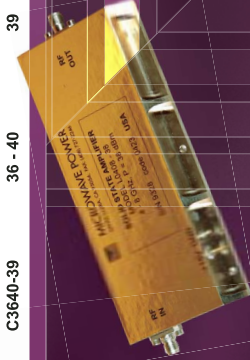
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L0218-32	2 - 18	32	1.4	31	35	5
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L0618-43	6 - 18	43	20	41.5	45	22
L0812-46	8 - 12	46	40	45	45	28
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L2630-39	26 - 30	39	8.0	38	40	15
L2632-37	26 - 32	37	5.0	36	38	10
L2640-31	26 - 40	31	1.2	30	30	5
L3040-33	30 - 40	33	2.0	32	33	9
L3337-36	33 - 37	36	4.0	35	40	12
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C1416-46	14 - 16	46	40	45	0.35	5.25
C1820-43	18 - 20	43	20	41.5	0.25	5.25
C2326-40	23 - 26	40	10	39	0.25	5.25
C2630-45	26 - 30	45	30	44	0.45	5.25
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BROADBAND DESIGN OF A SMALL NON-SYMMETRIC GROUND $\lambda/4$ OPEN SLOT ANTENNA

The broadband design of a small size, $\lambda/4$ open slot antenna is investigated. By properly choosing the dimensions of the open slot and of the rectangular conducting plate, which is connected to the end of the 50 Ω microstrip-line feed, a broadband antenna with a bandwidth of 94 percent is achieved with an overall size of $35 \times 30 \times 0.8$ mm. This design can be applied to small-size devices for wireless applications.

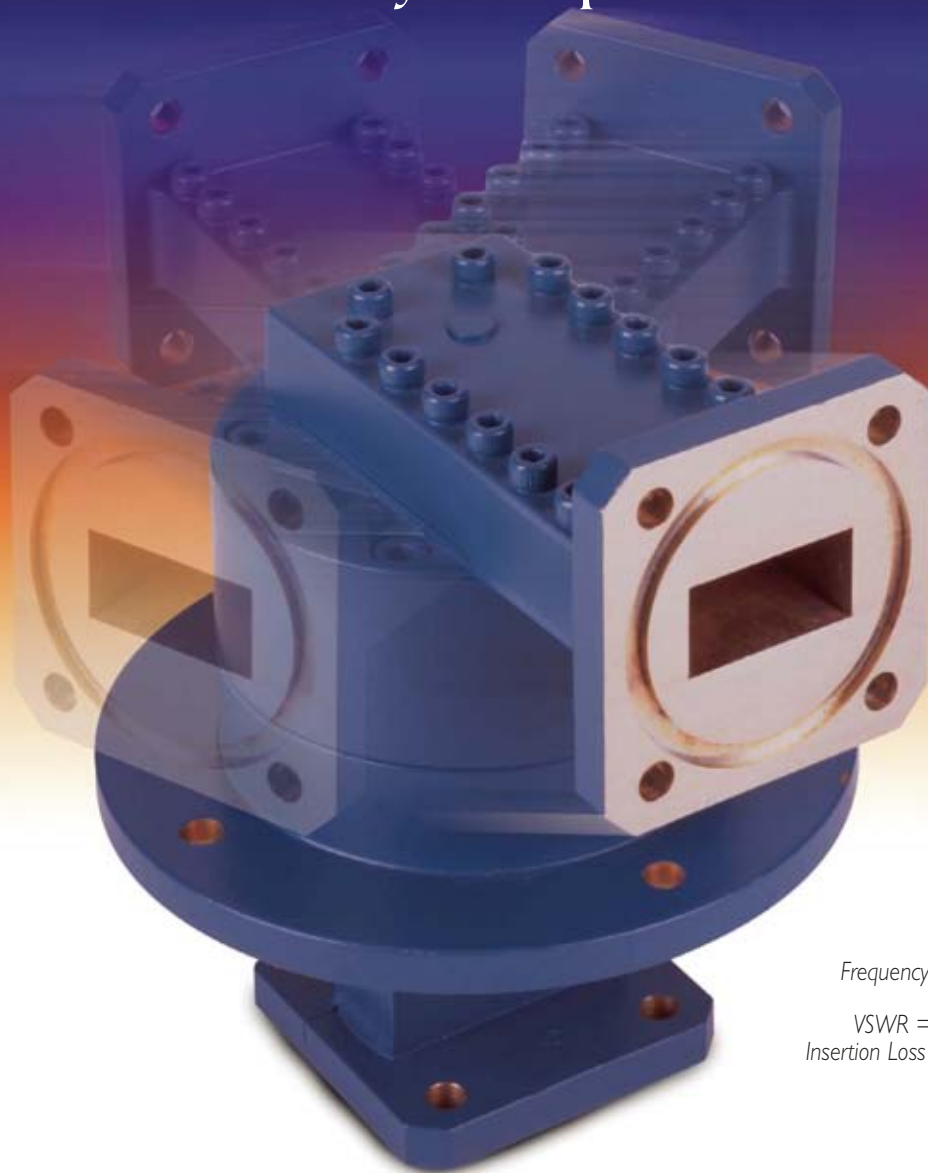
The wireless communication industry is developing rapidly and wireless communication products, PDAs, laptops and cell-phones are becoming a necessity of life. Communication systems need a wide frequency bandwidth to transmit and receive multimedia information at high data rates. Mobile wireless communication products must be easily portable and cheap to make them attractive to people. Because microstrip-line-fed slot antennas have a wide impedance bandwidth and a simple structure that is easily manufactured at low cost, they can be suitable for communication products such as wireless local area network (WLAN) or Bluetooth applications.

Many studies of wideband slot antennas fed by microstrip lines have been published.¹⁻⁴ These studies demonstrate that the design of a small size, wideband slot antenna is not an easy task. They show that while broadband designs are achievable, getting a small size as well is not easy. Therefore, how to reduce the antenna size and decrease its manufacturing

cost are important. Some broadband and small size slot antennas have recently been proposed.⁵⁻⁸ A monopole slot, at the center of the ground plane, was studied parametrically for its impedance bandwidth.⁵ The bandwidth obtained is approximately 50 percent. Two new designs of microstrip open slot antennas (L-slot and inverted T-slot) have been described⁶ to attain wider bandwidths with shorter vertical lengths. A quarter-wavelength slot antenna⁷ with an L-shaped horizontal and vertical tuning stub has also been published. The bandwidth of the quarter-wavelength slot antenna is 3 to 5 GHz, but it is not enough to cover most wireless communications. A WLAN notch antenna for dual-band and wideband operation has been implemented.⁸ The published open-slot antennas are

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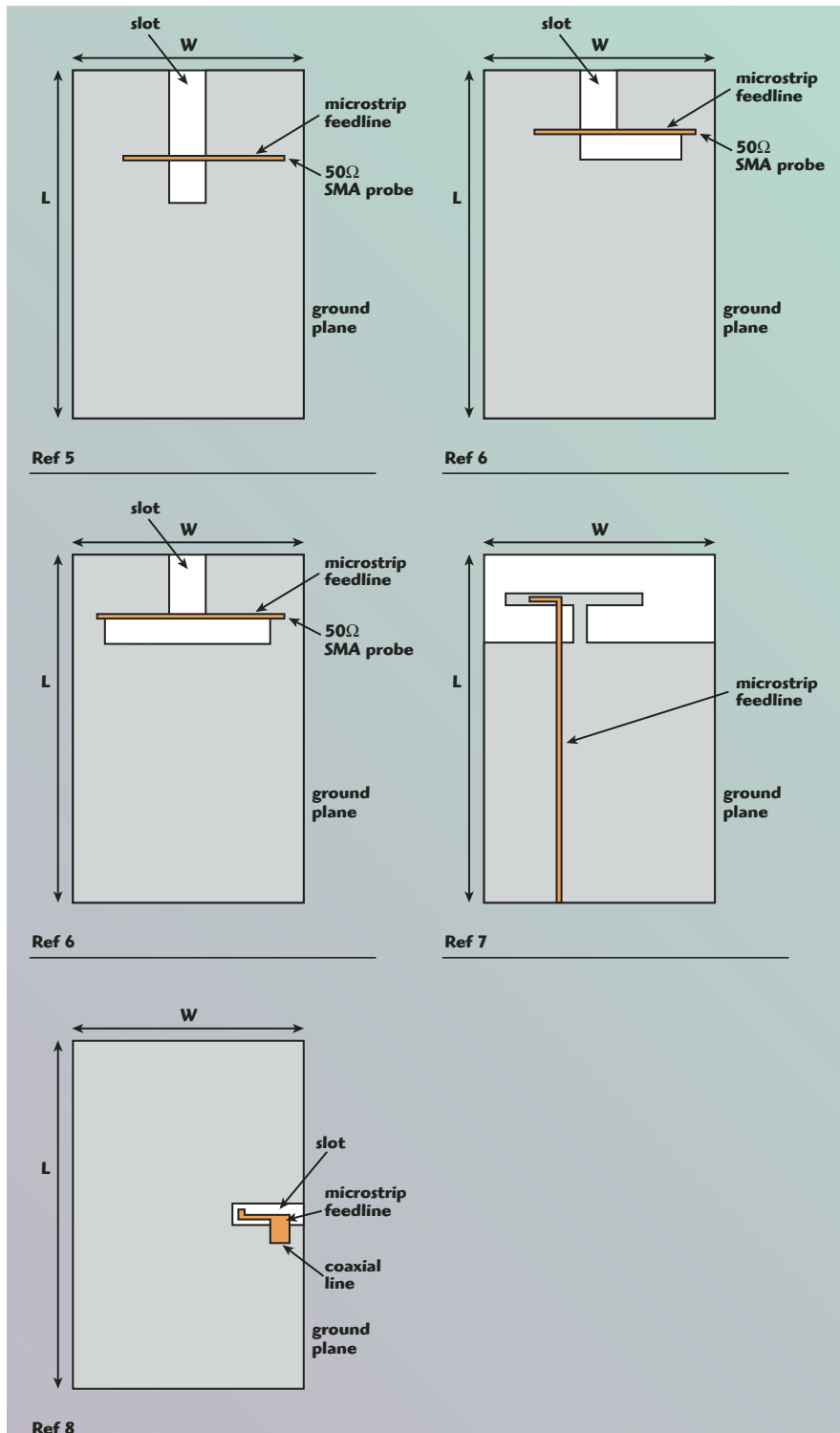
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▲ Fig. 1 Geometries of the antennas described in Ref. 5 to 8.

compared in **Figure 1** and their results are shown in **Table 1**.

In this article, a novel design for a non-symmetric ground $\lambda/4$ open slot antenna with a microstrip-line feed is proposed. By choosing the proper dimensions of the rectangular conducting plate, which terminates the $50\ \Omega$ microstrip-line feed, and that of the

open slot, a wide impedance bandwidth and a miniaturized antenna area can be obtained. The proposed antenna, printed on an FR4 substrate and fed by a $50\ \Omega$ microstrip-line, is implemented and investigated. The frequency range of the proposed antenna is approximately 2.2 to 6.1 GHz (94 percent), which can be used in

mobile wireless communication products, WLAN, Bluetooth and UWB.

ANTENNA DESIGN

The geometry of the proposed antenna is shown in **Figure 2**. The antenna is printed on an FR4 substrate with a thickness $h = 0.8$ mm, a relative permittivity $\epsilon_r = 4.4$ and dimensions L_1 and W_1 . The open slot consists of one open-ended, x-directed slot of length W_2 and one open-ended, z-directed slot of length L_5 , connected together on the right side of the ground plane. The open slot is etched in the ground plane and its location results in the non-symmetric ground. The coupling, between the rectangular conducting plate terminating the open end of the $50\ \Omega$ microstrip-line feed and the open slot on the non-symmetric ground, generates the wideband impedance of the small area antenna.

The length of the open-ended, x-directed slot W_2 and the length of the open slot, y-directed slot length L_5 are the major parameters, which determined the lower resonant mode. The higher resonant mode is excited by adjusting the dimensions of the feed structure. By properly choosing the dimensions of the open-ended, x-directed slot W_2 and the open-ended, y-directed slot L_5 , these two resonant modes can be coupled to provide a wide impedance bandwidth. The location of the rectangular conducting plate is close to the end edge of the open-ended, x-directed slot of length W_2 , which generates a good impedance matching of the proposed antenna. The center length of the open slot (approximately 32.5 mm) is approximately a quarter-wavelength in free space at 2.2 GHz.

PARAMETRIC STUDY AND DISCUSSION

The parametric study supplied helpful information to the antenna designers. It included the dimensions of the slot, the rectangular plate and the ground plane. Through these investigations, an optimal design is obtained, suitable for mobile wireless communication products in WLAN, Bluetooth and UWB.

Different Values of Rectangular Plate Width W_3

Figure 3 shows the return loss for different widths of the rectangular

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DCYR50125-10	500 - 1250	0.5 - 25	+10 @ 50 mA	-110
DCYR100200-12	1000 - 2000	0.5 - 28	+12 @ 50 mA	-108
DCYS160360-5	1600 - 3600	0.5 - 24	+5 @ 60 mA	-90
DCYS200400-5	2000 - 4000	0.5 - 15	+5 @ 50 mA	-90
DCYS250500-5	2500 - 5000	0.5 - 20	+5 @ 50 mA	-75
DCYS300600-5	3000 - 6000	0 - 25	+5 @ 50 mA	-80
DCYR400800-5*	4000 - 8000	0 - 18	+5 @ 130 mA	-84
DCYR5001000-5*	5000 - 10000	0 - 25	+5 @ 130 mA	-75
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TABLE I

COMPARISON OF SIZE AND BANDWIDTH
FOR THE ANTENNAS DESCRIBED IN REFERENCES 5 TO 8

Reference	Antenna Size (W × L) (mm)	Frequency Range (GHz)	Bandwidth (%)
5	50 × 80	2.42~4.31	56.17
6	50 × 80	2.24~5.36	82.11
6	50 × 80	2.56~5.80	77.51
7	50 × 80	2.37~4.38	59.56
8	40 × 80	3~5	50.00

patch W_3 . The other antenna dimensions are $L_1 = 35$ mm, $L_2 = 7$ mm, $L_3 = 14$ mm, $L_4 = 6$ mm, $L_5 = 14$ mm, $W_1 = 30$ mm, $W_2 = 18.5$ mm, $W_4 = 1.53$ mm and $W_5 = 5$ mm. As W_3 increases, the impedance bandwidth moves to a high frequency. It shows that the bandwidth is not very sensitive to W_3 .

Different Values of Slot Width L_4

Figure 4 shows the return loss with different widths for slot L_4 from 2 to 8 mm, with the other dimensions $L_1 = 35$ mm, $L_2 = 7$ mm, $L_3 = 14$ mm, $L_5 = 14$ mm, $W_1 = 30$ mm, $W_2 = 18.5$ mm, $W_3 = 6$ mm, $W_4 = 1.53$ mm and

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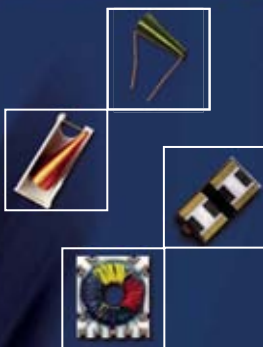
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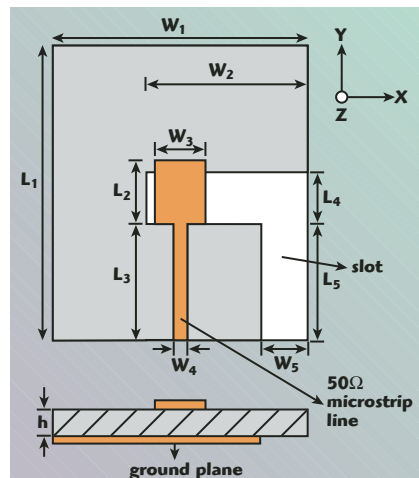


Fig. 2 Geometry of the proposed antenna.

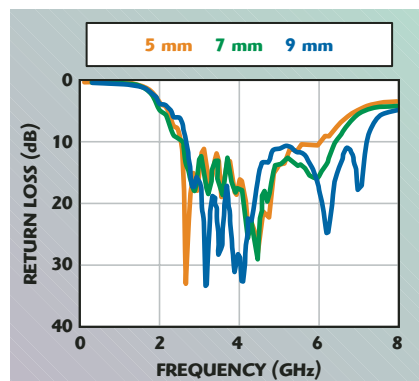


Fig. 3 Measured return loss for different values of W_3 .

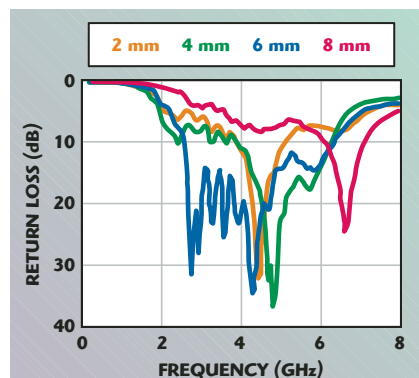


Fig. 4 Measured return loss for different values of L_4 .



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$W_5 = 5$ mm. The results indicate that the bandwidth is very sensitive to L_4 . When $L_4 = 6$ mm, a broader impedance bandwidth occurs. From these results, the dimension L_4 of the slot is set at 6 mm.

Different Values of Slot Width W_5

Figure 5 shows the return loss with different widths for slot W_5 . The other dimensions are $L_1 = 35$ mm, L_2

$= 7$ mm, $L_3 = 14$ mm, $L_4 = 6$ mm, $L_5 = 14$ mm, $W_1 = 30$ mm, $W_2 = 18.5$ mm, $W_3 = 6$ mm and $W_4 = 1.53$ mm. It shows that the bandwidth is more sensitive to W_5 than to W_3 . The symmetric structure (slot $W_5 = 0$ mm) exhibits a dual-frequency characteristic. However, the impedance matching at the higher frequency is not sufficient. With the slot W_5 added, a higher resonant mode is excited, which couples

to the lower resonant mode to create a wide impedance bandwidth.

Different Dimensions of the Ground Plane, L_1 and W_1

The measured return loss for different sizes of the ground plane is shown in **Figure 6**, with $L_2 = 7.5$ mm, $L_3 = 14$ mm, $L_4 = 6$ mm, $L_5 = 14$ mm, $W_2 = 19$ mm, $W_3 = 6$ mm, $W_4 = 1.53$ mm and $W_5 = 5.5$ mm. For the case with the ground plane dimensions $L_1 = 80$ mm and $W_1 = 50$ mm, the bandwidth obtained is more than 90 percent, which is larger than those shown in Table 1. Since the purpose of this work is to broaden the impedance bandwidth of an open slot antenna with a small size, it is observed that the broadband impedance bandwidth operation of the proposed design can be sustained with a small size ground plane of dimensions 35×30 mm.

OPTIMIZED DESIGN

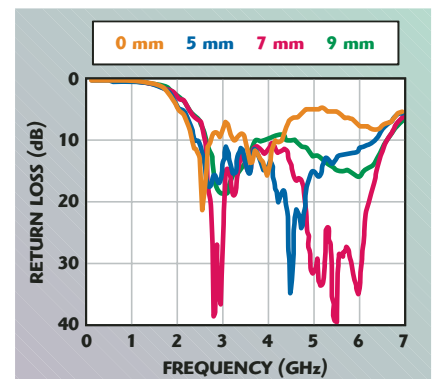
From these investigations, an optimized wideband slot antenna with small dimensions, 35×30 mm, can be obtained. The optimized parameters are $\epsilon_r = 4.4$, $h = 0.8$ mm, $L_1 = 35$

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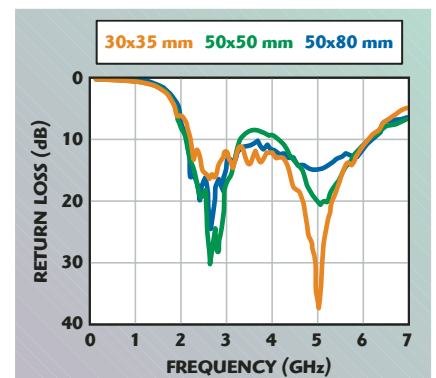
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▲ Fig. 5 Measured return loss for different values of W_5 .



▲ Fig. 6 Measured return loss for different sizes of the ground plane.

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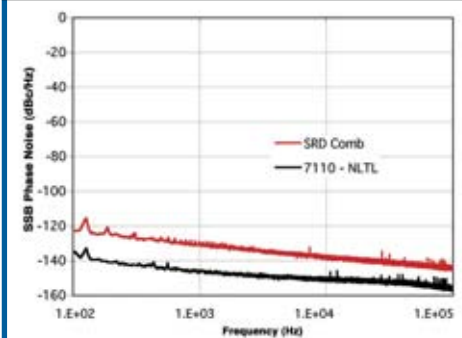
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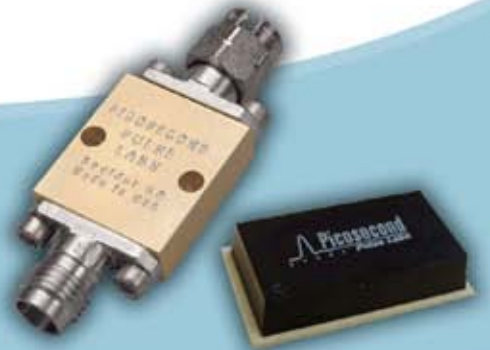
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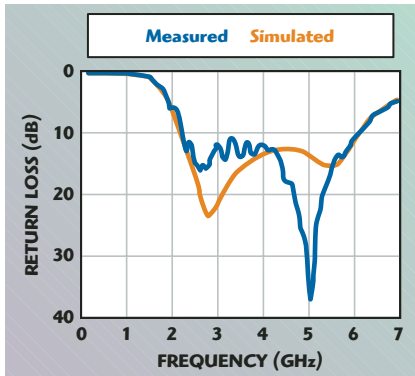


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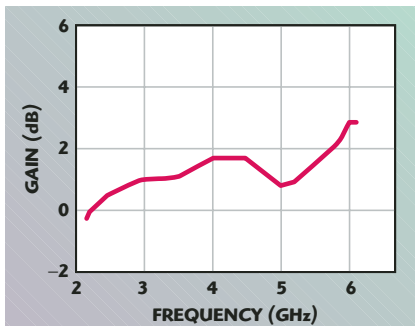
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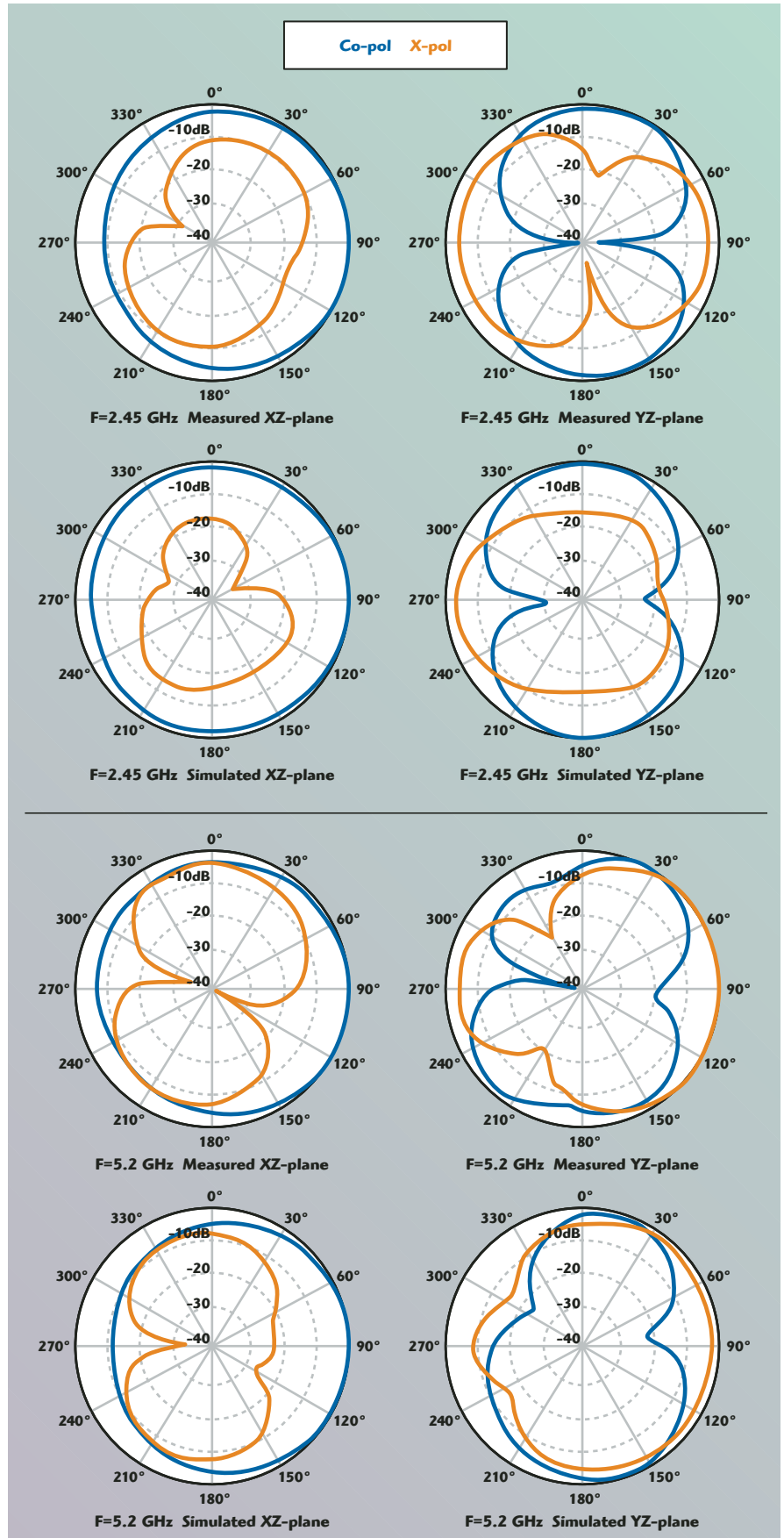


▲ Fig. 7 Measured and simulated return loss of the proposed antenna.



▲ Fig. 8 Measured gain of the proposed antenna.

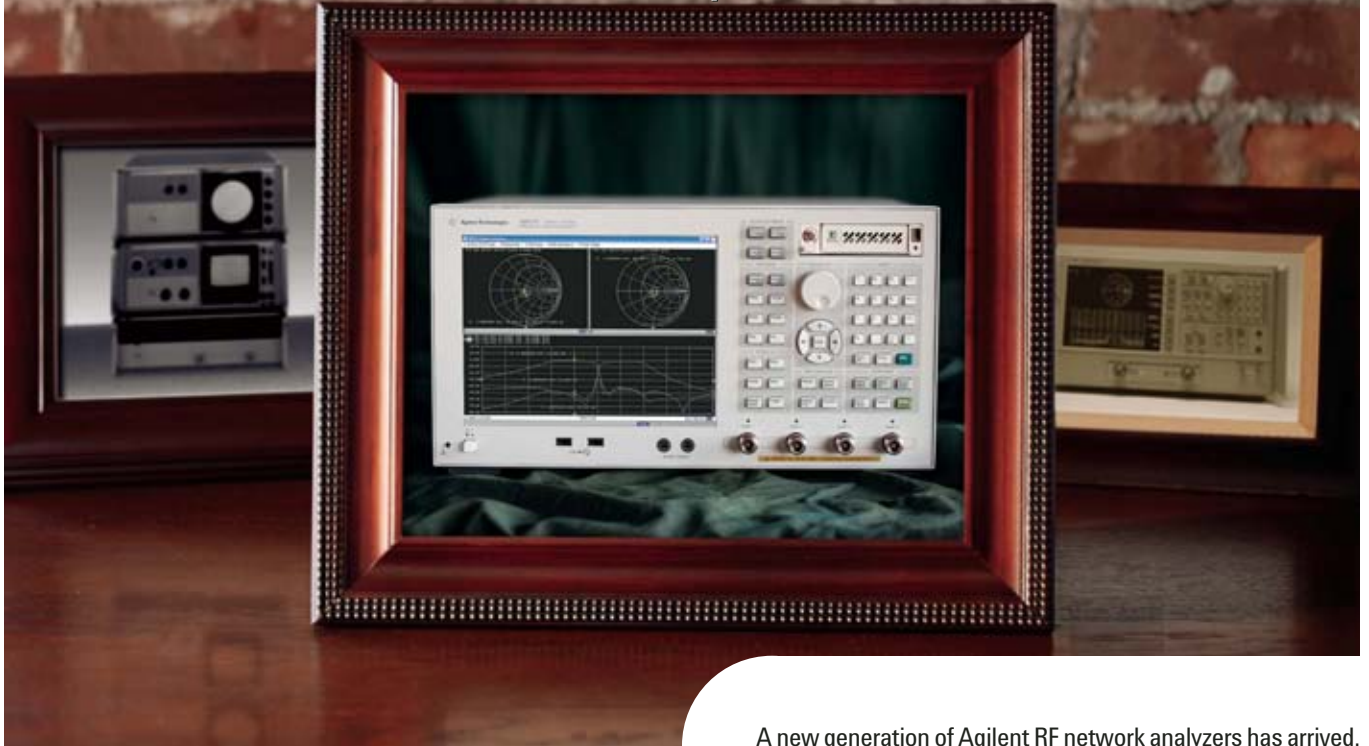
mm, $L_2 = 7.5$ mm, $L_3 = 14$ mm, $L_4 = 6$ mm, $L_5 = 14$ mm, $W_1 = 30$ mm, $W_2 = 19$ mm, $W_3 = 6$ mm, $W_4 = 1.53$ mm and $W_5 = 5$ mm. **Figure 7** shows the measured and simulated return loss of the proposed antenna. The measured data agree with the simulated data. The wide impedance bandwidth of the proposed antenna is approximately 94 percent (2.2 to 6.1 GHz), as determined from a 10 dB return loss, which is suitable for Bluetooth (2.4 to 2.4835 GHz) and WLAN (2.4 to 2.4835 GHz, 5.15 to 5.35 GHz and 5.725 to 5.850 GHz), and for the low band UWB (3.1 to 5.15 GHz) applications. In addition, the bandwidth obtained with a small size is larger than that of the ones shown in Table 1. **Figure 8** shows the measured gain of the proposed antenna. The gain variation over the operating bandwidth of the proposed design is less than 3.08 dB. The measured radiation patterns of the proposed antenna at two typical operation frequencies are also investigated. **Figure 9** shows the measured and simulated radiation patterns at 2.45 and 5.2 GHz. At higher frequencies, the radiation patterns of the proposed antenna degenerate because high order modes are excited. These radiation patterns are



▲ Fig. 9 Measured and simulated H-plane (XZ) and E-plane (YZ) radiation patterns of the proposed antenna.

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CONCLUSION

This article focuses on the wideband design of a small slot antenna. The coupling between the rectangular conducting plate, which is attached to the open end of the 50 Ω microstrip-line feed, and the $\lambda/4$ open slot with the non-symmetric

ground, generates a wideband impedance for a small area antenna. The 94 percent impedance bandwidth of the proposed antenna is achieved by using proper dimensions for the open slot and rectangular conducting plate. The overall size of the proposed antenna is $35 \times 30 \times 0.8$ mm. The proposed broad bandwidth, small size antenna is suitable for portable devices in wireless applications. ■

ACKNOWLEDGMENT

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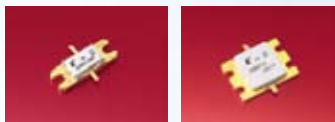
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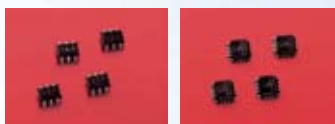
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ES/EGN35A180IV	3.4~3.6	53.0	12	50	0.65	IV
ES/EGN35A090IV	3.4~3.6	50.0	12	50	1.2	IV
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THE REQUIREMENTS AND PROCEDURES FOR TESTING WiMAX EQUIPMENT

The potential for WiMAX technology is driving its development at a pace aimed at effective mass deployment. This article outlines the requirements necessary for the development of specific test procedures and equipment.

WiMAX is a technology for fixed, nomadic and mobile applications that promises the delivery of broadband wireless access to the masses. For fixed and portable access applications, a delivery capacity of 40 Mbps per channel can be expected for typical cells with a radius of 3 to 10 km. Mobile network deployments are expected to provide up to 15 Mbps of capacity within a typical cell diameter of up to 3 km. There are conceptually three ways to achieve this high data throughput in mobile radio communication systems: large bandwidth, higher order modulation schemes and multiple antenna systems, referred to as multiple-input, multiple-output (MIMO). WiMAX deploys all three, each requiring dedicated testing. Also, to optimize the efficiency in terms of time and frequency resources and to enable flexibility for the network operator, WiMAX uses orthogonal frequency division multiple access (OFDMA) as the modulation scheme. This article explains the three techniques for achieving high data throughput and focuses on their impact on test and measurement requirements.

LARGE BANDWIDTH SYSTEMS

Larger bandwidths increase the data throughput because higher modulation frequencies enable more symbols (a symbol being the smallest unit of data transmitted at one time) to be transmitted per unit time. In other words, a large bandwidth results in a short symbol duration. This can be critical in multipath fading environments where a signal travels from the transmitter to the receiver along different scattered paths and possibly a direct line of sight path. Therefore, a receiver experiences a superposition of the same signal with different attenuations, phases and delays. The delay spread of the paths depends very much on the physical environment. Indoors, for example, the signals travel similar distances resulting in a smaller delay spread than in the countryside where the difference between the distances a signal travels can be large. Due to the delay spread, different symbols arrive at

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the same time making it hard for the receiver to distinguish between them, especially if the delay spread is large compared to the symbol duration. This effect is referred to as inter-symbol interference.

The orthogonal frequency division multiplexing (OFDM) transmission technique used by WiMAX has advantages in such fading environments because OFDM signals fill the bandwidth with a series of sub-carriers that individually have smaller bandwidths. This results in a longer symbol duration making the signal less susceptible to fading effects. WiMAX supports different bandwidths from 1.25 to 28 MHz and different numbers of sub-carriers, according to the system requirement and spectrum availability. The number of used sub-carriers can vary between 256, 512, 1024 and 2048. Furthermore, OFDM allows the symbol duration to be increased with redundant information by employing cyclic prefixes—the last part of a symbol is repeated at its beginning. To adapt to different fading

environments, WiMAX permits this cyclic prefix to be 1/4, 1/8, 1/16 or 1/32 of the symbol length. The drawback of a long cyclic prefix is a reduction in data throughput. Also, the large bandwidth of WiMAX makes the system susceptible to multi-path fading effects. How efficiently a receiver demodulates a signal under fading conditions can most easily be tested with signal generators that generate standard conforming signals and have an internal fading simulator. The large bandwidth of WiMAX also requires special testing of the transceiver components. For example, in a transmitter, a low frequency or I/Q signal from the baseband chip modulates an RF carrier, which is then amplified. For optimizing the transmitter, it is necessary to distinguish the performances of the baseband chip, I/Q modulator and amplifier. Therefore, modern signal generators and analyzers have to be utilized, not only to generate, demodulate and analyze broadband RF signals, but also the corresponding baseband signals. The

large bandwidth of WiMAX signals is a challenge for power amplifier and I/Q modulators. These components are typically tested by feeding a high purity signal to the component and analyzing the output signal to measure the deterioration of the signal caused by the component under test. The in-band deterioration is typically measured in terms of spectral flatness and flatness difference, which is the difference in level between adjacent sub-carriers. The modulated OFDM sub-carriers add up to an RF signal with a high dynamic range. This is typically quantified as the difference between peak and average power and referred to as the crest factor. WiMAX signals have high crest factors of the order of 12 dB. To avoid modulation errors, the power amplifier must be linear throughout such dynamic ranges. To test how an amplifier behaves for signals with different signal characteristics, tools are available to set the crest factor of a WiMAX signal generated by a signal generator. The out-of-band deterioration is measured in terms of the adjacent channel leakage ratio (ACLR). The ACLR gives the power that leaks into the adjacent channel with respect to the in-band power. Such tests of components require signal generators and analyzers with an ACLR and frequency response that is much better than the deterioration due to the component under test.

HIGH ORDER MODULATION

In a digitally modulated OFDM system like WiMAX, an in-phase (I) and a quadrature phase (Q) signal are modulated to each of the radio frequency sub-carriers. The I and Q signals are conveniently visualized in a constellation diagram where I is plotted versus Q. **Figure 1** shows such a diagram measured with a signal analyzer. In this figure, there are constellation points, which are discrete I and Q values. During a symbol time one of these I/Q pairs is transmitted per sub-carrier. To each constellation point a bit or a bit sequence is mapped. The different WiMAX modulation schemes, BPSK, QPSK, 16QAM and 64QAM, have 2, 4, 16 and 64 constellation points each corresponding to 1, 2, 3 and 4 bits, respectively. Therefore, the more constellation points, the higher the order

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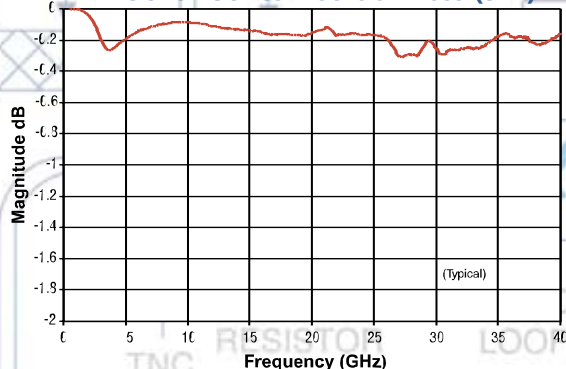
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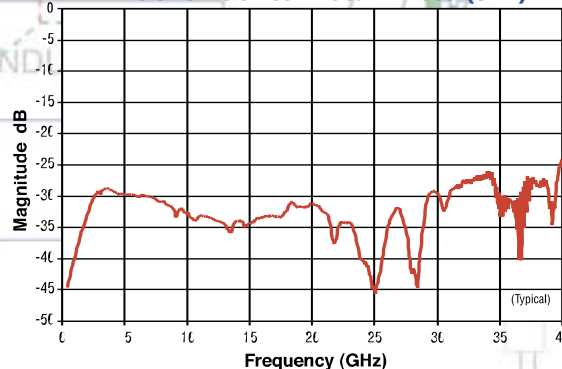
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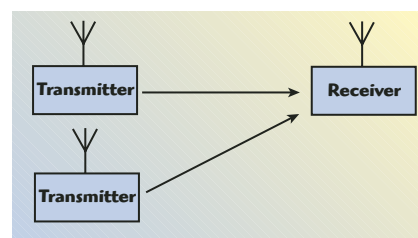
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▲ Fig. 1 Constellation diagram of a 64QAM WiMAX signal demodulated by a signal analyzer.

of the modulation, the more bits are transmitted per symbol. This means that the data rate is increased without increasing the bandwidth. The price of such higher order modulations is that the constellation points move closer together, making it harder for the receiver to distinguish the points and thus demodulate the signal correctly. This is especially true for low signal-to-noise ratios, in the presence of interference and multi-path fading. WiMAX then adapts the order of the modulation and the coding according to the overall transmission conditions. To test how a WiMAX receiver can demodulate signals in the real world, the operator needs to generate a standard conforming signal and simulate noise, fading conditions and interference. This is conveniently done by signal generators with an internal noise generator, fading simulator and a second baseband source to simulate interference. To cope with the complication of high order modulation, the transmitter and receiver need to have good modulation accuracy, which is typically measured in terms of error vector magnitude (EVM). The EVM equals the distance between the actual measured and the ideal constellation point in the I/Q diagram, normalized to the magnitude of the ideal constellation point. Signal analyzers with WiMAX functionalities facilitate the measurement of the transmitter's EVM. The EVM can be

measured for the individual subscriber, time slots or sub-carrier. To estimate the accuracy, with which a transmitter can generate a signal and a receiver demodulate it, requires a signal analyzer and a signal generator with an EVM much lower than the device under test. When designing transmitters and receivers with a low EVM, care must be taken with regards to some critical performance parameters, which require dedicated testing. In particular, the local oscillator that does the up- or down-conversion must be pure in terms of phase noise and broadband noise. Phase noise and broadband noise have a detrimental effect on the EVM because they lead to azimuthal and radial smearing of the constellation points, respectively. Also, the I/Q-modulator has to map the I and Q signals precisely at 90° with respect to each other and with a linear amplification in order to avoid distortions of the constellation diagram, resulting in an increased EVM.



▲ Fig. 2 Schematic illustration of a simple transmit diversity system.

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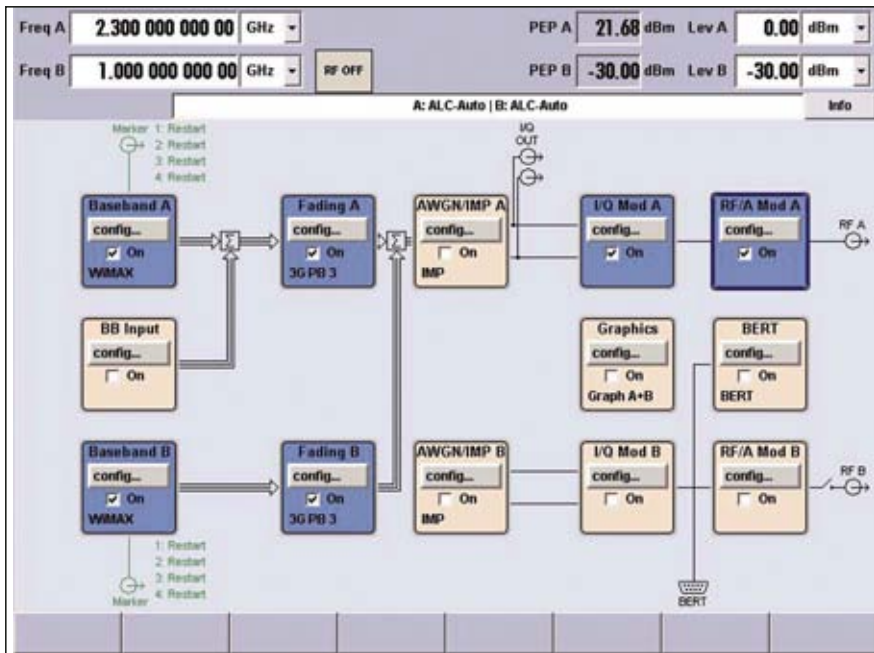
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▲ Fig. 3 Block diagram of a signal generator illustrating the signal flow for testing a transmit diversity system.

MIMO

WiMAX, like other modern radio communication standards such as 802.11n and E-UTRA, employs mul-

ti-ple antenna systems referred to as MIMO or spatial diversity. The technique either increases the signal-to-noise ratio or increases the data

throughput for a given resource or both. Transmit diversity refers to a system where different signals are transmitted from different antennas at the same time and frequency. **Figure 2** shows a schematic of such a system where the signals experience different multi-path fading. The characteristics of these fading channels are estimated by transmitting a known pattern and, with this channel estimation, the receiver can then distinguish between the signals from the transmit antennas. This requires the fading channels to be sufficiently different or uncorrelated. However, the antennas of a transceiver are bound to a limited physical area and residual cross talk between these antennas cannot be avoided. Due to this, the fading channels are actually correlated in amplitude and phase, deteriorating the performance of such a transmit diversity system. In the absence of multi-path fading or for 100 percent correlated fading channels, transmit diversity does not work. This means that the performance of a receiver for transmit diversity systems can only be evaluated with fading simulators that can simulate more than one fading channel and allow complex correlation factors between the paths of the fading channels. Such receivers are tested most effectively with a signal generator containing two baseband generators, which can generate standard conforming signals as they are transmitted from the two antennas, plus two internal fading simulators to simulate the different correlated fading channels. Such equipment means that a receiver in a transmit diversity system can be tested using only one box and with minimum cabling effort. **Figure 3** shows the block diagram of a signal generator configured for transmit diversity where the signals from the antennas are generated in the top and bottom blocks on the left; the two sig-

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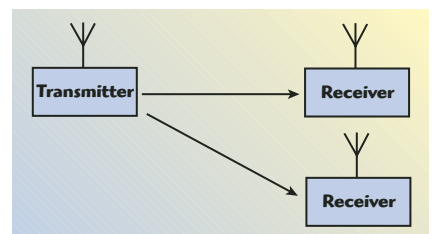
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▲ Fig. 4 Schematic illustration of a simple receive diversity system.

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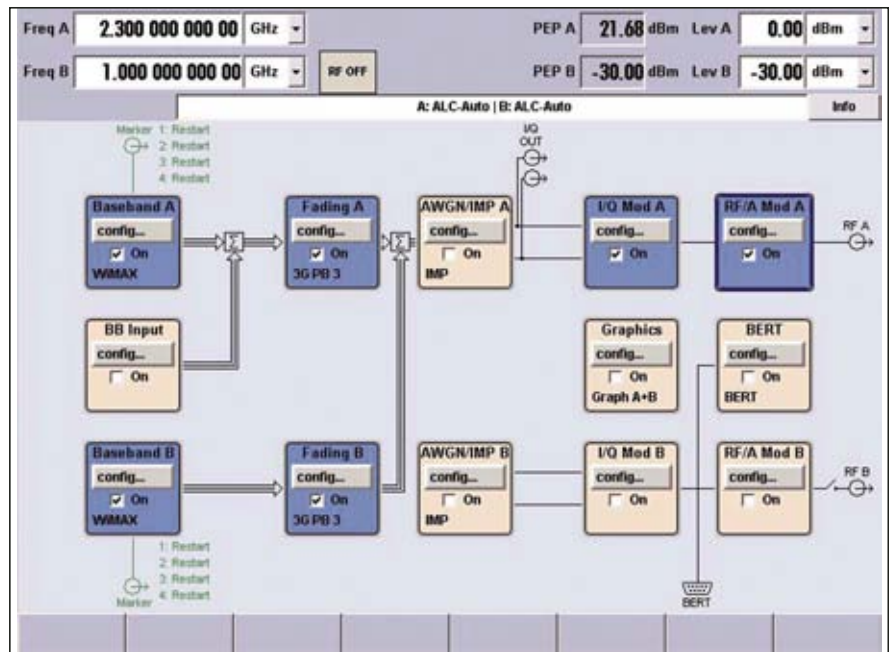
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nals are then faded in the next two blocks and then routed together and modulated to the RF carrier in the two blocks on the top right. This concept also applies to receive diversity systems, where a signal is transmitted from one antenna and received by two. **Figure 4** illustrates such a receive diversity system schematically. Performance measurements on receivers in receive diversity systems require one baseband signal, simulation of two correlated fading channels

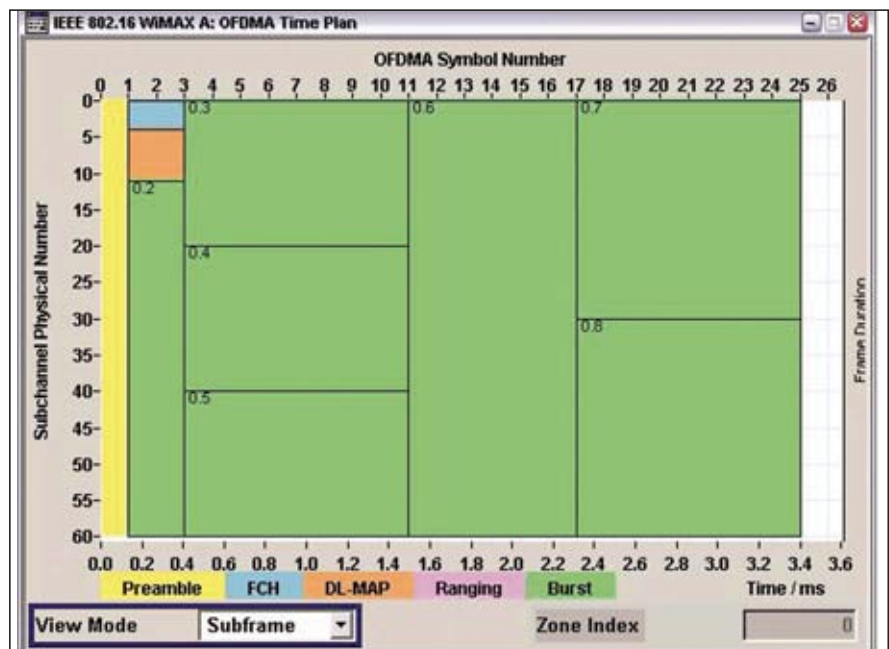
and radio frequency signals. **Figure 5** shows the block diagram of a signal generator set up for testing receive diversity systems.

OFDMA SYSTEMS

An OFDMA system is a combination of frequency division duplex (FDD) and time division duplex (TDD). This means that a part of the spectrum and time is allocated to each subscriber. In such a system, operators can offer different band-



▲ Fig. 5 Block diagram of a signal generator showing the signal flow for testing a receive diversity system.



▲ Fig. 6 Downlink map of an OFDMA WiMAX signal.



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widths and transmission time resources to the users according to their needs and level of service. In **Figure 6**, a time plan for a downlink signal is shown, where, on the x- and y-axes, the time and sub-channel numbers are plotted, respectively. The logical sub-channels are allocated to the physical sub-carrier according to defined permutation algorithms. The orange square in the figure represents the downlink-map or DL-Map. In this field, the time and sub-channel allocation of the users is described. To enable different base stations to operate in the same physical area, different times and sub-channels can be allocated to them. As can be seen, OFDMA systems offer a great deal of flexibility in optimizing resources efficiently. However, this flexibility comes at the price of a complex physical layer with many free parameters. This complexity is a challenge for the user interface of test and measurement equipment as many parameters need to be set and the impact of the parameter must be

illustrated to the user (in the form of graphical displays and concise tables, for example). Also, the high complexity of the physical layer presents the risk that manufacturers of transceivers will run into configuration problems. Emulating transmitters and receivers with signal generators and signal analyzers with flexible parameters helps to solve such configuration problems. These tests require the measurement equipment to make fast and easy changes to the WiMAX parameters. Such equipment has proved to be very useful during interoperability testing between subscribers and base stations—by using a signal analyzer, the contents of the DL-Map and UL-Map can automatically be demodulated down to the bit level. This allows the bits demodulated by the signal analyzer to be compared with the ones demodulated by the mobile station. During troubleshooting of an interoperability test, this is one of the first steps that needs to be taken, as the subscriber station needs to demodulate the DL-

Map in order to know what sub-carriers to demodulate and when. Once the DL-Map is demodulated correctly, the next logical step is to verify the contents of the UL-Map, which tells each subscriber station how to configure its transmitter in terms of what sub-carriers to use and when to do so. Only if the mobile station transmits its information at the requested sub-carriers with the correct timing, will the base station be able to demodulate the signal correctly. This highlights that timing is a parameter that may cause interoperability problems. Here, a signal analyzer can speed up the troubleshooting process, as it is able to record and display the signal in both link directions.

CONCLUSION

Large bandwidth signals are susceptible to fading effects. To cope with this, WiMAX deploys the robust OFDM modulation technique. The downside being that the signals have a high crest factor, requiring very linear power amplifiers. Furthermore, the large bandwidth requires power amplifiers and I/Q modulators with a flat frequency response. Transmitting signals with a high order of modulation requires very good modulation accuracy and a receiver that is able to distinguish between the constellation points even in the presence of noise, fading conditions and interference. Besides the generation of multiple signals, the receiver tests for multiple antenna systems require the simulation of multiple fading channels. The flexibility of an OFDMA system also comes at the price of a complex physical layer, which makes interoperability tests a challenge. Therefore, the testing of WiMAX equipment requires high end, easy to use test and measurement equipment to generate and analyze standard conform signals and to simulate interference effects. ■

Jan E. Prochnow studied physics at the University of Technology, Aachen, Germany, and received his PhD degree in the field of accelerator physics at CERN, Geneva, Switzerland. He has been a product manager for signal generator and power meters at Rohde & Schwarz headquarters in Munich, Germany, since 2004. His tasks include the marketing of test and measurement equipment for WiMAX.

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A TRIPLE-BAND POLYGONAL SLOT ANTENNA FOR WiMAX APPLICATIONS

A printed polygonal slot antenna, fed by a 50 Ω microstrip-line and with two narrow strips for three-band operation, is proposed and experimentally studied. The polygonal slot antenna was found to be broadband (1.85 to 5.83 GHz). When two narrow strips were inserted into the polygonal slot antenna, two bands were rejected. By properly choosing the length and location of the two narrow strips, a triple-band antenna can be achieved. The good impedance matching, good radiation patterns and antenna gain of the proposed antenna are investigated in this article. The design of the proposed antenna is suitable for WiMAX applications.

In recent years, wireless communications have progressed very rapidly. The IEEE 802.16 Working Group has created a new standard, commonly known as WiMAX (Worldwide Interoperability for Microwave Access), for a low cost, broadband, wireless access at high speed, which is easy to deploy.¹ WiMAX technology can reach a theoretical 30-mile radius coverage and achieve data rates up to 75 Mbps, a throughput higher than the 1.5 Mbps performance of typical broadband services.² At present, the development of WiMAX technology is the focus of the receiving industry. How to design the antennas for WiMAX applications has become important.

Microstrip-line slot antennas are light and easy to manufacture, are broadband, and have low profile and low cost. Several designs of broadband slot antennas have been proposed.³⁻⁵ WiMAX has been allocated three frequency bands, which will be called the low band (2.495 to 2.695 GHz), the median band

(3.25 to 3.85 GHz) and the high band (5.25 to 5.85 GHz), respectively. A broadband antenna must add filters to separate the bands, leading to a higher cost. Therefore, a broadband antenna is not very suitable for WiMAX. A wide-band stubby monopole was reported⁶ that is broadband but with a more complex structure. To design a triple-band antenna that fit the exact bands of WiMAX is not an easy task. In this article, a new design for a microstrip-lined printed polygonal slot antenna, with two rectangular narrow strips to obtain the dual band-rejected frequencies at 3 and 4.5 GHz, is proposed. The proposed antenna can easily be excited by a 50 Ω microstrip-line, printed on an FR-4 dielectric substrate. With this

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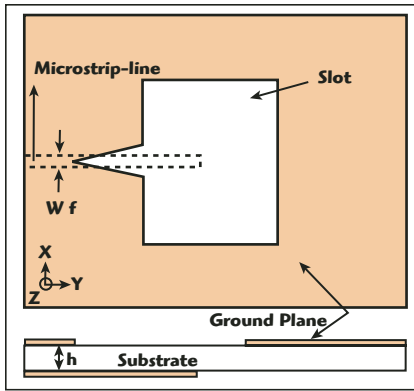
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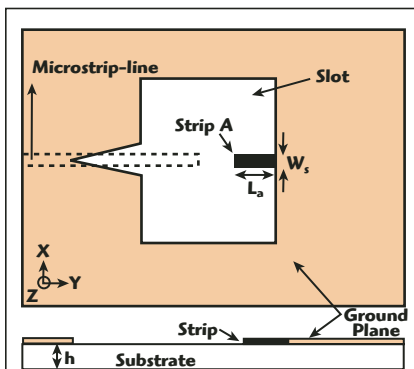
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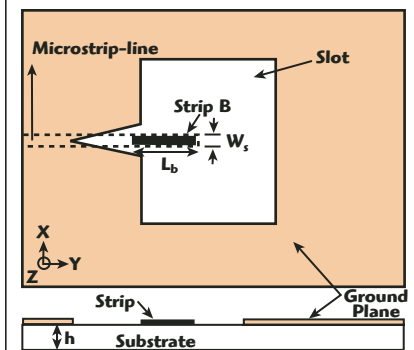
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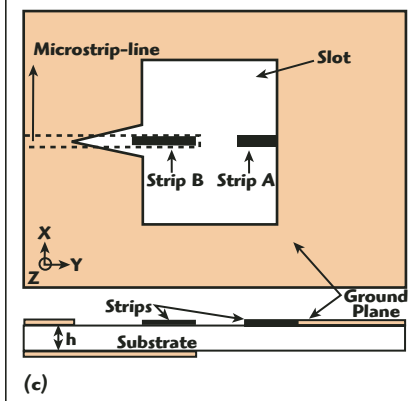
▲ Fig. 1 Structure of the broadband polygonal slot antenna.



(a)

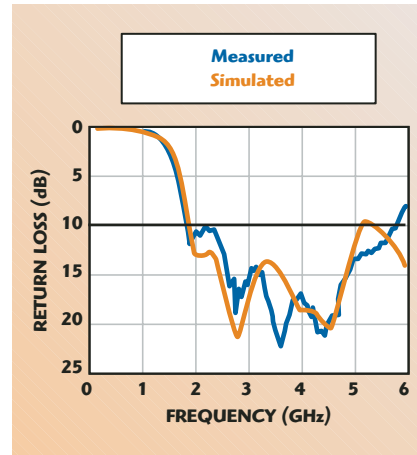


(b)

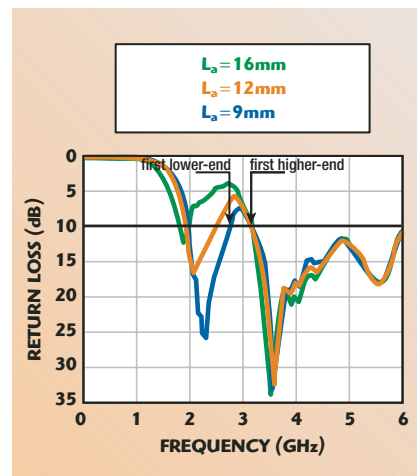


(c)

▲ Fig. 2 Structure of the proposed antenna (a) with strip A inserted, (b) with strip B inserted and (c) with both strips inserted.



▲ Fig. 3 Measured and simulated return loss of the broadband antenna.



▲ Fig. 4 Measured return loss with different lengths of strip A.

antenna design, a good impedance match and good radiation characteristics can be obtained. Details of the design and the experimental results of the proposed antenna are discussed.

ANTENNA DESIGN

Figure 1 shows the geometry of the broadband design of the polygonal slot antenna on a dielectric substrate. In this study, the dielectric material is FR-4, with a thickness h and a relative permittivity ϵ_r . For design convenience, the proposed antenna is fed by a $50\ \Omega$ microstrip-line, printed on the dielectric substrate. The microstrip-line was

placed symmetrically with respect to the centerline (y axis) of the polygonal slot. Then, by fine-tuning the polygonal slot and adjusting the length of the $50\ \Omega$ microstrip-line, a new resonant mode can be excited in the proximity of the fundamental resonant mode, and a good impedance matching over a broadband can be obtained. Then, two rejected bands are created, located at the proper frequencies to form the triple frequency bands used in WiMAX applications.

Figure 2 shows the geometry of the triple-band polygonal slot antenna on a dielectric substrate. Two narrow strips are inserted along the centerline of the polygonal slot. The width of the strips, w_s , is equal the width w_f of the microstrip-line. In order to reject two different frequency bands, the length of strip A is different from strip B. Strip A is connected to the ground plane of the polygonal slot antenna and its length is adjusted to reject the frequency band from 2.69 to 3.3 GHz. Strip B, which is coupled to the $50\ \Omega$ microstrip-line, is approximately a quarter-wavelength at the center frequency of the second rejected band (4.525 GHz). With two strips inserted, the polygonal slot antenna will have two rejected bands, leading to a triple-band WiMAX antenna.

EXPERIMENTAL RESULTS AND DISCUSSION

Polygonal Slot Antenna

Figure 3 shows the measured and simulated return loss of the polygonal slot antenna. The simulation was performed using the high frequency structure simulation (HFSS) software package from Ansoft, and the prototype characteristics of the proposed antenna were measured with a HP-

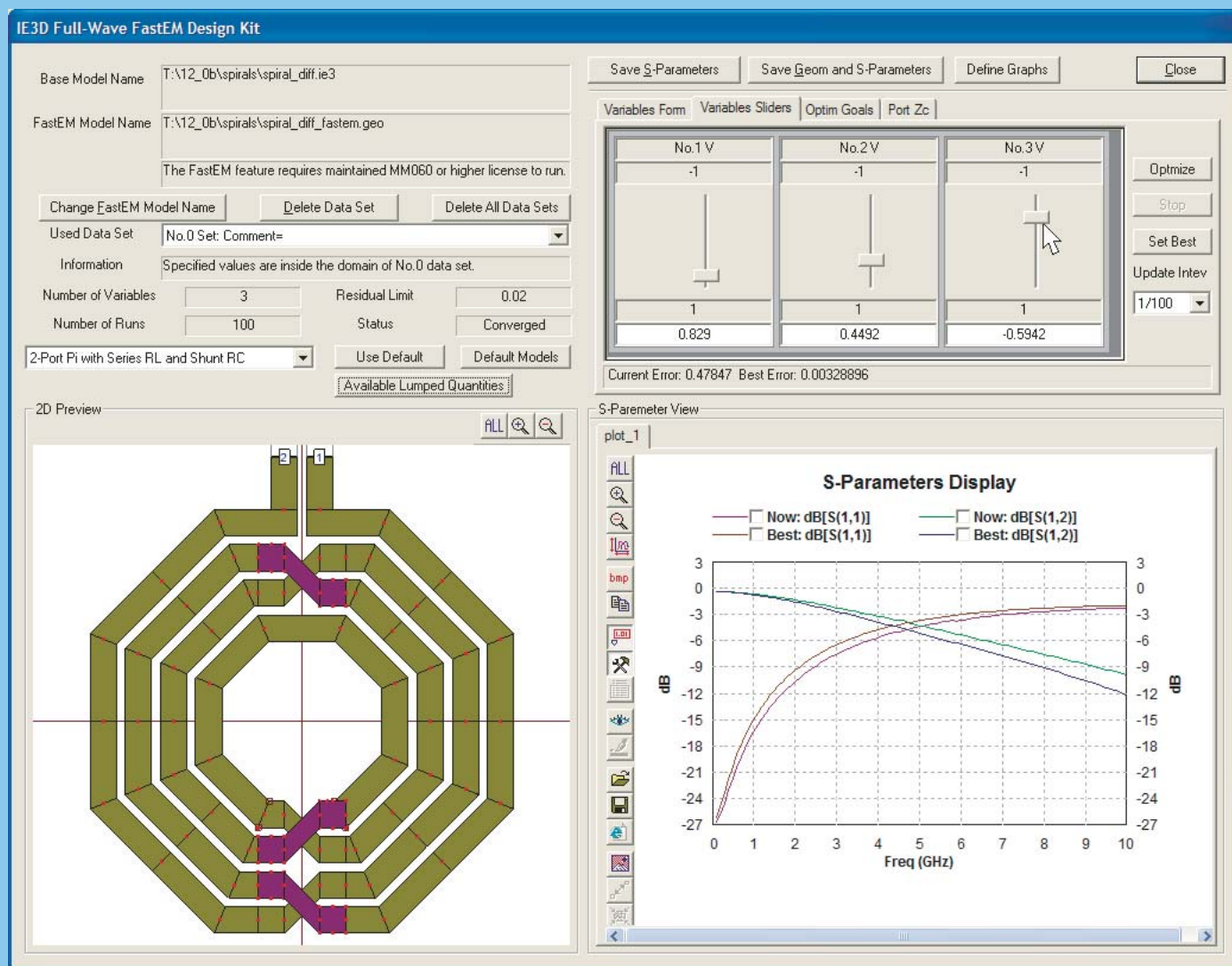
Antenna	L_a (mm)	1 st Lower-end Frequency (GHz)	1 st Higher-end Frequency (GHz)
A ₁	16	1.98	3.18
A ₂	14	2.28	3.18
A ₃	12	2.52	3.21
A ₄	10	2.67	3.21
A ₅	9	2.76	3.21



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Inserted Different Values of the Strip A

Figure 4 shows the measured return loss of the antenna, with a strip A of different lengths L_a inserted. As the length L_a decreases, the center frequency of the rejected band shifts to a higher frequency. When $L_a = 9$ mm, the lower end frequency of the first rejected band is above 2.695 GHz. It is observed that when L_a decreases, the higher end frequency of the first rejected band is slightly affected. The related results are listed in Table 1 with the parameters $w_f = w_s = 3.0$ mm, $h = 1.6$ mm, $\epsilon_r = 4.4$.

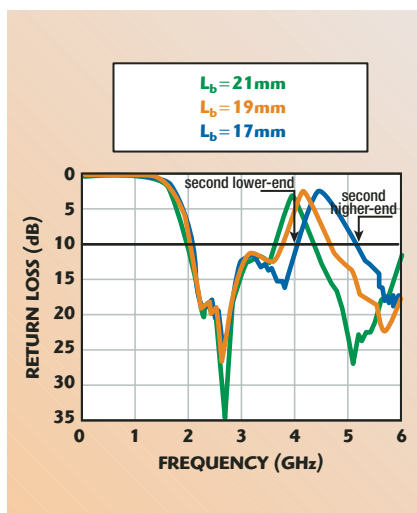
Inserted Different Values of the Strip B

Figure 5 shows the measured return loss of the antenna with a strip B of different lengths L_b inserted. As L_b decreases, the center frequency of the second rejected band shifts to a higher frequency. When $L_b = 17$ mm, the frequency of the second rejected band ranges from 3.99 to 5.1 GHz. It is suitable for the present application, between the low and median bands. The length L_b is approximately a quarter-wavelength at the center frequency of the second rejected band (4.525 GHz). The higher end frequency of the second rejected

band is greater than 5.25 GHz when L_b is less than 17 mm. Thus, setting $L_b = 17$ mm is a good choice for the present design. The related results are listed in Table 2, with the same parameters as in Table 1.

Combined Strip A and Strip B Proposed Antenna Design

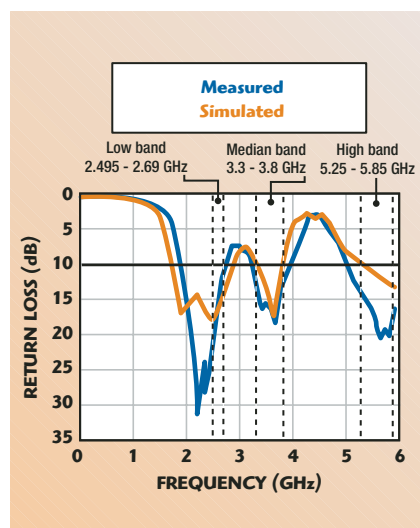
From what has been investigated, the relatively suitable strip lengths are $L_a = 9$ mm and $L_b = 17$ mm. After inserting the strips A and B simultaneously in the polygonal slot, the triple-band antenna for WiMAX applications can be obtained. Figure 6 shows the measured and simulated return loss of the proposed antenna. The three bandwidths (1.95 to 2.73 GHz, 3.27 to 3.99 GHz and 5.1 to < 6 GHz) are suitable for the WiMAX



▲ Fig. 5 Measured return loss with different lengths of strip B.

8072E network analyzer. The impedance bandwidth was greater than 100 percent (1.85 to 5.83 GHz) for a VSWR = 2.0. The broadband property of the polygonal slot antenna is obvious.

TABLE II CHARACTERISTICS OF THE PROTOTYPES WITH DIFFERENT LENGTHS L_b			
Antenna	L_b (mm)	2 nd Lower-end Frequency (GHz)	2 nd Higher-end Frequency (GHz)
B ₁	23	3.60	4.29
B ₂	21	3.69	4.35
B ₃	19	3.70	4.62
B ₄	17	3.99	5.10
B ₅	15	4.35	5.64



▲ Fig. 6 Measured and simulated return loss of the proposed antenna.

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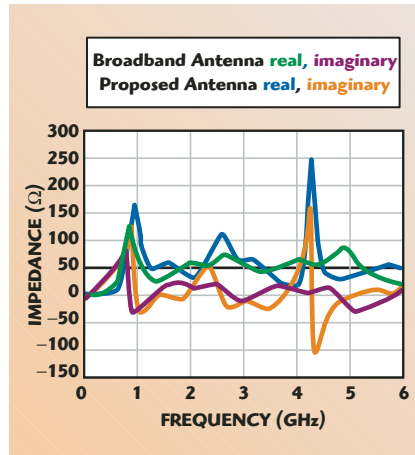
P/N	Bandwidth (GHz)	Test Freq. = 300MHz				Device Bias	
		Gain (dB)	PAE (%)	QPS (dB)	MT (dB)	V _{DS} (V)	I _{DS} (mA)
PW 110	DC - 1	26	19	33	1.8	4.7	68

P/N	Bandwidth (GHz)	Test Freq. = 900MHz				Device Bias	
		Gain (dB)	PAE (%)	QPS (dB)	MT (dB)	V _{DS} (V)	I _{DS} (mA)
PW 210	DC - 3	21	16	30	3.1	4.7	45
PW 250	DC - 3	18.5	16	30	3.3	4.7	45
PW 350	DC - 3	16.5	17.5	33	3.3	4.8	58
PW 370	DC - 3	14.5	17.5	33	3.6	4.8	58
PW 410	DC - 3	20.5	19	35	3.4	4.9	70
PW 450	DC - 3	18	19	35	3.7	4.9	70
PW 470	DC - 3	16	19	35	3.5	5.0	70
PW 510	DC - 3	20.5	20	38	3.4	5.4	85
PW 550	DC - 3	18.2	20	38	3.5	5.35	85
PW 570	DC - 3	16.2	20	38	3.6	5.4	85

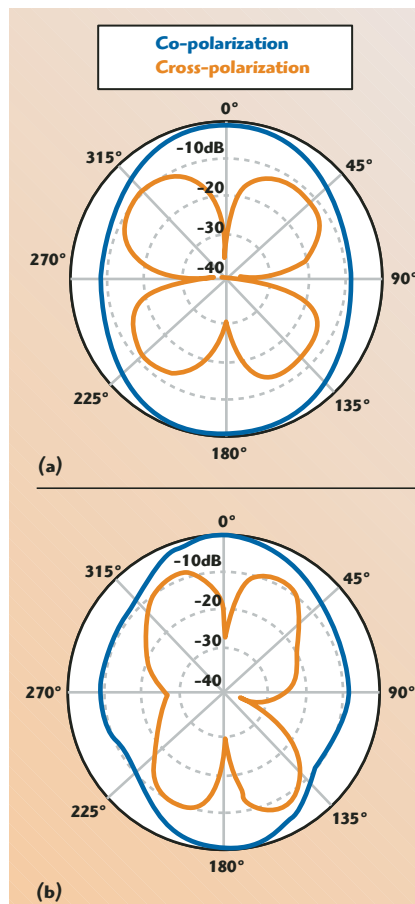
P/N	Bandwidth (GHz)	Test Freq. = 1.9GHz				Device Bias	
		Gain (dB)	PAE (%)	QPS (dB)	MT (dB)	V _{DS} (V)	I _{DS} (mA)
PH 230	1.5 - 3	17	22.5	38	3.2	5	85
PH 435	1.5 - 3	16.5	25.5	41	3.2	5	150
PH 460	1 - 3	15	22.5	41	3.5	5	150

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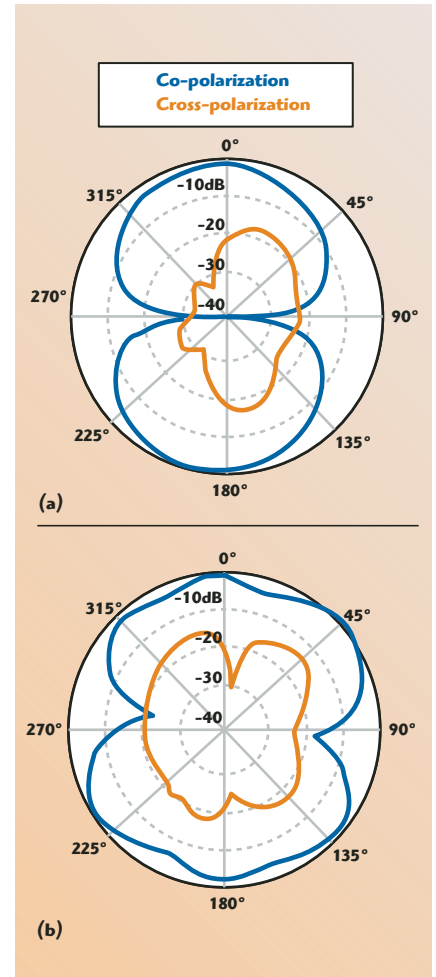


▲ Fig. 7 Impedance of the proposed broadband antennas.



▲ Fig. 8 Measured far-field radiation patterns of the proposed antenna in the x-z plane at (a) $f=2.5$ GHz and (b) $f=5.75$ GHz.

frequency bands. Figure 7 shows the impedance of both the proposed and broadband antennas. The real part of the impedance of the rejected band antenna is significantly increasing at the center frequency of the first and second rejected bands (2.995 and 4.525 GHz), and the maximum peak impedance of the second rejected



▲ Fig. 9 Measured far-field radiation patterns of the proposed antenna in the y-z plane at (a) $f=2.5$ GHz and (b) $f=5.75$ GHz.

band is 248 Ω . The variation of the imaginary part of the impedance of the proposed antenna, around the center frequency of the rejected bands, is larger than that of the broadband antenna. Figures 8 and 9 show the measured radiation patterns in the x-z and y-z planes, at 2.5 and 5.75 GHz, for the proposed design. The radiation characteristics were also investigated. Figure 10 shows the gain of the proposed antenna. The maximum peak antenna gains for the three operating bands are 5.7, 3.9 and 5.8 dBi, respectively, and the gain variations within the three bands are less than 2.9 dBi. The good gain characteristics of the antenna are very suitable for WiMAX applications.

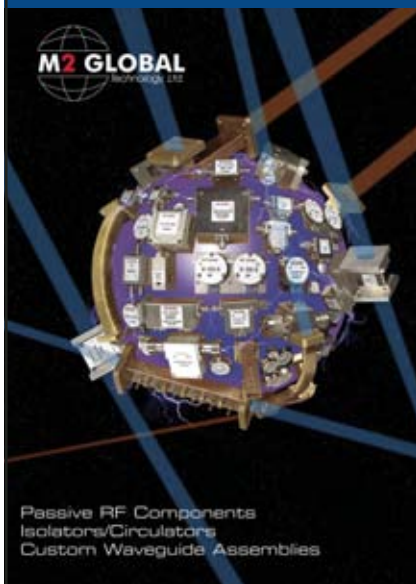
CONCLUSION

A novel polygonal slot antenna for WiMAX applications has been implemented. Inserting two narrow strips along the centerline of the polygonal

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WG Band	Waveguide Frequency Range (GHz)	Wavelength Rangeλo (mil)	Wavelength Rangeλo (mm)	Guide Wavelength Range (λg/λo)	Waveguide Impedance Range (Ω)	TE ₁₀ Cutoff Freq (GHz)	TE ₁₀ Cutoff λc (mil)	TE ₁₀ Cutoff λc (mm)	Internal Dimensions (mils)	Internal Dimensions (mm)
WR-28	26.5 - 40.0	445.4 - 295.1	11.313 - 7.495	1.650 - 1.177	621.9 - 443.6	21.1	560.0	14.22	280.0 x 140.0	7.112 x 3.556
WR-22	33.0 - 50.0	357.7 - 236.1	9.085 - 5.996	1.661 - 1.177	626.0 - 443.6	26.3	448.0	11.38	224.0 x 112.0	5.690 x 2.845
WR-19	40.0 - 60.0	295.1 - 196.7	7.495 - 4.997	1.613 - 1.173	608.3 - 442.4	31.4	376.0	9.55	188.0 x 94.0	4.775 x 2.388
WR-15	50.0 - 75.0	236.1 - 157.4	5.996 - 3.997	1.657 - 1.181	624.8 - 445.1	39.9	296.0	7.52	148.0 x 74.0	3.759 x 1.880
WR-12	60.0 - 90.0	196.7 - 131.1	4.997 - 3.331	1.690 - 1.186	637.2 - 447.1	48.4	244.0	6.20	122.0 x 61.0	3.099 x 1.549
WR-10	75.0 - 110.0	157.4 - 107.3	3.997 - 2.725	1.620 - 1.185	610.9 - 446.7	59.0	200.0	5.08	100.0 x 50.0	2.50 x 1.270
WR-08	90.0 - 140.0	131.1 - 84.3	3.331 - 2.141	1.746 - 1.177	658.1 - 443.6	73.8	160.0	4.06	80.0 x 40.0	2.032 x 1.016
WR-06	110.0 - 170.0	107.3 - 69.4	2.725 - 1.763	1.771 - 1.183	667.7 - 445.9	90.8	130.0	3.30	65.0 x 32.5	1.651 x 0.826
WR-05	140.0 - 220.0	84.3 - 53.6	2.141 - 1.363	1.777 - 1.176	669.7 - 443.3	115.7	102.0	2.59	51.0 x 25.5	1.295 x 0.648
WR-04	170.0 - 260.0	69.4 - 45.4	1.763 - 1.153	1.695 - 1.177	638.8 - 443.9	137.2	86.0	2.18	43.0 x 21.5	1.092 x 0.546
WR-03	220.0 - 325.0	53.6 - 36.3	1.363 - 0.922	1.627 - 1.183	613.5 - 445.9	173.6	68.0	1.73	34.0 x 17.0	0.864 x 0.432
WR-02.8	260.0 - 400.0	45.4 - 29.5	1.153 - 0.749	1.708 - 1.177	643.8 - 443.6	210.8	56.0	1.42	28.0 x 14.0	0.711 x 0.356
WR-02.2	325.0 - 500.0	36.3 - 23.6	0.922 - 0.600	1.771 - 1.185	667.7 - 446.7	268.2	44.0	1.12	22.0 x 11.0	0.559 x 0.279
WR-01.9	400.0 - 600.0	29.5 - 19.7	0.749 - 0.500	1.587 - 1.169	598.3 - 440.6	310.6	38.0	0.97	19.0 x 9.5	0.483 x 0.241
WR-01.5	500.0 - 750.0	23.6 - 15.7	0.600 - 0.400	1.620 - 1.175	610.9 - 442.8	393.4	30.0	0.76	15.0 x 7.5	0.381 x 0.191
WR-01.2	600.0 - 900.0	19.7 - 13.1	0.500 - 0.333	1.746 - 1.194	658.1 - 450.1	491.8	24.0	0.61	12.0 x 6.0	0.305 x 0.152
WR-01.0	750.0 - 1100.0	15.7 - 10.7	0.400 - 0.273	1.620 - 1.185	610.9 - 446.7	590.1	20.0	0.51	10.0 x 5.0	0.254 x 0.127

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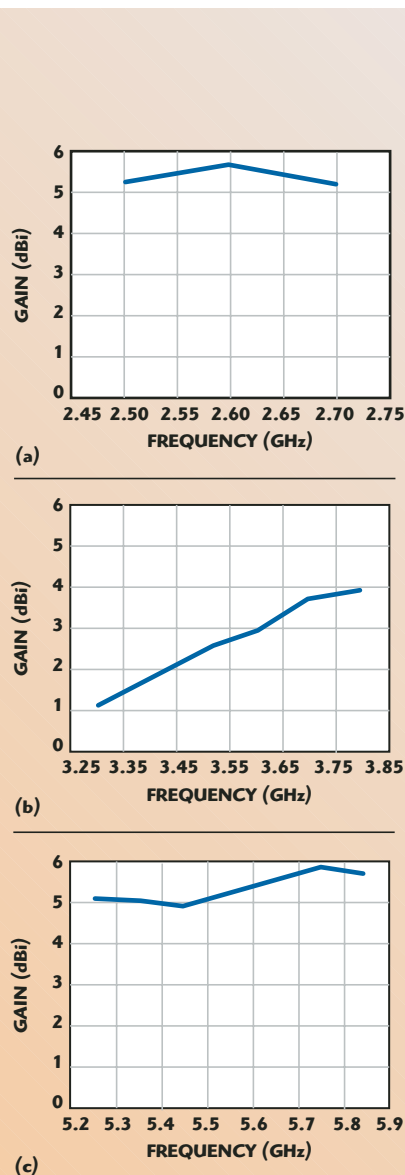
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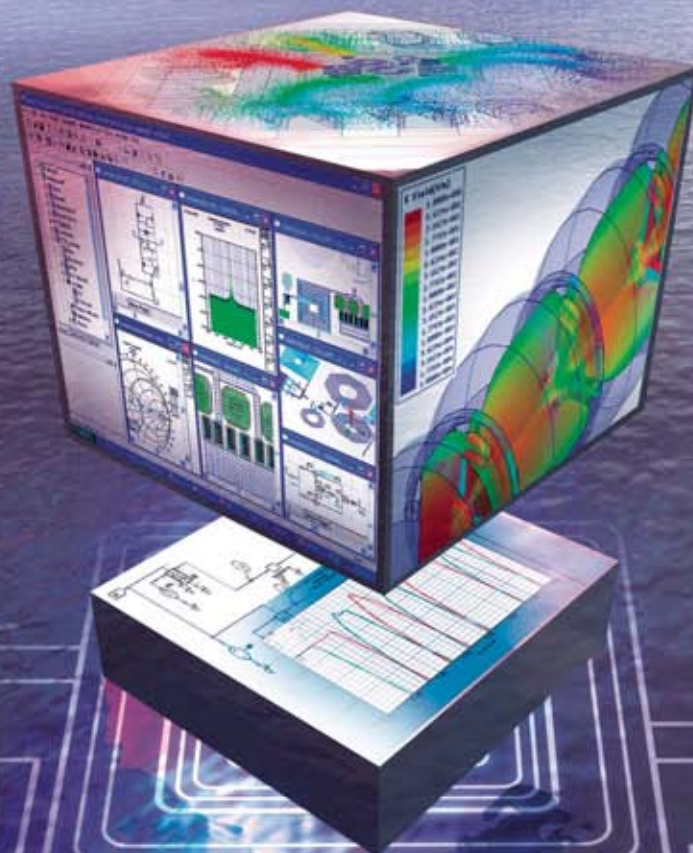
degree. His research interests include printed antenna for wireless communications and printed slot antenna for WiMAX applications.



▲ Fig. 10 Measured peak gain of the proposed antenna at the (a) low band, (b) median band and (c) high band.

slot antenna leads to two rejected bands, from which the triple-bands for WiMAX applications can be obtained. The triple-bands of the proposed design satisfy the WiMAX standard. The proposed antenna can be easily excited by a 50 Ω microstrip-line printed on the FR-4 dielectric substrate, and good impedance matching can be obtained for the three operating frequency bands of WiMAX. The good gain of the proposed antenna is very suitable for WiMAX applications. ■

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A 60 GHz MILLIMETER-WAVE CMOS RFIC-ON-CHIP DIPOLE ANTENNA

This article presents a 60 GHz millimeter-wave RFIC-on-chip dipole antenna, fabricated with a 0.18 μm CMOS process. A planar dipole-antenna structure with an integrated microstrip via-hole balun was adopted to design this RFIC-on-chip antenna. The die size of the chip is 0.75×0.66 mm. A finite element method (FEM)-based 3-D full-wave EM solver, HFSS, is used for design simulation. The measured VSWR of the designed 60 GHz RFIC-on-chip antenna is less than 3 from 55 to 65 GHz. The simulated H-plane radiation pattern is close to an omni-directional pattern. The simulated antenna radiation efficiency is approximately 16 percent, due to the CMOS substrate loss. The measured maximum antenna power gain is approximately -10 dB.

There is an increasing demand for broadband multimedia components to satisfy the ever-increasing capacity of wireless networks. In particular, for dense local communications, the 60 GHz band for wireless personal area network (WPAN) applications is of special interest for short-range communications, due to the RF attenuation of the atmospheric oxygen by 10 to 15 dB/km, in a bandwidth of approximately 8 GHz, centered around 60 GHz. This makes the 60 GHz band of utmost interest for all kinds of short-range wireless communications.¹ In order to pursue the RF system-on-chip (SoC) approach for a 60 GHz radio, antennas integrated with a low cost monolithically integrated CMOS RF front-end circuitry have been studied.^{2,3} In this article, a 60 GHz CMOS RFIC-on-chip dipole antenna is presented. A planar dipole-antenna structure with an integrated

microstrip via-hole balun was adopted to design this RFIC-on-chip antenna. A FEM-based 3-D full-wave EM solver, Ansoft HFSS, is used for design simulation. The antenna chip is fabricated with a 0.18 μm CMOS process. On-wafer measurements of the input VSWR and the antenna gain of the designed RFIC-on-chip antenna were made with a microwave probe station.

ANTENNA DESIGN

The proposed planar printed dipole antenna is shown in **Figure 1**. A microstrip via-hole balun acts as an unbalanced-to-balanced trans-

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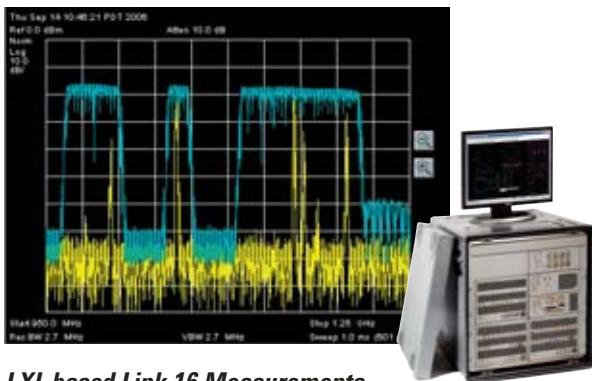


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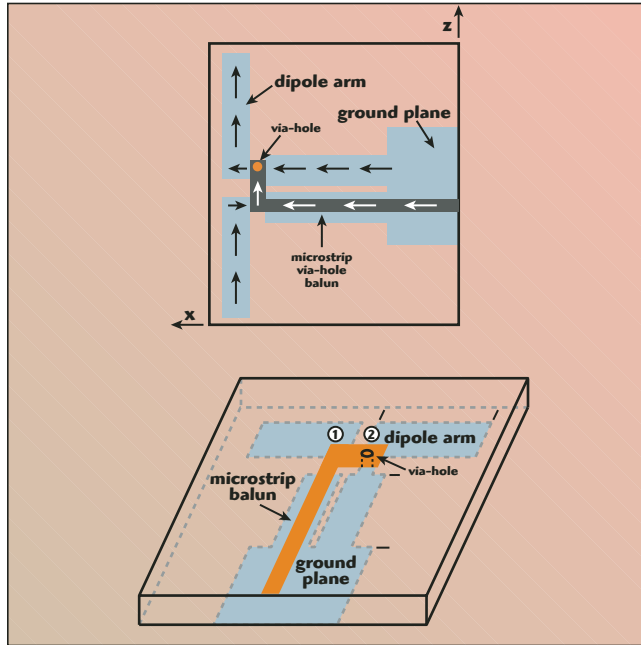


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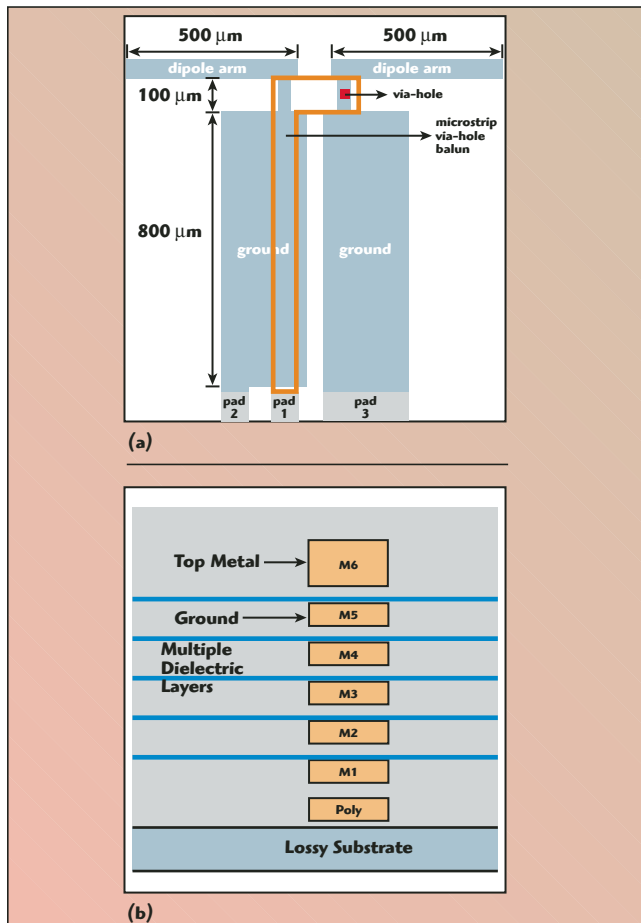


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former between the feed coaxial line and the two printed dipole strips.⁴ The length of the dipole strips is approximately a $1/4$ wavelength. The ground plane of the microstrip line and the dipole strips are in the same plane. As

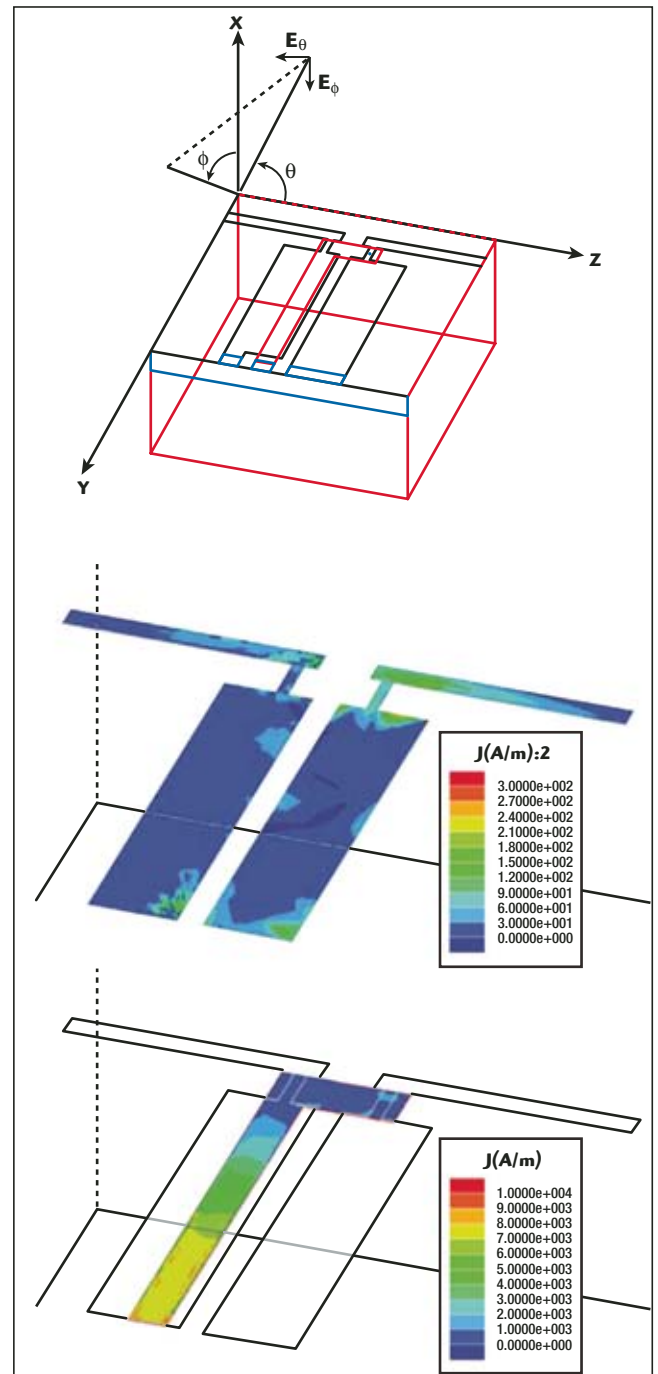


▲ Fig. 1 Planar dipole antenna with an integrated via-hole balun.



▲ Fig. 2 Chip layout (a) and cross-section (b) of the 60 GHz CMOS RFIC-on-chip antenna.

indicated, a via-hole permits the feed (point 2) of a printed dipole strip to have the same phase as the feed (point 1) of the other printed dipole strip. Due to the 180° phase difference between the top conductor and the ground plane of the microstrip line, the feed at point 2 of the printed dipole strip will have a 180° phase difference with the other feed at point 1. The widths of the dipole arm strips are chosen to be approximately one-tenth of a wavelength. The width of the microstrip feed-line is designed to have a characteristic impedance of 50Ω . The accurate dimensions of each part of the printed dipole and integrated via-hole balun must be numerically computed to achieve the de-



▲ Fig. 3 HFSS simulation scheme and simulated antenna current distribution.



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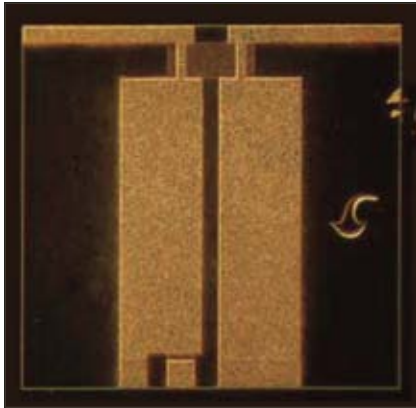
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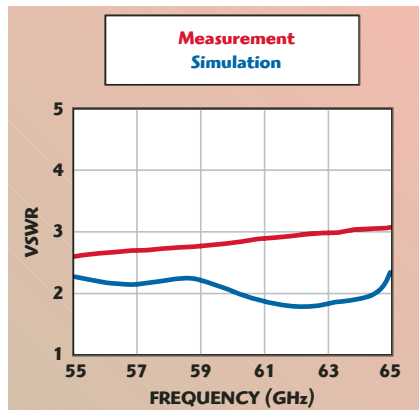
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sired performance of the printed dipole antenna. **Figure 2** shows the chip layout and the cross-section of the designed 60 GHz RFIC-on-chip dipole antenna fabricated with a 0.18 μm CMOS process.



▲ Fig. 4 Chip micrograph.



▲ Fig. 5 Simulated and measured antenna input VSWR.

SIMULATION AND MEASUREMENT RESULTS

Figure 3 shows the HFSS simulated antenna current distribution. The simulated current density vectors on the top and bottom metals show the balanced current distribution and the 180° phase difference of the flowing current vectors at the two feed points of the printed dipole. This shows the working of the integrated microstrip balun. **Figure 4** shows a chip micrograph of a fabricated 60 GHz CMOS RFIC-on-chip antenna. The chip size is 0.75 × 0.66 mm with a substrate thickness of approximately 500 μm . **Figure 5** shows the input VSWR of the antenna, measured on-wafer, which is less than 3 from 55 to 65 GHz. **Figure 6** and **Table 1** show the simulated antenna radiation patterns and power gain values in the H- and E-planes at 60 GHz. Note that the antenna power gain (absolute gain), G_p , is defined as

$$G_p = \text{directive gain} \cdot \text{radiation efficiency} \quad (1)$$

The simulated antenna radiation efficiency is approximately 16 percent, which may be due to the CMOS substrate loss. The H-plane pattern is close to an omni-directional pattern except for some attenuation in a certain direction. The simulated maximum, minimum and average power gains in the H-plane are approximately -9, -16 and

-11 dBi, respectively. The absolute power gain of the antenna was measured on-wafer with the technique described by Simons and Lee.⁵ As illustrated in **Figure 7**, two identical RFIC-on-chip antennas are placed face-to-face within a distance R . One antenna is used as a transmitting antenna and the other as a receiving antenna. It is noted that the distance R separating the two identical antennas should satisfy the far-field condition, which is equal to or greater than⁵

$$R = \frac{2D^2}{\lambda_0} \quad (2)$$

where D and λ_0 is the largest aperture dimension of the RFIC-on-chip antenna and the free-space wavelength at the operating frequency, respectively. From the Friis power transmission formula, the maximum antenna power gain (in the central forward direction of the dipole antenna) is given by

$$G_r G_t = G^2 = \left(\frac{P_r}{P_t} \right) \left(\frac{4\pi R}{\lambda_0} \right)^2 = |S_{21}|^2 \left(\frac{4\pi R}{\lambda_0} \right)^2 \quad (3)$$

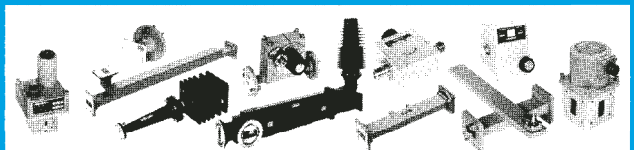
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G_t and G_r = gains of the transmitting and receiving antennas
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 P_r = power received

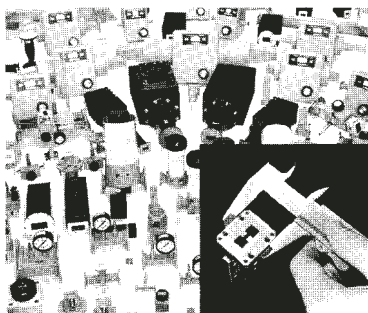
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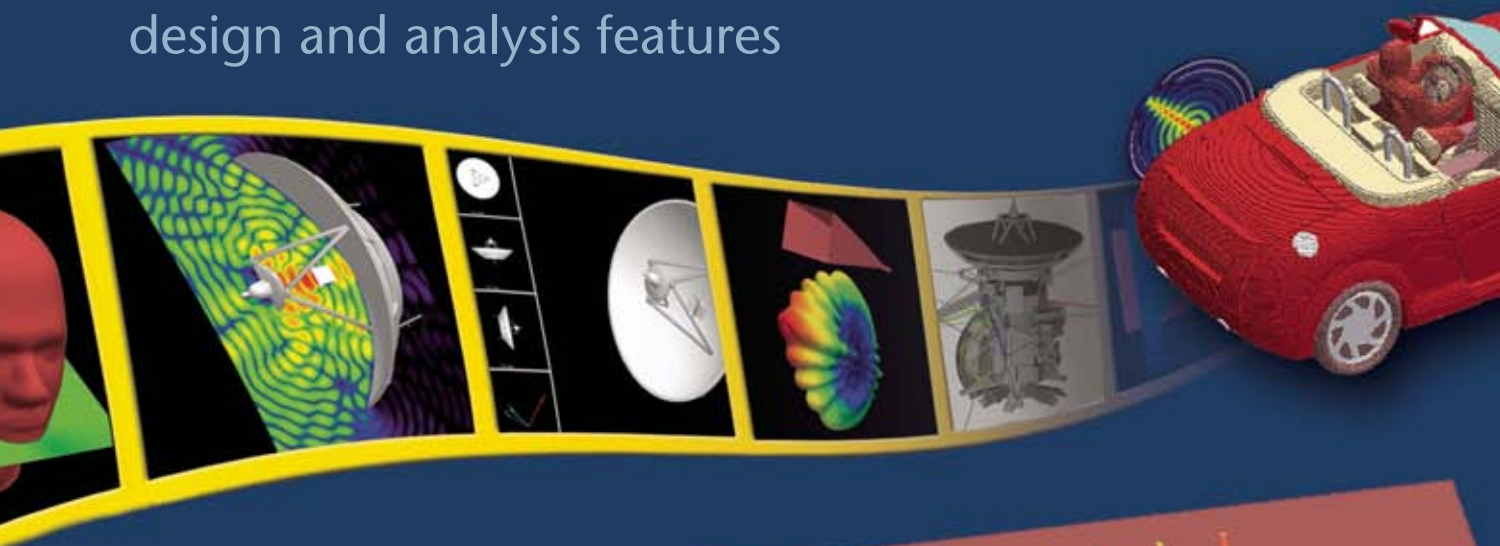
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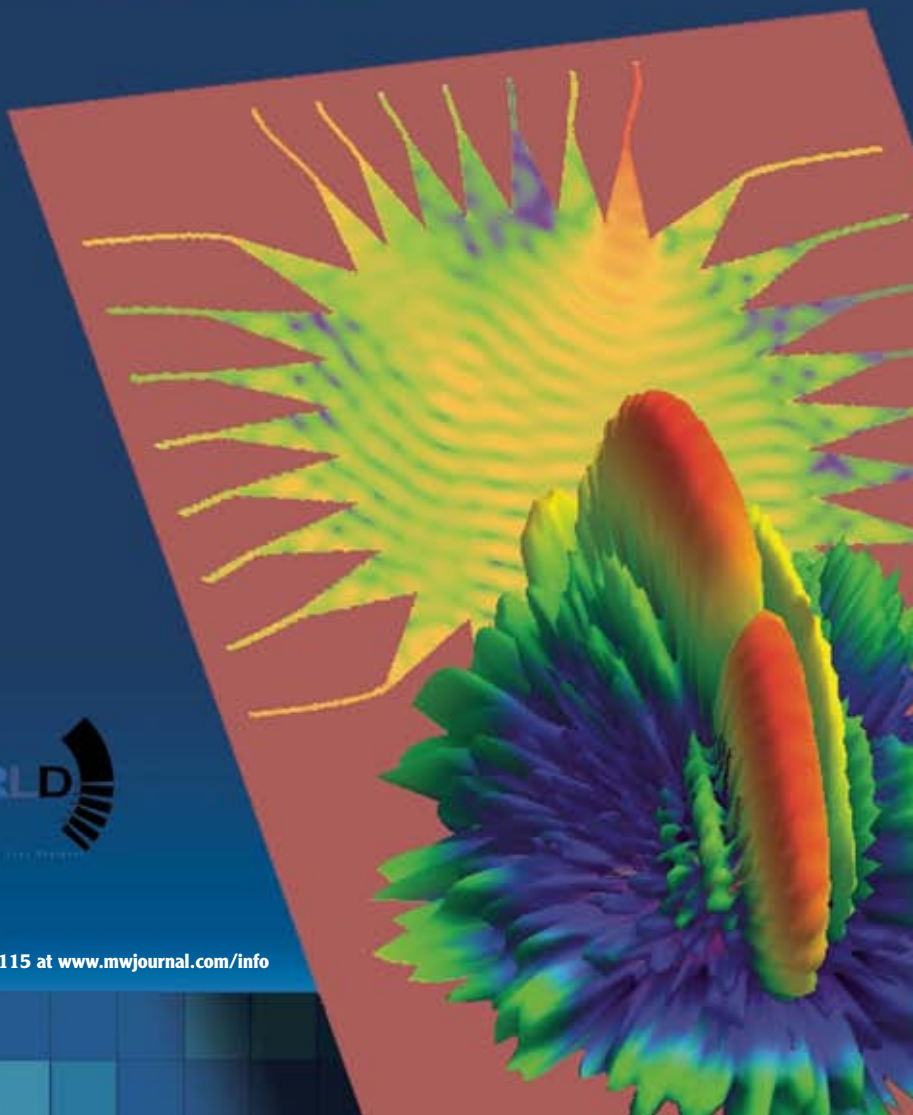


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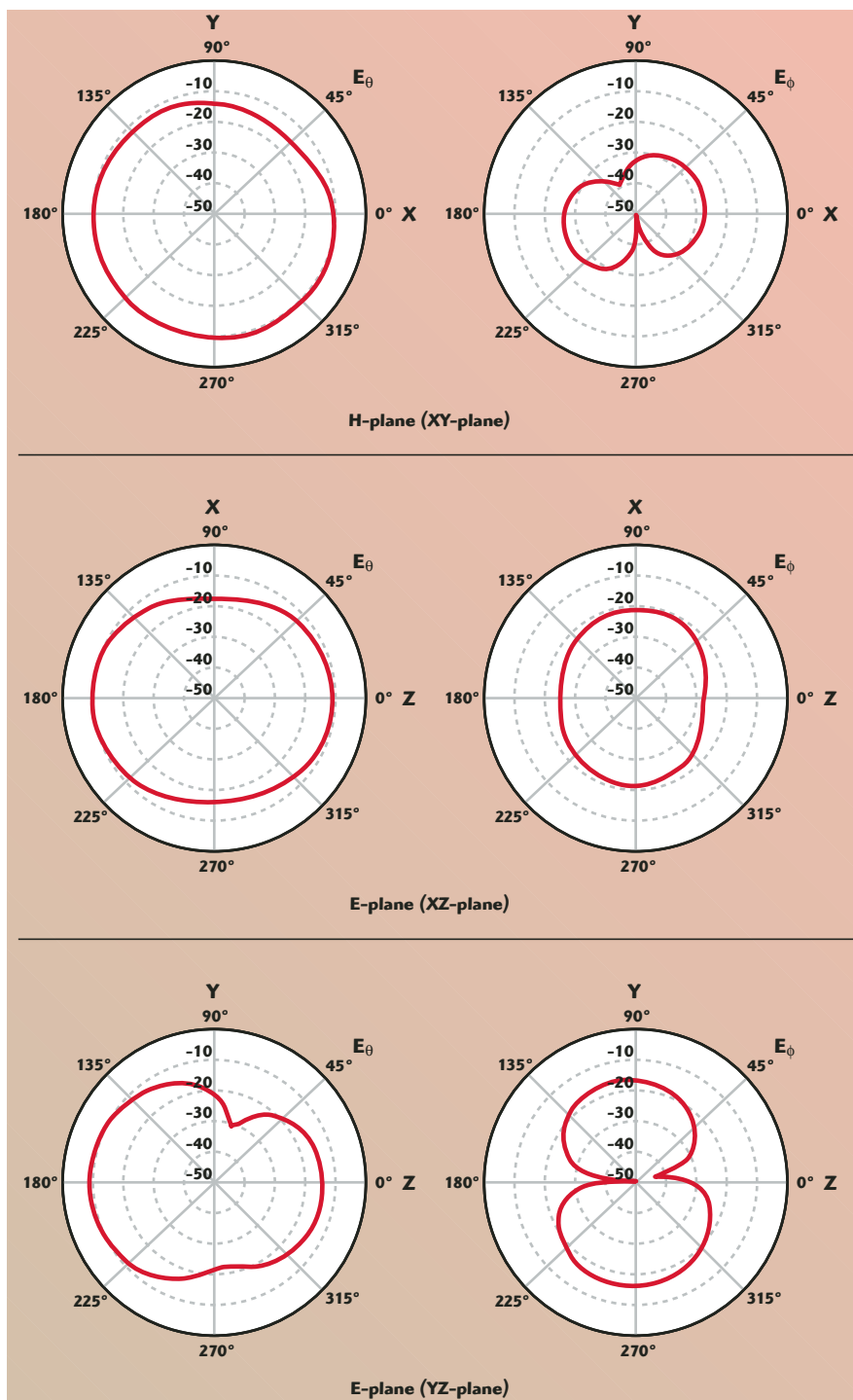
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▲ Fig. 6 Simulated antenna radiation patterns in the H- and E-planes at 60 GHz.

TABLE I						
SIMULATED ANTENNA POWER GAIN AT 60 GHz						
Simulated Power Gain	E_θ Field (dBi)			E_ϕ Field (dBi)		
	Max	Min	Average	Max	Min	Average
X-Y plane	-9.0	-15.9	-11.0	-25.4	-50.8	-31.0
X-Z plane	-9.9	-17.1	-13.0	-21.0	-27.2	-23.5
Y-Z plane	-9.2	-30.5	-15.8	-15.8	-53.9	-22.6

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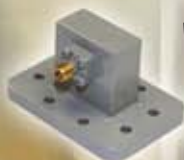
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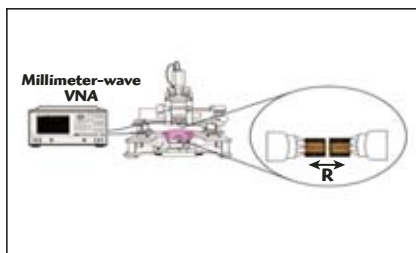
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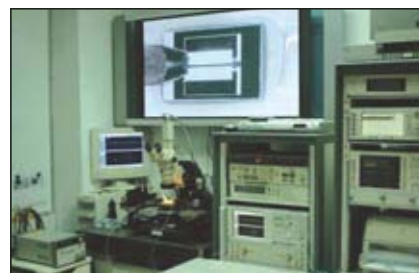
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▲ Fig. 7 Illustration of the on-wafer setup to measure the gain of the RFIC-on-chip antenna.



▲ Fig. 8 The probe station, on-wafer measurement setup.

TABLE II

**PERFORMANCE SUMMARY OF A 60 GHz CMOS
RFIC-ON-CHIP DIPOLE ANTENNA WITH VIA-HOLE BALUN**

	Simulation	Measurement
Frequency range (GHz)	57 to 64	55 to 65
VSWR	< 2.5	< 3.0
Radiation efficiency (%)	16	—
Max. antenna gain (dBi)	−9.0	−10.0
Chip size (mm)	0.75 × 0.66	

Similarly, since the two antennas are identical, $G_r = G_t = G$. The power ratio P_r/P_t is the measured direct transmission coefficient $|S_{21}|^2$ from the VNA. **Figure 8** shows a photograph of the probe-station, on-wafer measurement setup. The measured maximum antenna power gain at 60 GHz is approximately −10 dBi, which is in good agreement with the simulation results. **Table 2** shows the performance summary of the antenna radiation characteristics.

CONCLUSION

This article discussed the design, fabrication and on-wafer measurement of a 60 GHz millimeter-wave CMOS RFIC-on-chip dipole antenna with an integrated microstrip via-hole balun. This is to realize an RF system-on-chip (SoC) for a 60 GHz radio with the antenna integrated with a low cost, monolithically integrated, CMOS RF front-end circuitry. The antenna chip is fabricated with a 0.18 μm CMOS process with a chip size of 0.75 × 0.66 mm. The HFSS FEM-based 3-D full-wave EM solver is used for design simulation. The input VSWR and the maximum antenna power gain of the RFIC-on-chip antenna were measured on-wafer. The measured antenna VSWR is less than 3 from 55 to 65 GHz. The simulated H-plane radiation pattern is close to an omni-directional pattern and the simulated antenna radiation efficiency is approximately 16 percent, which may

be due to the CMOS substrate loss. The measured maximum antenna power gain at 60 GHz is approximately −10 dBi, which is in good agreement with the simulation results. The integration of the designed 60 GHz RFIC-on-chip antenna with a 60

GHz CMOS RF front-end circuit will be pursued. ■

ACKNOWLEDGMENTS

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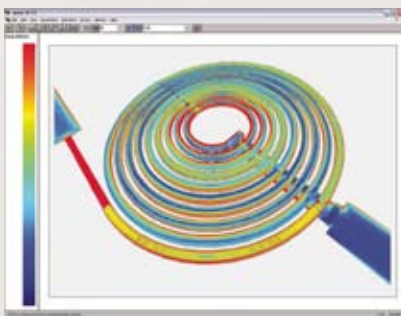
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A LOW PROFILE MULTI-BAND U-SHAPED APERTURE-COUPLED MICROSTRIP ANTENNA WITH A COIL

In this article, an L-shaped probe-fed, U-slot patch antenna with a coil element is studied. The L-shaped probe feed is used to enhance the impedance matching, which is necessary because of a low radiation resistance in the usable band. The coil contributes to the size reduction of the antenna and acts also as a resonance device to create a multi-band response. The measured impedance bandwidths are approximately 795 to 962 MHz and 1825 to 2308 MHz for a S_{11} less than -10 dB. This multi-band characteristic covers the cellular, PCS, IMT-2000 and WLL frequency bands. The measured results, for the radiation patterns, show relatively good characteristics.

Microstrip patches are an attractive type of antenna because of their low cost, conformability and ease of manufacture. The aperture-coupled configuration¹ also provides the advantage of isolating spurious feed radiation by using a common ground plane. The primary barrier to the implementation of these antennas in many applications, however, is their limited bandwidth, which is only of the order of a few percent for a typical patch radiator. Because of this, much work has been devoted to increasing the bandwidth of microstrip antennas. One technique that has been used is a near resonance aperture, resulting in a bandwidth of the order of 20 percent.² Other techniques that have been used extensively are aperture-coupled stacked patch antennas with a bandwidth of 30 to 50 percent.^{3,4} A broadband, air-filled, stacked U-slot patch antenna has been studied where a

bandwidth of the order of 44 percent can be achieved.⁵ A broadband, H-shaped, aperture-coupled, U-slot patch antenna⁶ with an impedance bandwidth of 21.7 percent has also been presented. In addition, a wideband microstrip patch antenna, with a tilted L-probe feeding⁷ and having an impedance bandwidth of 37.1 percent, has been described.

In this article, an alternative design technique that combines an L-shaped probe-fed, U-slot patch antenna with a coil is proposed. The L-shaped probe feed is used to enhance

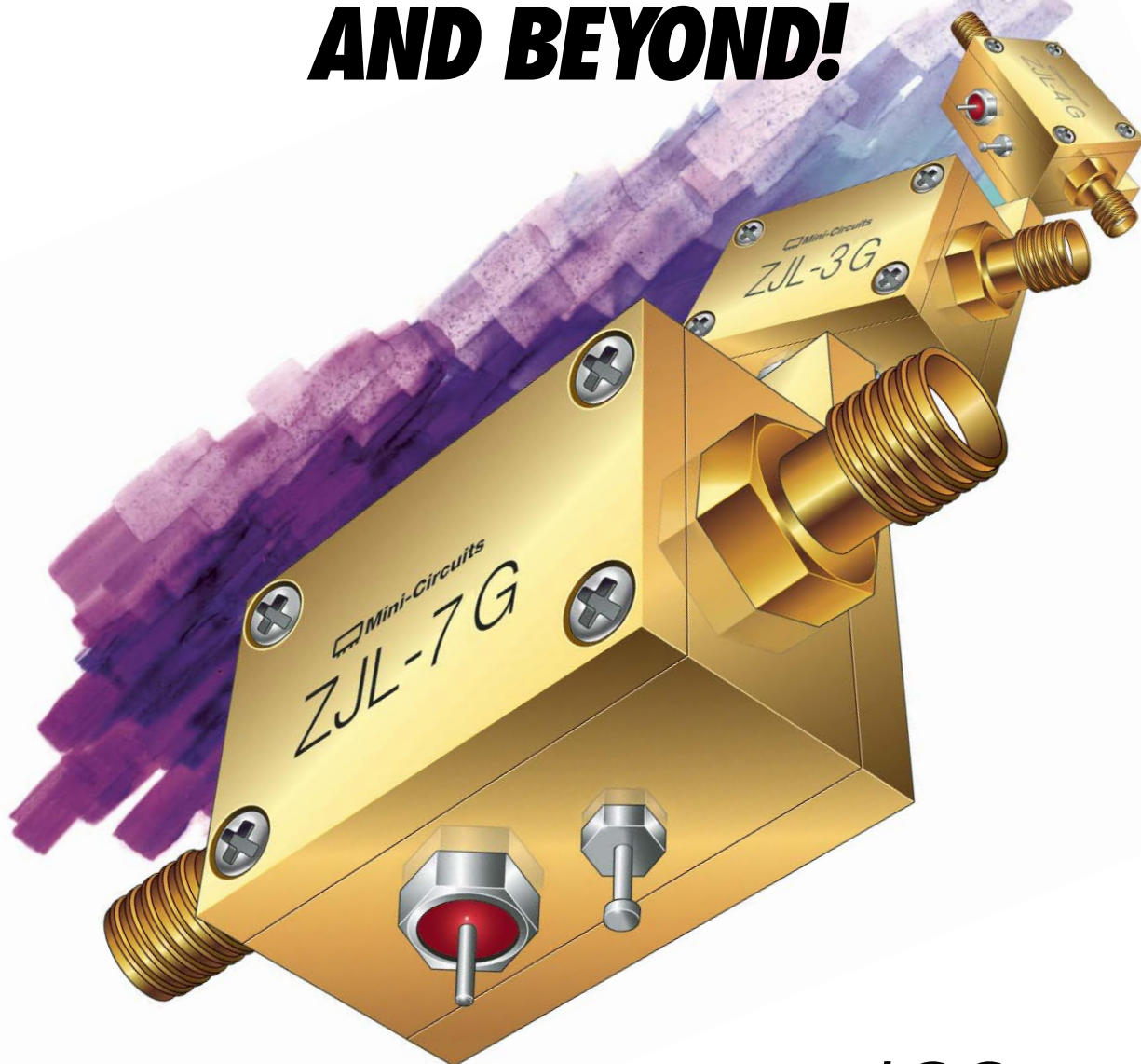
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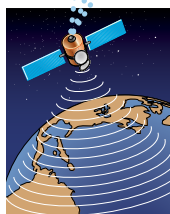
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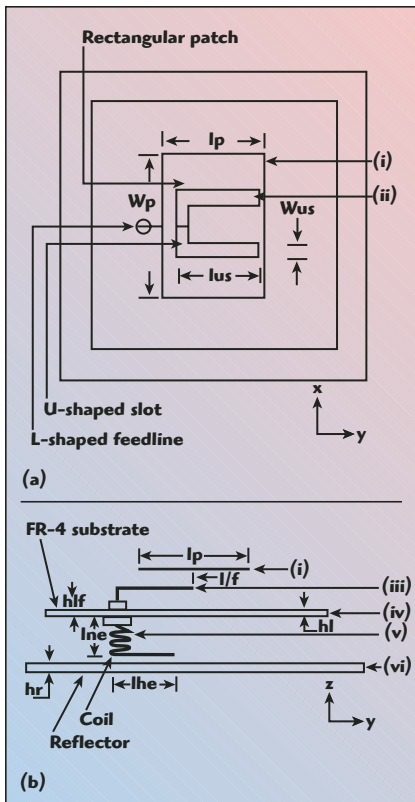


Fig. 1 Structure of the proposed antenna; (a) top view and (b) side view.

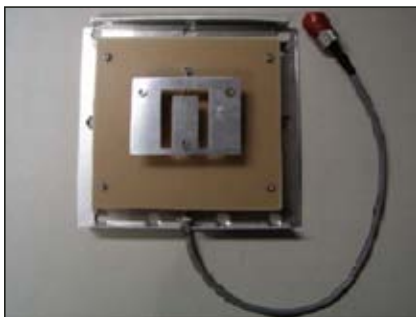


Fig. 2 The fabricated antenna.

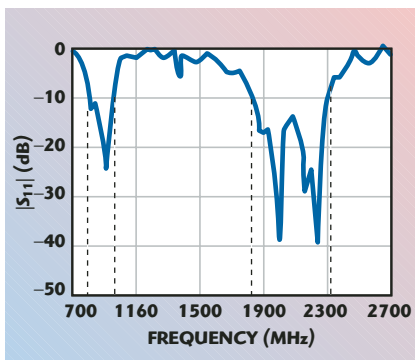


Fig. 3 Measured return loss.

the impedance matching, necessary because of a low radiation resistance in the usable band. In addition, the coil contributes to a reduction of the antenna size and acts as a resonance

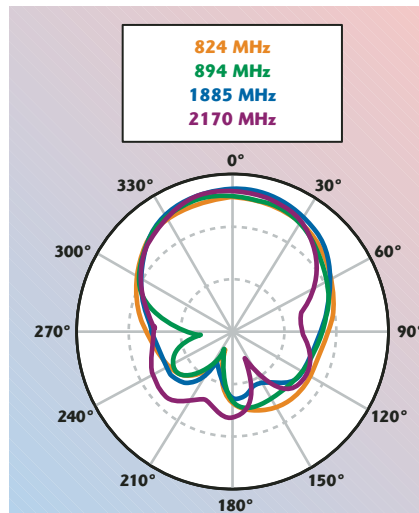


Fig. 4 Measured x-z radiation pattern.

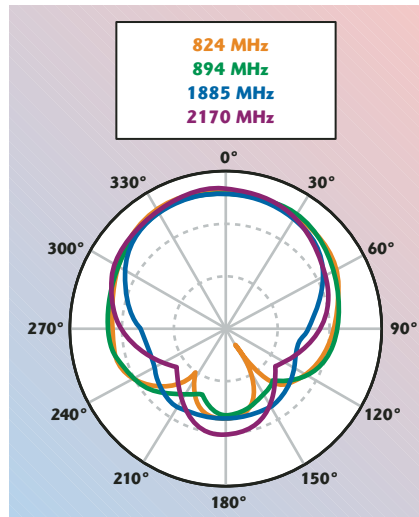


Fig. 5 Measured y-z radiation pattern.

device for the cellular band. A thick substrate is also used to enhance the bandwidth. The bandwidth characteristics of the proposed antenna depend highly on the thickness of the patch substrate as well as on the L-shaped feed line. The experimental impedance bandwidth is approximately 795 to 962 MHz and 1825 to 2308 MHz for a S_{11} less than -10 dB. Experimental results for the radiation patterns of the multi-band antenna are also presented.

ANTENNA STRUCTURE AND EXPERIMENTAL RESULTS

The geometry of an alternative design technique that combines an L-shaped probe-fed, U-slot patch antenna with a coil is shown in Figure 1. The design parameters of the antenna are: For the patch (i), $l_p = 52$ mm, $w_p = 71$ mm; for the U-shaped slot (ii), l_{us}

$= 33$ mm, $w_{us} = 40.5$ mm; for the L-shaped probe feed (iii), $l_{lf} = 38$ mm, $h_{lf} = 5.5$ mm; for the dielectric layer (iv), $\epsilon_{r1} = 4.6$, $l = 21$ mm, $h_1 = 1.6$ mm, $\tan\delta_2 = 0.0009$; for the coil (v), $l_{he} = 16.5$ mm; and for the aluminum reflector (vi), $l_r = 148$ mm, $w_r = 160$ mm, $h_r = 1.3$ mm. The resonances of the coil and of the U-slot patch with probe feeding occur on either sides of the operating band. Since the U-slot patch is used as a radiator and a resonator, its length cannot be changed to control the impedance at the L-shaped feed line, as would be done ordinarily with an aperture-coupled patch. The L-shaped probe feeding is used to enhance the impedance matching. This is necessary because of the low radiation resistance in the usable band. In addition, a coil is used to reduce the size of the antenna and acts as a resonance device for the cellular band. A thick substrate is used to enhance the bandwidth. The bandwidth characteristics of the proposed antenna depend highly on the thickness of the substrate patch and the L-shaped feed line, which improve of the coupling and the impedance matching. A photograph of the fabricated antenna is shown in Figure 2.

The return loss of the antenna was measured with an HP8510 network analyzer. The antenna size, including the reflector, is $160 \times 148 \times 34.5$ mm. The measured impedance bandwidths, shown in Figure 3, are approximately 795 to 962 MHz (19.8 percent at a center frequency of 880 MHz) and 1825 to 2308 MHz (24 percent at a center frequency of 2000 MHz), for a S_{11} of less than -10 dB. The experimental results for the return loss exhibit the dual-resonance characteristics of a multi-band of the antenna. After calibration using a horn antenna, the radiation patterns were measured. Figure 4 shows the measured x-z radiation patterns as a function of frequency. The half-beam width is approximately 90° . Figure 5 shows the measured y-z radiation patterns as a function of frequency. All the radiation patterns show good characteristics.

Figure 6 shows the measured gain versus frequency for the cellular and GSM bands. The gain is relatively high over most of the band, most probably because of the finite size of the antenna substrate, that is the power in the surface wave is not confined to the sub-



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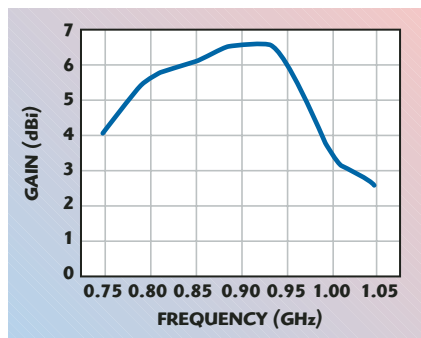
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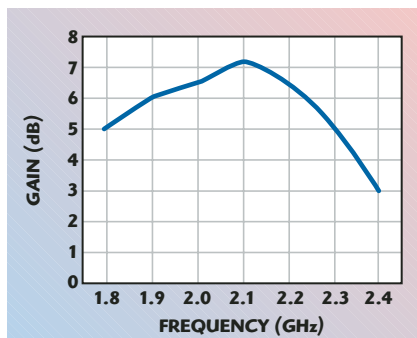


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▲ Fig. 6 Measured antenna gain in the cellular and GSM bands.



▲ Fig. 7 Measured antenna gain in the PCS, IMT-2000 and WLL bands.

strate but diffracted by the substrate edge, an effect which was not taken into account in the analysis. The measured gain is 5.5 dBi over the entire usable frequency band, but drops off rapidly past the band edges. The measured gain versus frequency in the PCS, IMT-2000 and WLL bands is shown in **Figure 7**. The measured gain is also 5.0 dBi over the entire usable frequency band, but drops off rapidly past the band edges. This is due to impedance mismatch and pattern degradation, as the back radiation level increases rapidly at these frequencies.

CONCLUSION

In this article, an L-shaped probed, U-slot patch antenna with a coil was described. The L-shaped probe feed is used to enhance the impedance matching necessary because of a low radiation resistance in the usable band. The coil contributes to the antenna size reduction and acts as a resonance device for the cellular band. The measured results on this antenna show a multi-band characteristic. The proposed reduced size antenna can be used in practical applications such as cellular, GSM, PCS, IMT-2000 and WLL. ■

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Bandwidth:

700 MHz

Step Size: 1 Hz

Internal Reference

Options:

TCXO Specifications	12.8 MHz
Temperature Stability	$\pm 1.5 \times 10^{-6}$
Aging first year	$\pm 2 \times 10^{-6}$
Operating Temp. Range	-10 to +60 °C

(With freq. adjustment through voltage control pin)

OCXO Specifications	13 MHz
Temperature Stability	$\pm 2.0 \times 10^{-6}$
Aging first year	$\pm 1 \times 10^{-7}$
Operating Temp. Range	-10 to +70 °C
Warm-Up Time:	10 min.
Additional Current Consumption	500 mA (warm-up)
After warm-up	200 mA (continuous)

External Reference Input:

10, 12.8, 13, 19.44 MHz
and multiples thereof
VCC: +13 VDC (± 3 V)

Bias Voltage:

Supply Current:

<800 mA @ 13 V

Bias Voltage Ripple:

100 mV p-p (Max)

RF Output Power:

(w/amp. option) +10 dBm (Min)

When Unlocked:

≤ 20 dBm

Spurious Suppression:

-65 dBc (Max)

Harmonic Suppression:

Amplifier/Filter option	15 dBc (Min)
Divider option (Full range model)	8 dBc (Min)
(Octave band in divider range)	15 dBc (Min)

Maximum Phase Noise

Offset	Frequency: 350 MHz (dBc/Hz)	Frequency: 1050 MHz (dBc/Hz)
100 Hz	-108	-100
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In today's fast paced mobile handset market, design houses and manufacturers are challenged to meet a variety of targets to satisfy network provider's high expectations in cellular and multimedia phones. Design cycle time, performance, feature requirements, form factor, quality and cost targets remain dominant selection criteria for mobile phone designers.

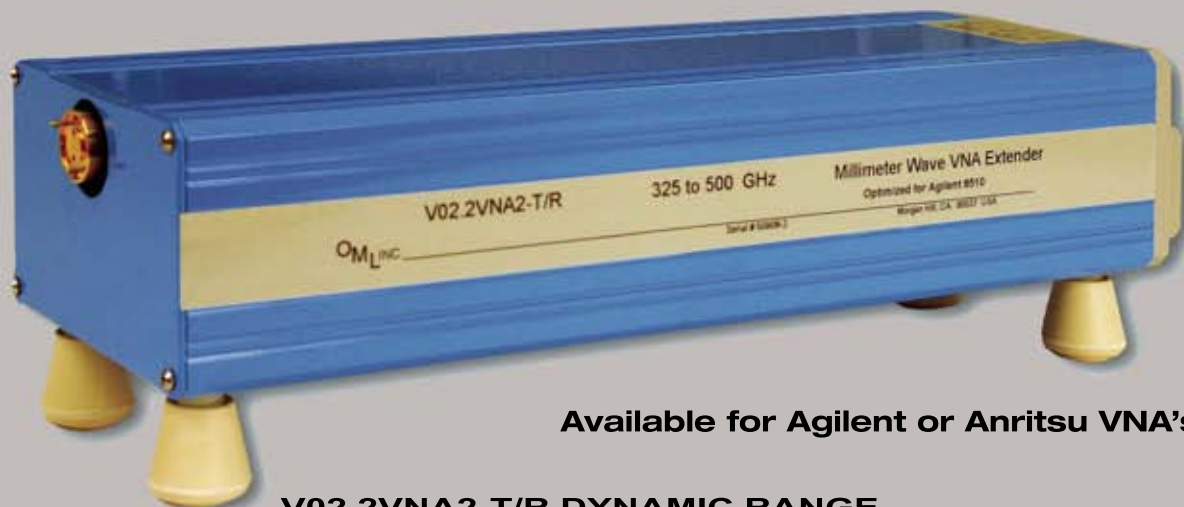
Next generation mobile multimedia applications (combining GSM/GPRS/EDGE/WCDMA/WLAN/GPS in one phone, for example) put even more stringent requirements on the hardware architecture. Partitioning of the baseband and RF components are critical handset design decisions with respect to functionality, performance, integration level, size and cost.

In an effort to lead the market trend in RF front-end architecture, integration and form factor size reduction, TriQuint Semiconductor has recently introduced its latest RF transmit

(TX) module, the TQM6M5001, which adds full linear EDGE functionality to its successful family of $6 \times 6 \times 1.1 \text{ mm}^3$ GSM/GPRS TX modules. This module family offers significant advantages in addressing these challenges using the TX module architecture already adopted with marketplace success by many GSM and EDGE phones.

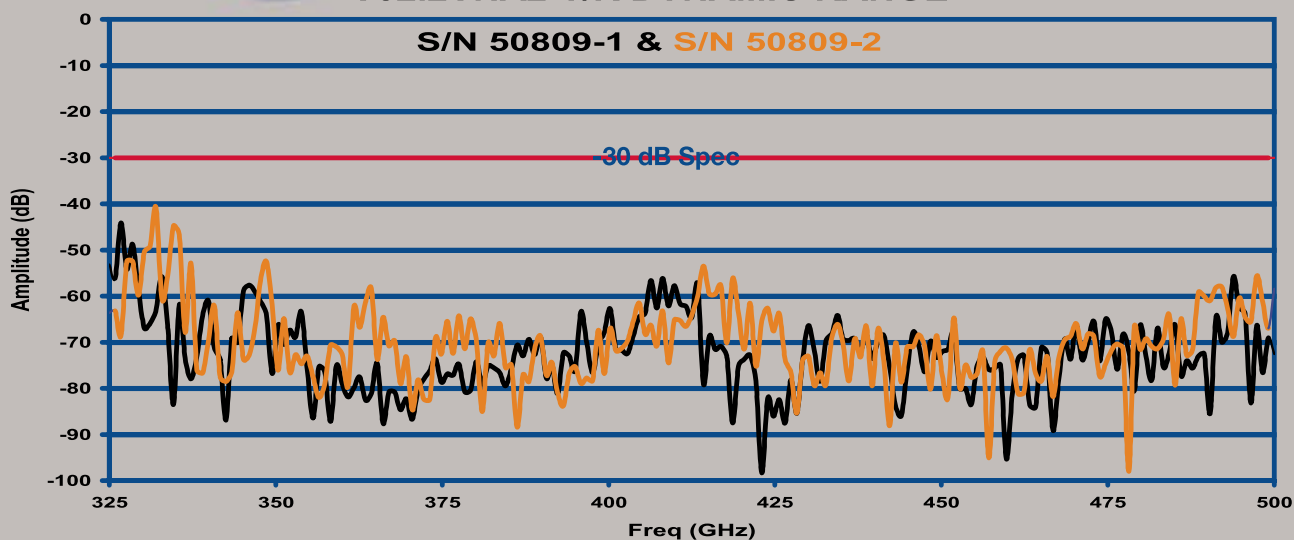
TX modules in this family incorporate all of the critical RF transmit functions between the transceiver and the antenna into a single module offering a 60 percent size reduction compared to competing discrete solutions. EDGE operation has been added with no increase in size and has pin-out compatibility with the existing GSM/GPRS product, TQM6M4002, by re-using a ground pin as the EDGE (8PSK) mode pin. The high level integration needed

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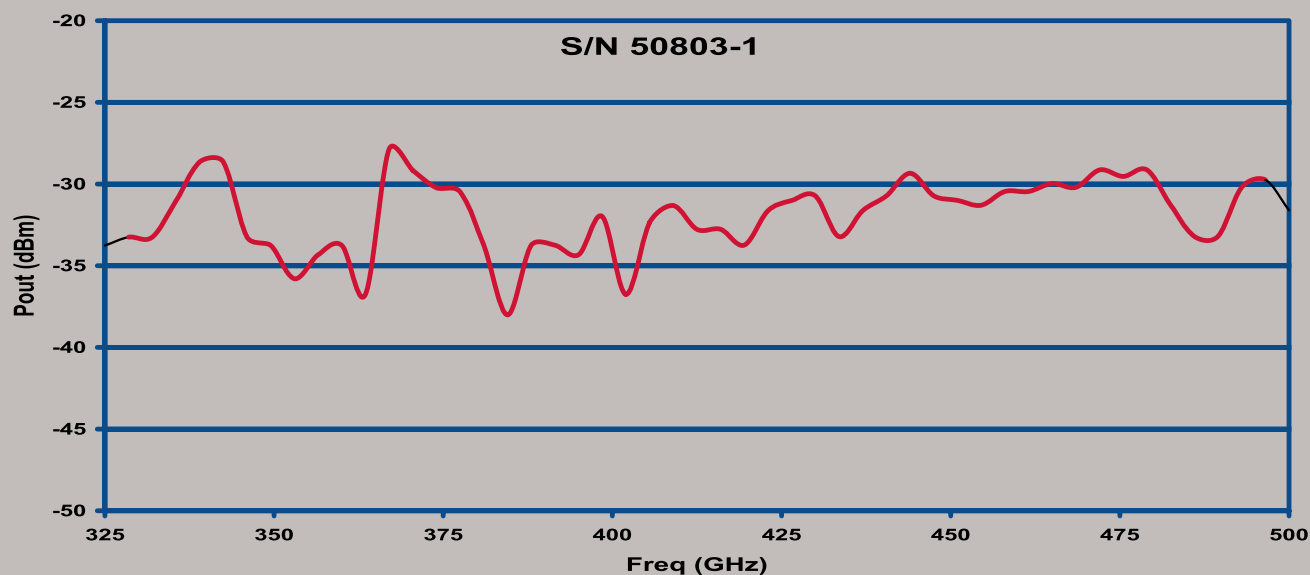


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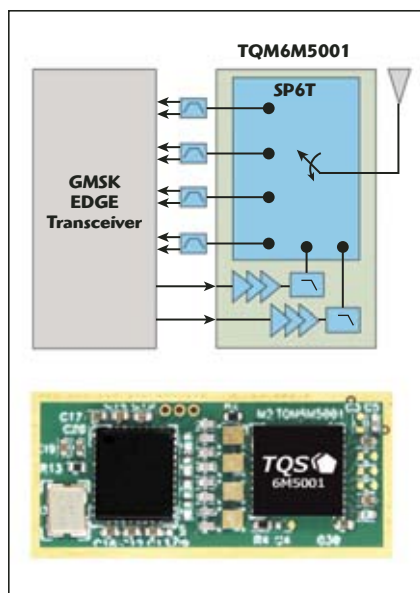


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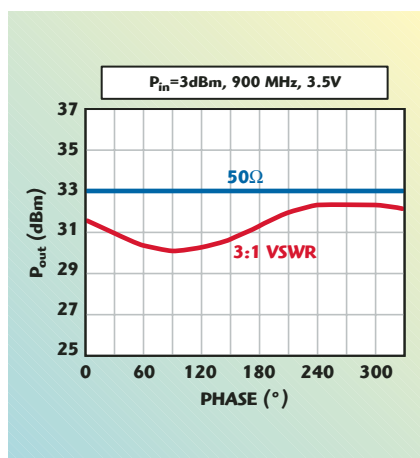
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▲ Fig. 1 The TQM6M5001-based GSM/EDGE RF reference design.



▲ Fig. 2 TQM6M5001 GMSK output power performance vs. a 3:1 VSWR at the antenna.

to develop such an advanced product—adding functionality while keeping to the previous generation's form factor—is possible by direct in-house control of key technologies including InGaP GaAs HBT and GaAs PHEMT circuits.

KEY DESIGN ADVANCES

The new TQM6M5001 EDGE-enabled TX module builds on the discrete GSM/EDGE 850/900 and DCS1800/PCS1900 PA blocks and integrated power control found in present generation power amplifier modules. It adds a low insertion loss, quad-band PHEMT transmit/receive SP6T switch with four RX-ports, harmonic and low pass filtering, integrated switch decoder, and full ESD protection—all in an unprecedented size of 36 mm². Full system level GSM/GPRS and EDGE compliance is assured when used with the latest generation of linear EDGE transceivers.

The TQM6M5001 EDGE TX module requires no external matching and eliminates the need to manage the PA-to-switch interface. This advancement in form factor and integration level was achieved in part by eliminating all surface-mount devices (SMD) inside the laminate-based module, resulting in clear size, cost and time-to-market advantages.

USER BENEFITS AND PROCESS TECHNOLOGY

The TQM6M5001 transmit module combines the functionality of a quad-band power amplifier (PA) with power control, a low pass transmit filter (LPF), a quad-band TX/RX switch including decoder and ESD protection into one module (see **Figure 1**). A fundamental advantage of this transmit module is its built-in PA-to-front-end interface. By combining PA and antenna switch functionality into one module, the system bill of materials is significantly reduced, adding simplified supply chain management to an already lengthy list of advancements that benefit the mobile phone manufacturer.

In EDGE (8PSK) mode the module serves as a linear gain block with approximately 30 dB of gain in GSM850/900 and 34 dB of gain in the DCS/PCS bands, respectively. It provides a zero-bit, multi-bit or continuous bias feature for the lowest current consumption in 8PSK mode. The TQM6M5001 was designed utilizing in-house six-inch processes: InGaP GaAs HBT for the PA function and GaAs PHEMT for the LPF and switch components. All control functions for the PA and switch are incorporated into a proprietary CMOS design. A dedicated control pin toggles between GSM and EDGE mode. All four switch RX ports are frequency independent allowing the user flexibility in handset phone-board layout.

Identical in size and pin-out to other GSM/GPRS TX module family members, the GSM/EDGE-enabled TQM6M5001 is also laminate-based and uses bondwire inter-

chip connections. All passive elements are integrated into the GaAs dies, thus eliminating the need for any SMDs inside the module. Full EDGE functionality could therefore be added to the module while maintaining a 6 × 6 × 1.1 mm³ footprint.

The TQM6M5001 transmit module architecture and interface is optimized for next generation multi-mode transceivers and baseband transceiver chip sets. By combining the TQM6M5001 GSM/EDGE TX module with TriQuint's small form factor RX SAW filters (1.4 × 1.2 mm² single filter series, or 2.0 × 1.5 mm² 2-in-1 filter series, for example) a complete RF solution is achieved with the assurance of full interface alignment and best-in-class RF performance.

DESIGN GOALS AND PERFORMANCE HIGHLIGHTS

A primary design goal met by the TQM6M5001 transmit module is full EDGE functionality and ETSI specification compliance in all four frequency bands (GSM850/900 and DCS1800/PCS1900) without compromising critical DC and RF performance in GSM/GPRS mode.

In GSM mode, the maximum output power in the GSM850/900 band is typically 33.5 dBm with a system power-added efficiency (PAE) of 42 percent. In DCS/PCS band, a maximum output power of 31.5 dBm is achieved with a system PAE of 38 percent. For maximum output power, the harmonic power is less than -36 dBm in all frequency bands. The input power level range between +1 and +5 dBm is aligned to most transceivers currently available on the market. Ruggedness of the new transmit module exceeds a VSWR of 30:1 and stability is guaranteed up to a VSWR of 20:1, with all spurious signals below -36 dBm.

Mobile handset designs are typically calibrated at an output power of 33 dBm in the GSM850/900 band and at 30.5 dBm in the DCS/PCS (high) band. Since the impedance of the antenna can deviate from the nominal 50 Ω value depending on operational environment (for example, metal plane vs. human ear), network providers are more and more focused on the total radiated output power at the antenna. For a typical mismatch

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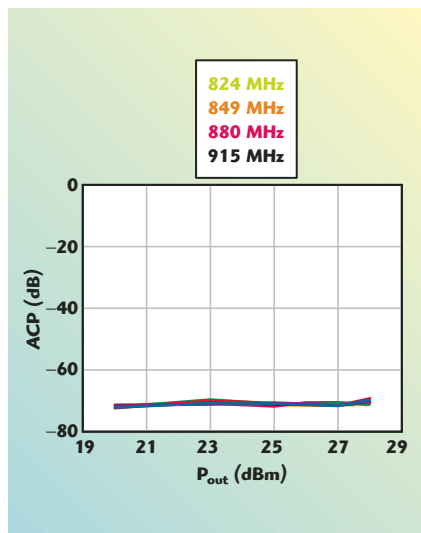


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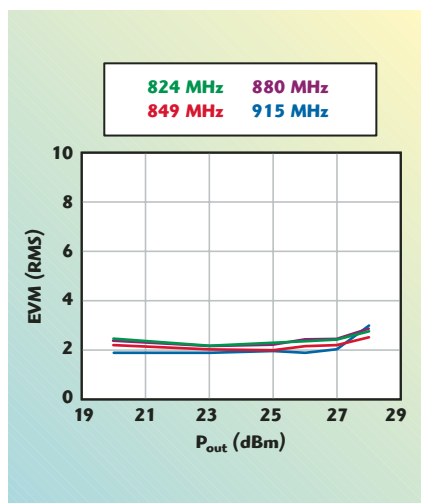
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▲ Fig. 3 Low band ACP400 performance vs. output power.

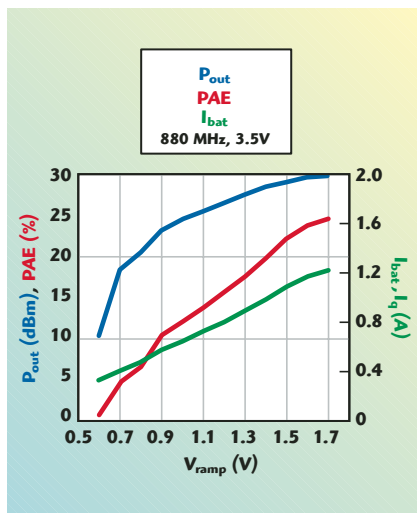


▲ Fig. 4 EVM (RMS) vs. frequency.

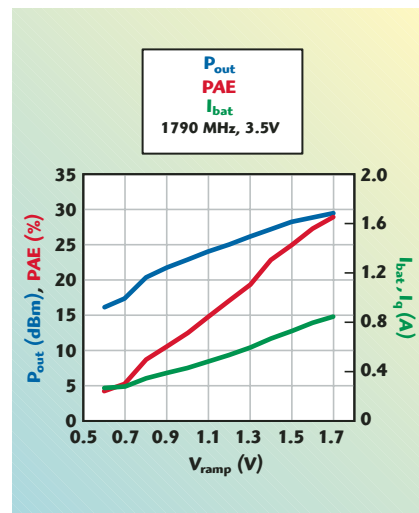
load (VSWR of 3:1), the peak-to-peak P_{out} variation of the TQM6M5001 vs. all phase angles is only 3 dB (see **Figure 2**). Therefore, the device is able to provide sufficient radiated output power even under widely varying operational conditions that the mobile phone might conceivably experience in daily use.

EDGE PERFORMANCE

The TQM6M5001 transmit module behaves like a linear gain block in 8PSK mode. This means the output power of the TX module is controlled by the level of the input power. The transceiver provides the power setting and power ramp of the TX signal. For an output power of 27 dBm at the antenna pin, the ACP400 at 400 kHz offset is typically lower than -65 dBc for nominal conditions (see **Fig-**



▲ Fig. 5 EDGE mode current consumption improvement using continuous bias at ACP400 of -58 dBc (GSM900).

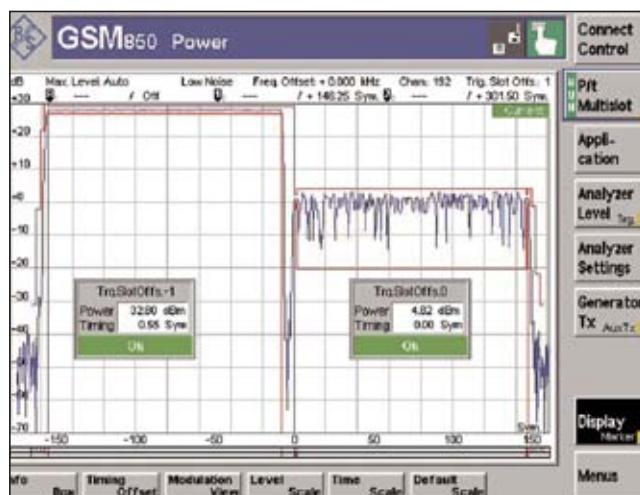


▲ Fig. 6 EDGE mode current consumption improvement using continuous bias at ACP400 of -58 dBc (DCS).

ure 3), and lower than -60 dBc for a minimum battery voltage of 3.2 V. EVM (RMS) performance is < 3 percent at the same output power level of 27 dBm showing full specification compliance with good margin (see **Figure 4**).

In EDGE (8PSK) mode the VRAMP pin is no longer used for setting the output power as was its function in GMSK mode. As previously noted the output power of the linear gain block is set by the input power as controlled by the transceiver. The V_{RAMP} pin now serves as a bias control input in EDGE mode, setting the idle current (continuous bias) depending on the output power. By varying the applied voltage between 0.6 and 1.7 V, operating current can be adjusted as a function of output power to benefit from improved PAE at low output power levels.

By utilizing this built-in feature of continuous bias in 8PSK mode, the current consumption at low output power can be improved significantly by re-adjusting the bias of the PA accordingly. The manufacturer has the option to use this feature in a multi-bit or continuous bias mode, or sim-



▲ Fig. 7 TQM6M5001 behavior of two subsequent bursts with maximum P_{out} in GMSK mode and minimum P_{out} in EDGE mode.

ply leave V_{RAMP} constant for zero-bit operation. For example, at 1790 MHz, with a V_{RAMP} voltage of 0.6 V, an output power up to 10 dBm can be achieved with an ACP400 of < -58 dBc, thus resulting in an average operating current of 0.32 A during an EDGE burst. With a control voltage of 1.7 V at the same P_{out} level the operating current would rise to approximately 0.75 A. More and more customers utilize this feature to their advantage as a current consumption benefit in next-generation handset designs.

Plots in **Figures 5** and **6** illustrate PAE and I_{bat} as a function of V_{RAMP} when optimized for an ACP400 of -58 dBc and shown at various output power settings (controlled by input power from the transceiver).

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By design, full multi-slot GSM/EDGE capability is assured with the TQM6M5001 EDGE TX module as part of an RF system solution for today's CMOS-based EDGE transceivers. **Figure 7** shows full power vs. time specification compliance by the TQM6M5001 in the extreme case of a full power GSM burst followed by the lowest power EDGE burst, as required by ETSI specifications.

SUMMARY AND OUTLOOK

High level integration continues to set the pattern for succeeding generations of mobile phone RF front-end modules. As more functionality is added to advanced phone devices and handset form factors continue to shrink or grow slimmer, manufacturers expect RF module solutions that not only meet specifications, but pay dividends such as enhanced PAE,

greater platform design facilitation and ease in generational transitioning that is inevitable as phones migrate from GSM/GPRS mode to full GPRS/EDGE, and beyond.

TriQuint has reached the next integration milestone with its $6 \times 6 \times 1.1 \text{ mm}^3$ multi-mode GSM GPRS/EDGE quad-band transmit module, the TQM6M5001, which offers mobile handset designers size and cost advantages to satisfy the high performance RF needs of next generation mobile handsets. Leveraging sophisticated in-house InGaP GaAs HBT and PHEMT GaAs processes with design expertise in power amplifiers, switches, signal filtering and CMOS design, TriQuint has successfully applied key processes and engineering skill sets to produce an RF transmit module with highly competitive performance and features.

With its EDGE functionality the TQM6M5001 is a significant step in the move toward fulfilling 3G RF radio and chipset concepts, which will further optimize the interface between transceiver and transmit modules across various modulation schemes. The successful implementation of cost-effective multi-mode phones will only be achievable if the combination of performance, cost, quality and form factor can be met in all respects. While the TQM6M5001 represents a significant contribution to the manufacture of new EDGE mobile phones, the company's design engineers are already addressing the need for W-CDMA and EDGE (WEDGE) transmit modules that leverage existing experience in GSM, EDGE, W-CDMA and WLAN/WiMAX PA and front-end modules to enable the next generation of 3G multimedia mobile handsets.

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	20 \pm 1	1.5	12	± 1.0	0.7	50
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1-4	1.30	0.8	20	± 0.7	$\pm 5^\circ$
2-18	1.50	1.40	15	± 0.4	$\pm 7^\circ$

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1-2	1.40	0.6	22	± 0.5	$\pm 8^\circ$
2-4	1.60	0.6	20	± 0.5	$\pm 10^\circ$
0.75-1.5	1.40	0.6	20	± 0.5	$\pm 8^\circ$



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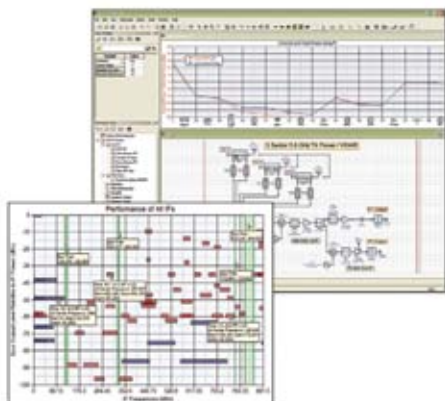
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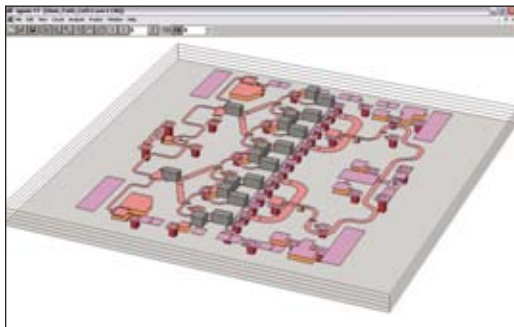
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PERFECTLY CALIBRATED PORTS FOR EM ANALYSIS

Sonnet pioneered the high frequency EM (electromagnetic) market, shipping the first commercially viable product in 1989. Since then, the company has continued regularly introducing significant capability into this market. Sonnet's new Version 11 expands upon this tradition with multiple new features that fundamentally change high frequency design methodology in many areas, but especially in the field of radio frequency integrated circuit (RFIC) design.

Each of the new Sonnet Version 11 features deserves an entire article. However, following a brief description of the new features, this piece will focus on the most significant feature, the new "Co-calibrated™ ports,"

shown in **Figure 1**. These are perfectly calibrated ports on the interior of a high frequency circuit, never before available in any EM tool. Perfect port calibration will completely change how high frequency design is accomplished, especially in the RFIC world.

Fig. 1 A 3-D planar circuit with numerous internal ports used for mounting surface-mount devices. ▼



Prominent among Version 11's new features is a fully revised interface to the Agilent Advanced Design System (ADS) framework. Designed with the support of Agilent, the interface now easily installs as a design kit. In addition, a free ADS interface to the free SonnetLite EM analysis is available. Absolutely invaluable to ADS users who use Sonnet as their primary EM tool, the interface is also seeing wide use by ADS users using Sonnet to double check EM results from other sources, and by project teams using multiple EM tools. Two menu selections literally transfer an entire EM layout into Sonnet, including all analysis and substrate information. The interface is completely bi-directional, so users can confidently go back and forth as desired. Finally, one attractive new feature is that Sonnet can create the popular ADS "layout look-alike" symbols in the ADS schematic. The user can actually see in the ADS schematic where a port is in the layout, as shown in

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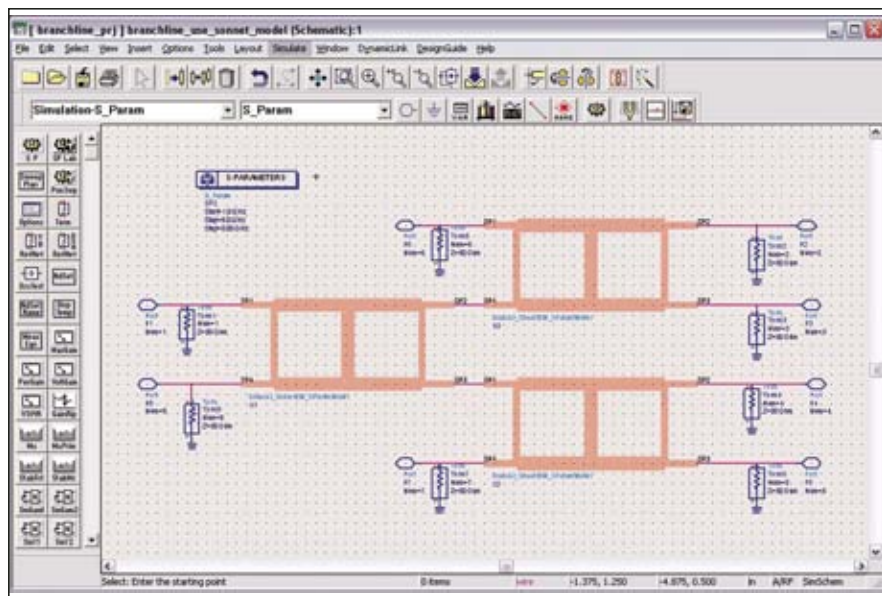
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▲ Fig. 2 Agilent ADS schematic with three "layout look-alike" schematic elements (pink) from Sonnet.

Figure 2. This is useful if there are dozens, or even hundreds of ports, a situation expected to become common with the introduction of Co-calibrated ports.

The same easy bi-directional transfer also continues to be available in the AWR Microwave Office interface and in the Cadence Virtuoso interface. New with Version 11 is an interface to AWR's X-model capability, where users can create parameterized high frequency models based directly on Sonnet data.

New to all three interfaces (Agilent, AWR and Cadence) is the ability to specify use of Sonnet's thick metal model and Sonnet's patented conformal meshing. The thick metal model uses multiple sheets to model thick metal. Simpler "tube-like" models of thickness force all current to flow on the surface of the metal regardless of frequency. That model loses validity when metal thickness is less than several skin depths. This is not a problem with the Sonnet multi-sheet model, which is valid over the complete frequency range. Sonnet's conformal meshing lowers subsection count by a factor of up to 100 for curving transmission line structures, all the while still including the high edge current necessary for high accuracy.

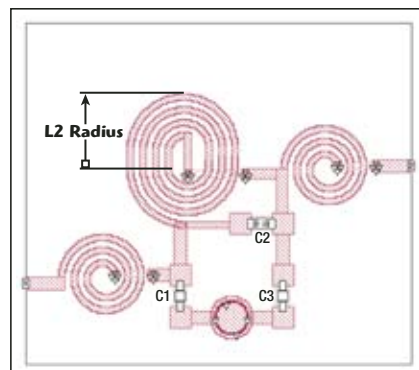
To further enhance Sonnet's interoperability, there are procedures for bi-directional transfer and specification of the new Co-calibrated ports in

all three frameworks, even though no framework is yet aware of this new concept. All three framework interfaces also now support direct use of Sonnet's remote execution and cluster computing capability. With remote execution, users set up and administer remote batch queues, easily submitting jobs to be performed anywhere on the network. With the addition of this capability to the interfaces, users may use these functions directly from the framework of their choice.

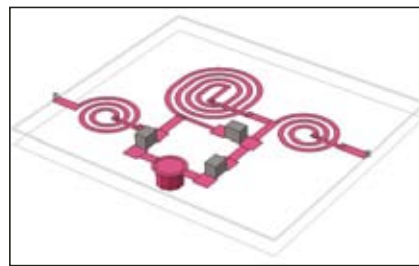
The cluster computing capability splits a multi-frequency job into multiple jobs for simultaneous execution. For example, if a job takes one hour per frequency and requires 10 frequencies, it is automatically split into 10 jobs with complete results (including interpolation capability) available in one hour. This means that what were previously overnight jobs now barely allow time for a cup of coffee and a chat with a friend.

A second cluster option is now available. Previously, cluster computing required use of third-party software. While that software is widely available in some large companies, availability is problematic elsewhere. Thus, cluster computing is now offered "for everyone else," that is, no third-party software is needed and it is easily administered.

Sonnet also now includes a 64-bit analysis engine. This means problem sizes over 2 Gbytes are now feasible.



▲ Fig. 3 Top view of an elliptic low pass filter with three pairs of Co-calibrated ports (C1, C2 and C3).



▲ Fig. 4 3-D view of the same filter.

These analysis engines are available for Windows XP64, Redhat 64 Linux and SuSE 64 Linux, and are even included in the cluster computing solution.

Any and all of these features are major events by themselves, but the really major event in Version 11 is "Co-calibrated ports." This is a completely new concept in high frequency EM analysis, so a little background is in order.

Sonnet analyzes 3-D planar circuits. Planar means that much of the circuit is on the surface of one or more stacked substrates. Vias connect between circuitry on different levels. 3-D means that all coupling between metal in all three dimensions is included.

Sonnet is a "shielded" analysis, that is, it analyzes the circuit inside a conducting, shielding box. This shielding box allows a mathematical formulation that results in an extremely low numerical noise floor, typically 140 to 180 dB down. There is another subtle, but incredibly important result of analyzing with a shielding box: The shielding sidewalls form perfect short circuit reference planes.

Thus, from the very beginning, Sonnet has always had perfectly calibrated sidewall ports. What is new in

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Version 11 is that a way has been discovered to perfectly calibrate all ports internal to the planar circuit. This allows perfectly calibrated, global ground referenced ports to be placed anywhere. All the tiny stray inductances and capacitances associated with (and between) all the internal ports in a group are now exactly removed.

This is a fundamental and brand new capability for high frequency EM design. Take, for example, a power FET amplifier, perhaps in the form of an RFIC. EM analysis cannot analyze the FET. Therefore, the FET is left out and internal ports are included in the EM analysis. Later, using a favorite framework, the nonlinear FET model is connected and a harmonic balance analysis is performed.

The problem with this old way is that the internal ports always include at least some tiny stray capacitances and inductances, electromagnetic artifacts of the way internal ports must be created and which are present in all EM analyses. These tiny port discontinuities cause large errors in certain situations, for example, at the inputs and outputs of power FETs, where they operate with impedances of only a couple ohms. Most EM analyses make no attempt at all to calibrate internal ports. Now, with Co-calibrated ports, exactly calibrated groups of internal ports are easily realized. The internal ports for the power FET are analyzed with absolutely all of the port discontinuities exactly removed.

The potential applications are limitless. For example, if the power FET is removed and perfectly calibrated ports substituted, why not take out all the resistors and capacitors in the RFIC and substitute Co-calibrated ports there, too? Now, with a single EM analysis, one may repeatedly populate the RFIC with different resistors, capacitors and transistors until an optimum design is achieved. **Figures 3 and 4** show a low pass elliptic filter designed in exactly this way.

With this design flow, design iterations are done at circuit theory analysis speed, hardly time enough for even a sip of coffee. In the old way, the designer would physically change one (or more, if you are desperate) components and then repeat the entire EM analysis. That approach can require weeks to complete a single design. In the new way, the best possible design can be determined in minutes. The old way of doing design is simply no longer viable.

The potential of perfectly calibrated internal ports is mind-boggling. Continuing with the power FET example, the power FET consists of an input manifold, gate fingers and an output manifold. Designers usually have a pretty good model for a single gate finger, but a model for the entire power FET can be elusive. Now the answer is simple. For the EM analysis, take out all the gate fingers and substitute a group of internal ports. If there are ten gate fingers, there are now 20 ports for the gate region. There is another port for the input to the gate manifold and one more port for the output manifold, for a total of 22 ports. Now simply connect 10 copies of the single gate finger model into the 20 internal ports.

Sonnet even includes the ability to automatically connect a user specified S-parameter data file or an ideal lumped component to the internal ports. There is no need to resort to a complicated schematic in the selected framework to do the connection. The S-parameter file can come from measurement, from a model in any design framework, from vendor supplied data (including models for surface-mount devices), or even from another Sonnet EM analysis. All this thanks to the box sidewalls providing perfect short circuit reference planes, critical in achieving Sonnet's perfect internal port calibration.

CONCLUSION

Sonnet's new Version 11 with 64-bit capability, an easy-to-administer cluster computing capability, significantly enhanced interfaces to Agilent, AWR and Cadence, and the new fundamentally significant Co-calibrated ports is simply going to change everything in planar microwave design.

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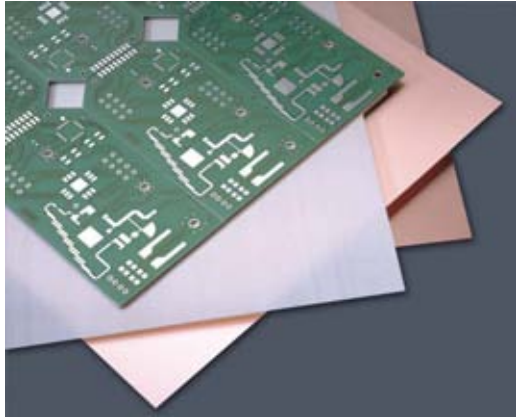
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HIGH FREQUENCY CIRCUIT MATERIAL FOR BASE STATION APPLICATIONS

A replacement product for PTFE woven glass circuit material has been introduced that provides superior mechanical and thermal properties, uses the RO4000® resin system for ease of fabrication and is a cost competitive option for base station antenna applications (see **Figure 1**).

The RO4230™ high frequency laminate extends the capabilities of the successful RO4000 product series into antenna applications. The ceramic-filled, glass-reinforced hydrocarbon-based material provides the controlled dielectric constant, low loss performance and excellent passive intermodulation response required for mobile infrastructure microstrip antenna applications.

One of the main advantages of the new RO4230 laminate is that it is fully compatible with conventional FR4 processing and does not require special treatments needed on PTFE-based laminates for plated-

through-hole preparation. Thus, it is an affordable alternative to PTFE antenna materials, allowing designers to optimize performance/price benefits.

THERMAL CHARACTERISTICS

The resin system of the RO4230 dielectric material is designed to provide thermo-mechanical properties critical to antenna design. Its coefficient of thermal expansion (CTE) in both the X and Y directions is similar to that of copper, thus minimizing the thermal effects of environmental conditions by reducing the stresses that can lead to warpage of the printed circuit board antenna. RO4230 material's glass transition temperature exceeds 280°C; this, coupled with low Z-axis CTE, provides excellent plated-through-hole reliability. In addition, its increased thermal conductivity over equivalent PTFE woven glass materials (0.44 W/m/K) allows for antenna designs with increased power handling capability.

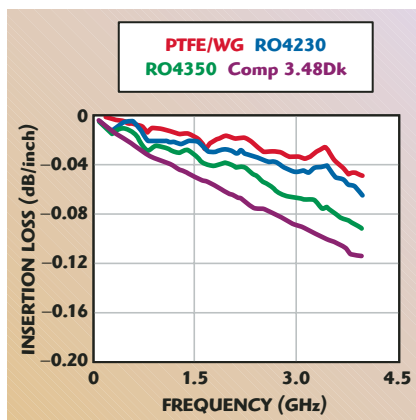
Fig. 1 A typical base station antenna and installation. ▼



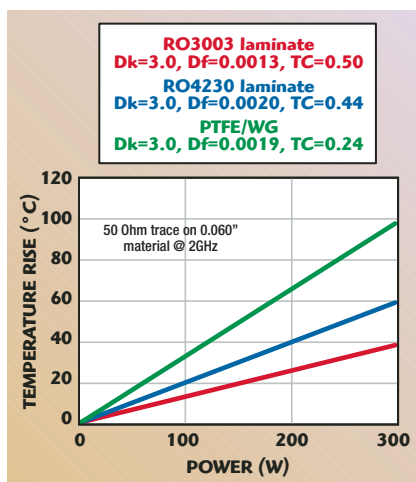
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To truly be an advantageous replacement for existing antenna circuit material requires that its electrical properties closely match the needs of antenna designers so existing antennas require minimal or no redesign. RO4230 laminate has a dielectric constant (Dk) of 2.98 ± 0.05 and a loss tangent (Df) of 0.0020 measured at 2.5 GHz and 0.0023 at 10 GHz. These values allow antenna designers to realize desired gain while minimizing signal loss in the feed network. In addition, RO4230 material has demonstrated low PIM performance, with values better than -155 and up to -162 dBc using two 43 dBm swept tones at 1900 MHz. **Figure 2** shows an insertion loss comparison with PTFE/woven glass, RO4350 laminate and a competitive thermoset material. **Figure 3** shows the effect of the RO4230 material's improved thermal conductivity.



▲ Fig. 2 A comparison of insertion loss of 0.030" RO4230 with RO4350B™ material and competitive thermoset materials.



▲ Fig. 3 The effect of thermal conductivity on power handling capability.

CONCLUSION

The market has had a need for an improved material for use in cellular base station antennas, satellite radio applications and WiMAX antennas, as well as others. RO4230 laminate was designed to provide an enhanced price/performance benefit over Dk 3.0 PTFE/woven glass materials.

RO4230 laminate is available in standard thicknesses of 0.030", 0.040" and 0.060" with 1 oz. electrodeposit-

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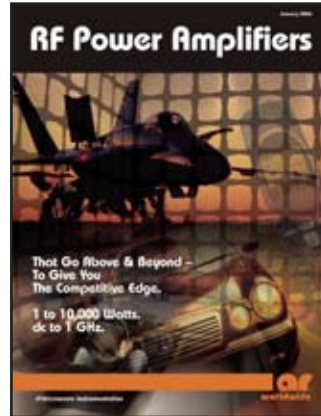


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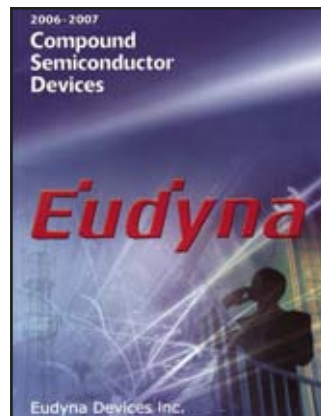


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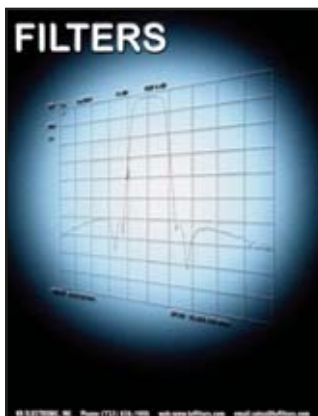


Product Selection Guide

The October 2006 product selection guide summarizes over 460 products including 40 new products. Newly redesigned are dedicated sections for connectorized modules, Designer's Kits, application circuits and a competitor cross reference table. This new selection guide contains over 71 new products released in 2006, which are not included in the 2006 Designer's Guide Catalog. In addition to the October selection guide, an updated version of Hittite's popular 2006 Designer's Guide CD-ROM is now available.

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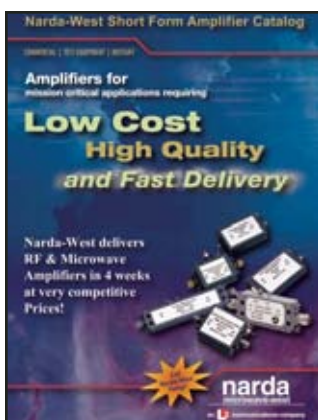


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This comprehensive Fall 2006 satellite communication and earth station equipment CD catalog features the company's up/downconverters, test translators, IF/video equalizers, redundancy switchover units, video modulators and modems. Specific products include synthesized converters with 1.0 kHz and 125 kHz step sizes, INMARSAT L- and C-band converters, pilot generators and receivers, crystal controlled converters, video exciters and custom designed products.

MITEQ Inc.,
Hauppauge, NY (631) 436-7400, www.miteq.com.

RS No. 319

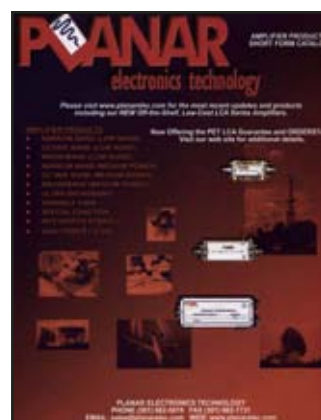


Short Form Amplifier Brochure

This brochure features the company's new amplifier product line that offers low cost, high quality and quick turnaround ("off the shelf" on some products and four weeks from time of order in most cases). These amplifiers are suitable for use in commercial, military, test equipment, prototype and laboratory applications. These new amplifiers broaden the already extensive line of amplifiers from Narda Microwave-West.

Narda Microwave-West,
Folsom, CA (916) 351-4500, www.nardamicrowave.com.

RS No. 320

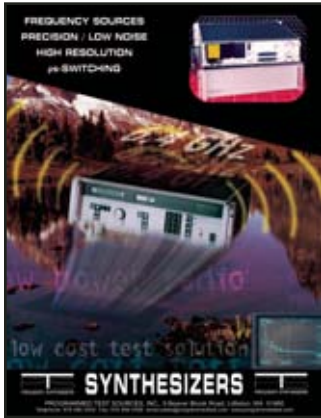


Short Form Catalog

This short form amplifier product catalog presents the company's full line of low noise and medium power amplifiers. Featured items highlight amplifier capabilities in narrow band, octave band, broadband and ultra-broadband, with low noise and medium power options. Also shown are higher power and variable gain amplifiers, as well as a section of new products.

Planar Electronics Technology,
Frederick, MD (301) 662-5019, www.planarelec.com.

RS No. 321

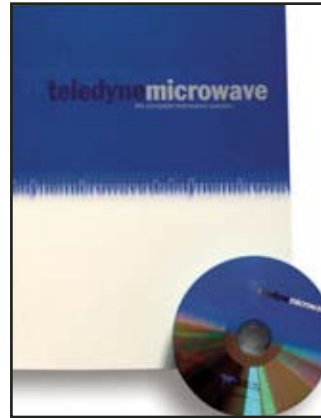


Product Catalog

This catalog describes the company's complete line of PTS frequency synthesizers. These synthesizers produce fast-switching, low phase-noise precision frequencies. With easy remote programming they are vital in advanced measurement or production systems and also serve as stand-alone test equipment. Numerous options and accessories that can be combined in a virtually limitless manner to provide a product that although not custom built, will closely match your specifications. Models range from 0.1 to 6400 MHz.

Programmed Test Sources Inc.,
Littleton, MA (978) 486-3400, www.programmedtest.com.

RS No. 322

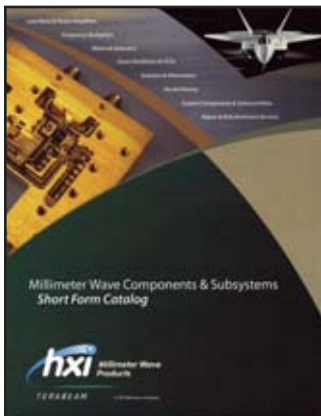


Product Catalog

This catalog features the company's product line that includes integrated microwave assemblies; transceiver subsystems; power and low noise amplifiers; BAW delay lines; isolators and circulators; filters: lumped element, combline and high power switched filters; YIG oscillators and filters; and frequency synthesizers. The catalog includes product descriptions, specifications, outline drawings, definitions, screening information, quality and reliability information, and ordering information.

Teledyne Microwave,
Mountain View, CA (650) 962-6944,
www.teledynemicrowave.com.

RS No. 323

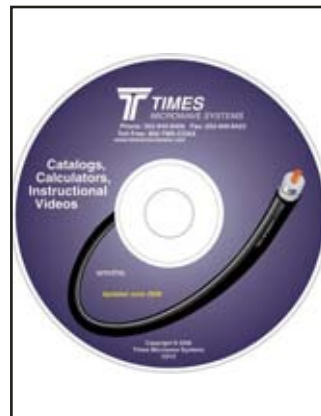


Short Form Catalog

This short form catalog highlights the company's millimeter-wave (MMW) products that include a complete line of components from 18 to 110 GHz. The millimeter-wave product availability includes low noise amplifiers, medium/high power amplifiers, mixers, detectors, Gunn oscillators and VCOs, frequency multipliers, PIN switches and attenuators, isolators and circulators, and custom sub-assemblies.

Terabeam/HXI,
Haverhill, MA (978) 521-7300, www.terabeam-hxi.com.

RS No. 324



CD-ROM Catalogs

This CD-ROM includes several new and updated brochures and catalogs including the newest edition of the LMR® Wireless Products Catalog with the latest updates to the LMR product line, HeliFoil™ ultra low loss coaxial cable and connectors, and Phase-Track™ 210 phase stable coaxial cable assemblies. This CD-ROM features an easy-to-use menu for navigation within each catalog. Also included are valuable "how-to" installation videos to assist users of LMR low loss coaxial cable products.

Times Microwave Systems,
Wallingford, CT (203) 949-8400, www.timesmicrowave.com.

RS No. 325



Product Catalog

The aerospace and defense product catalog combines the company's core product offering for space, commercial aircraft, aerospace electronics, defense electronics and in-flight networking applications. Also, the catalog provides nearly 700 pages of detailed information on products suitable for or specially designed for the aerospace and defense electronics industry. Products included in the catalog are AGASTAT timers and relays, AMP connectors and fiber optics, CII high performance, low power relays and power contactors.

Tyco Electronics Corp.,
Harrisburg, PA (800) 522-6752, www.tycoelectronics.com.

RS No. 326



Product Catalog

Weinschel Associates has a 40 year legacy as a supplier of high performance, high quality broadband passive components to the RF and microwave communities. This new full-line catalog provides a snapshot of product offerings in the company's fixed attenuator, termination, variable attenuator, DC block and coaxial adapter lines.

Weinschel Associates,
Gaithersburg, MD (301) 963-4630, www.weinschelassociates.com.

RS No. 327

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www.exposium.fr



■ 10 W Power Divider



This new line of 10 W power dividers is designed for antenna and test applications. The model 151-201-008 is an eight-way, 50 Ω power divider that operates in a frequency range from 800 to 2000 MHz. This unit offers 22 dB typical isolation, 1.5 dB maximum insertion loss, ± 0.4 dB maximum amplitude tracking, 10 W average power at the common port and SMA female connectors. Other configurations are available.

BroadWave Technologies Inc.,
Franklin, IN (317) 346-6101,
www.broadwavetech.com.

RS No. 216

■ Switch Matrix

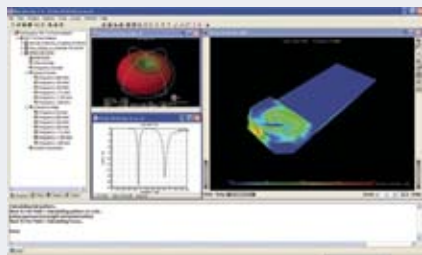


This HF/UHF switch matrix offers combined frequency bands in a single rack-mount housing. Designed for advanced signal reception applications, the model 1517 switch matrix is configured with 16 inputs and 16 outputs and can be arranged with any combination of HF (1.5 to 32 MHz) and UHF inputs (20 to 1000 MHz). It is contained in a 4U (7 inches high) rack-mount chassis and is intended for small- to medium-sized antenna interfacing installations.

Crane Aerospace & Electronics,
Electronics Group,
Redmond, WA (425) 882-3100,
www.craneae.com.

RS No. 218

■ EM Simulation



The MicroStripes 3D EM simulation solution for RF/microwave and antenna design which integrates with Applied Wave Research's Microwave Office® circuit design software has

reached version 7.5. It enables users to import any desired excitation waveform during the modeling process, run the simulation, and evaluate the results without any additional post-processing. This makes it possible, for example, to simulate the effect of a lightning strike, electromagnetic pulse or electrostatic discharge on a system using a pre-computed, analytic or measured waveform. In version 7.5, ground planes can also be used for models without meshing all of the space between the system and ground plane. Version 7.5 also reduces the computational resources required to model ferrite files.

Flomerics Ltd.,
Hampton Court, Surrey, UK
+44 (0) 20 8487 3000, www.flomerics.com.
RS No. 220

■ Portable Personal Antenna



The Freedom Antenna® is an all-in-one product with a completely redesigned look that is compatible with the top 10 selling cell phones sold in the US along with 200 other cell phone models. This antenna is a portable personal antenna with broadband capability to provide clearer reception for cellular phones and other wireless devices by extending the range and reducing dropped calls caused by hands-free and other demanding uses. Utilizing patented technology, the Freedom Antenna is compatible with all major wireless carriers and technologies and offers high performance in a slim package for both fixed and mobile hands-free use in vehicles, offices, homes and is ideal for travel. Price: \$34.95.

ARC Wireless Solutions Inc.,
Wheat Ridge, CO (303) 421-4063,
www.antennas.com.

RS No. 256

■ Two-way Power Divider

This two-way power divider operates in a frequency range from 350 to 6000 MHz. The broad frequency coverage allows multiple bands to share a common antenna or distributed antenna system. The design uses a multi-section microstrip design to achieve the bandwidth, offer adequate isolation and good input and output VSWR at a moderate price.

Microlab/FXR,
Parsippany, NJ (973) 386-9696,
www.microlab.fxr.com.

RS No. 254

■ Patch Antenna

The model MCR03-04-N is a reduced sized patch antenna that was designed for use with



GOES satellites. mWAVE Industries was contracted to design a reduced sized rugged patch antenna for use in high wind and

rough sea environments. The MCR03-04-N is only 9" across \times 2.75" in height. This new antenna operates in the GOES 402 MHz band and is right hand circular polarized (RHCP). The recorded gain was 4 dBic, recorded return loss was 14 dB and the HRPBW is 112 degrees.

mWAVE Industries LLC,
Gorham, ME (207) 857-3083,
www.mwavelle.com.

RS No. 221

■ 2.45 GHz Antenna

The RH and RAH series 2.45 GHz antennas are ideal for products requiring an ultra-compact, aesthetically pleasing antenna in a straight (RH series) or right-angle (RAH series) form factor. These quarter-wave antennas feature a



center frequency of 2.45 GHz and deliver a wide operational bandwidth and low VSWR. Despite their diminutive size, these antennas are able to resist shock and abuse. The antennas attach using a standard SMA or FCC-compliant Reverse Polarity SMA connector. Alternate connectors or custom colors are available for volume OEM customers. RH series and RAH series antennas are immediately available and priced under \$2.50 in high volume.

Antenna Factor,
Grants Pass, OR (800) 489-1634,
www.antennafactor.com.

RS No. 255

■ Ultra-wideband Radar Sensors

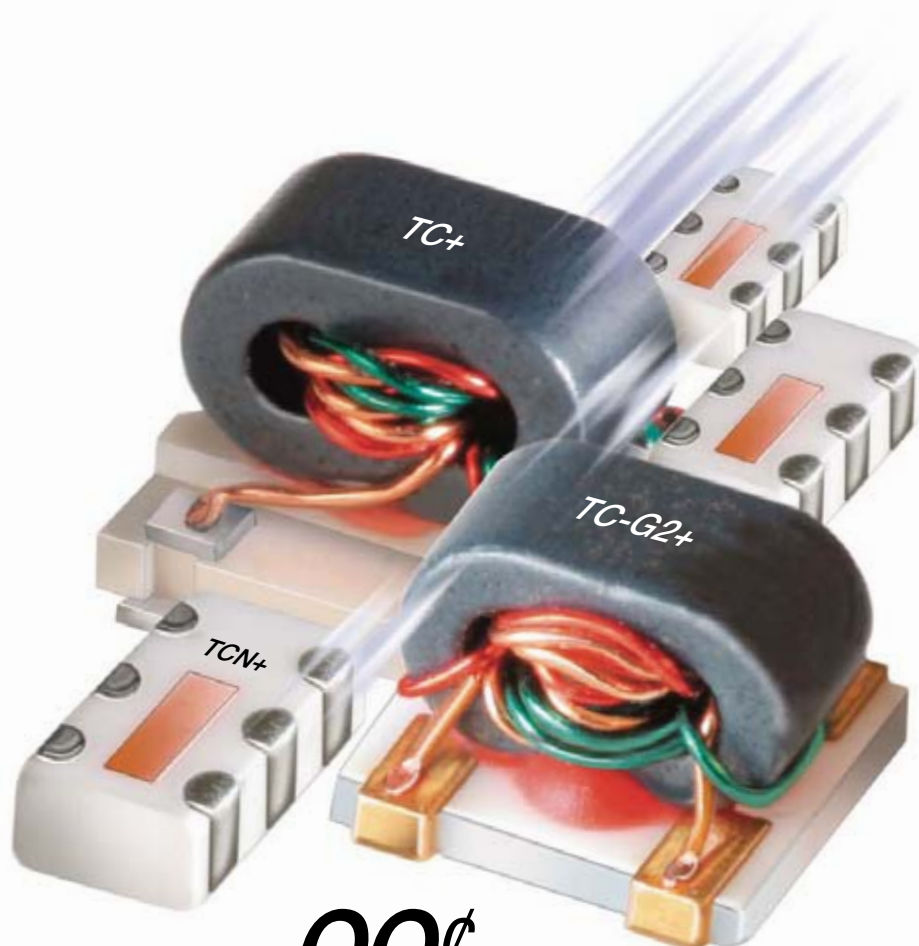
These 24 GHz ultra-wideband (UWB) radar sensors are primarily for driver-assistance systems. The 24 GHz short-range radar sensor is a highly-integrated "smart sensor" designed to improve safety and comfort functions in automotive applications by providing object detection and tracking to further support drivers. The UWB radar sensors are designed to resist inclement weather and harsh environmental conditions more than other sensing technologies, such as infrared devices. Additionally, the radar sensors can be deployed in security, military and unmanned vehicle operations, as well as mining and industrial sensing applications.



M/A-COM,
Lowell, MA (800) 366-2266,
www.macom.com.

RS No. 257

TINY RF & MICROWAVE TRANSFORMERS



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COMPONENTS

■ Flange-mount SMA Adapter

The redesigned flange-mount, SMA in-series adapter has been made shorter and offers lower VSWR. This unit operates in the DC to 18 GHz frequency range with a 1.20 m a x i m u m VSWR. These adapters are shorter, model 5311A, male/female units 0.98"



long compared with 1.13" in length for its predecessor; the model 5312A male/male is 0.95" compared to 1.00" and the model 5313A female/female is 1.01" compared with 1.25", respectively. The units are RoHS compliant and are ideal for panel-mounted applications.

Aeroflex/Inmet Inc.,
Ann Arbor, MI (734) 426-5553,
www.aeroflex-inmet.com.

RS No. 223

■ Digital Attenuator

This high speed, digitally-controlled attenuator operates in a frequency range from 2 to 19



GHz. This attenuator offers a maximum insertion loss of 4.5 dB and has a high speed driver offering switching between attenuation settings typically of less than 500 ns. The VSWR is 2.2 and the maximum operating RF input power is +20 dBm. The digital control is 8-bit true binary logic and the DC power supply on this model is ± 12 VDC (other voltages are also available).

American Microwave Corp.,
Frederick, MD (301) 662-4700,
www.americanmicrowavecorp.com.

RS No. 224

■ Coaxial Isolators and Circulators

This new range of broadband coaxial isolators and circulators operate in a frequency range from 2 to 20 GHz. These isolators and circulators offer good isolation and losses and power of 20 W in a small package with SMA and N type connectors. Applications include military and commercial products such as VSAT, video transmitter/receiver and PCS cellular. Delivery: Lead time of one week.

Electronika International Inc.,
Cleveland, OH (440) 743-7034,
www.electronikainc.com.

RS No. 225



■ I and Q Vector Modulator

The model M2V-82N-5JX is a 360°, 50 dB high dynamic range PIN diode, I and Q vector modulator that operates in a frequency range from 18 to 21.5 GHz. This device offers simultaneous phase and amplitude control. Across the entire band the phase and amplitude flatness is $\pm 10^\circ$ and ± 0.75 dB to 40 dB. The VSWR is better than 1.8. This device is capable of handling +15 dBm CW, 1 W maximum. With monotonic performance, this device is voltage-controlled via two (I and Q) inputs and switches in 350 ns. Size: $3.25" \times 3" \times 1"$.

G.T. Microwave Inc.,
Randolph, NJ (973) 361-5700,
www.gtmicrowave.com.

RS No. 226



■ Bandpass Filter

The model D-462 is a space qualified bandpass filter that operates in a frequency range from 75 to 150 MHz. Typical features include: 3 dB bandwidth of 0.05 percent, 70 dB shape factor of 5:1, operating temperature of -45° to $+80^\circ$ C



and package weight of < 25 grams. Comprehensive space environmental qualification performed in-house. Custom designs and package options are available (SMT, GPO, GPPO and SMA interfaces).

Networks International Corp.,
Overland Park, KS (913) 685-3400,
www.nicke.com.

RS No. 229

■ Directional Coupler

The model CS20-50-435/4 is a new 20 dB coupler that operates in a frequency range from 6 to 26.5 GHz with 0.9 dB insertion loss, 13 dB directivity and coupling, and flat within ± 1 dB. The VSWR is a maximum of 1.55 and the unit can handle 20 W into a 1.2 VSWR. Connectors are 2.92 mm and outline dimensions are $1.060" \times 0.625" \times 0.4"$.

Pulsar Microwave Corp.,
Clifton, NJ (973) 779-6262,
www.pulsarmicrowave.com.

RS No. 230



■ Flange-mount Drop-in Isolator

The L-series of flange-mount drop-in isolators features up to 15 percent bandwidth in the 8 to 40 GHz frequency range. These products are ideal for military and space applications with a steel housing that is gold plated for better RF performance. This temperature stable device of-



fers a typical loss of < 0.4 dB and VSWR and isolation > 20 dB. Size: $0.25" \times 0.50" \times 0.18"$.

Renaissance Electronics Corp.,
Harvard, MA
(978) 772-7774,
www.rec-usa.com.

RS No. 231

■ Phase Constant Attenuators

These PIN diode attenuators offer minimum phase variation with attenuation. The phase constant attenuators are available to cover the frequency range from 2 to 6 GHz and 6 to 18 GHz. The attenuators have an 8-bit digital control and offer an attenuation range in excess of 36 dB and a switching speed of less than 1.0 microsecond.

Rodelco Electronics,
Ronkonkoma, NY (631) 981-0900,
www.rodelcocorp.com.

RS No. 232



■ Miniature Coaxial Switch

The series CCR 33K miniature coaxial switch is designed to switch a microwave signal from a common input to either of two outputs and operates at frequencies from DC to 33.5 GHz. The latching single-pole, double-throw (SPDT) electro-

mechanical switch offers an insertion loss repeatability of ± 0.1 dB across the full bandwidth. On narrowband applications, the insertion loss repeatability can be as good as ± 0.05 dB with ultra low passive intermodulation. The characteristic impedance is 50 Ω and switch life is characterized at 5 million cycles. The switches are small with connector spacing compatible with K connectors.

Teledyne Relays,
Hawthorne, CA
(323) 777-0077,
www.teledynereleys.com.

RS No. 233

■ Public Safety and SMR Filter

The model CFB6-815 filter features a pass-band of 806 to 824 MHz and is ideally suited for in-building bi-directional amplifier applications that require a compact mechanical package. Isolation is specified at 90 dB at $F_c \pm 36$ MHz and the insertion loss is 1 dB. The design provides high "Q"

and stable temperature performance and provides an excellent building block for compact duplexers and multiplexers. Size: $1.90" \times 3.063" \times 6.094"$.

Trilithic Inc.,
Indianapolis, IN
(317) 895-3600,
www.trilithic.com.

RS No. 234



■ 3 dB Quadrature Combiner/Divider

The company's newly patented 3 dB quad coupler technology provides low insertion loss and exceptional amplitude balance. This bonded structure removes any air gaps within the circuit, ensuring consistent unit-to-unit performance. The model QH7622 is a 500 to 3000 MHz, 40+ W CW unit with insertion loss of 0.5 dB maximum, VSWR of 1.30 maximum, isolation of 15 dB minimum, phase balance of $90^\circ \pm 5^\circ$ and amplitude balance of ± 0.5 dB maximum. Size: $1.65" \times 1.10" \times 0.084"$.

Werlatone Inc.,
Brewster, NY (845) 279-6187,
www.werlatone.com.

RS No. 235

AMPLIFIERS

■ Ultra-wideband Low Noise Amplifier

The APT4-00502000-2410-D4 is a SMA connectorized low noise amplifier (LNA) that operates in a frequency range from 0.5 to 20 GHz. This amplifier offers an ultra low noise figure of 2.4 dB maximum (2.1 typical), a minimum output power of +10 dBm (+20 dBm IP3), a minimum gain of 23 dB, with a gain flatness across the entire band of ± 1.75 dB. Important for system integration is its VSWR, which is typically 2.0 for both the input and output. The amplifier comes with a three-year warranty and can be modified to cover down to 0.1 GHz with minor specification changes. Size: $1.4" \times 0.7" \times 0.29"$.

AmpliTech Inc.,
Hauppauge, NY (631) 435-0603,
www.amplitechinc.com.

RS No. 237

■ Solid-state Power Amplifier

The model BME27258-50 is a solid-state class AB linear amplifier that operates over the full frequency range from 20 to 2500 MHz in a single module. The typical P1dB is 40 W, with a saturated output power of 50 W. It has been designed for use in rugged military environments, and is capable of being produced at high rates of volume. The gain of this amplifier is 64 dB, ± 4 dB. The input VSWR is 2:1 (maximum). The harmonic rejection is -15 dBc, and its spurious signal is -60 dBc. Size: $6.4" \times 6.7" \times 1.4"$. Weight: five pounds.

Comtech PST,
Melville, NY (631) 777-8900,
www.comtechpst.com.

RS No. 217

■ Connectorized Wideband Power Amplifiers



The model HMC-C037 is a GaAs PHEMT MMIC, 0.5 W wideband power amplifier that operates in a frequency range from 10 MHz to 15 GHz and features an integrated heat sink and EMI filtered DC terminals. The integrated heat sink allows for ease-of-use in a lab environment, since no heat sink has to be designed and specified. The HMC-C037 typically delivers flat 12 dB gain up to 12 GHz, making this device ideal for broadband instrumentation, lab and test equipment applications, as the need for band switching is eliminated. The HMC-C037 also provides up to +37 dBm output IP3 and up to +28 dBm of output power at 1 dB compression.

Hittite Microwave Corp.,
Chelmsford, MA (978) 250-3343,
www.hittite.com.

RS No. 238

■ Surface-mount Monolithic Amplifier

The Gali-74 (RoHS compliant) is a wideband amplifier that offers high dynamic range and operates from DC to 1 GHz. Lead finish is SnAgNi. This amplifier offers repeatable performance from lot to lot and is enclosed in a SOT-89 package. It uses patented Transient Protected Darlington configuration and is fabricated using InGaP HBT technology. Expected MTBF is 500 years at 85°C case temperature. Gali-74+ is designed to be rugged for ESD and supply switch-on transients. Price: \$2.35 each (25).

Mini-Circuits,
Brooklyn, NY (718) 934-4500,
www.minicircuits.com.

RS No. 239

■ Successive Detection Log Video Amplifier



The model SDLVA-61F-80-582987-004 Option TBK, MS is a matched set of successive detection log video amplifiers (SDLVA) in a compact stacked configuration. This unit operates over 61.25 MHz ± 250 kHz and has been designed so that both modules share a common power terminal.

Planar Monolithics Industries,
Frederick, MD (301) 631-1579,
www.planarmonolithics.com.

RS No. 240

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E-mail: Cernex@cernex.com

■ Ultra-linear Amplifier

The model SM2025-42LS is an ultra-linear GaAs FET amplifier designed for digital video broadcast applications. The unit operates from 2 to 2.5 GHz with a P1dB of +42 dBm and OIP3 of +61 dBm, allowing for +35 dBm (min.) of COFDM power output at < -40 dBc ACP. Small-signal gain is 52 dB with a flatness of ± 0.5 dB across the band. Standard features include a single +12 VDC supply and thermal protection with auto reset. Size: 6" \times 2.5" \times 0.56".

Stealth Microwave Inc.,
Trenton, NJ (609) 538-8586,
www.stealthmicrowave.com.

RS No. 241

INTEGRATED CIRCUIT

■ GaAs Integrated Circuits

The first three members of this multi-function circuit (MFC) family of high performance GaAs ICs for point-to-point radio and satellite communications are the TG4402, TGC4403 and TGC4405. They address OEM needs for

frequency upconversion in the transmit and local oscillator chains. The TGC4405 provides a high level of integration for designs that specify RF upconversion, a local oscillator frequency doubler and output RF signal amplification in a small, single product. The TGC4402 was created for designs that require upconversion without an integral LO doubler or output amplifier, while the TGC4403 is a millimeter-wave frequency doubler that includes an output buffer amplifier. Both the TGC4405 and TGC4402 employ single-ended designs and therefore do not require external baluns.

TriQuint Semiconductor Inc.,
Hillsboro, OR (503) 615-8900,
www.triquint.com.

RS No. 222

SOURCES

■ Frequency Synthesizer



The WaveCor Dual frequency synthesizer is the latest addition to the WaveCor line of high performance DDS-based frequency synthesizers and features two independent microwave synthesizers in a single rack-mount enclosure. Each high performance synthesizer operates in a frequency range from 300 MHz to 18 GHz. At 9 GHz, the WaveCor Dual provides phase noise levels of -125 dBc/Hz at a 10 kHz offset and typical spurious levels of -65 dBc. Switching speeds are less than 300 ns maximum when tuning to any operating frequency. The WaveCor Dual's high reliability and performance are available in a 5U rack-mount chassis.

ITT Microwave Systems,
Lowell, MA (978) 441-0200,
www.ittmicrowave.com.

RS No. 244

■ High Performance VCOs

These ultra-wideband voltage-controlled oscillators (VCO) operate in a frequency range from 2 to 20 GHz. The VCOs feature an improved integrated voltage regulator, making them even more resistant to external power variations. By using the latest MMIC technology it has been possible to design a much smaller unit and also enhance uniform performance. The VCOs are available in two versions, drop-in (the VO3280 series) or in a SMA connector package (the VO4280 series). Other features include high power output directly from the oscillator, ultra broad bandwidth, with good phase noise density, high stability against load 'pulling' due to high isolation and a built-in low pass filter to reject harmonics. The range can be utilized in instruments and sen-



sors and is suitable for all types of high performance microwave applications.

sors and is suitable for all types of high performance microwave applications.

Sivers Ima,
Kista, Sweden +46 8 7036804,
www.siversima.com.

RS No. 245

■ Oven-controlled Crystal Oscillator

The C4550 oven-controlled crystal oscillator (OCXO) is a low cost, 25 by 25 mm package with a low profile packaged TO-8 crystal for better aging, g-sensitivity and temperature test performance. It has an available frequency range of 5 to 100 MHz



and temperature stabilities down to 5 ppb from -40° to 85°C. The proven performance of the TO-8 crystal achieves typical aging rates of 30 ppb/year and g-sensitivities less than 1 ppb/g. Applications include the wireless infrastructure, military and test equipment sectors.

Vectron International,
Hudson, NH (603) 598-0070,
www.vectron.com.

RS No. 246

■ L-band Voltage-controlled Oscillator

The model V582ME20-LF is an L-band voltage-controlled oscillator (VCO) that operates in a frequency range from 1115 to 1285 MHz. This VCO is designed for applications that include base stations, portable radios and mobile communications. The V582ME20-LF offers a low phase noise performance of -107 dBc/Hz at 10 kHz offset away from carrier. It provides an average tuning sensitivity of 55 MHz/V and covers the entire band from 0.5 to 4.5 V. The typical harmonic suppression is -17 dBc. This product is lead free and RoHS compliant. Size: 0.50" \times 0.50" \times 0.22". Price: \$18.95/VCO. Delivery: stock to four weeks.

Z-Communications Inc.,
San Diego, CA (858) 621-2700,
www.zcomm.com.

RS No. 247

SUBSYSTEM

■ 44 GHz Multiplier

This 44 GHz frequency multiplier subsystem is designed for Milstar SATCOM uplink applications. The design is a frequency quadrupler ($\times 4$) that includes various buffer, driver and output power amplifier functionality into one integrated module. The multiplier module receives an X-band input signal and multiplies the frequency up to



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fully cover the unclassified K-band Milstar up-link operating bandwidth. Typical performance specifications for the three output power options are: input F_{in} = X-band, 11 GHz center frequency, P_{in} = +14.25 to +18.25 dBm and input VSWR = 2.0.

Endwave Defense Systems,
Sunnyvale, CA (408) 522-3180,
www.endwave.com.

RS No. 219

TEST EQUIPMENT

■ USB Power Meters

The models 52012 and 52018 are the first two members of the new USB Power Meters series. Extending its product portfolio with the 52000 series family, the company is now providing reliable entry-level USB controlled CW power meters.



The new meters offer a frequency range from 10 MHz to 12.4/18.5 GHz and allow accurate power measurements between -50 dBm to +20 dBm. Its VSWR is better than 1:1.25 at 50 Ω impedance.

Boonton Electronics,
Parsippany, NJ (973) 386-9696,
www.boonton.com.

RS No. 248

■ Coaxial Noise Source

The model NW6G-26-CS is a coaxial noise source that sports a high 26 dB excess noise ratio (ENR). The NW6G-26-CS is ideal for noise figure measurements and built-in test applications. The unit features flatness



better than ± 1.75 dB, typically ± 1 dB over the frequency range from 10 MHz to 6 GHz and comes with calibrated cardinal ENR frequencies. VSWR is excellent for a high output ENR source, at better than 1.35. Size: 0.75" \times 0.5" \times 1.25" excluding connectors.

NoiseWave Corp.,
East Hanover, NJ (973) 386-1119,
www.noisewave.com.

RS No. 250

■ Base Station Interface Tester



This base station interface tester can be used to emulate OBSAI RP3, RP3-01 and RP1 (timing) interfaces enabling the development and verification of individual RF or baseband mod-

ules without the presence of other base station parts. The tester supports simultaneous testing of up to four active RP3 or RP3-01 links at line rates 768, 1536 and 3072 Mbps defined by OBSAI. It can operate both in master and slave modes for RP1 synchronization and timing and interface analyzer features include BER measurements, analysis of RP1 timing and testing of synchronization capability. Received interface data can be captured according to user defined triggering rules and viewed as waveforms in a logic analyzer window with color-coding for erroneous data.

Elektrobit,
Oulu, Finland +358 40 344 2000,
www.elektrobit.com.

RS No. 249

■ Microwave Counters



The CNT-90XL family of 27 to 60 GHz microwave counters offers high resolution and measurement speed, with the measurement speed for power and frequency up to 250,000 frequency samples/s. The graphical display shows frequency changes over time directly on-screen, for analysis of e.g. FM or AM, power or frequency switching, VCO settling and post-tuning drift. Built-in statistical processing presents numerical stability data and also frequency distribution histograms on-screen for analysis of frequency or power stability or modulation.

Pendulum Instruments AB,
Bromma, Sweden +46 8 598 51057,
www.pendulum-instruments.com.

RS No. 251

■ Baseband Analyzer



The FMU36 baseband analyzer is aimed at chipset development for mobile phones and base stations. With a frequency range up to 36 MHz it performs the measurement ahead of the RF signal and measures the I/Q signals in the baseband. For low frequency applications such as radio transmission via RFID or measurements on ADSL modems, the instrument features high sensitivity even at very low frequencies. The baseband analyzer combines all functions in one instrument and runs without an external PC, and for use in measurement systems it can be remote-controlled via GPIB or LAN.

Rohde & Schwarz GmbH & Co. KG,
Munich, Germany +49 89 4129-13779,
www.rohde-schwarz.com.

RS No. 253



Radio Waves, a growing manufacturer of high-quality antennas for the commercial microwave market, has an opportunity for a microwave antenna design engineer. Applicants should have two to ten years experience with a wide range of passive microwave devices and antennas, including waveguide components, microstrip transmission lines, patch antenna arrays, and reflector antennas. Experience with modern electromagnetic modeling software is highly desirable. MSEE or BSEE plus equivalent experience is a plus.

- Experience designing microwave antennas (2–80 GHz)
- Experience designing PCS base station sector antennas is a plus

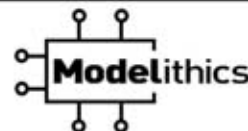
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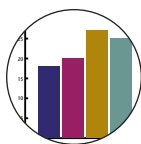
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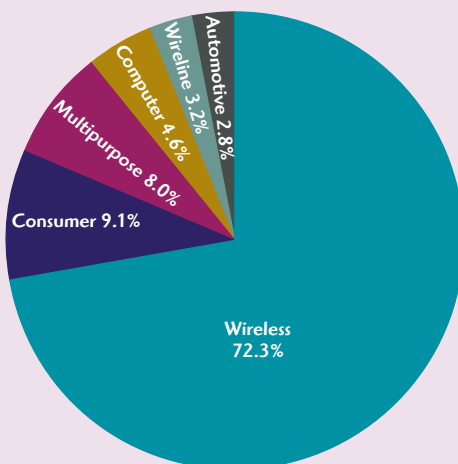
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2006 DSP THIRD QUARTER RESULTS

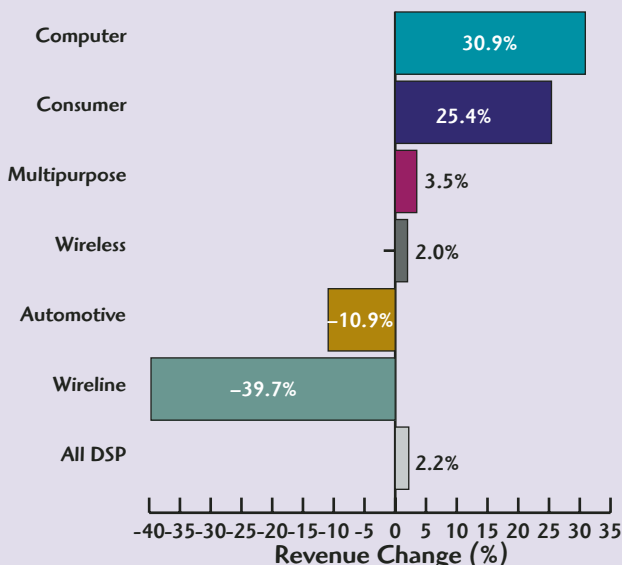
Although September DSP chip shipments were up a phenomenal 32.5% over the previous month (on a three-month rolling average basis), that was not enough to lift shipments for the third quarter beyond 2.2% (to the \$2.2 B level). Of course, that is on a revenue basis. On a unit basis, quarterly shipments were up a more respectable 6.7%, but that means that ASPs were off by 4.3%, largely due to a severe (10%) drop in quarterly prices for DSPs in cellphones. Forward Concepts attributes most of that drop to a greater mix of low end cellphones for the third-world market, not a decrease in silicon area value. Computer and consumer segments had dramatic gains over Q2, while wireline (telecom) shipments were down almost 40%, as illustrated in the chart. In light of the lackluster Q3 growth and lower cellular forecasts for the fourth quarter by Nokia, Motorola and Texas Instruments, and problems at Infineon/BenQ, Forward Concepts believes that the touted projections (by others) of billion-unit cellphone shipments will not happen in 2006. Consequently, Forward Concepts is lowering its 2006 DSP chip revenue forecast from 15% to 10% (to the \$8.4 B level).

DSP Shipments

Q3/2006: \$2.2 B



DSP Quarterly Shipment Change Q3 2006/Q2 2006



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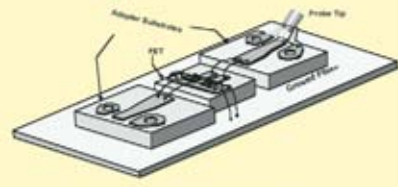
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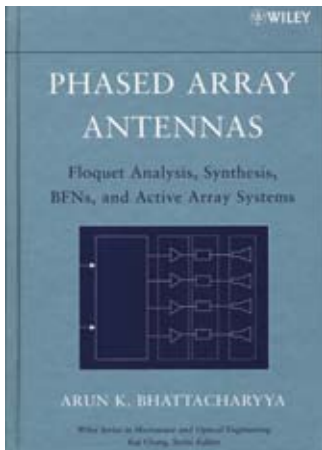
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Phased Array Antennas: Floquet Analysis, Synthesis, BFNs and Active Systems

A.K. Bhattacharyya
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The purpose of this book is to present in a comprehensive manner the analysis and design of phased array antennas and systems. The book includes recent analytical developments in the phased array arena published in journals and conference proceedings. Efforts have been made to develop the concepts in a logical manner starting from fundamental principles. Detailed derivations of theorems and concepts are provided to make the book as self-contained as possible. Several design examples and design guidelines are included. It should be useful for antenna engineers and researchers, especially those involved in the detailed design of phased arrays. It can be used either as a text in an advanced graduate-level course or as a reference book for array professionals. The reader is assumed to have a basic knowledge of engineering mathematics and antenna engineering at a graduate level. The book contains 14 chap-

ters that may be broadly divided into three sections. The first section, which includes Chapters 1 to 6, is mostly devoted to the development of the Floquet modal-based approach to phased array antennas, starting with an introductory chapter. The second section, which includes Chapters 7 to 10, presents applications of the approach to important array structures. The third section, which includes Chapters 11 to 14, is not directly related to the Floquet modal analysis as such; however, it covers several important aspects of phased array design. This section includes beam array synthesis, array beam forming networks, active phased array systems and statistical analysis of phased arrays, with respect to the amplitude and phase uncertainties of the amplifiers and phase shifters. Several practice problems are included at the end of each chapter to provide the reader with an interactive experience.

Practical MMIC Design

Steve Marsh
Artech House • 373 pages; \$119, £72
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The aim of this book is to introduce the engineer to the basic technology of MMICs. Chapter 1 offers an introduction to MMICs and a history of their development. The first choice that must be made when designing a MMIC is the component technology that will be used and this choice will then lead to a decision as to which foundry process is required. This is the subject of Chapter 2. Because of the strong link between component technology and foundry suppliers, Chapter 3 describes the type of procedures the designer may go through when designing a MMIC with an external foundry. He must be able to take ideas for the circuit topology and accurately predict the performance of the circuit when implemented in MMIC form. Chapter 4 reviews the concept of S-parameter representation of components, discusses how a foundry typically goes about characterizing the indi-

vidual components and describes the commonly used equivalent topologies for both active and passive components. Chapter 5 begins with the basic principles of impedance matching and shows how impedances may be plotted and transformed using the Smith chart and goes on to discuss the design of passive elements. Sections are then devoted to different functional types of chips that can be designed, including amplifiers, oscillators, mixers and digital circuits. Chapter 6 describes the format of layout data files and the type of CAD tools that create them. It continues by outlining the circuit array procedure and concludes with comments about mask manufacturing. Chapter 7 gives a brief overview of the typical processing steps involved in the fabrication of MMICs, while Chapter 8 is concerned with the test and measurements that are performed on whole wafers.



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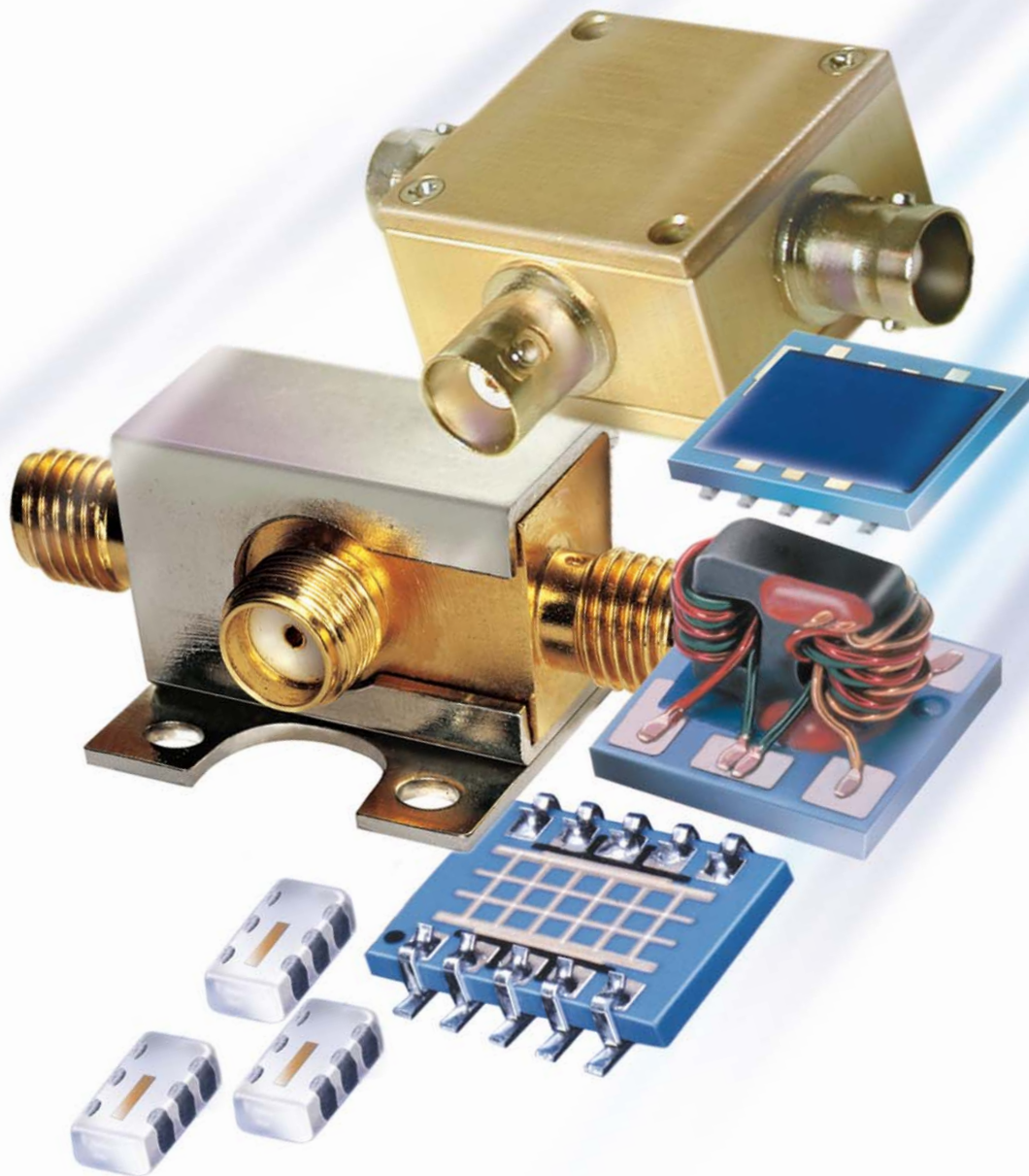
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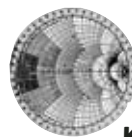
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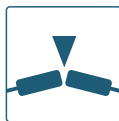
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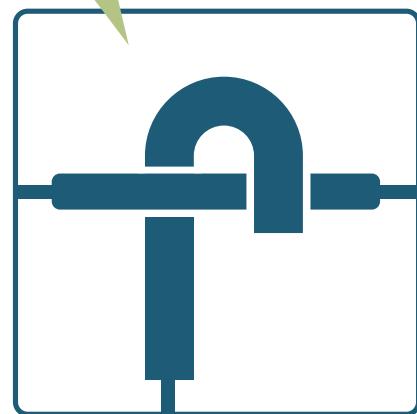
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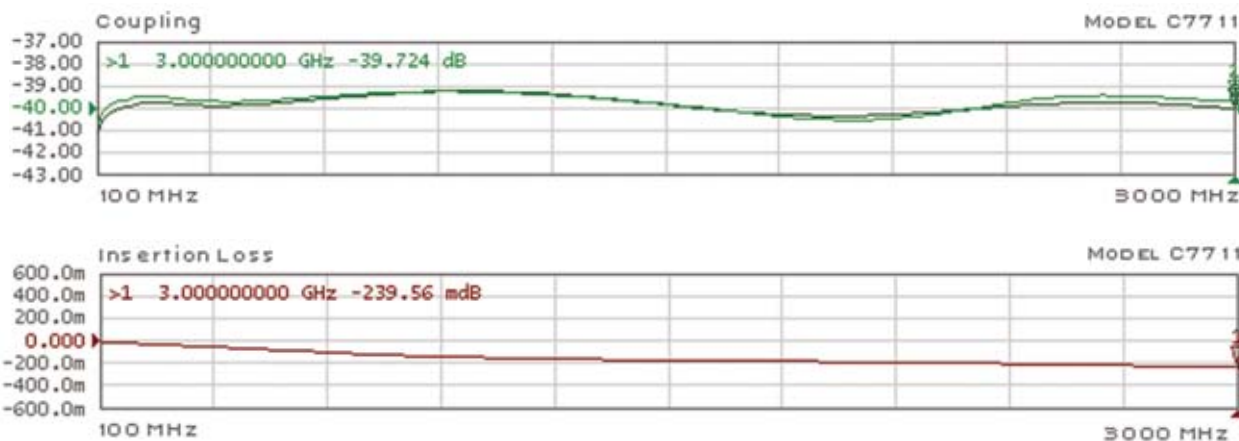


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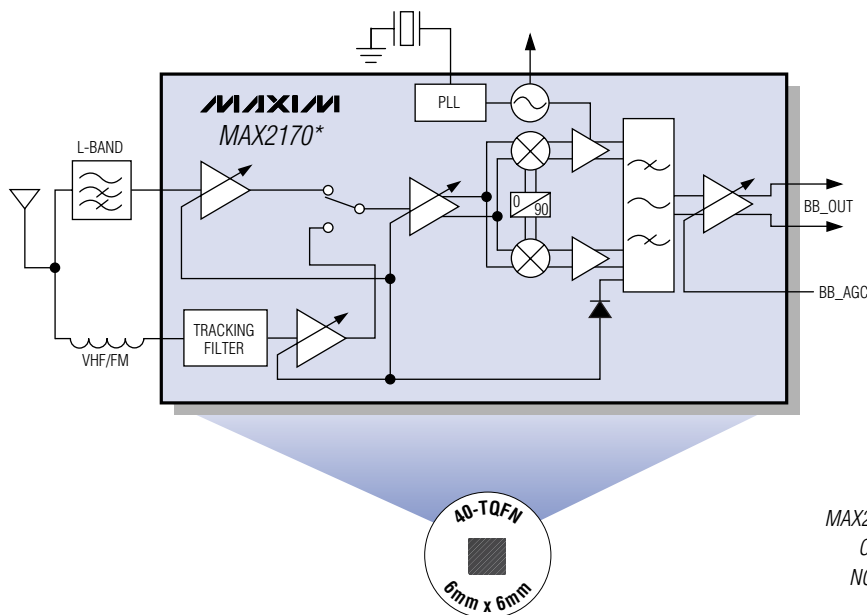
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C7734	Dual Directional	30-2500	100	43	±1.5	0.35	1.25:1	18	3.5 x 2.6 x 0.7
C7148	Bi Directional	60-600	200	10	±1.0	0.35	1.20:1	20	6.0 x 4.0 x 0.75
C7711	Dual Directional	100-3000	100	40	±1.0	0.35	1.25:1	18	3.0 x 2.2 x 0.7
C7783	Bi Directional	200-1000	200	20	±0.75	0.2	1.20:1	20	3.0 x 1.5 x 0.53
C6600	Bi Directional	200-2000	200	20	±1.2	0.25	1.25:1	18	4.0 x 2.0 x 0.72
C7152	Bi Directional	300-3000	100	20	±1.0	0.35	1.20:1	15	3.7 x 2.0 x 0.75
C7811	Dual Directional	500-2500	100	40	±0.5	0.2	1.25:1	20	3.0 x 2.0 x 0.6
C7753	Bi Directional	700-4200	100	20	±1.0	0.35	1.25:1	18	1.8 x 1.0 x 0.6

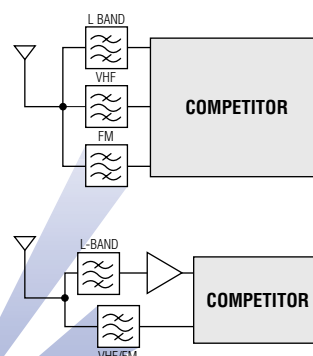
Visit <http://mwj.hotims.com/11712-152> or use RS# 152 at www.mwjjournal.com/info

FUTURE
PRODUCT

Digital Audio Broadcast (DAB) Tuner Integrates FM Path and Internal Tracking Filter



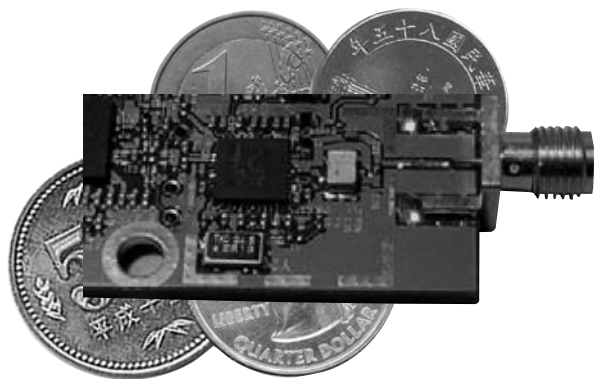
Maxim
vs.
Competition



MAX2170* ELIMINATES ONE OR TWO
COSTLY EXTERNAL FILTERS;
NO EXTERNAL RF LNA NEEDED

- Tiny Solution Footprint
- First Adjacent Channel Handling of +40dBc in VHF Band
- Integrated VHF/FM Tracking Filter
- -100dBm VHF Band-III Sensitivity
- -100dBm L-Band Sensitivity
- Industry-Standard 2.048MHz Low IF
- DMB-T Compliant

REFERENCE DESIGNS AVAILABLE



In This Issue

Custom RF ICs
Mobile TV Tuners
Digital Radio Receivers
Automotive TV Solutions
Cell-Phone RF Modems
RF Front-Ends for GPS
Wireless Audio Distribution
Base-Station RF Blocks

*Future product—contact factory for availability.

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Maxim's Custom High-Perform

Fully Tested and Packaged

RF ASICs Are Designed to Your Specifications

Large Selection of High-Frequency Technologies

- Complementary Bipolar (F_t to 17.2GHz)
- Bipolar (Trench Isolated, F_t to 27GHz)
- BiCMOS (Trench Isolated, F_t to 25GHz)
- SiGe (Trench Isolated, Three Processes, F_t to 125GHz)
- SiGe BiCMOS (Trench Isolated, Two Processes, F_t to 95GHz)
- RFCMOS (0.18 μ m and Nanometer Geometries)



RF ASIC Designs Begin with Our Extensive Product Market Library

Maxim Products

- MIMO Wi-Fi, WiMAX Transceivers
- Wideband I/Q Modulators with Synthesizer
- High-Speed Data Converters
- GPS Receivers
- Ultrasound Receivers

End Markets

- Wireless Consumer
- Cable and TV Tuners
- Test and Measurement
- Military
- Medical

For More Information on Custom Wireless Designs, Go to:

www.maxim-ic.com/Wireless or Contact Us at: Wireless@maximhq.com

Performance RF/Analog ASICs

Devices from a Single Supplier

Design and Development Support

QuickChip Prototyping

Maxim provides rapid-response ASIC service. Semicustom device arrays, known as “QuickChips,” offer designers a selection of uncommitted semiconductor devices to interconnect as needed.

Multiproject Wafer Designs

Maxim offers multiproject wafer (MPW) runs on our IC processes. These are run on a regular basis and offer lower cost prototyping options.

Production and Packaging

Maxim is a full-service ASIC supplier offering the latest in packaging technologies. RF models are available for all our available packages. QFN and UCSP™ are two of the many excellent packages used in RF applications.

A full range of leading-edge products can be modified and customized to your requirements.

***Wi-Fi
Mobile TV
ADC and DAC***

***WiMAX
Digital Radio
Media Solutions***

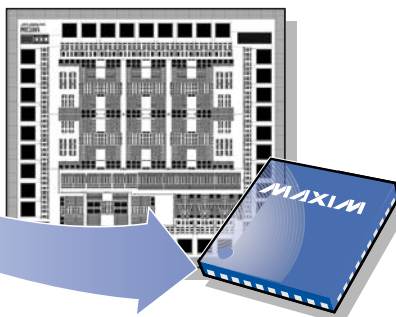
***GPS
Cellular Receiver
Fiber***

Any of the leading products in this design guide can be customized for you. Maxim can design a customized solution, or you can design your own solution. In either instance, Maxim will fabricate the solution for you.

**YOUR CUSTOM
NEED**



**Maxim's UNIQUE
SOLUTION**



For More Information on Custom ASIC Designs, Go to:
www.maxim-ic.com/ASICs or Contact Us at: Wireless@maximhq.com

UCSP is a trademark of Maxim Integrated Products, Inc.

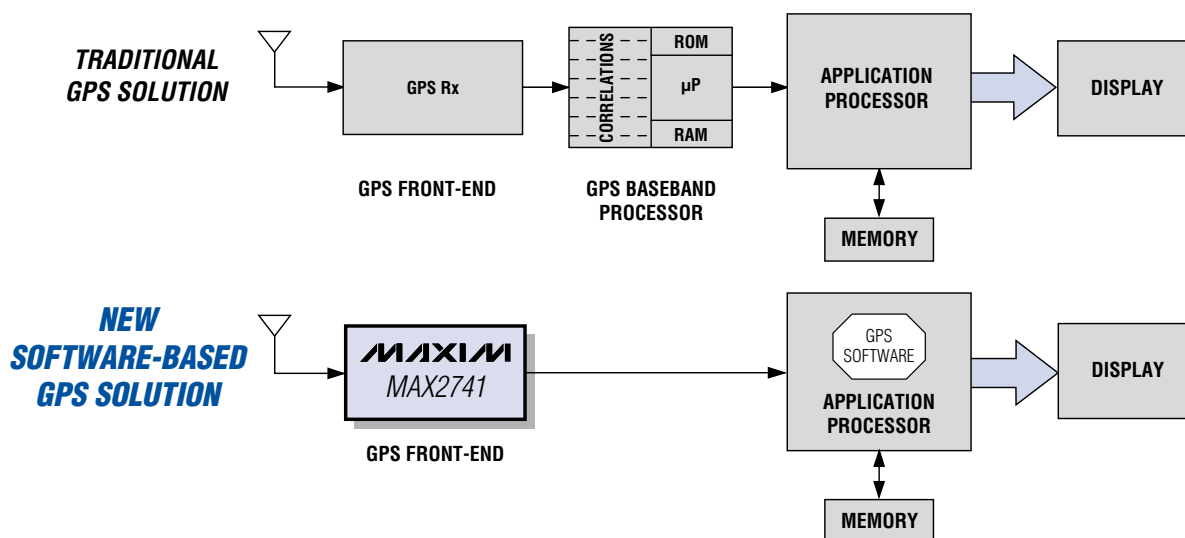


Turn Your UMPC or Laptop Computer into a Full GPS Navigation System

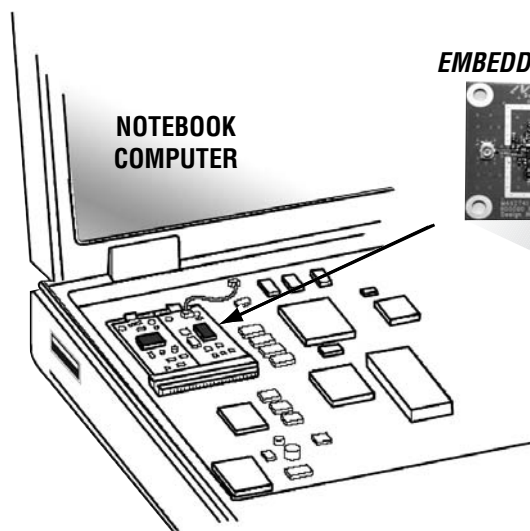
Unique Software-Based GPS Cuts Cost and Size by 50%

Maxim's revolutionary global positioning system (GPS) technique uses the system's host processor to perform all the required GPS calculations and eliminates the need for a costly, bulky GPS baseband IC. In addition, our highly integrated and flexible RF IC, the MAX2741, maximizes the reuse of other system resources, such as the reference clock. Also, the low BOM count of this software-based GPS further reduces the size and cost of your GPS solution.

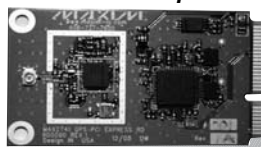
Maxim's GPS solution offers unmatched flexibility to broaden the number of location-based applications in ultra-mobile PCs (UMPCs), laptops, PDAs, and smartphones. Available in both stand-alone and assisted GPS modes and various form factors, the software can be optimized for different usage models, such as automotive navigation, personal navigation, or single-position-fix applications.



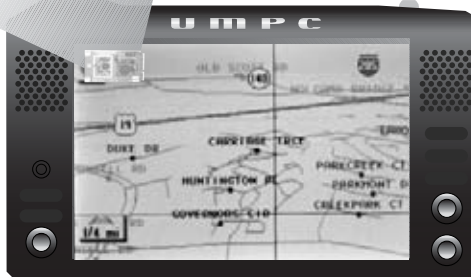
Complete USB and PCI Express® Reference Designs Available



EMBEDDED PCI Express GPS



For More Information on How Our Unique Software-Based GPS Solution Cuts Cost and Size, Visit:
www.maxim-ic.com/SoftwareGPS

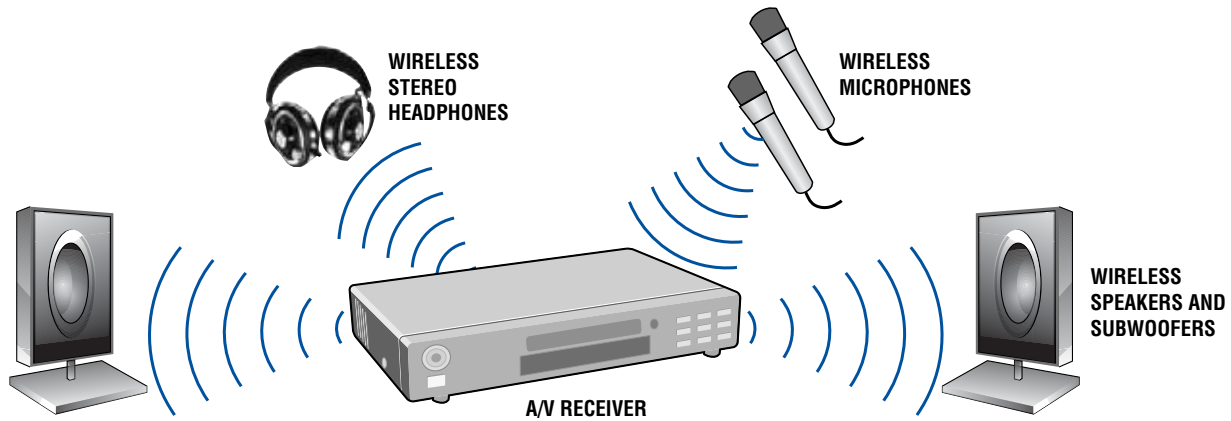


ULTRA-MOBILE PC

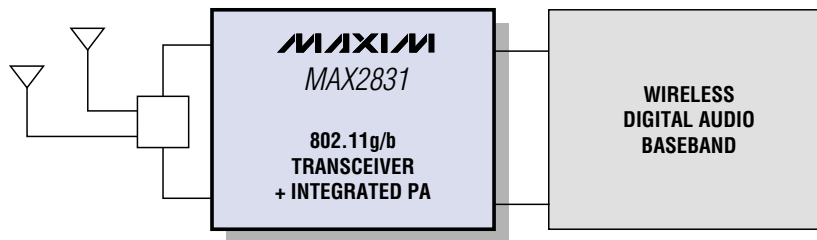
PCI Express is a registered trademark of PCI-SIG Corp.



Complete Digital Wireless Audio Reference Design Provides CD-Quality Audio and Longest Range



DIGITAL WIRELESS AUDIO REFERENCE DESIGN



Digital Wireless Audio Reference Design

- Robust Coexistence and Interference-Resistant Performance
- CD-Quality Digital Audio (Up to 16 Bit/48kps Uncompressed)
- Up to Four Channels per Wireless Link
- Point-to-Multipoint Unidirectional Audio Link
- Bidirectional Data Link Up to 20kbps
- Low Latency (Configurable Up to 17ms)
- 50m Indoor Range, 100m Outdoor Range

MAX2831 RF Performance

- Ultra-Low 65mA Receive Current
- 10 μ A Shutdown Current
- Best-in-Class Sensitivity (-75dBm at 54Mbps 802.11g)
- Integrated +18dBm 802.11g PA
- Integrated Crystal Oscillator Allows Use of Low-Cost Crystals
- Lowest BOM Cost Solution

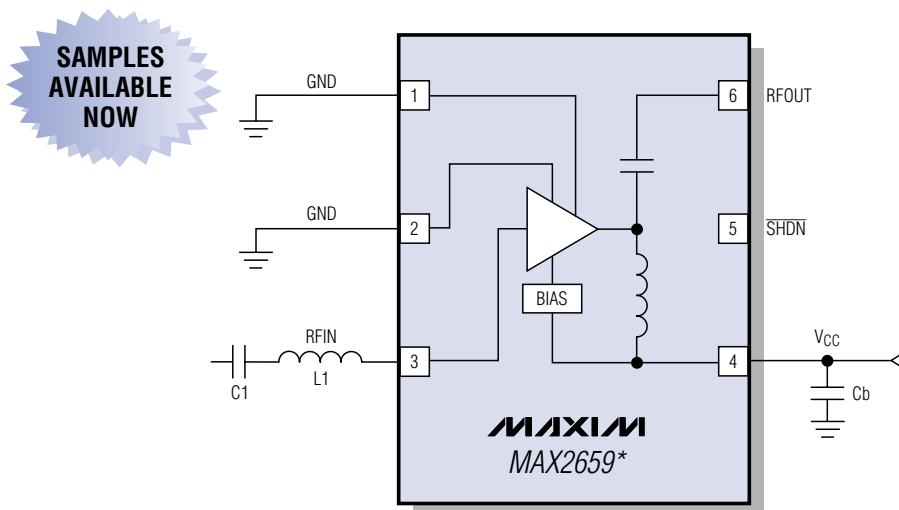
The Full Digital Wireless Audio Reference Design Is Available upon Request.
For More Information, Contact Us at: WLAN@maximhq.com



0.9dB Noise Figure, 20dB Gain, GPS Low-Noise Amplifier (LNA) Improves Performance over Your Existing Solution

Ultra-Small Leadless Packaging Saves Size and Cost

Designed for GPS applications, the MAX2659* LNA operates at the GPS frequency 1575.42MHz with 20dB of gain and a low noise figure of 0.9dB. This high-performance device operates from a +1.6V to +3.3V single supply while only consuming a 4mA supply current. In addition, the MAX2659 includes a 50 Ω output-matching circuit and a shutdown-control pin. This LNA is available in a miniature 1.5mm x 1.0mm x 0.75mm, leadless 6-pin TDFN package.



INPUT MATCH $L1 = 6.5nH$
INPUT DC BLOCK $C1 = 1800pF$
SUPPLY BYPASS $Cb = 33nF$

- High 20dB Gain
- Ultra-Low 0.9dB Noise Figure
- Integrated 50 Ω Output-Matching Circuit
- 4mA Supply Current
- +1.6V to +3.3V Supply Voltage
- Ultra-Small, RoHS-Compatible, Leadless 6-Pin TDFN Package

For More Information on Maxim's GPS Solutions,
Go to: www.maxim-ic.com/GPS

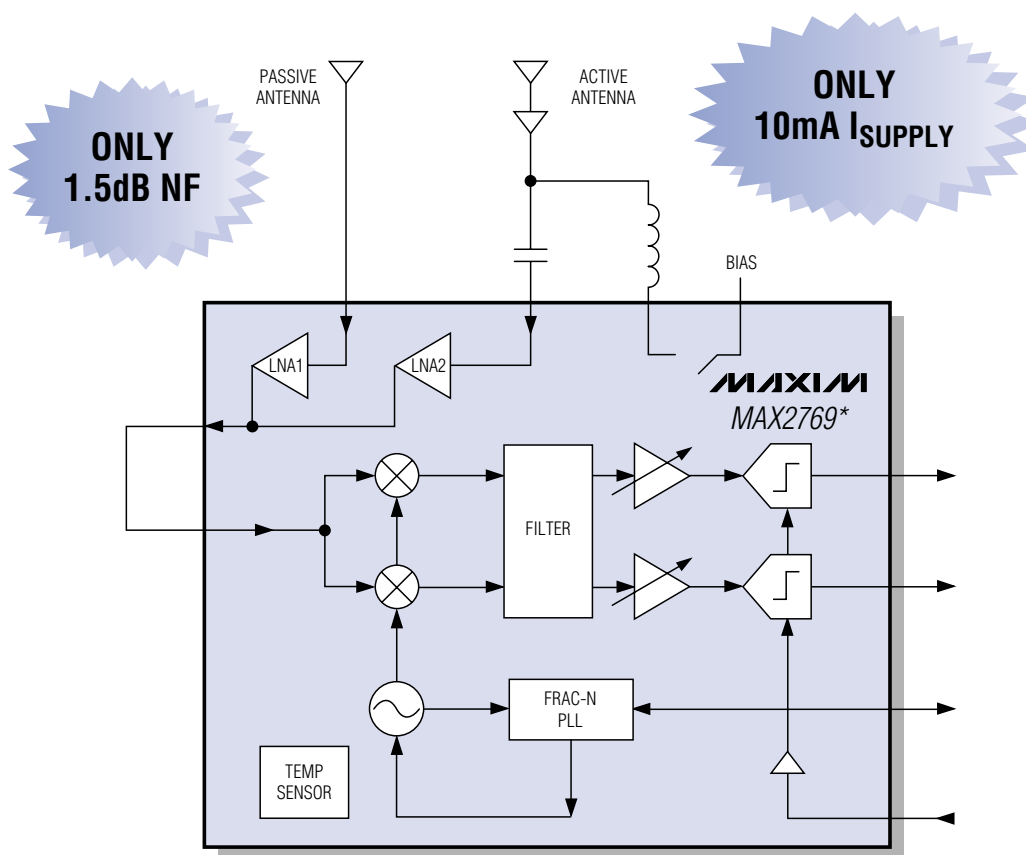
*Future product—contact factory for availability.



Is Your GPS System Performance Limited by Your RF Front-End?

Improve Your GPS and Galileo Performance and Reduce Cost with the First Fully Programmable, Universal GNSS RF Receiver

The MAX2769* is a single-conversion, low-IF GPS receiver offering a minimum NF of 1.5dB. The integrated ADC output is quantized in 1 or 2 bits for both I and Q channels, or up to 4 bits for the I channel. The fully integrated fractional-N synthesizer and VCO enable programming of the IF frequency between 0 and 8MHz, while operating with any reference frequencies ranging from 8MHz to 44MHz. The MAX2769 includes an integrated active-antenna sensor and a dual-input uncommitted LNA for separate passive- and active-antenna inputs. With its programmable power-savings mode, the MAX2769 consumes as low as 10mA.



Three Packages Available

- Leadless 28-Pin QFN
- Wafer-Level Packaging (WLP)
- Known-Good Die (KGD)

SAMPLES
AVAILABLE

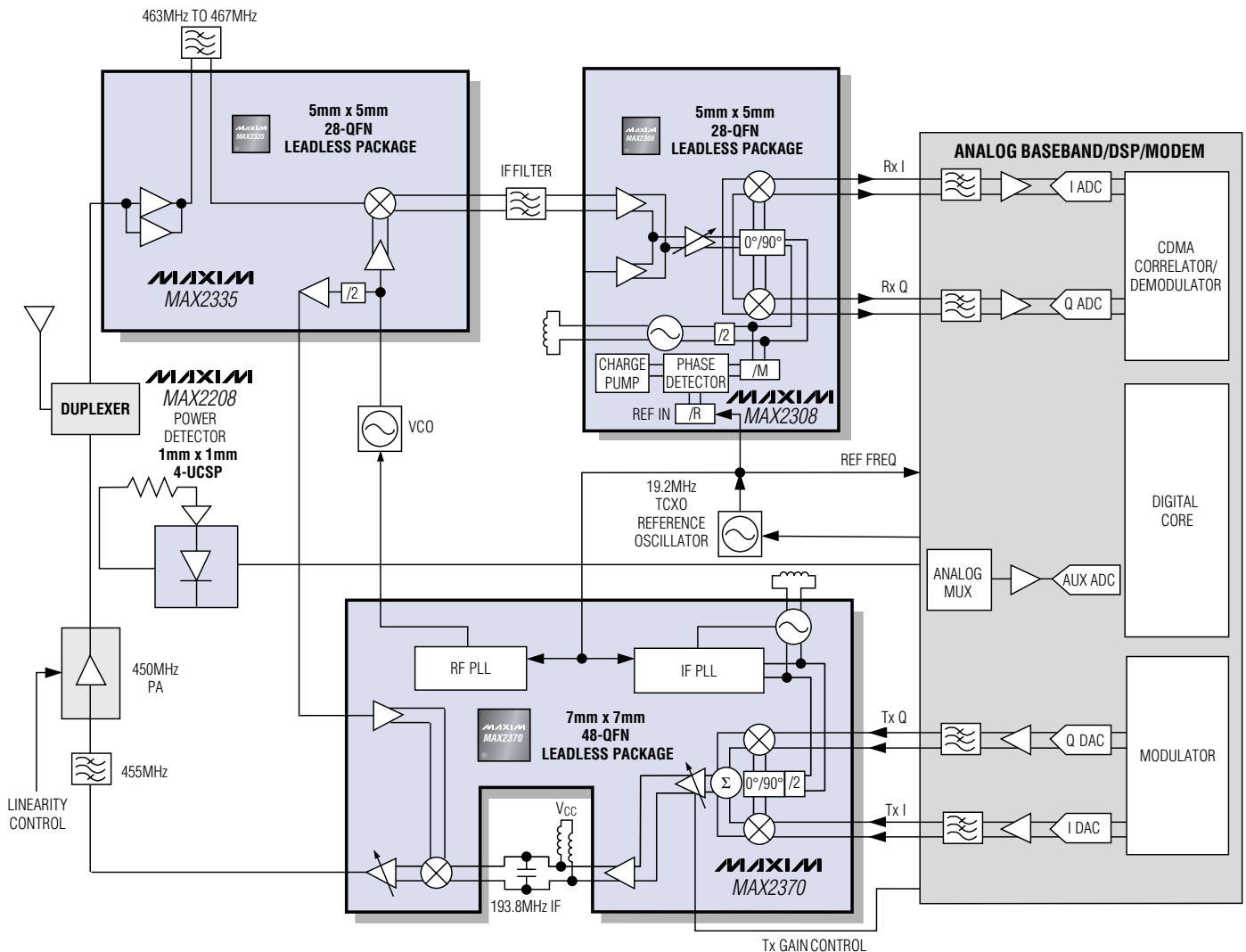
Ideal for

- Cellular E911/E112
- Location-Based Services
- Asset Tracking/Telematics
- Portable Navigation System
- Automotive Navigation
- Digital Cameras

*Future product—contact factory for availability.

Production-Ready 450MHz RF Chipset for Your OFDM or CDMA System Design

Based on the successful versions of our 800MHz and 1900MHz cellular chipsets, the MAX2335 LNA/mixer, MAX2308 IF Rx, and MAX2370 quadrature Tx provide an easy-to-implement, low-cost, high-performance solution for your 450MHz system.



MAX2335 LNA/Mixer

- 2.2dB Cascade Noise Figure
- Low-Gain Mode Minimizes Average Current
- LO Output Buffer for Use with MAX2370 Tx

MAX2308 IF Rx

- Complete IF Subsystem Includes VCO and Synthesizer
- VGA with > 110dB Gain Control
- Quadrature Demodulator

MAX2370 Quadrature Tx

- +10dBm (typ) Output Power
- -66dBc (typ) ACPR at ± 1.125 MHz Offset
- Dual Synthesizer for RF and IF Local Oscillators

Widest Range of Digital Broadcast Radio Tuners

Maxim's digital radio receivers enable highly integrated, cost-effective designs that are very space efficient. Digital radio is going global, and Maxim has solutions for every part of the world.

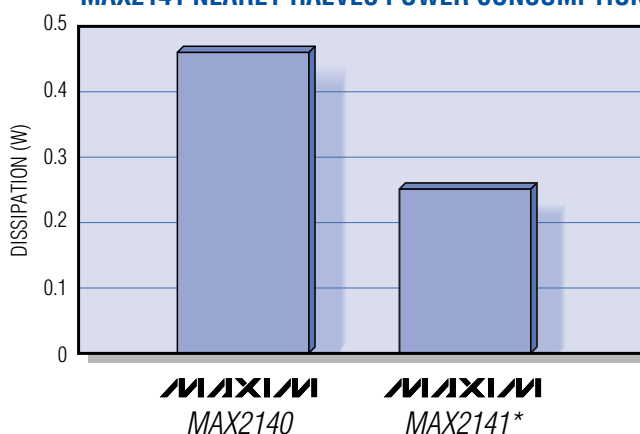
Digital Audio Receivers for International Standards

Part	Standard	Region
MAX2141*	SDARS	North America
MAX2161/MAX2162	ISDB-Tsb	Japan/Brazil
MAX2170	DAB	Europe/Canada

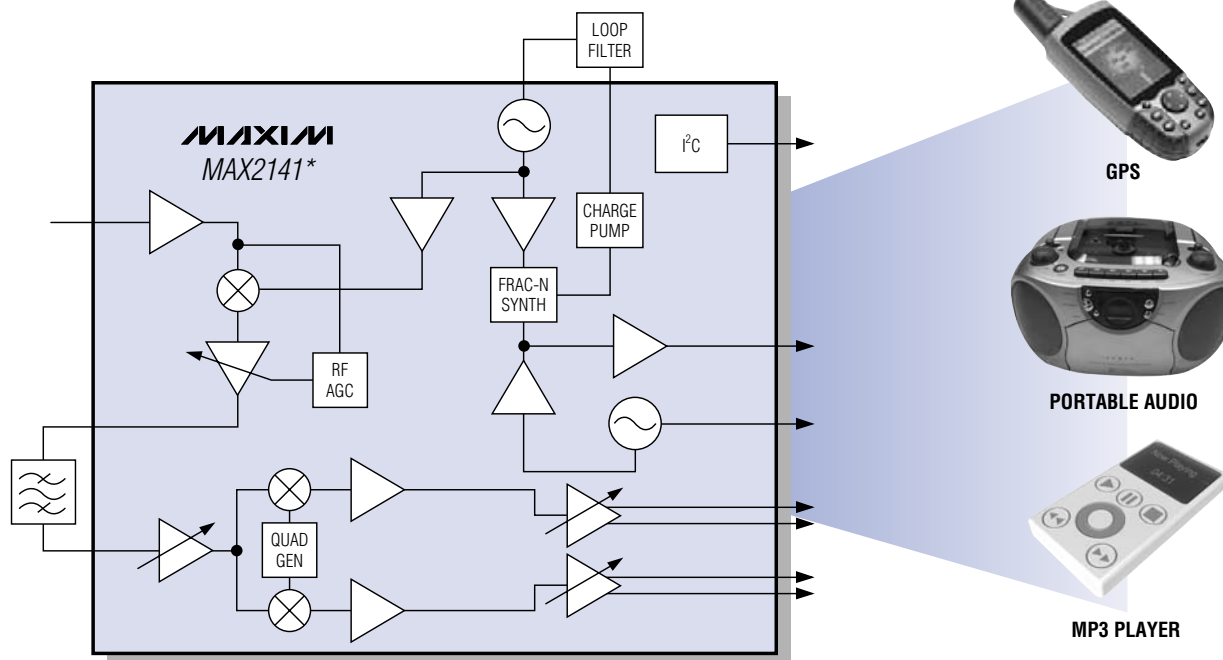
MAX2141* Enables Low-Power Broadband XM Satellite Radio® Receivers

The MAX2141 is Maxim's second-generation dual-ensemble receiver featuring low power consumption for XM Satellite Radio applications. It is pin compatible with the industry-standard MAX2140. Also, its much lower heat dissipation allows for placement into an automotive radio head.

MAX2141 NEARLY HALVES POWER CONSUMPTION



IDEAL FOR SDARS LOW-POWER APPLICATIONS



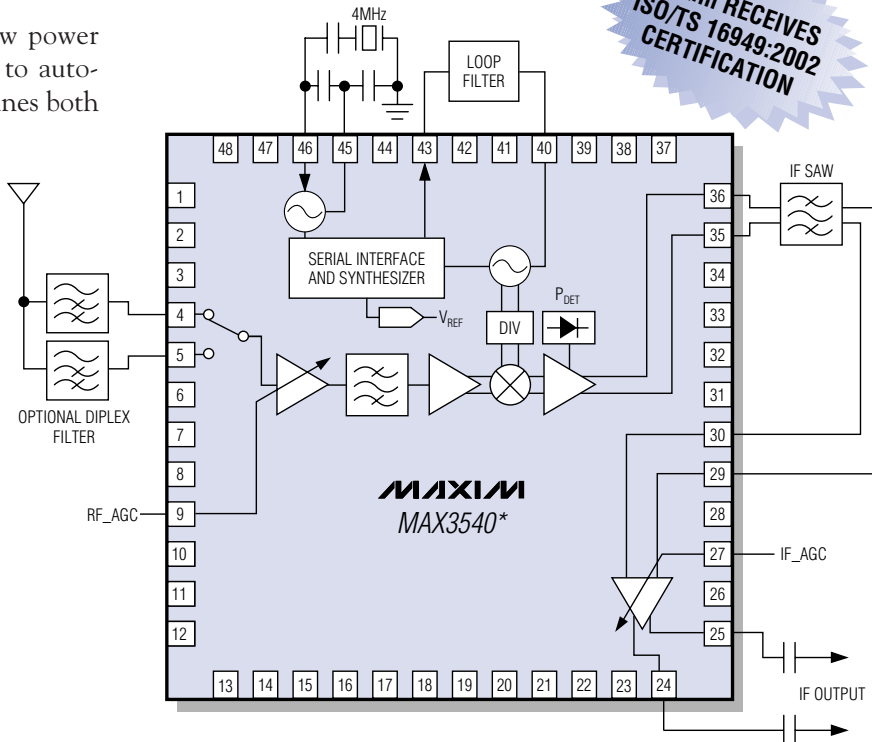
XM Satellite Radio is a registered trademark of XM Satellite Radio, Inc.
 *Future product—contact factory for availability.

Maxim's Television Tuners Expand Automotive Entertainment Options

Ultra-Compact MAX3540* Tunes Analog and Digital TV

The MAX3540's small size and low power consumption make it uniquely suitable to automotive TV. Its traditional architecture tunes both analog and digital TV signals.

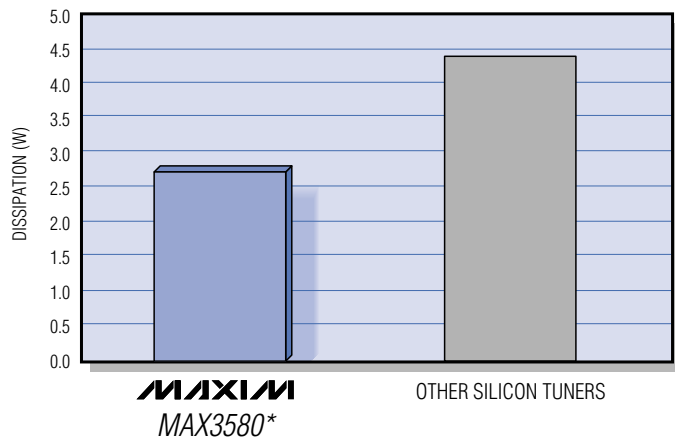
- 50MHz to 860MHz Frequency Range
- 36MHz/44MHz IF Frequency
- On-Chip Triple-Band Tracking Filter
- ATSC, NTSC, and PAL Compliant
- 800mW Power Dissipation
- 3.3V Supply



MAX3580's Novel Architecture Drastically Shrinks Automotive Diversity Tuner Designs, Meets MBRAI and NorDig Requirements

The MAX3580* is a multistandard digital TV tuner covering DVB-T (Europe), DMB-T/H (China), and ISDB-T 13 segment (Japan). Its direct-conversion architecture eliminates SAW filters. On-chip RF filtering reduces the need for external RF filtering, typically needed by traditional CAN-type tuners. This integration results in a greatly reduced overall solution size. The MAX3580 is specified to operate over the -40°C to +85°C temperature range.

POWER DISSIPATION IN A FOUR-TUNER AUTOMOTIVE DIGITAL TV



Broadcast standards dedicated to mobile TV are becoming established or are on the way in many countries around the world. Maxim offers a full range of solutions for mobile TV tuners.

*Future product—contact factory for availability.

Maxim's Full Range of Mobile TV Tuners

Part	Standard	Region
MAX2160	ISDB-T 1 segment	Japan/Brazil
MAX2165*	DVB-H, DVB-T	Europe
MAX2170*	DMB-T	Europe/China
MAX3540*	ATSC, NTSC, PAL	All
MAX3580*	DVB-T, DMB-T/H ISDB-T 13 segment	Europe/China/ Japan

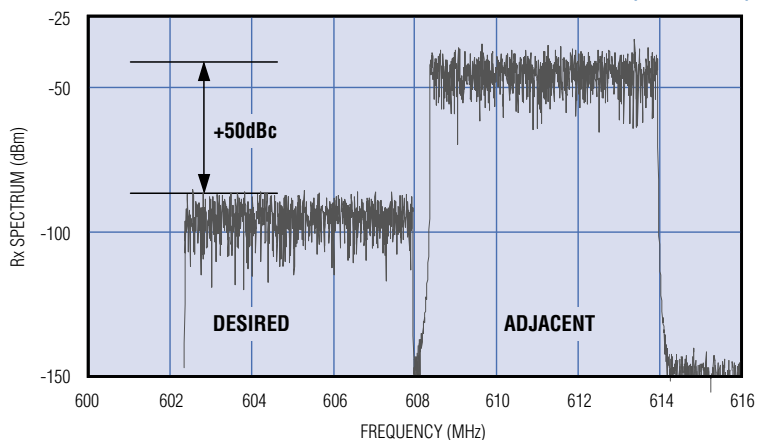
Mobile TV and Digital Radio Tuners for Japan and Brazil

Maxim Sets the Standard for Mobile TV/Radio

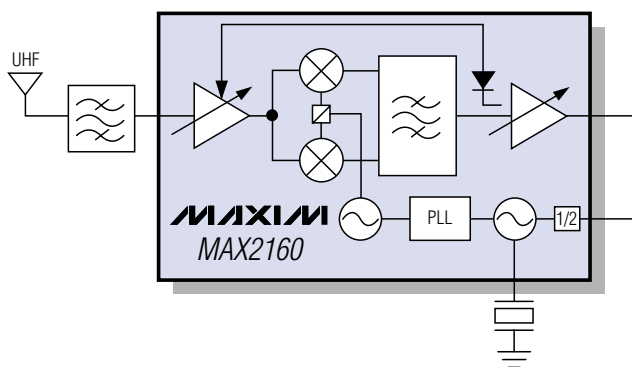
Superior adjacent-channel performance and leading-edge, flip-chip packaging combine to make an unparalleled mobile ISDB-T solution for cellular, portable, automotive, and gaming applications.

The MAX2160/MAX2161/MAX2162* mobile ISDB-T solutions set the standard for adjacent-channel protection ratio at better than 50dBc for both analog and digital adjacent channels.

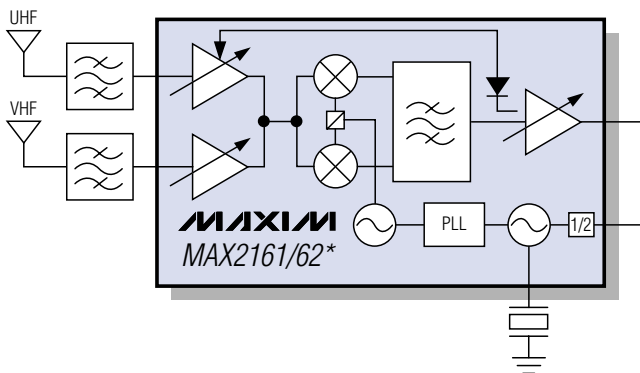
ADJACENT-CHANNEL PROTECTION IN VHF BAND (MAX2161)



MAX2160 1-SEGMENT UHF

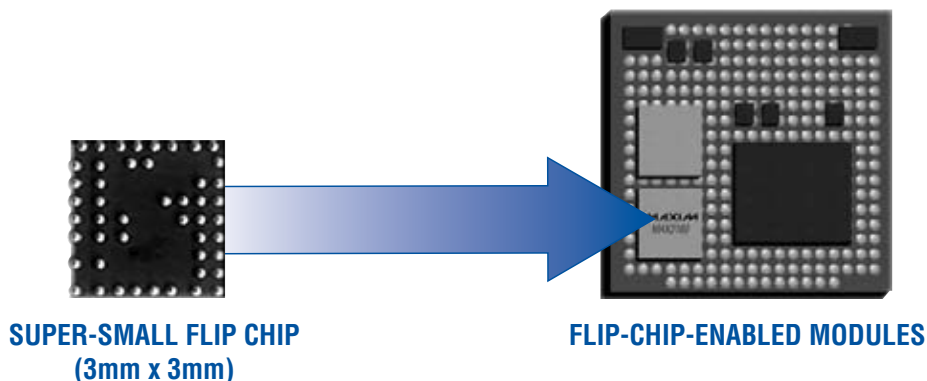


MAX2161/MAX2162 1-/3-SEGMENT VHF/UHF



Maxim Leads the Way with Fully RF-Tested Flip-Chip Solutions

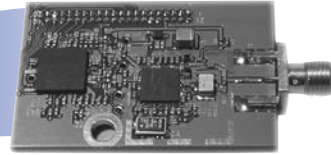
Production RF-tested flip-chip technology enables the smallest modules and system-in-package (SiP) solutions. Along with flip-chip packages, the MAX2160/MAX2161/MAX2162 are also available in a lead-free QFN and bare die.



*Future product—contact factory for availability.

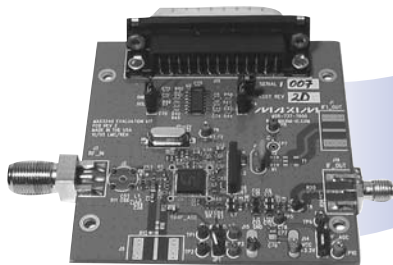
Maxim's RF TV and Radio Group Provides

DAB RADIO IN CANADA

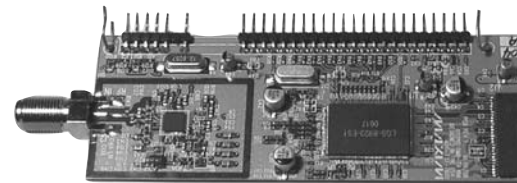


**MAX2170* DAB USB DONGLE
REFERENCE DESIGN**

DIGITAL TERRESTRIAL
TV IN THE US

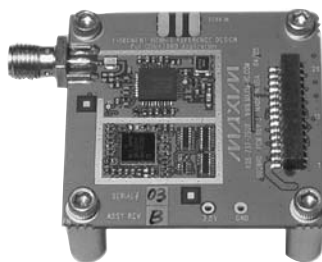


MAX3540* ATSC TUNER BOARD



MAX3580* DVB-T REFERENCE DESIGN

Maxim has a worldwide team of dedicated field application engineers to assist in application of RF tuner ICs and reference designs. This extensive team can call upon decades of RF design experience with Maxim's Wireless Business Unit to overcome your unique challenges.

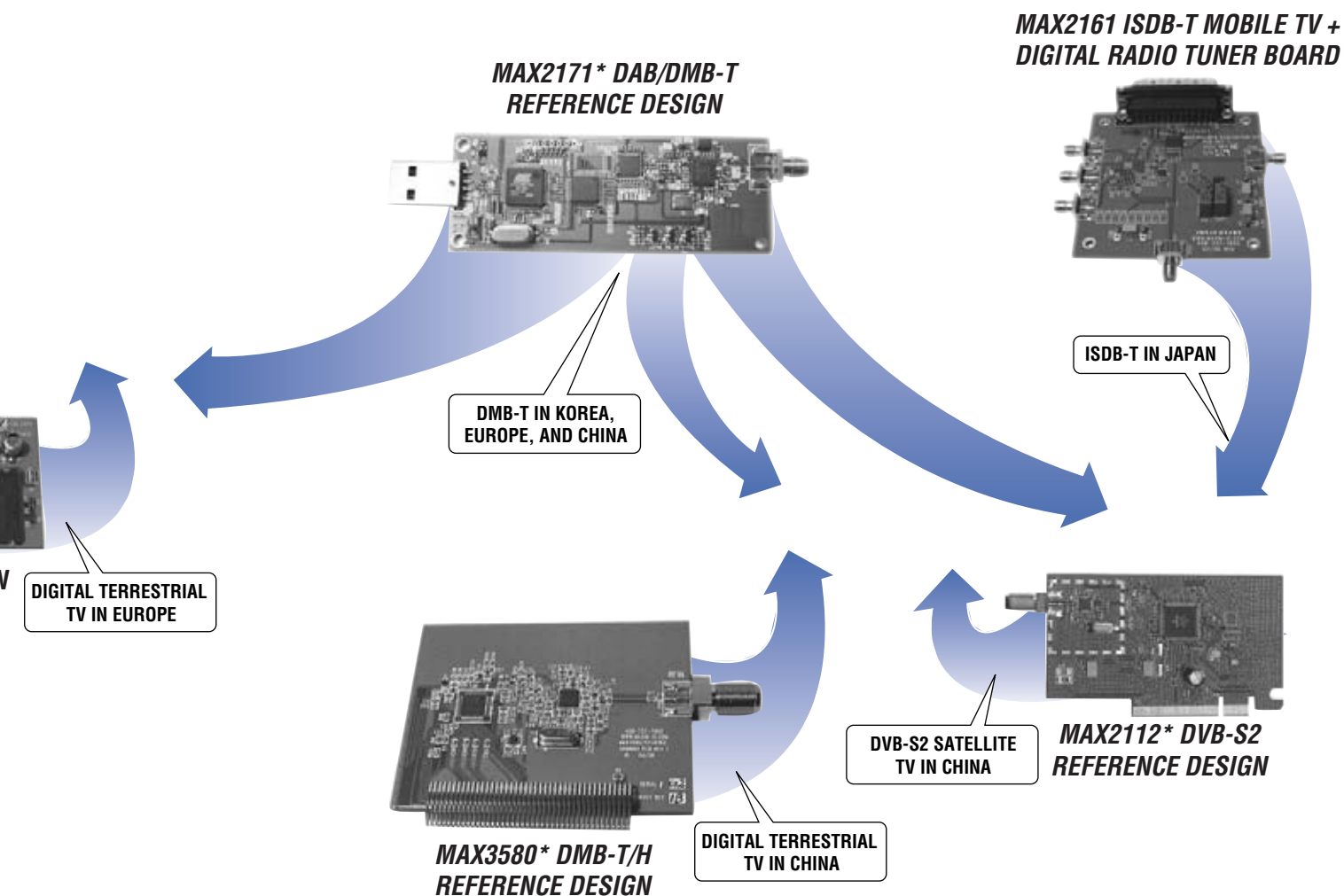


**MAX2160 ISDB-T MOBILE TV
REFERENCE DESIGN**

MOBILE TV AND DIGITAL
RADIO IN BRAZIL

*Future product—contact factory for availability.

Applications Support with Global Reach



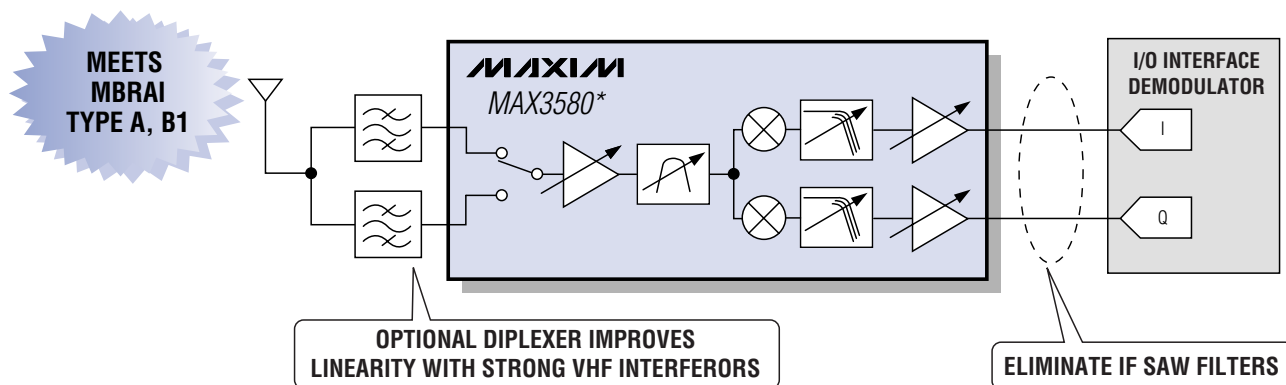
Maxim's TV and Radio Group operates several strategic applications labs inside and outside the US to develop reference design boards combining Maxim RF tuners with industry-leading digital baseband ICs. Please let us know which baseband demodulator partner you would like to work with for your set-top box or mobile TV application.

*Future product—contact factory for availability.

Digital Terrestrial-TV Tuners for Mobile, Portable, and Set-Top Applications

MAX3580* VHF/UHF DVB-T Tuner

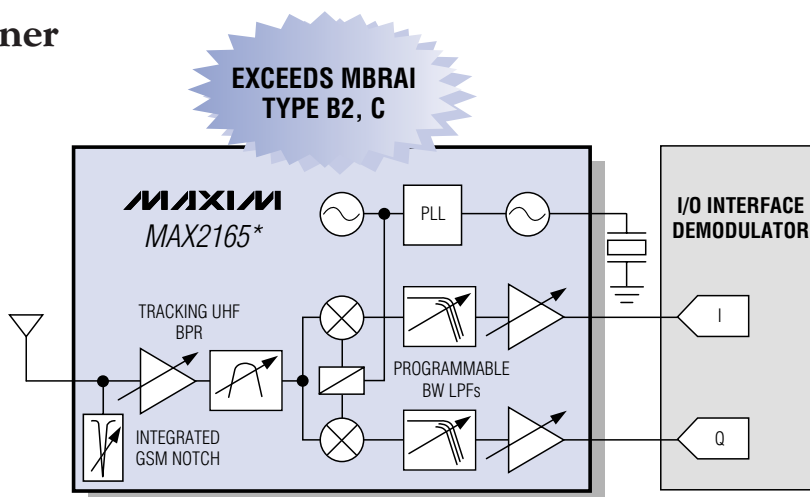
The MAX3580 3.3V digital TV tuner is compatible with DVB-T, ISDB-T, and DMB-T/H standards for both portable and set-top applications, while meeting MBRAI and NorDig industry standards.



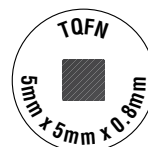
- 6/7/8MHz Channels (Variable BW-LPF)
- Integrated RF-Tracking Filters
- Integrated DC-Offset Correction
- MBRAI and NorDig Unified 1.0.2 Compliant

MAX2165* UHF DVB-H Tuner

- 6/7/8MHz Channels (Variable BW-LPF)
- Integrated RF-Tracking Filter
- Integrated DC-Offset Correction
- MBRAI and NorDig Unified 1.0.2 Compliant
- +2.85V Supply Voltage



Feature	MAX3580*	MAX2165*
Bands	VHF/UHF	UHF
Standards	DVB-T, ISBD-T (13 segment), DMB-T/H	DVB-H, DVB-T (UHF)
Cellular notch	—	Yes
Typical NF (dB)	5	3.5
MBRAI compliance	Type A, B1	Type B1, C
Package (5mm x 5mm)	32-TQFN	28-TQFN
Power consumption (mW)	680	24 at 8% duty cycle



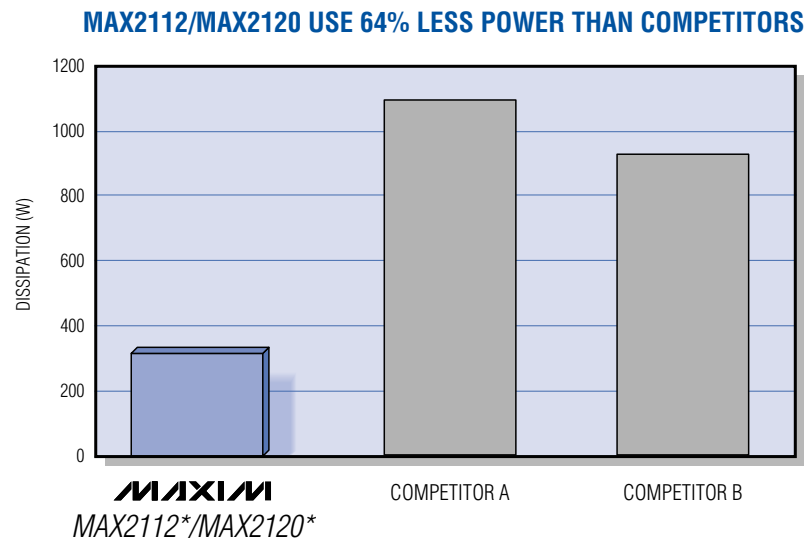
*Future product—contact factory for availability.



3.3V Satellite Tuners Boast 8PSK Performance at Only 330mW of Power Consumption

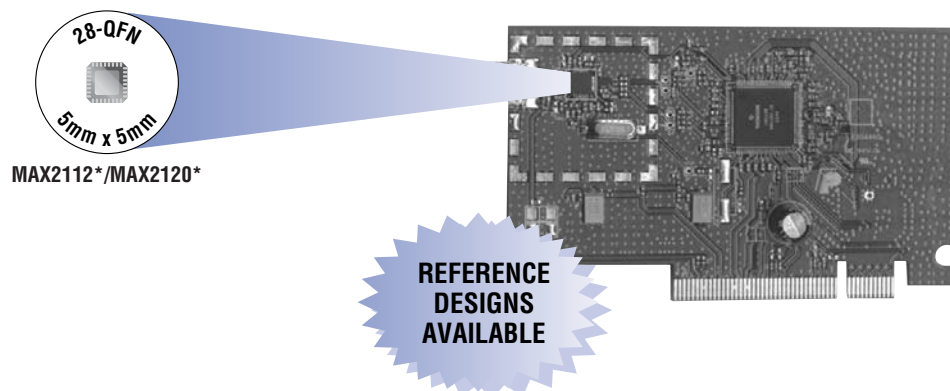
Small Package Is Ideal for Multituner Set-Top Applications

The MAX2112*/MAX2120*, Maxim's newest satellite tuners, offer the highest performance at the lowest power of any competitive solution. The MAX2112 meets DVB-S2 requirements, while the MAX2120 is targeted for the highly competitive DVB-S market.



- 3.3V Supply
- 8dB NF Enables Reception of Weak Free-to-Air Signals
- IIP3 of +15dBm Provides Immunity from Adjacent-Channel Interference
- Automatic Configuration of PLL and VCO Simplifies Firmware
- Operation at -40°C Enables Outdoor Applications
- Small 5mm x 5mm, 28-Pin QFN Package

VERY SMALL SOLUTION FOOTPRINT REQUIRES LESS THAN 9cm² OF PCB AREA



*Future product—contact factory for availability.

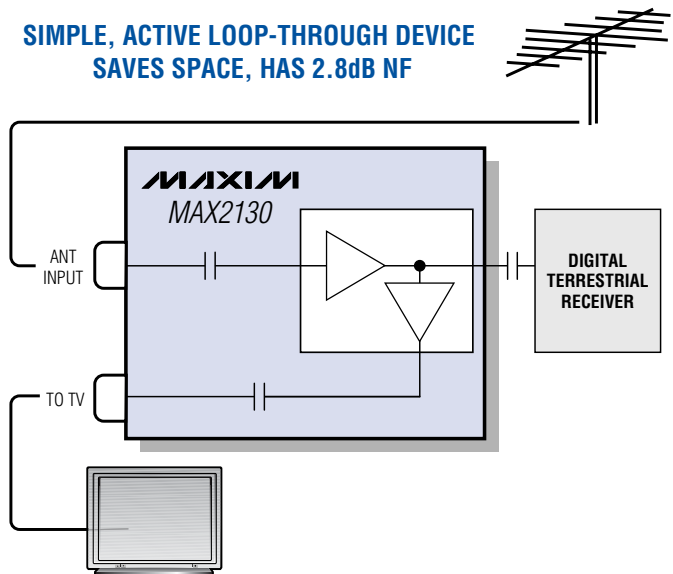
Low-Noise Amp for TV Tuners and Set-Top Boxes

Eliminates Broadband Splitter and Improves SNR

The MAX2130 is ideal for digital terrestrial receivers (DVB-T or VSB). The amplifier has a low 2.8dB noise figure and an IIP3 of 17.5dBm. The MAX2130 also has a second integrated loop-through output. The unbalanced input and outputs allow use with existing canned-tuner architectures.

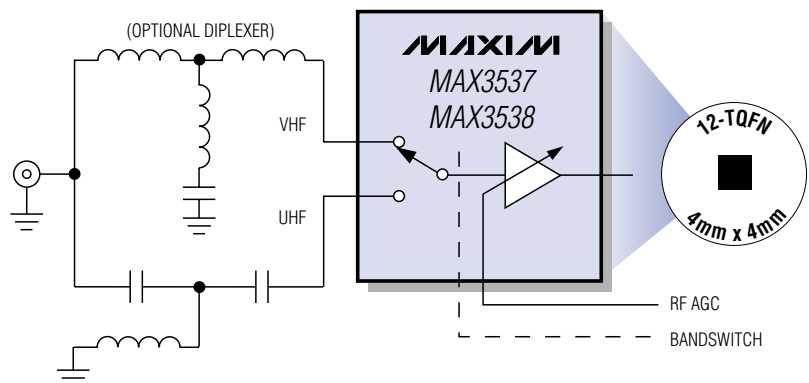
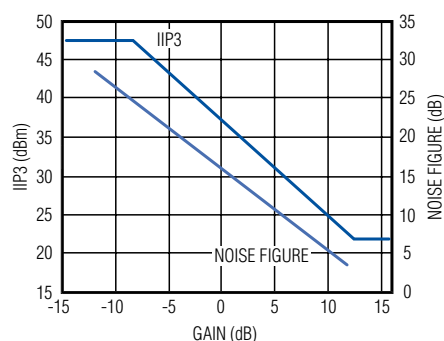
When used with a pin-diode attenuator, the low-noise MAX2130 provides enough gain (15dB) at low input levels to deliver an acceptable signal-to-noise ratio (SNR) to the receiver. Also, it simultaneously provides low distortion during high signal-level conditions. The loop-through output eliminates the need for a splitter or directional coupler to provide a TO TV output. The part requires a 5V supply and draws 93mA.

**SIMPLE, ACTIVE LOOP-THROUGH DEVICE
SAVES SPACE, HAS 2.8dB NF**



Broadband Variable-Gain Amps Meet Tough Linearity Requirements, Improve TV-Tuner NF and AGC Range

IIP3 AND NOISE FIGURE vs. GAIN

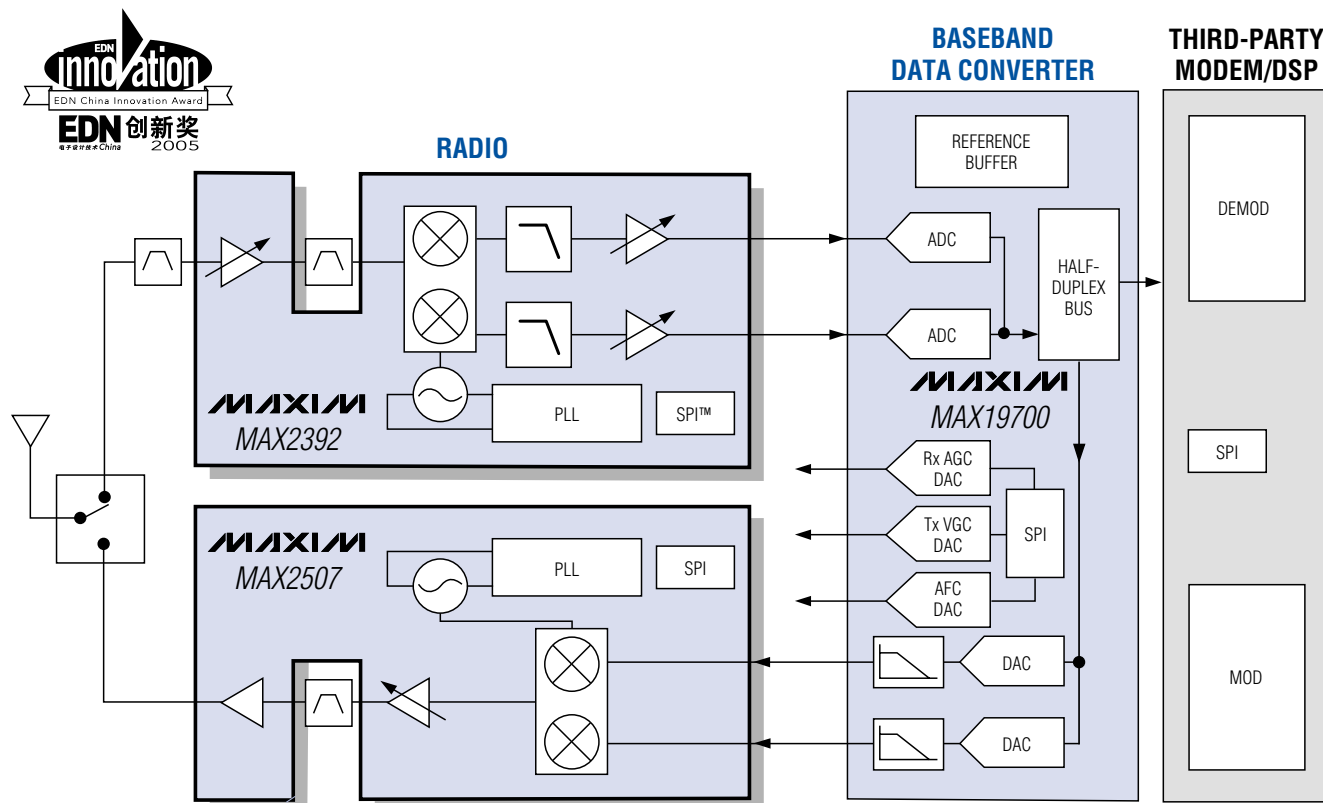


- 50MHz to 878MHz Operating Frequency Range
- Improve Sensitivity for Low-Input-Power Applications
- Very High IIP3: +33dBm at 12dB Backoff

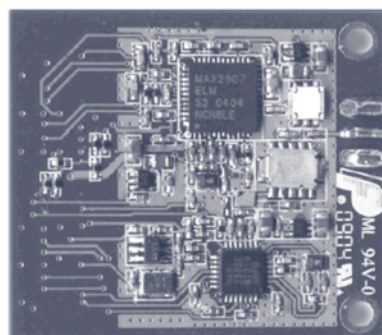
- On-Chip Bandswitch Works with External Diplex Filter to Significantly Reduce 2nd-Order Distortion
- Single-Ended Inputs and Outputs Eliminate Expensive Baluns

Save Size and BOM Cost with Two-Chip TD-SCDMA Zero-IF Radio Architecture

Maxim's zero-IF radio architecture reduces implementation size and saves BOM cost[†] by eliminating components such as PA and IF SAW filters.

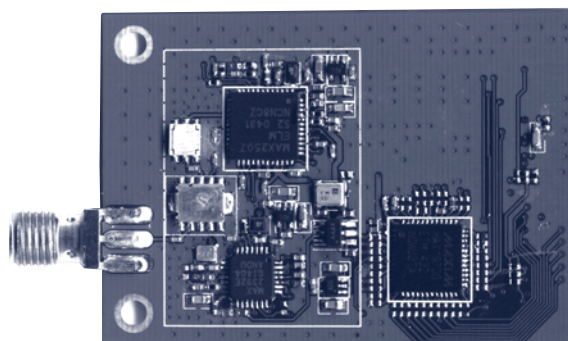


**ANALOG INTERFACE
ZERO-IF REFERENCE DESIGN**



**CHOICE OF TWO
REFERENCE DESIGNS
FOR EASY
IMPLEMENTATION**

**DIGITAL INTERFACE
ZERO-IF REFERENCE DESIGN**



Zero-IF Receivers

Part	Applications	Chip Rate (Mcps)	RF Band (MHz)	Synthesizer
MAX2392	TD-SCDMA	1.28	2010 to 2025	On chip
MAX2393	WDD/TD-SCDMA	3.84/1.28	1900 to 1920	On chip

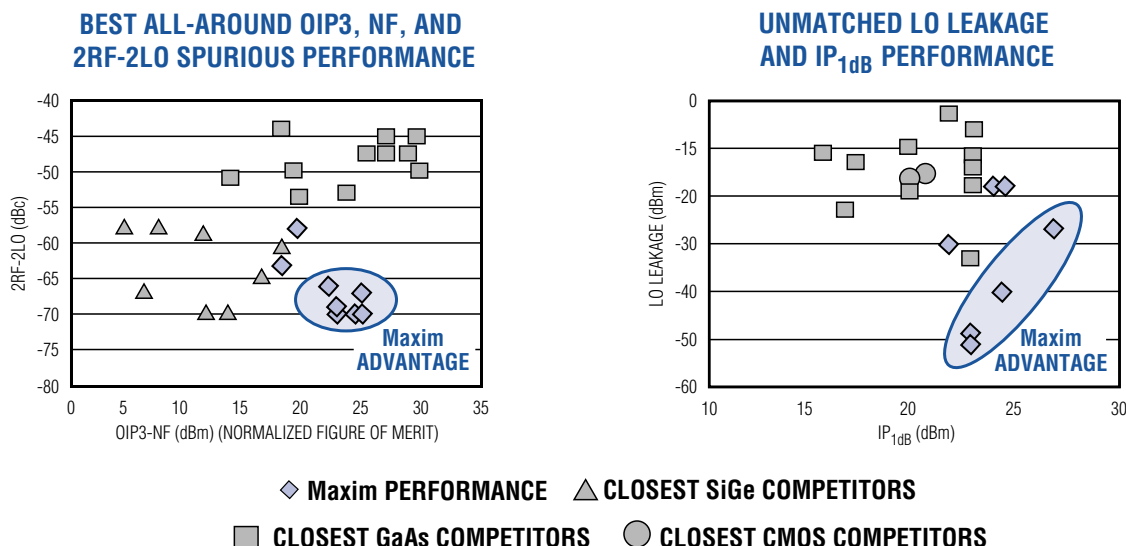
Zero-IF Transmitter

Part	Applications	Chip Rate (Mcps)	RF Band (MHz)	Synthesizer
MAX2507	TD-SCDMA	3.84	2010 to 2025	On chip

SPI is a trademark of Motorola, Inc.
[†]Contact factory for pricing details.

Lowest Noise, Highest Linearity SiGe Mixers

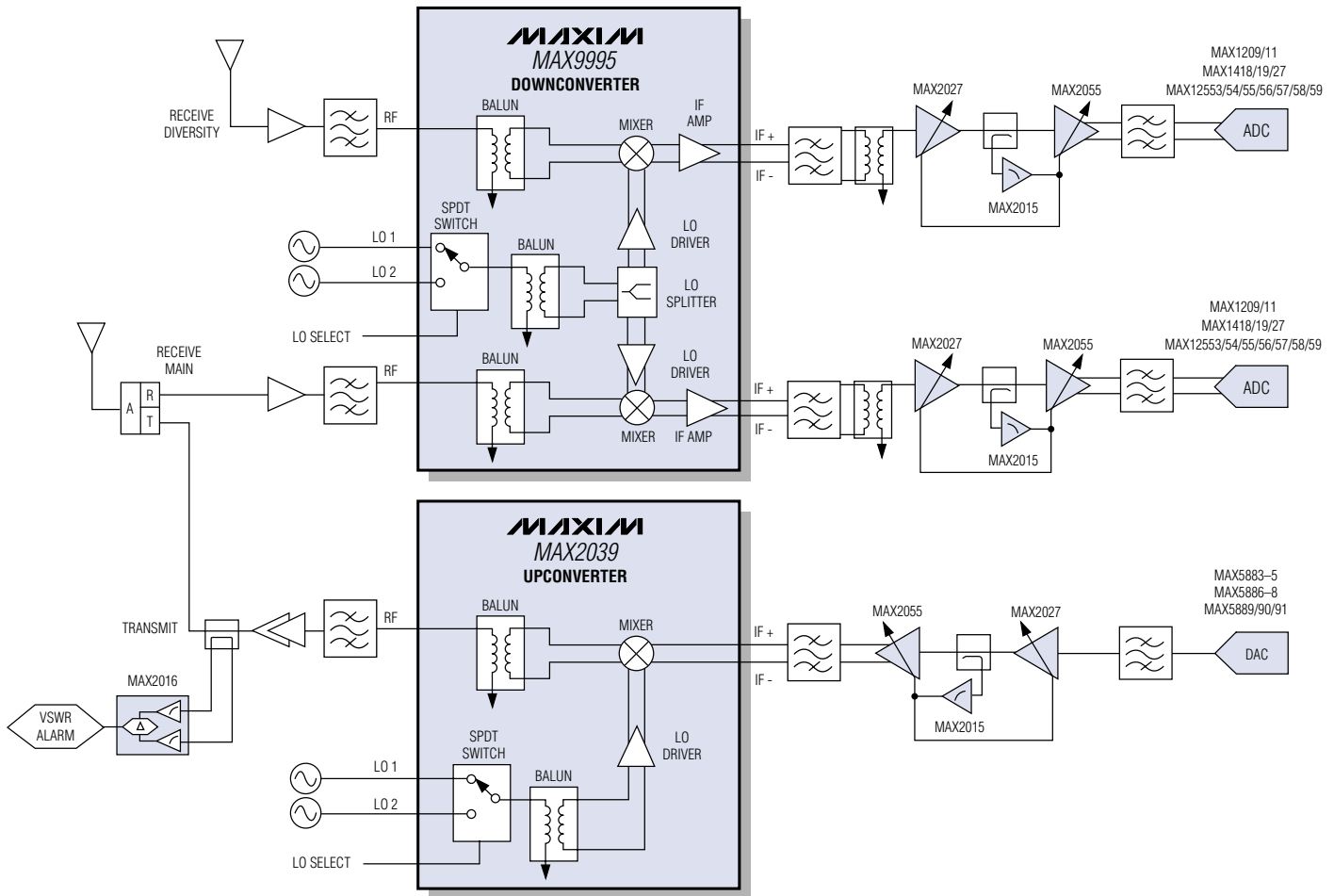
Complete Line of Up-/Downconverters for Wireless Infrastructure



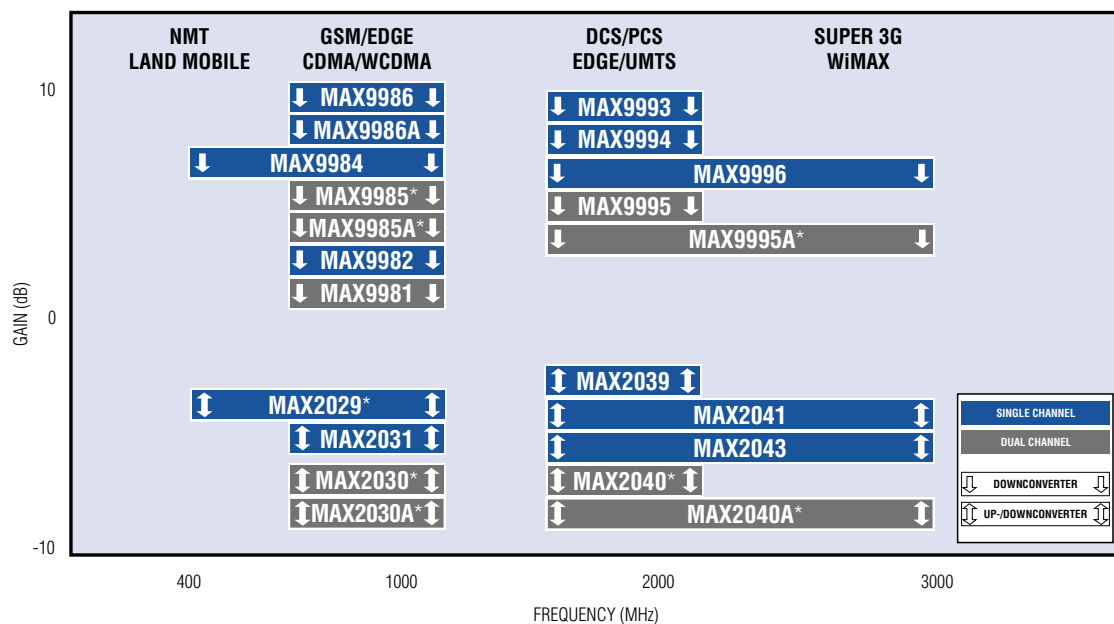
- **Lowest NF Equates to Less Gain Needed Ahead of Mixer, Allowing**
 - Relaxation of ADC Dynamic-Range Requirements
 - Relaxation (or Complete Elimination) of AGC
 - Greater Receiver Resiliency to Blockers
- **Unparalleled 2RF-2LO Performance**
 - Eases Filtering Requirements
 - Allows Design to Employ Lower IF Frequencies, Leading to
 - Easier Frequency Planning
 - Use of More Cost-Effective, Low-IF ADCs
- **Highest Levels of Integration**
 - Low LO Drive Needed Due to On-Chip LO Buffers
 - On-Chip LO Switches Support Frequency Hopping
 - On-Chip IF Amplifiers
 - Integrated RF and LO Baluns
- **Compact, 5mm x 5mm, 20-Pin and 6mm x 6mm, 36-Pin TQFN**
- **Pin-Compatible Parts for the 850MHz/900MHz and 2GHz Bands**

Lowest Noise, Highest Linearity SiGe Mixers

Complete Line of Up-/Downconverters for Wireless Infrastructure

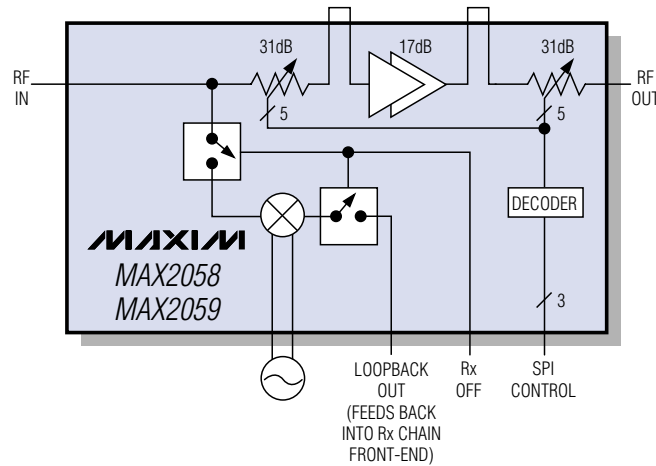


SOLUTIONS COVERING ALL 400MHz TO 3000MHz WIRELESS STANDARDS

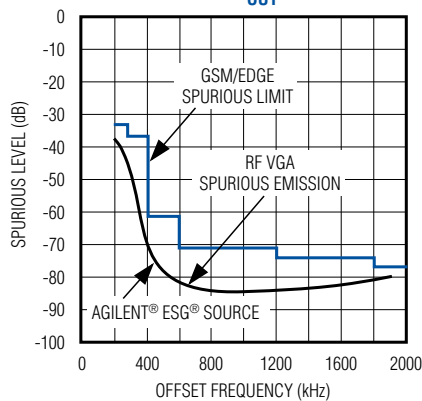


*Future product—contact factory for availability.

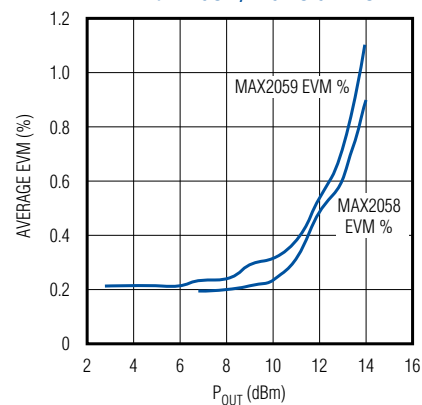
RF VGAs Deliver Up to 62dB of Digitally Controlled Dynamic Range



MEET ALL GSM/EDGE SPURIOUS EMISSIONS LIMITS WITH $P_{OUT} = +12\text{dBm}$



YIELD 0.5% EVM PERFORMANCE FOR +12dBm GSM/EDGE SIGNALS



- **Ideal for GSM/EDGE Applications**
 - 800MHz to 1000MHz (MAX2058)
 - 1800MHz to 2200MHz (MAX2059)
- **Up to 62dB SPI-Controlled Gain Range in 1dB Steps Allows for**
 - 12dB Static Control
 - 30dB Dynamic Control
 - > 10dB Lineup Compensation
 - Maximum Gain of 10.6dB/10.7dB*
- **Excellent Linearity**
 - 32.3dBm/31.8dBm OIP3*
 - 19dBm/18.4dBm OP_{1dB}*

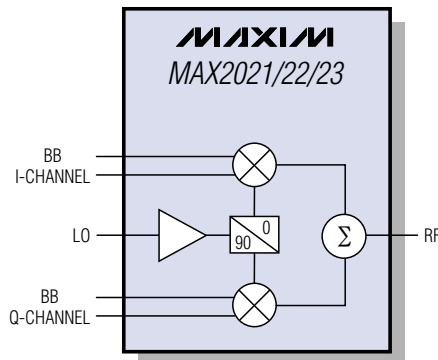
- **Built-In Loopback Test Mixer**
 - Ideal for Performing Simultaneous Diagnostics of the Tx and Rx Chains in Real-Time
 - Switch-In/Switch-Out Capability
- **Matched 50Ω Inputs and Outputs Simplify Design and Reduce Off-Chip Component Cost**
- **Pin-Compatible Lowband and Highband Versions in Space-Saving, 6mm x 6mm, 40-Pin, Lead-Free TQFN**

For More Information on the MAX2058/MAX2059, Go to:
www.maxim-ic.com/MAX2058-9info

Agilent and ESG are registered trademarks of Agilent Technologies.
 *MAX2058/MAX2059, respectively.

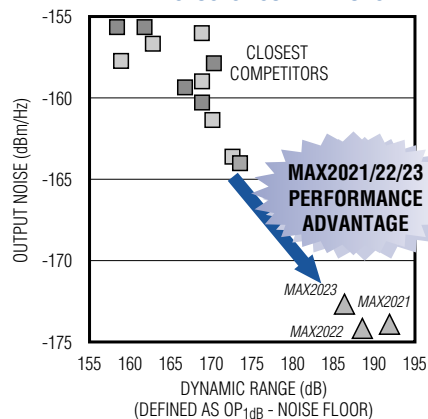
Highest Linearity, Lowest Noise Zero-IF Modulators/Demodulators

**SUPPORT
4-CARRIER
WCDMA**

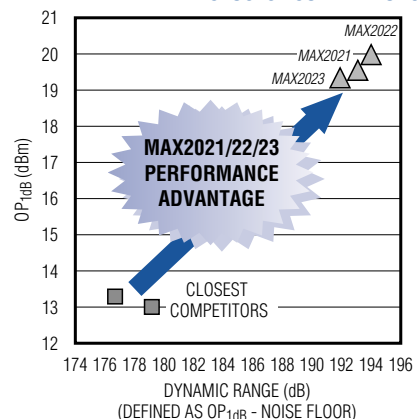


**MAX2022
SELECTED AS ONE OF
Microwaves & RF
MAGAZINE'S TOP
PRODUCTS
FOR 2005**

**MODULATOR MODE: 13dB GREATER
DYNAMIC RANGE, 10dB LESS OUTPUT NOISE
THAN CLOSEST COMPETITORS**



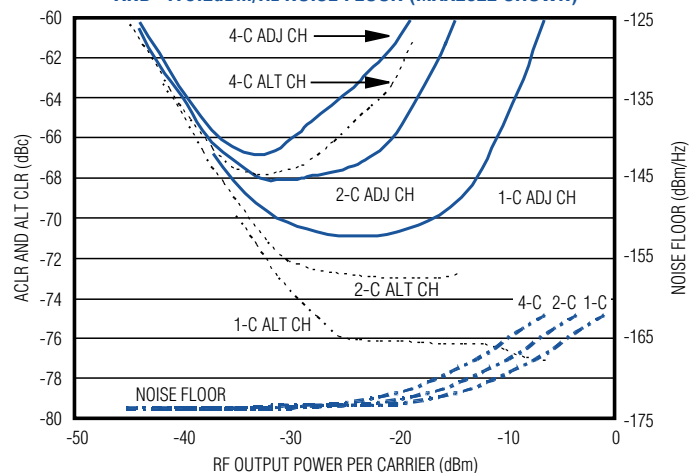
**DEMODULATOR MODE: 15dB GREATER
DYNAMIC RANGE, 7dB GREATER OP_{1dB}
LINEARITY THAN CLOSEST COMPETITORS**



Wide Range of Applications

Feature	MAX2021	MAX2022	MAX2023
RFID	✓		
GSM 850MHz/900MHz	✓		
WCDMA 850MHz	✓		
cdma2000™ 850MHz	✓		
Cable head-end equipment	✓		✓
DCS/PCS		✓	✓
cdma2000 1900MHz		✓	✓
WCDMA/UMTS		✓	✓
2.35GHz/2.7GHz WiMAX		✓	

**TRUE 4-CARRIER UMTS OPERATION
USING -27dBm/CARRIER WITH > 65dBc ACLR
AND -173.2dBm/Hz NOISE FLOOR (MAX2022 SHOWN)**



For More Information on the MAX2022, Go to:
www.maxim-ic.com/2022info

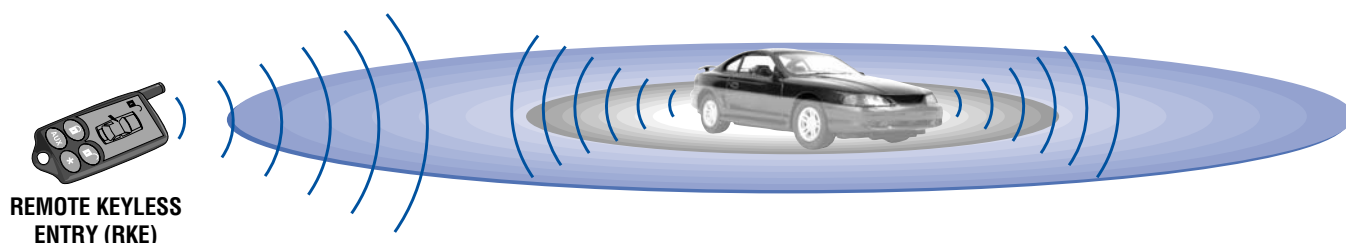
cdma2000 is a trademark of Telecommunications Industry Association.



Industry's Highest Performance Family of 300MHz to 450MHz Transceivers

Increase Range and Add Two-Way Capabilities to Car Alarms, RF Modules, Remote Controls, Wireless Meters, and Home-Security Systems

Maxim's MAX7030/MAX7031/MAX7032 family of crystal-referenced VHF/UHF transceivers are easy-to-use, high-performance devices that allow quick two-way implementation of one-way systems. Housed in small, 5mm x 5mm, 32-pin TQFN packages, these transceivers are perfect for low-cost, high-volume applications where space is critical, such as two-way key fobs, security products, garage-door openers, and remote sensors. These transceivers use a fractional-N PLL for the transmitter and a fixed-N PLL for the receiver, eliminating the need for separate transmit and receive crystal-reference oscillators. The MAX7030/MAX7031/MAX7032 are rated over the entire automotive temperature range (-40°C to +125°C).



- +10dBm Output Power
- 12mA Tx Current (FSK)
- -114dBm (ASK)/-110dBm (FSK) Rx Sensitivity
- 6.1mA Rx Current

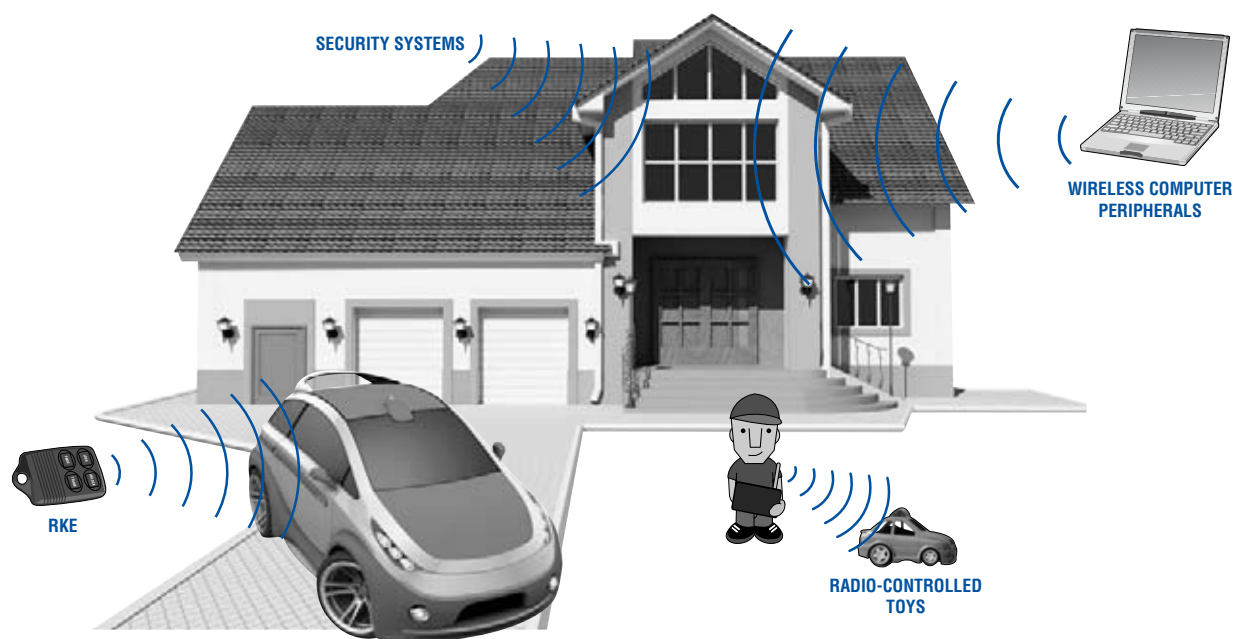
Part	RF Frequency (MHz)	Modulation	FSK Deviation (kHz)
MAX7030LATJ	315	ASK	—
MAX7030MATJ	345	ASK	—
MAX7030HATJ	433.92	ASK	—
MAX7031LATJ	308	FSK	±51.4
MAX7031MATJ15	315	FSK	±15.5
MAX7031MATJ50	315	FSK	±49.5
MAX7031HATJ17	433.92	FSK	±17.2
MAX7031HATJ51	433.92	FSK	±51.7
MAX7032	SPI programmable	ASK/FSK	SPI programmable

For Information on Maxim's RKE Products,
Go to: www.maxim-ic.com/MAX7030DG

300MHz to 450MHz Transmitters and Receivers Double the Range of Your RKE Systems

Ideal for Battery-Powered Equipment, Including Key Fobs, Car Alarms, Home Security, Garage-Door Openers, and Remotes

Maxim offers a range of transmitters and receivers designed for a variety of RKE applications. The MAX1472/MAX7044/MAX1479 have the highest efficiency of any PLL-based transmitter, and the MAX1470/MAX1473/MAX7033/MAX1471/MAX7042 provide the best RF sensitivity.



Ideal for

- RKE and Remote Start
- RF Remote Controls
- Security Systems
- Tire-Pressure Monitoring (TPM)
- Wireless Computer Peripherals
- Wireless Game Consoles
- Wireless Sensors
- Radio-Controlled Toys

Part	Type	Temp Range (°C)	Power Consumption (mA)	RF Performance at 315MHz	Modulation	Price [†] (\$)
MAX1472	Tx	-40 to +125	5.3 (typ) (ASK at 50% duty cycle)	+10dBm output	ASK	0.96
MAX7044	Tx	-40 to +125	7.7 (typ) (ASK at 50% duty cycle)	+13dBm output	ASK	1.05
MAX1479	Tx	-40 to +125	6.7 (typ) (ASK at 50% duty cycle)	+10dBm output	ASK/FSK	0.97
MAX1470	Rx	-40 to +85	5.5 (typ)	-112dBm with 53dB image rejection	ASK	1.51
MAX1473	Rx	-40 to +85	5.2 (typ)	-114dBm with 50dB image rejection	ASK	1.67
MAX7033	Rx	-40 to +105	5.2 (typ)	-114dBm with 50dB image rejection	ASK	1.69
MAX1471	Rx	-40 to +125	7.0 (typ)	-114dBm (ASK)/-108dBm (FSK) with 45dB image rejection	ASK/FSK	2.39
MAX7042	Rx	-40 to +125	6.2 (typ)	-110dBm with 45dB image rejection	FSK	1.80

[†] 10k-up recommended resale. Prices provided are for design guidance and are FOB USA. International prices will differ due to local duties, taxes, and exchange rates. Not all packages are offered in 1k increments, and some may require minimum order quantities.